

DEPARTMENT OF BASIC SCIENCE ACADEMIC YEAR 19-20 EVEN SEMESTER CIRCULAR

Ref No: CEC/BS/DAC/ACY/2019-20/OR/01

Date: 07-02-2020

This is to inform the members of Department Advisory Committee that meeting is scheduled on 12-02-2020 at 10: 00 AM in Physics Laboratory.

Agenda:

- Commencement of classes for 2nd semester students
- Organizing Battle of Science- Project Exhibition
- Organizing value added courses/ circular courses in the curriculum
- Organizing FDP

Dr. Jyothi P Department of Mathematics

HCD Department of Mathematics City Engineering College Doddatallasandra, Bangalore-62



DEPARTMENT OF BASIC SCIENCE

Department Advisory Committee Meeting

Date: 12-02-2020 Time: 10:00 AM Venue: Physics Laboratory

List of DAC Members

Sl. No	Member Name	Designation	Role
1	Dr. P Rajasekar	HOD & Professor	Convenor P Quia
2	Mrs. Sunitha N	Assistant Professor	Member M
3	Mrs. Anu Radha U	Assistant Professor	Member
4	Mrs. Sowmya P	Assistant Professor	Member Courter
5	Dr. K Sujatha	HOD & Professor	Member
6	Mrs. Nagashree G	Assistant Professor	Member GA
7	Mrs. Ashwini Hindiholi	Assistant Professor	Member Achil.
8	Dr. Jyothi P	Associate Professor	Member Lat
9	Vanitha G R	Assistant Professor	Member
10	Mrs. Gayatri	Assistant Professor	Member Gent
11	Mrs. Kalavathi	Assistant Professor	Member Vlad
12	Mrs. Gana Priya	Assistant Professor	Member DerPV
13	Mrs. Reena Patro	Assistant Professor	Member Dan Pobe

Agenda of the Meeting:

- Commencement of classes for 2nd semester students
- Organizing Battle of Science- Project Exhibition
- Organizing value added courses/ certificate courses in the curriculum Organizing FDP



Minutes of Meeting:

The members discussed suggestions for improvement and reviewed the meeting agenda.

- Battle of Science is a project exhibition focuses on displaying interests and diverse projects.
- Discussed about a location with enough space for display of projects and ECE laboratory are chosen for exhibition.
- Setting up a registration process for participants.
- · Providing certificates to all participants and cash prize for winners.
- Certificate Course on public speaking skills to be organized.

D. C. ZajerSen

Convenor Dr. Rajasekhar P Department of Chemistry

Dr P. RAJASEKHAR, M.Sc; M.Phi: Ph.D HE & D OF THE DEPT. OF CHEMISTRY ...Y ENGINEERING COLLEGE, UDDUS' Allasendra, Kanakapura Main Road EANGALORE - 560 062. Ph (O) 26669313 (M) 92428 92734

Dr. Jyothi P Department of Mathematics

HOD Department of Mathematics City Engineering College Docidakallasandra, Bangalore-62

Academic Calendar of VTU, Belagavi for EVEN Semester of 2019-2020 (Jan 2020 – July 2020)

	II Sem B. E. / B. Tech. / B. Arch	IV & VI Sem B. E. /B. Tech. IV, VI&VIII Sem B. Arch.	VIII Sem B.E / B.Tech & X Sem B. Arch	IV Sem MCA	VI Sem MCA	IV Sem MBA	IV Sem M. Tech.	IV Sem M. Arch.	II Sem M. Tech.	II Sem MCA	II Sem MBA	II Sem M. Arch.
Commencement of EVEN Semester	10.02.2020	10.02.2020	10.02.2020	27.01.2020	27.01.2020	10.02.2020	27.01.2020	27.01.2020	05.03.2020	05.03.2020	14.02.2020	14.02.2020
Last Working day of EVEN Semester	01.06.2020	01.06.2020	01.06.2020	20.05.2020	20.05.2020	01.06.2020	20.05.2020	20.05.2020	22.06.2020	22.06.2020	05.06.2020	05.06.2020
Practical Examination	03.06.2020 To 13.06.2020	03.06.2020 To 13.06.2020	-	26.05.2020 To 30.05.2020		4	-		25.06.2020 To	25.06.2020 To	_	
Theory Examinations	15.06.2020 To 04.07.2020	15.06.2020 To 20.07.2020	03.06.2020 To 11.06.2020	03.06.2020 To 18.06.2020		03.06.2020 To 28.06.2020	03.06.2020 To 10.06.2020	~	30.06.2020 01.07.2020 To	30.06.2020 01.07.2020 To	08.06.2020 To	09.06.2020 To
Viva Voce	-	_	15.06.2020 To 20.06.2020	-		-	-	2	-	-	-	20.06.2020
Summer Project / Professional training	-	-	-	-	22.05.2020 To 30.05.2020 (Submission of report to VTU)	01.04.2020 To 15.04.2020 (Submission of report to VTU)	12.06.2020 To 25.06.2020 (Submission of report to VTU)	-	13.07.2020 To 31.07.2020	-	23.06.2020 To 21.07.2020	01.07.2020 To 25.08.2020
Commencement of ODD Semester	27.07.2020	27.07.2020	27.07.2020	27.07.2020	-	-	-	-	03.08.2020	27.07.2020	27.07.2020	28.08.2020

NOTE

- 1. College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notified separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.
- 3. If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day.
- 4. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTRAR

CITY ENGINEERING COLLEGE BENGALURU 560061 ACADEMIC CALENDER APPLIED SCIENCE AND HUMANITIES 2019-2020

DAY	DATE	FEBUARY-2020	T	März-2020		April-2020		Mai-2020		Juni-2020		
WED	DATE	EVENT	DATE	EVENT	1	EVENT	DATE	EVENT	DATE	EVENT		
THU	-				2							
FRI	-				3		1	MAYDAYGH				
CAT	1				1		2					
CLIN	2				E	MAHAVIRAJAYANTIGH	4		1	LAST WORKINGDAY OF 2nd, 4th, 6th&8thsemester		
MON	3		2		6	Law and the second second	4		1			
	1	Momoncurriculamenri	2		7		- 5		1-2-			
WED	5	chment	4		8		6	ETHNICDAY	3	THEORY EXAM		
THU	6	andmomoncurriculam	5		9		7	SPORTSDAY	4	8thSEM03.6.20to11.06.20VIVAV OCE 8thSem		
FR	7		6		10	GOODFRIDAY-GH	8		5	15.06.20to20.06.20		
SAT	8	2ndSatuarday	7		11	2ndsatuardayholiday	9	CHRONICLES	6			
SUN	9	CONTRACTOR OF STREET	8		12		10		7	Carlo Carlos de La Francia		
MON	10	Startingof2nd, 4th, 6th, and8thsemester	9		13		11		8	THEORY EXAMS 4th		
TUE	11		10		14	AMBEDKAR JAYANTI	12		9	&6thSEMs 15.06.20to20.07.20		
WED	12	PHASE-2INDUCTIONPRO	11		15		13		10			
THU	13	GRAMME 10.2.2020	12		16		14		11			
FRI	14	TO 20.2.20	13		17		15		12			
SAT	15		14	2ndSaturday	18		16	OPEN DAY/EXHIBITION	13	THEORY EXAMSSECONDSEM		
SUN	16	ALL THE SAL DECK	15		19		17	和我是他没有这些 一次我们	14	15.06.20to04.07.20		
NON	17		16	FIRSTINTERNALASSESME	20		18		15			
UE	18	PHASE-2INDUCTIONPRO	17	NT	21		19		16	PRACTICALEXAMS 2nd,		
VED	19	GRAMME 10.2.2020 TO 20.2.20	18	2nd,4th,6th&8thsemester	22		20	THIRD		2nd, 4th&6thSEMESTERS 03.06.20to13.06.20GRADUAT		
ни	20		19		23		21	INTERNALTESTASSRS SMENT2ND,4TH,6TH,&	18	IONDAYAFTER 20.07.2020		
R	21	MAHASHIVARATHRI-GH	20		24	BATTLE OF SCIENCE EVENT(First year)	22	SMEN12ND/41H/61H/&				

CITY ENGINEERING COLLEGE



ACADEMIC YEAR: 2019-20

DEPARTMENT OF BASICSCIENCE <u>COURSE PREFERENCE</u>

Name of the Faculty: Dr. Sujatha K

Designation: Professor and HOD

Sl. No	Course Code and Name	Year/Semester
1.	18PHY22 ENGINEERING PHYSICS FOR C SECTION	2020/II

Ke

Signature of Faculty

Department of Physics

12 HOD

Department of Physics



ACADEMIC YEAR: 2019-20

DEPARTMENT OF BASICSCIENCE <u>COURSE PREFERENCE</u>

Name of the Faculty: Mrs. Nagasree G

Designation: Assistant Professor

Sl. No	Course Code and Name	Year/Semester
1.	18PHY22 ENGINEERING PHYSICS FOR C SECTION	2020/II

(gut

Signature of Faculty Department of Physics

HOD

Department of Physics



CITY ENGINEERING COLLEGE TIME TABLE –SECOND SEMESTER MAY – 2020-21 PHYSICS CYCLE

SECTION:	C
0-0-10-10	-

DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON	CIV	ELE		MAT	РНҮ		EGD	EGD	
TUE	ELE	РНҮ		CIV	MAT		←PHYL/E	GDL/ELEL/	C1/C2/C3→
WED	MAT	ELE	GAK	РНҮ	EGH	NCH	←PHYL/E	GDL/ELEL/	C2/C3/C1→
THU	РНҮ	MAT	BRE	ELE	CIV	TUN	РНҮ	EGH	LIBARARY
FRI	MAT	←PHYL		EGDL/ELEL/	C3/C1/C2→		EDUSAT/DE	P/COLLEGE	ACVIVITIES
SAT	ELE	CIV		РНҮ					

MAT- Dr. Jyothi.P CIV - Prof.Veeresh EGH - Dr.K.Sujatha & Prof. Nagashree G PHYL-Dr.K.Sujatha & Prof. Nagashree G ELE – Dr. Shalini Prasad PHY - Dr.K.Sujatha & Prof. Nagashree G EGD – Prof. Shruthi & Prof Anil ELEL - Prof. Mallikarjuna.G.S & Dr. Shalini Prasad

PROCTORS - Prof. Nagashree G & Prof. Shruthi

Ruemarenes

Principal City Engineering College, Bangalore-560.061

PRINCIPAL

HOD



CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER DEC – 2019-20 PHYSICS CYCLE

Dr.	K. Sujatha						SUBJEC	T CODE: 18	PHY12
DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON					С				
TUE							←	PHYL/C1	→
WED			IAK			LUNCH	←	PHYL/C2	→
THU	С	←PHYL/B3	BREA	PHY	L/B3→	LUI			
FRI									
SAT									

Ruemania

Principal City Engineering College, Bangalore-560.061

PRINCIPAL

HOD



CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER DEC – 2019-20 PHYSICS CYCLE

Mrs	Mrs. Nagashree. G SUBJECT CODE: 18PHY12								
DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON									
TUE		С							
WED			EAK	С		LUNCH			
THU			/BRE			L UN			
FRI		←PHYL		EGDL/ELEL/	C3/C1/C2→				
SAT				С					

Principal City Engineering College, Bangalore-560 061

PRINCIPAL

HOD

VISVESVARAYA TECHNOLOGICAL UNIVERSITY, BELAGAVI

B.E. SYLLABUS FOR 2018-2022

ENGINEERING PHYSICS

(Common to all Branches)

(Effective from the academic year 2018-19)

Course Code : 18PHY12/22	CIE Marks : 40
Contact Hours/Week: 05(3L+2T)	SEE Marks: 60
Total Hours: 50 (8L+2T per module)	Exams. Hours: 03
Semester: I/II	Credits: 04(3:2:0)

Course Learning Objectives: This course (18PHY12/22) will enable students to

- Learn the basic concepts in Physics which are very much essential in understanding and solving engineering related challenges.
- Gain the knowledge of newer concepts in modern physics for the better appreciation of modern technology

MODULES MODULE-I :

Oscillations and Waves

Free Oscillations: Definition of SHM, derivation of equation for SHM, Mechanical and electrical simple harmonic oscillators (mass suspended to spring oscillator), complex notation and phasor representation of simple harmonic motion. Equation of motion for free oscillations, Natural frequency of oscillations.

Damped and forced oscillations: Theory of damped oscillations: over damping, critical & under damping, quality factor. Theory of forced oscillations and resonance, Sharpness of resonance. One example for mechanical resonance.

Shock waves: Mach number, Properties of Shock waves, control volume. Laws of conservation of mass, energy and momentum. Construction and working of Reddy shock tube, applications of shock waves.

Numerical problems

(RBT Levels L1, L2, L3)

MODULE-II:

Elastic properties of materials:

Elasticity: Concept of elasticity, plasticity, stress, strain, tensile stress, shear stress, compressive stress, strain hardening and strain softening, failure (fracture/fatigue), Hooke's law, different elastic moduli: Poisson's ratio, Expression for Young's modulus (Y), Bulk modulus (K) and Rigidity modulus (n) in terms of α and β . Relation between Y, n and K, Limits of Poisson's ratio.

Bending of beams: Neutral surface and neutral plane, Derivation of expression for bending moment. Bending moment of a beam with circular and rectangular cross section. Single cantilever, derivation of expression for young's' modulus

Torsion of cylinder: Expression for couple per unit twist of a solid cylinder (Derivation), Torsional pendulum-Expression for period of oscillation.

Numerical problems

(RBT Levels L1, L2, L3)

Page 1 of 9

MODULE- III:

Maxwell's equations, EM waves and Optical fibers

Maxwell's equations: Fundamentals of vector calculus. Divergence and curl of electric field and magnetic field (static), Gauss' divergence theorem and Stokes' theorem. Description of laws of electrostatics, magnetism and Faraday's laws of EMI. Current density & equation of Continuity; displacement current (with derivation) Maxwell's equations in vacuum

EM Waves: The wave equation in differential form in free space (Derivation of the equation using Maxwell's equations), Plane electromagnetic waves in vacuum, their transverse nature, polarization of EM waves(Qualitative)

Optical fibers: Propagation mechanism, angle of acceptance. Numerical aperture. Modes of propagation and Types of optical fibers. Attenuation: Causes of attenuation and Mention of expression for attenuation coefficient. Discussion of block diagram of point to point communication. Merits and demerits Numerical problems

(RBT Levels L1, L2)

MODULE IV:

Quantum Mechanics and Lasers

Quantum mechanics: Introduction to Quantum mechanics, Wave nature of particles, Heisenberg's uncertainty principle and applications (non confinement of electron in the nucleus), Schrodinger time independent wave equation, Significance of Wave function, Normalization, Particle in a box, Energy eigen values of a particle in a box and probability densities

Lasers: Review of spontaneous and stimulated processes, Einstein's coefficients (derivation of expression for energy density). Requisites of a Laser system. Conditions for laser action. Principle, Construction and working of CO2 and semiconductor Lasers.

Application of Lasers in Defense (Laser range finder) and Engineering (Data storage) Numerical problems

(RBT Levels L1, L2, L3)

MODULE-V:

<u>Material science</u>

Quantum Free electron theory of metals: Review of classical free electron theory, mention of failures. Assumptions of Quantum Free electron theory, Mention of expression for density of states, Fermi-Dirac statistics (qualitative), Fermi factor, Fermi level, Derivation of the expression for Fermi energy, Success of QFET.

Physics of Semiconductor: Fermi level in intrinsic semiconductors, Expression for concentration of electrons in conduction band, Hole concentration in valance band (only mention the expression), Conductivity of semiconductors(derivation), Hall effect, Expression for Hall coefficient(derivation)

Dielectric materials: polar and non-polar dielectrics, internal fields in a solid, Clausius-Mossotti equation(Derivation), mention of solid, liquid and gaseous dielectrics with one example each. Application of dielectrics in transformers.

Numerical problems

(RBT Levels L1, L2, L3)

Page 2 of 9

Course Outcomes:

Upon completion of this course, students will be able to

- 1. Understand various types of oscillations and their implications, the role of Shock waves in various fields and Recognize the elastic properties of materials for engineering applications
- 2. Realize the interrelation between time varying electric field and magnetic field, the transverse nature of the EM waves and their role in optical fiber communication.
- 3. Compute Eigen values, Eigen functions, momentum of Atomic and subatomic particles using Time independent 1-D Schrodinger's wave equation
- 4. Apprehend theoretical background of laser, construction and working of different types of laser and its applications in different fields
- 5. Understand various electrical and thermal properties of materials like conductors, semiconductors and dielectrics using different theoretical models.

Question paper pattern:

Note:- The SEE question paper will be set for 100 marks and the marks will be proportionately reduced to 60.

- The question paper will have ten full questions carrying equal marks.
- Each full question consisting of 20 marks.
- There will be two full questions (with a maximum of four sub questions) from each module.
- Each full question will have sub question covering all the topics under a module.
- The students will have to answer five full questions, selecting one full question from each module.



LESSON PLAN FOR EVEN SEMESTER FOR ACADEMIC YEAR 2019 - 20

Course Title: Engineering Physics	Course Code : 18PHY22
Total contact hours: L:T:P:S :: 05 (3L+2T)	End Tenn Marks : 100
Internal Marks: 40	
Semester : II	Academic year 2019-20
Lesson plan Author: Dr k Sujatha &	Date 10/02/2020
Nagashree G	Date 10/02/2020

Course Objective:

This course (18PHY12/22) will enable students to

C Learn the basic concepts in Physics which are very much essential in understanding and solving engineering related challenges.

O Gain the knowledge of newer concepts in modern physics for the better appreciation of

Course Outcomes:

On completion of this course, students will have know ledge. in:

CO I: Understand various types of oscillations and their implications, the role of Shock waves in various fields and Recognize the elastic properties of materials for engineering applications CO2: Realize the interrelation between time varying ele iric field and magnetic field, the transverse nature of the EM waves and their role in optical fiber communication.

0

C03: Compute Eigen values, Eigenfunctions, mom..:ntum of Atomic and subatomic particles using Time independent 1-D Schrodinger's wave quation

CO4: Apprehend theoreti cal background of laser, construction and working of different types of laser and its applications in different fields

COS: Understand various electrical and theimal properties of materials like conductors, semiconductors and dielectrics using difthent theoretical models.

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
			Level	(CO)
1	I	Definition of SHM, derivation of equation for SHM, Mechani cal and electrica l simpl e harmonic oscillators (mass suspended to sprin g osc illator), complex notation and phasor representation of simple harmonic motion.	R,U .	COI
1	2	Equation of motion for free oscillations, Ntural frequency or oscillations.	R,U	COl

MODULE-I

		dampingQual ity factor.		
	4		R,U,E,C	
		Theory offorced oscillations and		COl
		resonance, Sharpness of resonance.		
		One example for mechanical		
		resonance.		
2	1		· R,U	COl
		Mach number, Properties of Shock		
		waves, control volume.		
	2		R,U	CO 1
		Laws of conservation of mass,		
		energy and momentum		
	3		R,U	COl
		Construction and working of		
		Reddy shock tube, applications of		•
		shock waves.		
		Numerical problems		

MODULE-2	2

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
4	ľ	Concept of elasticity, plasticity, stress, strain, tensile stress, shear stress, compressive stress, strain hardening and strain softening	R,U	C02
	2	Failure (fracture/fati gue), Hooke's law, different elastic moduli : Poisson's ratio, Expression for Young's modulus (Y)	R,U ()	C02
	3	Bulk modulus (K) and Rigidity modulus (n) in terms of and p. Relation between Y, n and K, Limits of Poisson's ratio	R,U	C02
5	I	Neutral surface and neutral plane, Derivation of expression for bending moment	R,U	C02
	2	Bending moment of a beam with circular and rectan gular cross section	R,U	CO2
	3	Single cantileve r, derivation of expression for young's' modulus	R,U	C02
	4	Expression for couple per unit twist of a solid cylinder (Derivation), Torsional pendulum-Expression for period of oscillation. Numerical problems	R.U	CO2

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
			Levei	(CO)
6	1	Fundamentals of vector calculus.	R.U	C03
	2	Divergence and curl of electric field and magnetic field (static), Gauss' divergence theorem and Stokes' theorem.	R.U	C03
	3	Description of laws of electrostatics, magnetism and Faraday's Jaws of EM1	R,U,E	C03
	4	Current density & equation . of Continuity; displacement current (with derivation) Maxwell's equations in vacuum	R,U	C03
7	1	The wave equation in differential form in free space (Derivation of the equation using Maxwell's equations),	R,U	C03
	2	Plane electromagnetic waves in vacu um, their transverse nature, polarization of EM waves(Qualitative)	R,U	C03
8		Propagation mechanism, angle of acceptance. Numerical apertu re.	R.U,C	C04
	2	Modes of propagation and Types of optical fibers.	R,U,Al	C04
	3	Attenuation: Causes of attenuation and Mention of expression for attenuation coefficient.	R,U	C04
	4	Discussion of block diagram of point to point communication. Merits and demerits	R,U	C04
	5	Numerical problems	R,U	C04

MODULE-4

Week	Days/	Contents of Module	Bloom's	Course
	Date		Taxonomy	Outcome
			Level	_(COl
9	1	Introduction to Quantum mechanics, Wave nature of particles, Heisenberg's uncertainty principle and applications		C04
	2	Schrodinger time independent wave equation, Significance of Wave function		C04
1	3	Normal ization, Particle In a box, Energy eigen values of a particle in a box and proba bility densities.	R,U	C04 ·
10	1	Review of spontaneous and stimul ated processes, Einstein's	R,U	C04

	_coefficients (derivation of e pr sion for energy density)		
2	Requisites of a Laser system.	<u>,</u> B,,,U	C04
3	Conditions for laser action. Principle	R,U	C04
	Construction and working of CO2		
	and semiconductor Lasers.		
4	Application of Lasers in Defense	R,U	C04
	(Laser range finder) and Engineering		
	(Data storage) '		
	Numerical problems		

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
	Date		Level	(CO_1
13	I	Review of classical free electron theory, mention of failures.	R,U,A2	C04
	2	Assumptions of Quantum Free electron theery	R,U	C04
	3	Mention of expression for density of states	R,U	COS
	4	Fermi-Dirac statistics (qualitative), Fermi factor	RU	COS
14	1	Fermi level, Derivation of the expression for Fermi energy, Success of QFET.	R,U,E	COS
	.2	Fermi level in intrinsic semiconductors	R,U	COS
	3	Expression for concentration of electrons in conduction band	R,U	COS
	4	Hole concentration in valance band (only mention the expression)	R,U	COS
15	I	Conductivity of semiconductors(derivation), Hall effect, Expression for Hall coefficient(derivation)	R,U	COS
	2	polar and non-polar dielectrics	R,U.A1,C	COS
	3	internal fields in a solid	R,U	COS
	4	Clausius-Mossotti equation(Derivation)	R,U	COS
16	1	mention of solid, liquid and gaseous	R,U	COS
	2	dielectrics with one example each.	R,U	COS
	3	Application of dielectrics in transformers	R,U	COS
	4	Numerical problems	R.U,Al,C	COS

MODULE-S

. *

Bloom's Taxonomy Level.

· R-Remembering U-Understanding A-Applying A2-Analysing E-Evaluating C-Creating

Text Books:

1. A Text book of Engineering Physics- M.N A vadhanulu and P.G. Kshirsagar, l0th revised Ed, S. Chand & Company Ltd, New Delhi

··· ·

2. Engineering Physics-Gaur and Gupta-Dhanpat Rai Publications-2017

3. Concepts of, Modem Physics-Arthur Beiser: 6th ;Tata McGraw-Hill Edu Pvt Ltd-New Delhi 2006

Reference books:

I. Introduction to Mechanics —MK Verma: 2nd Ed, University Press(India) Pvt Ltd, Hyderabad 2009

2. Lasers and Non Linear Optics - BB laud, 3rd Ed, New Age International Publishers 2011

3. Solid State Physics-S O Pillai, 8th Ed- New Age International Publishers-2018

4. Shock waves made simple- Chintoo S Kumar, K Takayama and K.PJ Reddy: Willey India Pvt. Ltd. New Delhi2014

5. Introduction to Electrodynamics- David Griffiths: 4th Ed, Cambridge University Press 2017

Ke

Signature of Staff

Signature of HOD



Question Bank

Course Name: Engineering Physics

Course Code: 18PHY22

Semester: II

Section: C

Module 1-Free oscillations

1. Define Simple Harmonic Motion. Derive the equation of motion foe SHM.

2.Derive the expression for force constants for series and parallel combination of springs.

3.Explain how Complex notation Phasor representation is represented.

4.Define free oscillations with example. Mention the equation of motion of natural frequency of vibration.

5. What are Damped oscillations. Give the theory. Discuss the case of under damping, over damping and critical damping.

6.Define Quality factor with equation. Give its Physical significance.

7.What are Forced Oscillations .Derive the expressions for amplitude and Phase of Forced vibrations. Explain all the three cases.

8.Write a short notes on a)Sharpness of Resonance b)Helmoltz Resonator

Shock waves

1. Define Mach Number and Mach angle

2.Distinguish between Acoustic ,Ultrasonic ,subsonic, supersonic, transonicand hypersonic waves.

0

3. What are shock waves and mention the properties of shock waves.

4.Explain Control Volume.

5.State and explain the law of conservation of mass ,momentum and energy with expressions .

6.Describe the construction and working of Reddy Shock tube experiment.

7. What are the applications of Shock waves.



Module 2-Eiastic properties of materials

- 1. Explain Elasticity and Plasticity with examples.
- 2.Explain the importance of elasticity in engineering materials.
- 3.Explain the terms Stress and Strain. Discuss the three types of Stresses.
- 4.Discuss briefly the effect of stress, temperature, annealing and impurities on elasticity.
- 5.Describe Strain hardening and Strain softening.
- 6.State and explain Hooke's law with stress-strain curve.
- 7.Discuss three different moduli of elasticity with equations.
- 8.Define Lateral Strain and Linear Strain and s derive the expression for Poisson's ratio.
- 9.Derive the relation between shear strain, longitudinal strain and compression strain.
- 10. Derive the relation between Y,η and G.
- 11. Derive the relation between K, Y and 6.
- 12. Derive the relation between K, and Y.
- 13.Discuss the limiting values of $\mathbf{6}$ and limitations of Poisson's ratio.
- 14.Define Beam and explain different types of beams and mention their engineering applications .
- 15.Define neutral surface and neutral axis.
- 16.Define bending moment and derive the expression for bending moment in terms of moment of inertia. Mention the expression for bending moment for circular and rectangular cross section.
- 17.Describe a single cantilever and hence derive the expression for depression.
- 18.Explain Torsional oscillations. Derive the expression for Couple per unit twist for a solid cylinder.
- 19.Mention the expression for Time period for Torsional oscillations .Briefly explain the applications of torsional pendulum.



Module 3

Maxwell's Equations and Electro magnetic waves

1.Explain Scalar Product and Vector product.

2.Describe Vector Operator and explain the concepts of gradient, divergence and curl along with physical significance.

3.Discuss three different types of integration like linear ,surface and volume integrations.

4.Explain Gauss flux theorem in electrostatics and magnetism.

5.Derive Gauss Divergence theorem. Mention Stokes theorem.

6.Discuss Maxwell- Ampere's law, Biot-Savarts law.

7.Explain briefly the Faraday's law of electromagnetic induction. Express the same in the differential form of maxwell's equation in the case of time-varying fields.

8.Discuss Continuity equation. Define Dispalcement current and arrive the expression for the same.

9.List the Maxwell's equations for time-varying condition and for static conditions .

10.Derive wave equation in terms of electric field using Maxwell's equations.

11 .Explain the plane electromagnetic waves in vacuum along with the equations for E,B

and c.

12. Explain the transverse nature of electromagnetic waves and explain linear ,elliptical and circular polarizations.

Optical Fibers

1.Describe the propagation mechanism of light through in an optical fiber.

2. What is numerical aperture? Obtain an expression for numerical aperture in an optical fiber and then arrive the condition for propagation .

3.Explain modes of propagation and V number.

4.Explain different types of optical fibers.



5. Define attenuation. Explain different types of attenuation, mention the expression for attenuation coefficient.

6.Explain point to point communication system with the help of block diagram. ...

7.Explain merits and demerits of optical fiber communications.

Module 4- Quantum Mechanics

I.Give a brief account of blackbody radiation and Planck's radiation law with two conditions.

2.Explain dual nature of matter waves.

3.State de Broglie's hypothesis. Show tat the deBroglie wavelength of an electron is found to be equal to 1.226N nm.

4. Explain Heisenberg's uncertainity principle and show that electrons cannot exists within the nucleus.

5. Construct one dimensional time independent schrodinger wave equation.

6. What are the properties of wavefunction.

7.Explain the terms probability density, normalization.

8.Discuss Eigenvalues and Eigenfunctions.

9.Solve schrodinger wave equation for the allowed energy values in the case of particle in a box.

10. Discuss Probability for a particle in a potential well of infinite height.



Lasers

1.Explain Induced absorption, Spontaneous emission, stimulated emission.

2.Derive the expression for energy density using Einstein's coefficients.

3.Explain the requisites of a laser system.

4.Explain the condition for laser action.

5.Explain three different vibrational modes of CO₂ molecule. With a neat energy level diagram explain the construction and working of CO₂ laser .
6. Explain the construction and working of Semiconductor laser .

7.Describe how a laser range finder is made use of in defense.

8.Explain how data storage is achieved in a compact disc.

Module 5 - Material Science

1.What are the assumptions of classical free electron theory and the failures of classical free electron theory.

2. What are the assumptions of Quantum free electron theory.

3.Define density of states and mention the expression for density of states.

4.Explain Fermi levei, Fermi energy, Fermi-Dirac statistics.

5.Define Fermi Factor. Discuss the variation of Fermi Factor on different conditions of temperature and energy.

6.Derive the expression for Fermi energy at zero Kelvin. Mention the expression for Fermi velocity and Fermi temperature.

7. Discuss the success of Quantum free electron theory.

8.Discuss the Fermi level in intrinsic semiconductor. Mention the expression for electron and hole concentration in intrinsic semiconductor.



9.Derive the relation between Fermi energy and energy gap for an intrinsic semiconductor.

10.Derive the expression for electrical conductivity of semiconductors.

11.What is Hall Effect? Obtain the expression for Hall voltage in terms of Hall coefficient.

12.What are dielectric materials .Explain the types of dielectric materials. Discuss solid ,liquid and gaseous dielectric with one example each.

13.Explain polarization and the types of polarization. Mention the relation between dielectric constant and polarization.

14.Define internal field in case of solids and mention its expression for one dimensional case, three dimensional caseand Lorentz field.

15.Derive Clausius-Mossotti equation.

16.Mention the application of dielectric in transformers.

Gut

Staff Mrs. Nagasree G Department of Physics

HOD Dr. Sujatha Department of Physics



Assignment Questions

Odd Semester 19-20

Course Name: Engineering Physics

Course Code: 18PHY22

Semester: II

Section: C

Module 1-Free oscillations

1.Define Simple Harmonic Motion. Derive the equation of motion foe SHM.

2.Derive the expression for force constants for series and parallel combination of springs.

3.Explain how Complex notation Phasor representation is represented.

4.Define free oscillations with example. Mention the equation of motion of natural frequency of vibration.

5. What are Damped oscillations. Give the theory. Discuss the case of under damping, over damping and critical damping.

6.Define Quality factor with equation. Give its Physical significance.

7.What are Forced Oscillations .Derive the expressions for amplitude and Phase of Forced vibrations. Explain all the three cases.

8.Write a short notes on a)Sharpness of Resonance b)Helmoltz Resonator

Shock waves

1. Define Mach Number and Mach angle

2.Distinguish between Acoustic ,Ultrasonic ,subsonic, supersonic, transonicand hypersonic waves.

0

3. What are shock waves and mention the properties of shock waves.

4.Explain Control Volume.

5.State and explain the law of conservation of mass ,momentum and energy with expressions .

6.Describe the construction and working of Reddy Shock tube experiment.

7. What are the applications of Shock waves.



Module 2-Eiastic properties of materials

- 1.Explain Elasticity and Plasticity with examples.
- 2.Explain the importance of elasticity in engineering materials.
- 3.Explain the terms Stress and Strain. Discuss the three types of Stresses.
- 4.Discuss briefly the effect of stress, temperature, annealing and impurities on elasticity.
- 5.Describe Strain hardening and Strain softening.
- 6.State and explain Hooke's law with stress-strain curve.
- 7.Discuss three different moduli of elasticity with equations.
- 8.Define Lateral Strain and Linear Strain and s derive the expression for Poisson's ratio.
- 9.Derive the relation between shear strain, longitudinal strain and compression strain.
- 10. Derive the relation between Y,η and G.
- 11. Derive the relation between K, Y and 6.
- 12. Derive the relation between K, and Y.
- 13.Discuss the limiting values of $\mathbf{6}$ and limitations of Poisson's ratio.
- 14.Define Beam and explain different types of beams and mention their engineering applications .
- 15.Define neutral surface and neutral axis.
- 16.Define bending moment and derive the expression for bending moment in terms of moment of inertia. Mention the expression for bending moment for circular and rectangular cross section.
- 17.Describe a single cantilever and hence derive the expression for depression.
- 18.Explain Torsional oscillations. Derive the expression for Couple per unit twist for a solid cylinder.
- 19.Mention the expression for Time period for Torsional oscillations .Briefly explain the applications of torsional pendulum.



Module 3

Maxwell's Equations and Electro magnetic waves

1.Explain Scalar Product and Vector product.

2.Describe Vector Operator and explain the concepts of gradient, divergence and curl along with physical significance.

3.Discuss three different types of integration like linear ,surface and volume integrations.

4.Explain Gauss flux theorem in electrostatics and magnetism.

5.Derive Gauss Divergence theorem. Mention Stokes theorem.

6.Discuss Maxwell- Ampere's law, Biot-Savarts law.

7.Explain briefly the Faraday's law of electromagnetic induction. Express the same in the differential form of maxwell's equation in the case of time-varying fields.

8.Discuss Continuity equation. Define Dispalcement current and arrive the expression for the same.

9.List the Maxwell's equations for time-varying condition and for static conditions .

10.Derive wave equation in terms of electric field using Maxwell's equations.

11.Explain the plane electromagnetic waves in vacuum along with the equations for E,B and c.

12. Explain the transverse nature of electromagnetic waves and explain linear ,elliptical and circular polarizations.

Optical Fibers

1.Describe the propagation mechanism of light through in an optical fiber.

2. What is numerical aperture? Obtain an expression for numerical aperture in an optical fiber and then arrive the condition for propagation .

3.Explain modes of propagation and V number.

4.Explain different types of optical fibers.



5. Define attenuation. Explain different types of attenuation, mention the expression for attenuation coefficient.

6.Explain point to point communication system with the help of block diagram. ...

7.Explain merits and demerits of optical fiber communications.

Module 4- Quantum Mechanics

I.Give a brief account of blackbody radiation and Planck's radiation law with two conditions.

2.Explain dual nature of matter waves.

3.State de Broglie's hypothesis. Show tat the deBroglie wavelength of an electron is found to be equal to 1.226N nm.

4. Explain Heisenberg's uncertainity principle and show that electrons cannot exists within the nucleus.

5. Construct one dimensional time independent schrodinger wave equation.

6. What are the properties of wavefunction.

7.Explain the terms probability density, normalization.

8. Discuss Eigenvalues and Eigenfunctions.

9.Solve schrodinger wave equation for the allowed energy values in the case of particle in a box.

10. Discuss Probability for a particle in a potential well of infinite height.



Lasers

1.Explain Induced absorption, Spontaneous emission, stimulated emission.

2.Derive the expression for energy density using Einstein's coefficients.

3.Explain the requisites of a laser system.

4.Explain the condition for laser action.

5.Explain three different vibrational modes of $C0_2$ molecule. With a neat energy level diagram explain the construction and working of $C0_2$ laser.

6. Explain the construction and working of Semiconductor laser .

7.Describe how a laser range finder is made use of in defense.

8.Explain how data storage is achieved in a compact disc.

Module 5 - Material Science

1.What are the assumptions of classical free electron theory and the failures of classical free electron theory.

2. What are the assumptions of Quantum free electron theory.

3.Define density of states and mention the expression for density of states.

4.Explain Fermi levei, Fermi energy, Fermi-Dirac statistics.

5.Define Fermi Factor. Discuss the variation of Fermi Factor on different conditions of temperature and energy.

6.Derive the expression for Fermi energy at zero Kelvin. Mention the expression for Fermi velocity and Fermi temperature.

7. Discuss the success of Quantum free electron theory.

8.Discuss the Fermi level in intrinsic semiconductor. Mention the expression for electron and hole concentration in intrinsic semiconductor.



9.Derive the relation between Fermi energy and energy gap for an intrinsic semiconductor.

10.Derive the expression for electrical conductivity of semiconductors.

11. What is Hall Effect? Obtain the expression for Hall voltage in terms of Hall coefficient.

12.What are dielectric materials .Explain the types of dielectric materials. Discuss solid ,liquid and gaseous dielectric with one example each.

13.Explain polarization and the types of polarization. Mention the relation between dielectric constant and polarization.

14.Define internal field in case of solids and mention its expression for one dimensional case, three dimensional caseand Lorentz field.

15.Derive Clausius-Mossotti equation.

16.Mention the application of dielectric in transformers.

(gr)

Staff Mrs. Nagasree G Department of Physics

HOD

Dr. Sujatha Department of Physics

SUB CODE:18PHY22

19/8

CITY ENGINEERING COLLEGE I Internal Test

Sem & Branch: CS/EC/CIV/ME Sub Name: Engineering Physics Max Marks: 50

USN

C

1

E

Date:17/03/2020 Time: 10:30-12:00 Duration: 1:30 hr.

Note: Answer all Questions selecting any ONE FULL questions from each part

Q No.	Sub Q No.	Questions	Marks	CO' s
		PART-A		
1	at a	Define SHM. Derive the equation for SHM.	6	CO2
1	b	 A mass 0.5 kg causes an extension 0.03 m in a spring and the system is set for oscillations. Find (i) force constant K of the spring (ii) angular frequency ω and (iii) period T of the resulting oscillation 	4	
		OR		
2	a	Distinguish between acoustic, ultrasonic, subsonic, supersonic, transonic and hypersonic waves.	ú	co
	h	The distance between two pressure sensors in a shock tube is 150 mm. The time taken by a shock wave to travel this distance is 0.3 ms. If the velocity of sound under the same condition is 340 m/s, find the Mach number of the shock tube.	4	
	•	PART-B		52
3	1	What are damped oscillations? Cive the theory. Discuss the case of under damping.	i i	CO
		OR		
4		Describe the construction, working and characteristics of Reddy Shock tube with suitable diagram.	10	CO

		PART-C		
	а	Derive the expressions for force constants for series and parallel combination of springs.	6	CO3
5	b	A free particle is executing simple harmonic motion in a straight line. The maximum velocity it attains during oscillation is 62.8 m/s. Find the frequency of oscillation, if its amplitude is 0.5 m.	4	

		OR		
6	a	Give the description of shock waves and mention the applications of Shock waves.	6	CO2
	b	Write a short notes on Sharpness of resonance.	4	

PART-D

7	Define three elastic Modulus. Derive the relation between shearing strain, longitudinal strain and compression strain.	10 . 0	•
	OR	•	

nd 10	CO3
1	and 10

9	a	State and explain the law of conservation of mass, momentum and energy with expressions.	6	CO
			0	
1	b	Explain Control volume.	-1	
		OR		5 A. 6-
10	a	State and explain Hooke's law with stress strain curve.		
			43	CO.
	b	Discuss briefly the effect of stress, temperature, annealing and impurities on elasticity.	-4	

CO1—Understand various types of oscillations and their implications, the role of shoel: waves in various fields and recognize the elastic properties of materials for engineering applications.

CITY ENGINEERING COLLEGE

DEPARTMENT OF ______PHYSICS

SCHEME FOR VALUATION

Internal Test

Question	ction: 'C' Sec ud sen Da Details of the answer	Marks Distribution	Total Marks
No.	SHM definition A Explanation availue upto $\frac{d^2x}{dt^2} + \omega^2 3t = 0$	3M 3M	6
	w= 12		
Ъ	Data, x=0.03m, m=0.5kg K= FK= 163.3 N/m	2H 2M	4
	$W = \sqrt{\frac{1}{16}} = 18.1 \text{ sod}/\text{s}$ $W = \sqrt{\frac{1}{16}} = 2.877 \text{ Hz}, T = \frac{1}{7} = 0.355 \text{ (OR)}$		
© ©	Distinguish blu all the Nance	24×3	64
E	- 1 - 2	2M	
3	Damped Oscillations definition & theory to md ² x + x dx + kx = 0 araive up to md ² x + x dx + kx = 0 dt + t + x dt + kx = 0 (-b-b ² -c) + (-b-b ² -c) up to x = (c + De	2M 2H At 441	lo
	upto x= (e +De	2M	

DEPARTMENT OF PHYSICS

-

4

SCHEME FOR VALUATION

Internal Test

emester & Section: C', 2nd Sem	Date: 173	2020
Question Details of the answer	Marks Distribution	Total Marks
No. upto $\alpha = \frac{\chi_0}{2} \left[\left[1 + \frac{b}{\sqrt{b^2 - \omega^2}} \right] \left[-\frac{b}{\sqrt{b^2 - \omega^2}} \right] e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} \right] e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} \left[\left[\frac{b}{\sqrt{b^2 - \omega^2}} \right] e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} \right] e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}}} e^{-\frac{b}{\sqrt{b^2 - \omega^2}}} e^$		10 M
(A) Explanation of shock wave F Reddy tube capt. Explanation Construction and working Post C	2M 4M 4M	юђ
(5) @ Explanation 1 diagons Derve up to $k_s = \frac{k_1 \cdot k_2}{k_1 \cdot k_2}$ and up to $k_p = K_1 \cdot k_2$	2M 2M 2M	6M
(b) Given Vmar=628m/5 & a= 0.5	m LH	2
w = dx = asin wt v = dx = awcoswt = aw (1-sin w) dt = wa , $w = \frac{1}{25.6}$ and $\frac{1}{25.6}$	st im	411
Staff $V = \frac{\omega}{2\pi} = 20$ Hz		HOD

CITY ENGINEERING COLLEGE

DEPARTMENT OF ______PHYSICS

SCHEME FOR VALUATION

Internal Test

3

Date: 17 3 20 20 Semester & Section: C Sec Total Marks Details of the answer Question Marks Distribution No (a) shock waves decorptions 6) 3M 6M shuck wavep applications 3M short notee on shapness 2M 6 40 2M ge sonaule de Post-D Debinition of Yi Ki and N 6M Garrie pelation blue, & all **WM** the three strains 4M elaughton streint compression steain = shaaing strain 0 Define and Copan toaced vibration 2M 8 besultant toxo = - 2 dr - ki +fsinpt 2M upto dir + 2b dr + wir = I sn(PH) RB LOM a= Flm/ (40°p++ (w-p)opto 4M Staff

CITY ENGINEERING COLLEGE hysics DEPARTMENT OF SCHEME FOR VALUATION

Date: 17 3 2020 Semester & Section: 2nd Sec Total Marks Details of the answer Question Marks Distribution NO. Explanation of mass, momentum (a) 3×2M 6M 6 and enorgy 47 control volume explanation 4M 6 (or) tooko's law explanation graph and explanation 67 (2) $(1\hat{0})$ 3M Explanation of stoess, temp 2M 41 b anneating and imposition on am obsticit

Staff

				SUB C	ODE:	18PF
					11/	/
	1	Sem	CITY ENGINEERING COLLEGE & Branch: CS/EC/CIV/ME Name: Engine		18	
				-		
	P	viax	Marks: 50	Date	e:09/0	6/202
	Δ	Vote:	4000000	Dur	e: 10:.	30-12
			Answer all Questions selecting any ONE FULL questions from e	Dur	ation:	1:30
	Q	Su	b	each pa	111	
I	No.	Q				
		No.	Questions			
	-		D · D · D · D · D · D · D · D · D · D ·	M:	arks	CO.
3		а	Derive the relation between K, Y and σ			S
-		b	Define neutral surface and neutral axis			
-		Give	and neutral axis	6		CO1
-				4		COL
		a	OR Explain different types of Optical fibers.			
2	1 10	Ь	l lie refraat	T		
			The refractive indices of core and cladding are 1.5 and 1.48 respectively in an optical fiber. Find the numerical aperture and angle of acceptance. PART-R	6	C	°O2
			Sit Of appoints	4	G	~
	1		- Int - D			02
		1	Derive the expression for energy density using Einstein's coefficients.			
-	_		energy density using Einstein's coefficients.	10		
		D	OR OR	10	CO	4
		di	OR efine attenuation. Explain different types of attenuation with suitable agrams.			
			with suitable	10	CO	
T	а	Ex	PART-C			-
1-		TL	main Spontaneous emission			
	b	Way	e average output power of a laser source is emitting a laser beam of velength 6328 A° is 5 mw. Find the number of photons emitted of	6	cou	7
		seco	velength 6328 A° is 5 mw. Find the number of photons emitted per body the laser.		CO4	
-						

4

6	Define Bending moment and derive the expression for bending moment in terms of moment of inertia.	10	C01 C01	
---	--	----	------------	--

PART-D

7	What is numerical aperture. Obtain the expression for numerical aperture in an optical fiber and then arrive the condition for propagation.	10	CO2
---	---	----	-----

8	Explain three different vibrational modes of co2 molecule. With a neat	10	001
	energy level diagram explain the construction and working of co2 laser.	10	CO4

PART-E

	a	Describe how a laser range finder is made use of in defence.	6	CO4
9	b	Calculate the angular twist of a wire of length 0.3 m, and radius 0.2×10^{-3} m when a torque of 5 x 10 ⁻⁴ Nm is applied. Rigidity modulus of the material 8 x 10 ⁻¹⁰ N/m ²	4	CO4
		OR		-

10	Explain Torsional oscillations. Derive the expression for Couple per unit twist for a solid cylinder.	10	CO1
----	---	----	-----

CO1—Understand various types of oscillations and their implications, the role of shock waves in various fields and recognize the elastic properties of materials for engineering applications.

CO2---Reliaze the interrelation between time varying electric field and magnetic field, the transverse nature nature of the EM waves and their role in Optical fiber communications.

CO4---Apprehend theoretical background of laser, construction and working of different types of laser and its applications in different fields.

CITY ENGINEERING COLLEGE

DEPARTMENT OF Physics

SCHEME FOR VALUATION

Semester & Section: I Sem C Date: 09 06 2020 Sec Question Details of the answer Marks Total No. Distribution Marks Pagt-A 2100000000000 \bigcirc Relation blo KIY, & , diapour 3 162-20)87 up to 6 (a) Y= 8× (1-20) 6 neutral scopae explanation neutral explanation VA CILIS (OR) Optical fibers endaughorm (a) Banding Ca 6 types undays Three kuo N-1= 1 ni2-n2 - n1= 1.5. n2 0 Ь 4 N-A-70.245 whiled of qu ward a teor Post -B Explanation on absorption and F a emission process, all three 10 otgu 201200 helke) arrive up to U Co (OR) Attenuation il dopinition istoria solati 0 Three different types of attenuction 10 with explanation with L'agrans Staff HOD

CITY ENGINEERING COLLEGE SCHEME FOR VALUATION Internal Test Ind/c Semester & Section: Sec Date: 96/2020 Question Details of the answer No Marks Total Distribution Marks 5 Post-C sportaueous and stimulated 6 emission explanation DE= hc 6 1=6328 1 NIDE = 5 mW Pautat = 5 mW 4 $\Delta E = 3 - 143 \times 10^{19} J$ $N = 1 - 59 \times 10^{16}$ Bending moment detinition 6 0) 2 diappens and explanation arrive up to Linear Strain = Y 10 arrive up to bending moment = Y is post -7 Numerical aperture explanation 10 9 D) explanations diaporn and 0 actue up to Stan N-A= Vni-ni ot go avinto Sind LN-A OR E) 8 Three mader of Vibrations appoint and explanation 10 ration of every level darson

Staff 1

CITY ENGINEERING COLLEGE DEPARTMENT OF Physics SCHEME FOR VALUATION Internal Test Semester & Section: \mathbb{I} Date: 09 06 2010 Question Details of the answer Marks Total No. Distribution Marks Part -E (9) (9) laser range finder explanation and use in defence explanation and we $C = \frac{TinR^4}{2L}$ $T' = \frac{TinR^4}{2L} \theta$ $L = 0.3 m_3$ $\theta = 0.75 \text{ Yed}$ $R = 0.2 \times 10^3 m$ $n = 5 \times 10^4 Nm_3$ 6 **b** (OR) 10 Torsional oscillations explanation diaprono with explanation arrive up to $F = \frac{nr\theta}{l} (2\pi r dr)$ Ø avive up to C = (IINR4)

Year: 2019 - 2020

Semester : Odd / Even

Name of the Teacher Designation Department

. Dr. K. Sujatta & Nagoshace. G R mi : Prof & HOD Asst. : Physics

Sem/ Branch

Subject Code

ATTEMPAN

CIPONE.

Subject

S1020

1020

20

22055

1020

SCOL ANT

18PH122

2

Impach

Man Man Marrier

1.511

Engineering phys

and the second

 Initials at the End of the

 1st Month
 2nd Month
 3rd Month
 Semester

 Staff
 Galaine
 Galaine
 Galaine
 Galaine

 HOD
 Mminhr
 Mminhr
 Mminhr
 Mminhr

 Principal
 PRINCIPAL
 Maintrian
 Minhr

CITY ENGINESTING COLLEGE

CITY ENGINEERING COLLECE

ATTENDANCE os

01

ŧ)

	+		+													
SI. Nó.)	Reg.No.	Name	1002	1/2	Y.	Na	102	15/02	22	24	252	26	27 82	28/02	29	2/3
St. I	Indes	U. U.	1	2	3	4	5	6	7	8	9	10	11	12	13	14
1	ICEITCS020	Phogyasharee N		•	+	,	1	2	3	4	5	6	7	8	9	10
12	ICE 1905006	Amig Rehability			1	1	1	2	3	4	6	6	7	8	9	10
3		Amit Singh M -		1	1	2	3	3	4	5	5	6	7	8	8	9
4	(5013	B M Puncetto -	1	2	З	4	4	5	6	6	6	73	8	9	0	10
. 5	CS014	Bhapu Pakash Rr	1	2	3	4	5	6	ъ	त	8	9	10	11	12	13
6	CS015	Bhavana S	1	1	2	3	4	5	6	7	7	7	8	9	9	10
17	.CS017	Bindhushace G -	I	2	3.	4	5	6	7	8	9	10	11	12	13	14
8015	csolg	Changena D-SC(HABI	.5E	VID	314	2	3	3	4	4	5	6	7	8	9	10
9	CS028	Deepthy Rashmi R 1	1	2	3	В	4	5	6	17	8	8	9	10	11	11
10	CS033	Hasish Baby K P/	1	2	3	4	5	6	6	6	7	8	9	10	10	11
11	CS036	Imgan Khan Nr			+	1	2	З	4	5	6	7	8	9	to	11
12	05046	Kauthika Kigankumozi		1	١	2	8	4	5	26	7	8	9	10	10	11
13	CS0.58	Nishanth Nayaka N R			1	'	•	•	•	2	8	4	5	6	6	7
14	05065	Pacothi CK /	1	7	8	4	4	5	6	17	8	9	10	11	12	13
15	CS067	Rahul K R -	•	'	1	2	3	4	5	5	5	5	6	7	7	8
16	and the second se	shankalinga M Mattimani			1	(1		3	5	4	5	6	7	7.	8
17	Contraction of the local division of the loc	Saima sheik	•	.1	2	2	8	4	5	6	7	7	8	9	0	11
18		Sambang? sniteja	,	1	14	• -			-	2	3	4	Ş	6	7	8
<u>19</u> 20		Spd Mitaib ulla		,	2	3	3	4	5	6	7	7	8	9	10	()
20	CS102		1	2		2	3	3	3	-	4	5	6	7	8	9
21		X semantha Meguy	Contraction of the	2	3	4	5	6	6	7	8	8	8	9	9	10
23	1	Anil K	1	-	0	3	4	5-	7	7	8		10	11	12	-
23	EC002	Apoosva Kulkasni		2	-		-	- 10	6	2	3	4	5	6	4	8
25	and the second se	chasan yadav	1	1	3	4	5		0	7	8	9	10	11	12	13
20	Ecco 4 No. of Abs.	Faiz about My	and a				-				-			'	•	1.
	Initials										-					
2	muais												1			

~

ATTENDANCE

								-									-	
SI. No.	Reg.No.	nks	Tost Ma		10/2	-11/2	23	13/2	514	642	212	22	252	262	22	2 1 20	2/2	wit
26	- Frank		50 50	60 Annua	18	2.	3	4	5	6	7	8	9	10	11	12	13	14
27	ECOOD	Madhust	DICC. N	1/	1	2	3	4	4	5	6	7	8	91	10	u	12	-13
28	- Address - Addres	Moora	the second se	-	1	2	8	4	5	6	7	8	9	9	10	11	12	12
29		peaveon				+	2	2	3	4	E	5	6	7	8	9	9	10
30	EC00S	Rohana	- 50 · Ar	/		•	1	1	2	3	3	4	5	5	5	6	6	7
31	E0009	Suparya	Gar		1	2	3	З	4	5	6	7	8	8	9	10	11	12
20		Vishuas	and the second sec	1	1	1	2	2	3	4	4	4	4	5	6	7	8	9
33	ICE ITOVOS	shatun	thala c	M		•	1	2	3	4	5	- 5	5	6	7	8	9.	10
34	19000	Appoar	arcie	1	1	1	2	б	3	4	4	5	6	6	7	8	8	9
/35		2 pavao	and the second sec	1		-	-		•		• .	- '			-	-	2	-2
36		pavitejo				1	2	3	4	5	6	170	8	91	10	11	14	12
37		+ Veeno			. 1	2	3	4	5	6	7	-8-	9	10	M	12	13	14
38	19MEOD		so n			2	3	3	4	5	6	17 2	8	9/	10	11	4	12
39	ITEC.	- shatar			1	2	3	4	5	6	7	810	9	10	21	12	13	14
40	LIEC.	Mohd	Aquib		1.5	11	200	18		-10	1							
41 87	- Vine i	27110	Le statut	1 F.	1	The second		120		1.5.50			-					
42 -	- LIVE	allegi	10-11-12 P		1				1	-					*			
43 -	. Louis	11.03	CA 08.				33		1							_		
44	evis h	of the	173						1	1		de	-	-		-	-	1
45	Vie I	1 20 1	Xislant		24		-			1		11.	-	-	1	-		
46	1202	BALAS	100.031			1	33						-	-	-	-	-	-
47 6	1	HI PEL	Sall sal	A SING			1	1	12				-	-	-	-		-
48 0	4.104	11/38	100 201	1. 1. 1.	1		13		a la						-			
49	4 4	01/22	March 1				•	19	1	1				-	-			
50		121.25		· ····································				1	J.M.					-				-
	No. of Abs	i.	1 Land			31				1						-	-	
	Initials				d		and	1	12		-							
1000	and the second second	and the second second			Tran Party		2.25	-						-	_	_	_	_



DEPARTMENT OF BASIC SCIENCE ACADEMIC YEAR 19-20 ODD SEMESTER CIRCULAR

Ref No: CEC/BS/DAC/ACY/2019-20/OR/01

Date: 25-07-2019

This is to inform the members of Department Advisory Committee that meeting is scheduled on 08-08-2019 at 10: 00 AM in Physics Laboratory.

Agenda:

- Commencement of classes for 1st semester students
- Student Induction Programme for 1st semester students
- · Conduction of Talents day
- Organizing value added courses/ certificate courses, seminars & webinars in the curriculum.

HOD

HEAD OF THE DEPT. OF PHYSICS Y ENGINEFTING COLLEVE, Dour vikalisisandra Roadkepura Main Road, BANGALORE - 560 062.



DEPARTMENT OF BASIC SCIENCE

Department Advisory Committee Meeting

Date: 08-08-2019 Time: 10:00 AM Venue: Physics Laboratory

DAC Members present in the meeting:

SI. No	Member Name	Designation	Role	Signature
1	Dr. Rajasekar. P	HOD & Professor	Convener	Paulos
2	Mrs.Sunitha.N	Assistant Professor	Member	B
3	Mrs. Anu Radha U	Assistant Professor	Member	A
4	Mrs. Sowmya P	Assistant Professor	Member	Son P
5	Dr.Sujatha	HOD & Professor	Member	The second
6	Mrs.Nagashree. G	Assistant Professor	Member	GA
7	Mrs.Ashwini Hindiholi	Assistant Professor	Member	Achart
8	Dr.Jyothi	Assosciate Professor	Member	Just
9	Vanitha G R	Assistant Professor	Member	Vette
10	Mrs. Gayatri annasagaram	Assistant Professor	Member	Get.
11	Mrs.Kalavathi	Assistant Professor	Member	Kolecti.
12	Mrs.Gana Priya	Assistant Professor	Member	Roada
13	Mrs.Reena Patro	Assistant Professor	Member	RAPP

Agenda of the Meeting:

- Inauguration programme for 1st semester students on 25^h Sep 2019.
- · Commencement of orientation Programme from 26th Sep 2019.
- · Conduction of Talents day on 19th Aug 2019.
- · Classes for 1st semester students will be from 8th Aug 2019.
- Organizing value added courses/ certificate courses in the curriculum like Entrepreneurship and innovation.
- · Organizing seminars and webinars.



Minutes of Meeting:

The members discussed suggestions for improvement and reviewed the meeting agenda.

- The committee decided to organize Certification course on "Communication Proficiency" It was discussed to conduct of Talents day on 19th Aug 2019.
- Committee decided to conduct webinar on Introduction to Research Methodology. Committee members agreed to conduct a seminar on environmental pollution.

6. fine Convener

Dr. Rajasekhar. P

Dr P. RAJASEKHAR, M.Sc; M.Phil; Ph.D Hit 1D OF THE DEPT. OF CHEMISTRY CITY ENGINEERING COLLEGE, BEBUILT Standard, Kanakapura Main Road BANGALORE - 560 062. Ph (O) 26869313 (M) 92428 92734

Department of Physics

HEAD OF THE DEPT. OF PHYSICS ... Y ENGINEFPING COLLESS, Dou-Akalinsandra Russidapuis Main Road, BANGALORE - 560 082.

	I Sem B. E. / B. Tech. / B. Arch. (Tentative)	III, V & VII Sem B. E. /B. Tech. III, V,VII & IX Sem B. Arch.	III & V Sem MCA	III Sem MBA	III Sem M. Tech.	III Sem M. Arch.
Commencement of ODD Semester	01.08.2019	29.07.2019	29.07.2019	08.08.2019	26.08.2019	08.09.2019
Last Working day of ODD Semester	29.11.2019	30.11.2019	30.11.2019	05.12.2019	23.12.2019	06.01.2020
Practical Examinations	03.12.2019 To 13.12.2019	03.12.2019 To 13.12.2019	03.12.2019 To 07.12.2019	-		
Theory Examinations	16.12.2019 To 04.01.2020	16.12.2019 То 07.02.2020	09.12.2019 To 28.12.2019	09.12.2019 To 04.01.2020	27.12.2019 To 10.01.2020	08.01.2020 To 22.01.2020
nternship Viva-Voce	-	•	-	a <u>-</u>	12.01.2020 To 19.01.2020	•
Professional training Organization study	-		•	•	-	-
Commencement of EVEN Semester	27.01.2020	10.02.2020	27.01.2020	27.01.2020	27.01.2020	01.02.2020

Academic Calendar of VTU, Belagavi for ODD Semester of 2019-2020 (Jul 2019 - Jan 2020)

Accul All Hode Crown NOTE

- VII Semester B. E / B. Tech students shall have to undergo Internship for a period of four Weeks. .
- . I Semester B. E/ B. Tech / B. Arch Students shall compulsorily undergo Induction Program for a period of 3 Weeks (two phases) as per the schedule given by VTT First phase 11 days in first semester and second phase 10 days in second semester.
- College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notifie 1. separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.

PRINCIPAL TECHNOS

- If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTR

alast	August	2010	0	ntomh	er-2019	020(OD	October-2019	No	vember-2019	Dec	ember-2019
AY		EVENT	-	DATE		DATE	EVENT	DATE	EVENT		EVENT
		IOM ON CURI		DAIE	EVENT	DAIE	CVENI	DAIL	LYUN	DATE	
START	INGOF	IGHER SEME	STERS(3rd			1					
5	th & 7th	sem 29.7.2019	mon)			2					
						2	GANDH JAYANTI				
THU	1	STATRTING OF	FIRSTSEM			3			10111000		
									KANAKADASA RAJMOTSVA(DH		
R	2					4		1)		
SAT	3					5		2			
SUN	4			1		6		3		1	La la cara de
MON	5			2	VINAYAKA CHATURTI	7	MAHALAYA AMAVASYA(DH) VIJAYA	4	4	2	
TUE	6			3	FIRST	8	DASHAMI(DH)	5	SECOND OF	3	
WED	7	FIRST SEM INC	DUCTION	4	ASSESSMENT	9		6	FOR1st SEM	4	
THU	8			5	3rd, 5th, 7th semester	10		7		5	
FRI	9			6		11		8		6	
SAT	10	2nd Satuarday	/ holiday	7		12	2nd satuarday holida	-	2nd satuarday h	7	
SUN	11			8		13		10		8	
MON	12	bakrid(DH)		9		14		11		9	
TUE	13			10	MOHARAM(DH)	1000		12		10	THIRD CIE
WED	14			11	morrowitery	16		13			FOR FIRST SEM
THU	15	INDEPENDENC	E DAY(DH)	12		17		14		12	
FRI	16			13		18		15	KANAKA JAYAN	13	
SAT	17			14	2nd Saturday	19		16		14	
SUN	18			15		20		17		15	By the start
MON	19	TALENTSDAY		16		21	SECOND INTERNAL	18	INTERNAL TEST	16	
TUE	20			17		22	ASSESSMENT 3rd, 5th, & 7th	19	ASSRSSMENT	17	
WED	21			18		23	semester	20	3rd,5th,&7th semesters	18	FOR 1ST SEM
THU	22			19		24		21	School S	19	TOIL TOIL COLUM
FRI	23			20		25		22		20	
SAT	24	4th sataurday		21	FIRST CIE FOR FIRST SEM.	26	4th satuarday holiday	22	4th satuarday		LAST WORKING DAY 1ST
SUN	25	in social only		22		27		23		21	SEM(REVISED)
MON	26			23		28		24		23	A CARLES AND
TUE	27			24		29	DEEPAVALI(DH)	25		23	1
WED	28	_		25		30		27	IAB TESTS		VTU PRACTICAL: 1s
THU	29			26		31		28	- 3rd,5th,&7th SEMs		CENTER 22
TRI	30			27				20	Last working day	20	2.19 To 3.01.2 THEORY
AT	31	5th Satuarday		28	4TH satuarday HOLIDAY			30	LAST WORKING DAY 3rd, 5th& 7th SEM	28	EXAMS 1st SEMESTERS 6.01.20to28.0 .2020
UN 10N				30					Rou		1.1
UE				50				-		10.00	un

CITY ENGINEERING COLLEGE

Kanakapura Main Road, BANGALORE - 550 061



ACADEMIC YEAR: 2019-20

DEPARTMENT OF BASICSCIENCE <u>COURSE PREFERENCE</u>

Name of the Faculty: Dr. Sujatha K

Designation: Professor and HOD

Sl. No	Course Code and Name	Year/Semester
1.	18PHY12 ENGINEERING PHYSICS FOR B SECTION	2019/I

Ke

Signature of Faculty

Department of Physics

12 HOD

Department of Physics



ACADEMIC YEAR: 2019-20

DEPARTMENT OF BASICSCIENCE <u>COURSE PREFERENCE</u>

Name of the Faculty: Mrs. Nagasree G

Designation: Assistant Professor

Sl. No	Course Code and Name	Year/Semester
1.	18PHY12 ENGINEERING PHYSICS FOR A SECTION	2019/I

(gut

Signature of Faculty Department of Physics

HOD

Department of Physics



CITY ENGINEERING COLLEGE TIME TABLE – FIRST SEMESTER 2019-20 **PHYSICS CYCLE**

SEC	CTION: A							ROOM NO	D: A006
DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON	MAT	РНҮ		ELE	CIV		← PHY	L/EGDL/ELEL/A1/A2	2/A3→
TUE	ELE	MAT		РНҮ	ELE		CIV	EGH	LIBARARY
WED	CIV	←PHYL/	EAK	EGDL/ELEI	L/A2/A3/A1→	LUNCH	РНҮ	МАТ	
THU	ELE	CIV	/BRE.	PHY MAT		ILUY	←PH	IYL/EGDL/ELEL/A3	A1/A2→
FRI	EGD	EGD		MAT	РНҮ		EDUSAT/DEP/COLLEGE ACVIVITIES		VIVITIES
SAT	РНҮ	ELE		EGD					

MAT-Dr. Jyothi.P **CIV - Prof.Veeresh** EGH - Dr.K.Sujatha & Prof. Nagashree G PHYL-Dr.K.Sujatha & Prof. Nagashree G ELE - Prof. Mallikarjuna.G.S PHY - Dr.K.Sujatha & Prof. Nagashree G EGD - Dr. Karunakara, Prof.Avinash ELEL - Prof. Mallikarjuna.G.S & Prof.Ravindra.S

PROCTORS - Prof. Nagashree.G & Prof. Veeresh

Ruemurenes

Principal City Engineering College, Bangalore-560 061

HOD

PRINCIPAL



CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER 2019-20 PHYSICS CYCLE

SECTION: B

ROOM NO: A005

DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON	CIV	ELE		MAT	РНҮ		EGD	EGD	
TUE	ELE	РНҮ		CIV	МАТ		←PHYL/F	GDL/ELEL/I	B1/B2/B3→
WED	MAT	ELE	AK	РНҮ	EGH	LUNCH	←PHYL/B	EGDL/ELEL/I	B2/B3/B1→
THU	РНҮ	MAT	BREA	ELE	CIV	ra	РНҮ	EGH	LIBARARY
FRI	MAT	←PHYL		EGDL/ELEL/	/ B3/B1/B2→		EDUSAT/DEP/COLLEGE ACVIVITIES		ACVIVITIES
SAT	ELE	CIV		РНҮ					

MAT- Dr. Jyothi.P CIV - Prof.Veeresh EGH - Dr.K.Sujatha & Prof. Nagashree G PHYL-Dr.K.Sujatha & Prof. Nagashree G ELE – Dr. Shalini Prasad PHY - Dr.K.Sujatha & Prof. Nagashree G EGD – Prof. Shruthi & Prof Anil ELEL - Prof. Mallikarjuna.G.S & Dr. Shalini Prasad

PROCTORS - Prof. Nagashree G & Prof. Shruthi

29

HOD

Russurenes

Principal City Engineering College, Bangalore-560 061

PRINCIPAL



CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER 2019-20 PHYSICS CYCLE

Dr.	K. Sujatha						SUBJEC	T CODE: 18	PHY12
DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON					В				
TUE		В					←	-PHYL/B1	→
WED			GAK	В		LUNCH	←	-PHYL/B2	→
THU	В		BRE			TUN	В		
FRI		←PHYL/B3		PHY	L/B3→				
SAT				В					

Russureres

Principal City Engineering College, Bangalore-560.061

PRINCIPAL

HOD



CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER 2019-20 PHYSICS CYCLE

Mrs	Mrs. Nagashree. G SUBJECT CODE: 18PHY12								2
DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON		Α					←	PHYL/A2	→
TUE			-	Α		-			
WED		←PHYL/A2	BREAK	PHY	YL/A2→	LUNCH	Α		
THU			/BR	А		LUI	← PHYL/A2		→
FRI					Α				
SAT	Α								

Russurenes

Principal City Engineering College, Bangalore-560.061

PRINCIPAL

HOD

VISVESVARAYA TECHNOLOGICAL UNIVERSITY, BELAGAVI

B.E. SYLLABUS FOR 2018-2022

ENGINEERING PHYSICS

(Common to all Branches)

(Effective from the academic year 2018-19)

Course Code : 18PHY12/22	CIE Marks : 40
Contact Hours/Week: 05(3L+2T)	SEE Marks: 60
Total Hours: 50 (8L+2T per module)	Exams. Hours: 03
Semester: I/II	Credits: 04(3:2:0)

Course Learning Objectives: This course (18PHY12/22) will enable students to

- Learn the basic concepts in Physics which are very much essential in understanding and solving engineering related challenges.
- Gain the knowledge of newer concepts in modern physics for the better appreciation of modern technology

MODULES MODULE-I :

Oscillations and Waves

Free Oscillations: Definition of SHM, derivation of equation for SHM, Mechanical and electrical simple harmonic oscillators (mass suspended to spring oscillator), complex notation and phasor representation of simple harmonic motion. Equation of motion for free oscillations, Natural frequency of oscillations.

Damped and forced oscillations: Theory of damped oscillations: over damping, critical & under damping, quality factor. Theory of forced oscillations and resonance, Sharpness of resonance. One example for mechanical resonance.

Shock waves: Mach number, Properties of Shock waves, control volume. Laws of conservation of mass, energy and momentum. Construction and working of Reddy shock tube, applications of shock waves.

Numerical problems

(RBT Levels L1, L2, L3)

MODULE-II:

Elastic properties of materials:

Elasticity: Concept of elasticity, plasticity, stress, strain, tensile stress, shear stress, compressive stress, strain hardening and strain softening, failure (fracture/fatigue), Hooke's law, different elastic moduli: Poisson's ratio, Expression for Young's modulus (Y), Bulk modulus (K) and Rigidity modulus (n) in terms of α and β . Relation between Y, n and K, Limits of Poisson's ratio.

Bending of beams: Neutral surface and neutral plane, Derivation of expression for bending moment. Bending moment of a beam with circular and rectangular cross section. Single cantilever, derivation of expression for young's' modulus

Torsion of cylinder: Expression for couple per unit twist of a solid cylinder (Derivation), Torsional pendulum-Expression for period of oscillation.

Numerical problems

(RBT Levels L1, L2, L3)

Page 1 of 9

MODULE- III:

Maxwell's equations, EM waves and Optical fibers

Maxwell's equations: Fundamentals of vector calculus. Divergence and curl of electric field and magnetic field (static), Gauss' divergence theorem and Stokes' theorem. Description of laws of electrostatics, magnetism and Faraday's laws of EMI. Current density & equation of Continuity; displacement current (with derivation) Maxwell's equations in vacuum

EM Waves: The wave equation in differential form in free space (Derivation of the equation using Maxwell's equations), Plane electromagnetic waves in vacuum, their transverse nature, polarization of EM waves(Qualitative)

Optical fibers: Propagation mechanism, angle of acceptance. Numerical aperture. Modes of propagation and Types of optical fibers. Attenuation: Causes of attenuation and Mention of expression for attenuation coefficient. Discussion of block diagram of point to point communication. Merits and demerits Numerical problems

(RBT Levels L1, L2)

MODULE IV:

Quantum Mechanics and Lasers

Quantum mechanics: Introduction to Quantum mechanics, Wave nature of particles, Heisenberg's uncertainty principle and applications (non confinement of electron in the nucleus), Schrodinger time independent wave equation, Significance of Wave function, Normalization, Particle in a box, Energy eigen values of a particle in a box and probability densities

Lasers: Review of spontaneous and stimulated processes, Einstein's coefficients (derivation of expression for energy density). Requisites of a Laser system. Conditions for laser action. Principle, Construction and working of CO2 and semiconductor Lasers.

Application of Lasers in Defense (Laser range finder) and Engineering (Data storage) Numerical problems

(RBT Levels L1, L2, L3)

MODULE-V:

<u>Material science</u>

Quantum Free electron theory of metals: Review of classical free electron theory, mention of failures. Assumptions of Quantum Free electron theory, Mention of expression for density of states, Fermi-Dirac statistics (qualitative), Fermi factor, Fermi level, Derivation of the expression for Fermi energy, Success of QFET.

Physics of Semiconductor: Fermi level in intrinsic semiconductors, Expression for concentration of electrons in conduction band, Hole concentration in valance band (only mention the expression), Conductivity of semiconductors(derivation), Hall effect, Expression for Hall coefficient(derivation)

Dielectric materials: polar and non-polar dielectrics, internal fields in a solid, Clausius-Mossotti equation(Derivation), mention of solid, liquid and gaseous dielectrics with one example each. Application of dielectrics in transformers.

Numerical problems

(RBT Levels L1, L2, L3)

Page 2 of 9

Course Outcomes:

Upon completion of this course, students will be able to

- 1. Understand various types of oscillations and their implications, the role of Shock waves in various fields and Recognize the elastic properties of materials for engineering applications
- 2. Realize the interrelation between time varying electric field and magnetic field, the transverse nature of the EM waves and their role in optical fiber communication.
- 3. Compute Eigen values, Eigen functions, momentum of Atomic and subatomic particles using Time independent 1-D Schrodinger's wave equation
- 4. Apprehend theoretical background of laser, construction and working of different types of laser and its applications in different fields
- 5. Understand various electrical and thermal properties of materials like conductors, semiconductors and dielectrics using different theoretical models.

Question paper pattern:

Note:- The SEE question paper will be set for 100 marks and the marks will be proportionately reduced to 60.

- The question paper will have ten full questions carrying equal marks.
- Each full question consisting of 20 marks.
- There will be two full questions (with a maximum of four sub questions) from each module.
- Each full question will have sub question covering all the topics under a module.
- The students will have to answer five full questions, selecting one full question from each module.



LESSON PLAN FOR ODD SEMESTER FOR ACADEMIC YEAR 2019-20

Course Title: Engineering Physics	Course Code : 18PHY21
Total contact hours: L:T:P:S :: 05 (3L+2T)	End Tenn Marks : 100
Internal Marks: 40	
Semester : IIII	Academic year 2019-20
Lesson plan Author: Dr k Sujatha &	Date 08/08/2021
Nagashree G	Date 00/00/2021

Course Objective:

This course (18PHY12/22) will enable students to

C Learn the basic concepts in Physics which are very much essential in understanding and solving engineering related challenges.

O Gain the knowledge of newer concepts in modern physics for the better appreciation of

Course Outcomes:

On completion of this course, students will have know ledge. in:

CO I: Understand various types of oscillations and their implications, the role of Shock waves in various fields and Recognize the elastic properties of materials for engineering applications CO2: Realize the interrelation between time varying ele iric field and magnetic field, the transverse nature of the EM waves and their role in optical fiber communication.

0

C03: Compute Eigen values, Eigenfunctions, mom..:ntum of Atomic and subatomic particles using Time independent 1-D Schrodinger's wave quation

CO4: Apprehend theoreti cal background of laser, construction and working of different types of laser and its applications in different fields

COS: Understand various electrical and theimal properties of materials like conductors, semiconductors and dielectrics using difthent theoretical models.

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
			Level	(CO)
1	1	Definition of SHM, derivation of equation for SHM, Mechani cal and electrica l simpl e harmonic oscillators (mass suspended to sprin g osc illator), complex notation and phasor representation of simple harmonic motion.	R,U.	COl
1	2	Equation of motion for free oscillations, Ntural frequency or oscillations.	R,U	COI

MODULE-I

		dampingQual ity factor.		
	4		R,U,E,C	
		Theory offorced oscillations and		COl
		resonance, Sharpness of resonance.		
		One example for mechanical		
		resonance.		
2	1		· R,U	COl
		Mach number, Properties of Shock		
		waves, control volume.		
	2		R,U	CO 1
		Laws of conservation of mass,		
		energy and momentum		
	3		R,U	COl
		Construction and working of		
		Reddy shock tube, applications of		•
		shock waves.		
		Numerical problems		

MODULE-2	2

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
4	ľ	Concept of elasticity, plasticity, stress, strain, tensile stress, shear stress, compressive stress, strain hardening and strain softening	R,U	C02
	2	Failure (fracture/fati gue), Hooke's law, different elastic moduli : Poisson's ratio, Expression for Young's modulus (Y)	R,U ()	C02
	3	Bulk modulus (K) and Rigidity modulus (n) in terms of and p. Relation between Y, n and K, Limits of Poisson's ratio	R,U	C02
5	I	Neutral surface and neutral plane, Derivation of expression for bending moment	R,U	C02
	2	Bending moment of a beam with circular and rectan gular cross section	R,U	CO2
	3	Single cantileve r, derivation of expression for young's' modulus	R,U	C02
	4	Expression for couple per unit twist of a solid cylinder (Derivation), Torsional pendulum-Expression for period of oscillation. Numerical problems	R.U	CO2

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
			Levei	(CO)
6	1	Fundamentals of vector calculus.	R.U	C03
	2	Divergence and curl of electric field and magnetic field (static), Gauss' divergence theorem and Stokes' theorem.	R.U	C03
	3	Description of laws of electrostatics, magnetism and Faraday's Jaws of EM1	R,U,E	C03
	4	Current density & equation . of Continuity; displacement current (with derivation) Maxwell's equations in vacuum	R,U	C03
7	1	The wave equation in differential form in free space (Derivation of the equation using Maxwell's equations),	R,U	C03
	2	Plane electromagnetic waves in vacu um, their transverse nature, polarization of EM waves(Qualitative)	R,U	C03
8		Propagation mechanism, angle of acceptance. Numerical apertu re.	R.U,C	C04
	2	Modes of propagation and Types of optical fibers.	R,U,Al	C04
	3	Attenuation: Causes of attenuation and Mention of expression for attenuation coefficient.	R,U	C04
	4	Discussion of block diagram of point to point communication. Merits and demerits	R,U	C04
	5	Numerical problems	R,U	C04

MODULE-4

Week	Days/	Contents of Module	Bloom's	Course
	Date		Taxonomy	Outcome
			Level	_(COl
9	1	Introduction to Quantum mechanics, Wave nature of particles, Heisenberg's uncertainty principle and applications		C04
	2	Schrodinger time independent wave equation, Significance of Wave function		C04
1	3	Normal ization, Particle In a box, Energy eigen values of a particle in a box and proba bility densities.	R,U	C04 ·
10	1	Review of spontaneous and stimul ated processes, Einstein's	R,U	C04

		_coefficients (derivation of e pr sion for energy density)		
	2	Requisites of a Laser system.	_B,,,U	C04
	3	Conditions for laser action. Principle	R,U	C04
		Construction and working of CO2		
		and semiconductor Lasers.		
	4	Application of Lasers in Defense	R,U	C04
		(Laser range finder) and Engineering		
		(Data storage) '		
		Numerical problems		

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
	Date		Level	(CO_1
13	I	Review of classical free electron theory, mention of failures.	R,U,A2	C04
	2	Assumptions of Quantum Free electron theery	R,U	C04
	3	Mention of expression for density of states	R,U	COS
	4	Fermi-Dirac statistics (qualitative), Fermi factor	RU	COS
14	1	Fermi level, Derivation of the expression for Fermi energy, Success of QFET.	R,U,E	COS
	.2	Fermi level in intrinsic semiconductors	R,U	COS
	3	Expression for concentration of electrons in conduction band	R,U	COS
	4	Hole concentration in valance band (only mention the expression)	R,U	COS
15	I	Conductivity of semiconductors(derivation), Hall effect, Expression for Hall coefficient(derivation)	R,U	COS
	2	polar and non-polar dielectrics	R,U.A1,C	COS
	3	internal fields in a solid	R,U	COS
	4	Clausius-Mossotti equation(Derivation)	R,U	COS
16	1	mention of solid, liquid and gaseous	R,U	COS
	2	dielectrics with one example each.	R,U	COS
	3	Application of dielectrics in transformers	R,U	COS
	4	Numerical problems	R.U,Al,C	COS

MODULE-S

. *

Bloom's Taxonomy Level.

· R-Remembering U-Understanding A-Applying A2-Analysing E-Evaluating C-Creating

Text Books:

1. A Text book of Engineering Physics- M.N A vadhanulu and P.G. Kshirsagar, l0th revised Ed, S. Chand & Company Ltd, New Delhi

··· ·

2. Engineering Physics-Gaur and Gupta-Dhanpat Rai Publications-2017

3. Concepts of, Modem Physics-Arthur Beiser: 6th ;Tata McGraw-Hill Edu Pvt Ltd-New Delhi 2006

Reference books:

I. Introduction to Mechanics —MK Verma: 2nd Ed, University Press(India) Pvt Ltd, Hyderabad 2009

2. Lasers and Non Linear Optics - BB laud, 3rd Ed, New Age International Publishers 2011

3. Solid State Physics-S O Pillai, 8th Ed- New Age International Publishers-2018

4. Shock waves made simple- Chintoo S Kumar, K Takayama and K.PJ Reddy: Willey India Pvt. Ltd. New Delhi2014

5. Introduction to Electrodynamics- David Griffiths: 4th Ed, Cambridge University Press 2017

Ke

Signature of Staff

Signature of HOD



Question Bank

Course Name: Engineering Physics

Course Code: 18PHYS12

Semester: I

Section: A, B

Module 1-Free oscillations

1.Define Simple Harmonic Motion. Derive the equation of motion foe SHM.

2.Derive the expression for force constants for series and parallel combination of springs.

3.Explain how Complex notation Phasor representation is represented.

4.Define free oscillations with example. Mention the equation of motion of natural frequency of vibration.

5. What are Damped oscillations. Give the theory. Discuss the case of under damping, over damping and critical damping.

6.Define Quality factor with equation. Give its Physical significance.

7.What are Forced Oscillations .Derive the expressions for amplitude and Phase of Forced vibrations. Explain all the three cases.

8.Write a short notes on a)Sharpness of Resonance b)Helmoltz Resonator

Shock waves

1. Define Mach Number and Mach angle

2.Distinguish between Acoustic ,Ultrasonic ,subsonic, supersonic, transonicand hypersonic waves.

0

3. What are shock waves and mention the properties of shock waves.

4.Explain Control Volume.

5.State and explain the law of conservation of mass ,momentum and energy with expressions .

6.Describe the construction and working of Reddy Shock tube experiment.

7. What are the applications of Shock waves.



Module 2-Eiastic properties of materials

- 1. Explain Elasticity and Plasticity with examples.
- 2.Explain the importance of elasticity in engineering materials.
- 3.Explain the terms Stress and Strain. Discuss the three types of Stresses.
- 4.Discuss briefly the effect of stress, temperature, annealing and impurities on elasticity.
- 5.Describe Strain hardening and Strain softening.
- 6.State and explain Hooke's law with stress-strain curve.
- 7.Discuss three different moduli of elasticity with equations.
- 8.Define Lateral Strain and Linear Strain and s derive the expression for Poisson's ratio.
- 9.Derive the relation between shear strain, longitudinal strain and compression strain.
- 10. Derive the relation between Y,η and G.
- 11. Derive the relation between K, Y and 6.
- 12. Derive the relation between K, and Y.
- 13.Discuss the limiting values of σ and limitations of Poisson's ratio.
- 14.Define Beam and explain different types of beams and mention their engineering applications .
- 15.Define neutral surface and neutral axis.
- 16.Define bending moment and derive the expression for bending moment in terms of moment of inertia. Mention the expression for bending moment for circular and rectangular cross section.
- 17.Describe a single cantilever and hence derive the expression for depression.
- 18.Explain Torsional oscillations. Derive the expression for Couple per unit twist for a solid cylinder.
- 19.Mention the expression for Time period for Torsional oscillations Briefly explain the applications of torsional pendulum.



Module 3

Maxwell's Equations and Electromagnetic waves

1.Explain Scalar Product and Vector product.

2.Describe Vector Operator and explain the concepts of gradient, divergence and curl along with physical significance.

3.Discuss three different types of integration like linear, surface and volume integrations.

4.Explain Gauss flux theorem in electrostatics and magnetism.

5.Derive Gauss Divergence theorem. Mention Stokes theorem.

6.Discuss Maxwell- Ampere's law, Biot-Savarts law.

7.Explain briefly the Faraday's law of electromagnetic induction. Express the same in the differential form of maxwell's equation in the case of time-varying fields.

8.Discuss Continuity equation. Define Displacement current and arrive the expression for the same.

9.List the Maxwell's equations for time-varying condition and for static conditions.

10. Derive wave equation in terms of electric field using Maxwell's equations.

11.Explain the plane electromagnetic waves in vacuum along with the equations for E, B and c.

12. Explain the transverse nature of electromagnetic waves and explain linear , elliptical and circular polarizations.

Optical Fibers

1.Describe the propagation mechanism of light through in an optical fiber.

2. What is numerical aperture? Obtain an expression for numerical aperture in an optical fiber and then arrive the condition for propagation.

3.Explain modes of propagation and V number.

4.Explain different types of optical fibers.



5. Define attenuation. Explain different types of attenuation, mention the expression for attenuation coefficient.

6.Explain point to point communication system with the help of block diagram.

7.Explain merits and demerits of optical fiber communications.

Module 4- Quantum Mechanics

I. Give a brief account of blackbody radiation and Planck's radiation law with two conditions.

2.Explain dual nature of matter waves.

3.State de Broglie's hypothesis. Show that the de-Broglie wavelength of an electron is found to be equal to 1.226N nm.

4. Explain Heisenberg's uncertainty principle and show that electrons cannot exists within the nucleus.

5.Construct one dimensional time independent Schrodinger wave equation.

6. What are the properties of wavefunction.

7.Explain the terms probability density, normalization.

8.Discuss Eigenvalues and Eigenfunctions.

9.Solve Schrodinger wave equation for the allowed energy values in the case of particle in a box.

10. Discuss Probability for a particle in a potential well of infinite height.



Lasers

1.Explain Induced absorption, Spontaneous emission, stimulated emission.

2.Derive the expression for energy density using Einstein's coefficients.

3.Explain the requisites of a laser system.

4.Explain the condition for laser action.

5.Explain three different vibrational modes of CO₂ molecule. With a neat energy level diagram explain the construction and working of CO₂ laser .
6. Explain the construction and working of Semiconductor laser .

7.Describe how a laser range finder is made use of in defense.

8.Explain how data storage is achieved in a compact disc.

Module 5 - Material Science

1.What are the assumptions of classical free electron theory and the failures of classical free electron theory.

2. What are the assumptions of Quantum free electron theory.

3.Define density of states and mention the expression for density of states.

4.Explain Fermi level, Fermi energy, Fermi-Dirac statistics.

5.Define Fermi Factor. Discuss the variation of Fermi Factor on different conditions of temperature and energy.

6.Derive the expression for Fermi energy at zero Kelvin. Mention the expression for Fermi velocity and Fermi temperature.

7. Discuss the success of Quantum free electron theory.

8.Discuss the Fermi level in intrinsic semiconductor. Mention the expression for electron and hole concentration in intrinsic semiconductor.



9.Derive the relation between Fermi energy and energy gap for an intrinsic semiconductor.

10.Derive the expression for electrical conductivity of semiconductors.

11.What is Hall Effect? Obtain the expression for Hall voltage in terms of Hall coefficient.

12.What are dielectric materials .Explain the types of dielectric materials. Discuss solid ,liquid and gaseous dielectric with one example each.

13.Explain polarization and the types of polarization. Mention the relation between dielectric constant and polarization.

14.Define internal field in case of solids and mention its expression for one dimensional case, three-dimensional case and Lorentz field.

15.Derive Clausius-Mossotti equation.

16.Mention the application of dielectric in transformers.

Gut

Staff Mrs. Nagasree G Department of Physics

HOD Dr. Sujatha Department of Physics



Assignment Questions

Odd Semester 19-20

Course Name: Engineering Physics

Course Code: 18PHYS22

Semester: II

Section: C

Module 1-Free oscillations

1.Define Simple Harmonic Motion. Derive the equation of motion foe SHM.

2.Derive the expression for force constants for series and parallel combination of springs.

3.Explain how Complex notation Phasor representation is represented.

4.Define free oscillations with example. Mention the equation of motion of natural frequency of vibration.

5. What are Damped oscillations. Give the theory. Discuss the case of under damping, over damping and critical damping.

6.Define Quality factor with equation. Give its Physical significance.

7.What are Forced Oscillations .Derive the expressions for amplitude and Phase of Forced vibrations. Explain all the three cases.

8.Write a short notes on a)Sharpness of Resonance b)Helmoltz Resonator

Shock waves

1. Define Mach Number and Mach angle

2.Distinguish between Acoustic ,Ultrasonic ,subsonic, supersonic, transonicand hypersonic waves.

0

3. What are shock waves and mention the properties of shock waves.

4.Explain Control Volume.

5.State and explain the law of conservation of mass ,momentum and energy with expressions .

6.Describe the construction and working of Reddy Shock tube experiment.

7. What are the applications of Shock waves.



Module 2-Eiastic properties of materials

- 1.Explain Elasticity and Plasticity with examples.
- 2.Explain the importance of elasticity in engineering materials.
- 3.Explain the terms Stress and Strain. Discuss the three types of Stresses.
- 4.Discuss briefly the effect of stress, temperature, annealing and impurities on elasticity.
- 5.Describe Strain hardening and Strain softening.
- 6.State and explain Hooke's law with stress-strain curve.
- 7.Discuss three different moduli of elasticity with equations.
- 8.Define Lateral Strain and Linear Strain and s derive the expression for Poisson's ratio.
- 9.Derive the relation between shear strain, longitudinal strain and compression strain.
- 10. Derive the relation between Y,η and G.
- 11. Derive the relation between K, Y and 6.
- 12. Derive the relation between K, and Y.
- 13.Discuss the limiting values of $\mathbf{6}$ and limitations of Poisson's ratio.
- 14.Define Beam and explain different types of beams and mention their engineering applications .
- 15.Define neutral surface and neutral axis.
- 16.Define bending moment and derive the expression for bending moment in terms of moment of inertia. Mention the expression for bending moment for circular and rectangular cross section.
- 17.Describe a single cantilever and hence derive the expression for depression.
- 18.Explain Torsional oscillations. Derive the expression for Couple per unit twist for a solid cylinder.
- 19.Mention the expression for Time period for Torsional oscillations .Briefly explain the applications of torsional pendulum.



Module 3

Maxwell's Equations and Electro magnetic waves

1.Explain Scalar Product and Vector product.

2.Describe Vector Operator and explain the concepts of gradient, divergence and curl along with physical significance.

3.Discuss three different types of integration like linear ,surface and volume integrations.

4.Explain Gauss flux theorem in electrostatics and magnetism.

5.Derive Gauss Divergence theorem. Mention Stokes theorem.

6.Discuss Maxwell- Ampere's law, Biot-Savarts law.

7.Explain briefly the Faraday's law of electromagnetic induction. Express the same in the differential form of maxwell's equation in the case of time-varying fields.

8.Discuss Continuity equation. Define Dispalcement current and arrive the expression for the same.

9.List the Maxwell's equations for time-varying condition and for static conditions .

10.Derive wave equation in terms of electric field using Maxwell's equations.

11.Explain the plane electromagnetic waves in vacuum along with the equations for E,B and c.

12. Explain the transverse nature of electromagnetic waves and explain linear ,elliptical and circular polarizations.

Optical Fibers

1.Describe the propagation mechanism of light through in an optical fiber.

2. What is numerical aperture? Obtain an expression for numerical aperture in an optical fiber and then arrive the condition for propagation .

3.Explain modes of propagation and V number.

4.Explain different types of optical fibers.



5. Define attenuation. Explain different types of attenuation, mention the expression for attenuation coefficient.

6.Explain point to point communication system with the help of block diagram. ...

7.Explain merits and demerits of optical fiber communications.

Module 4- Quantum Mechanics

I.Give a brief account of blackbody radiation and Planck's radiation law with two conditions.

2.Explain dual nature of matter waves.

3.State de Broglie's hypothesis. Show tat the deBroglie wavelength of an electron is found to be equal to 1.226N nm.

4. Explain Heisenberg's uncertainity principle and show that electrons cannot exists within the nucleus.

5. Construct one dimensional time independent schrodinger wave equation.

6. What are the properties of wavefunction.

7.Explain the terms probability density, normalization.

8. Discuss Eigenvalues and Eigenfunctions.

9.Solve schrodinger wave equation for the allowed energy values in the case of particle in a box.

10. Discuss Probability for a particle in a potential well of infinite height.



Lasers

1.Explain Induced absorption, Spontaneous emission, stimulated emission.

2.Derive the expression for energy density using Einstein's coefficients.

3.Explain the requisites of a laser system.

4.Explain the condition for laser action.

5.Explain three different vibrational modes of CO_2 molecule. With a neat energy level diagram explain the construction and working of CO_2 laser.

6. Explain the construction and working of Semiconductor laser .

7.Describe how a laser range finder is made use of in defense.

8.Explain how data storage is achieved in a compact disc.

Module 5 - Material Science

1.What are the assumptions of classical free electron theory and the failures of classical free electron theory.

2. What are the assumptions of Quantum free electron theory.

3.Define density of states and mention the expression for density of states.

4.Explain Fermi levei, Fermi energy, Fermi-Dirac statistics.

5.Define Fermi Factor. Discuss the variation of Fermi Factor on different conditions of temperature and energy.

6.Derive the expression for Fermi energy at zero Kelvin. Mention the expression for Fermi velocity and Fermi temperature.

7. Discuss the success of Quantum free electron theory.

8.Discuss the Fermi level in intrinsic semiconductor. Mention the expression for electron and hole concentration in intrinsic semiconductor.



9.Derive the relation between Fermi energy and energy gap for an intrinsic semiconductor.

10.Derive the expression for electrical conductivity of semiconductors.

11. What is Hall Effect? Obtain the expression for Hall voltage in terms of Hall coefficient.

12.What are dielectric materials .Explain the types of dielectric materials. Discuss solid ,liquid and gaseous dielectric with one example each.

13.Explain polarization and the types of polarization. Mention the relation between dielectric constant and polarization.

14.Define internal field in case of solids and mention its expression for one dimensional case, three dimensional caseand Lorentz field.

15.Derive Clausius-Mossotti equation.

16.Mention the application of dielectric in transformers.

(gr)

Staff Mrs. Nagasree G Department of Physics

HOD

Dr. Sujatha Department of Physics 1 C E 1 9

Subject Code: 18PHY12

CITY ENGINEERING COLLGE

FIRST INTERNAL TEST

Branch : CS Sub Name : Engg. Physics Sem & Sec : I, A/B Duration : 1 ½ hrs

Т

Date :19/09/2019 Time:10:30 to 12:00 Max. Mark:50

QNo.	Answer all questions	Marks	CO's	BT level
	PART A	,_	1	, eve.
1	Derive the expression for energy density using Einstein's coefficients with suitable diagrams?	10	CO4	BTI
	OR			
2	Set up time-independent one-dimensional Schrodinger wave equation. What are the properties of wavefunction.	10	CO3	BT2
	PART B	1		
3	Explain the requisites of a laser system and the condition for laser action with suitable diagrams.	10	CO4	BT1
	OR			
4	Derive the relation between Shear strain, longitudinal strain and elongation strain.	10	COI	BTI
	PART C			
	a)Explain Heisenberg's uncertainity principle and show that electrons cannot exists inside the nucleus.	6	CO3	BT2
5	b)An electron has a speed of 100 m/s. The inherent uncertainity in its measurement is 0.005%.Find the corresponding uncertainities that arises in the measurement of its position.	4	CO3	BT5
	OR	1		
6	Describe the construction and working of CO_2 laser with the help of energy level diagram. Explain the three modes of vibration.	10	CO4	BT1
	PART D	4		
	State and explain Hooke's law with stress – strain curve and discuss three	4		0.771
	different elastic moduli with equations.	6	COI	BT1
	The average output power of a laser emitting a laser beam of wavelength 6328 A ⁰ is 5 mW. Find the number of photons emitted by the source.	4	COI	BT5
	OR	1		
8	Solve Schrodinger wave equation for the allowed energy values in the case of particle in a box.	10	C03	BT2

	PART E	_		•
	Discuss the wave function, Probability densities and its Eigen energy values for a particle in a box with a suitable graph.	7	CO4	BTI
9	Calculate the de Broglie wavelength associated with an electron having a kinetic energy of 100 eV.	3	CO4	BTS
	OR			-
10	Explain the construction and working of semiconductor laser. Give three applications.	10	CO4	BTI

Course Outcomes:

CO1 : Understand various types of oscillations and their implications, the role of Shock waves in various fields and recognize the elastic properties of materials for engineering applications.

CO3 : Compute Eigen values ,Eigen functions, momentum of atomic and subatomic particles using Time independent 1-D Schrodinger wave equation.

CO4 : Apprehend theoretical background of laser, construction and working of different types of laser and its applications in different kinds.

Blooms Taxonomy:

BT1-Knowledge BT2-Understand BT3-Apply BT4-Analyzing BT5-Evaluate BT6--Creating

DEPARTMENT OF PHYSICS

SCHEME FOR VALUATION

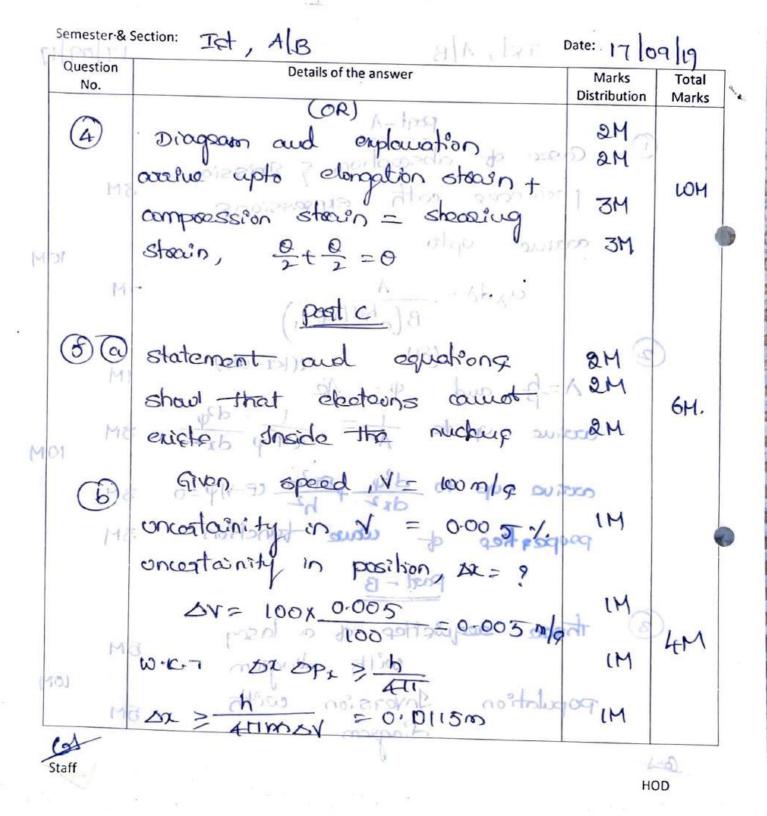
Internal Test

Date: 17 09 19 Semester & Section: ISt, AB Question Details of the answer Marks Total No. (1) Casee of absorption & Smission 3M poore coep with expression & 3M accurve upto No. Distribution Marks 10M undo = A B(chalka _1) JM (2) $\Lambda = \frac{h}{p}$ and $\psi = Ac$ Marrine roporto $\frac{1}{\Lambda^2} = \frac{1}{4\pi^2 \psi} \frac{d^2 \psi}{dx^2}$ 3M .10 MOI active pup to $\frac{d^2 \psi}{dx^2} + \frac{8\pi i^2 m}{h^2} (E-V)\psi = 0$ 3M (3) These of which is 3M (3) These encloses of a laser 5M with diagram 5M Dopulation Shversion with 5M (D) LOM Cont Staff

DEPARTMENT OF PHYSICS

SCHEME FOR VALUATION

Internal Test



DEPARTMENT OF PHYSICS

SCHEME FOR VALUATION

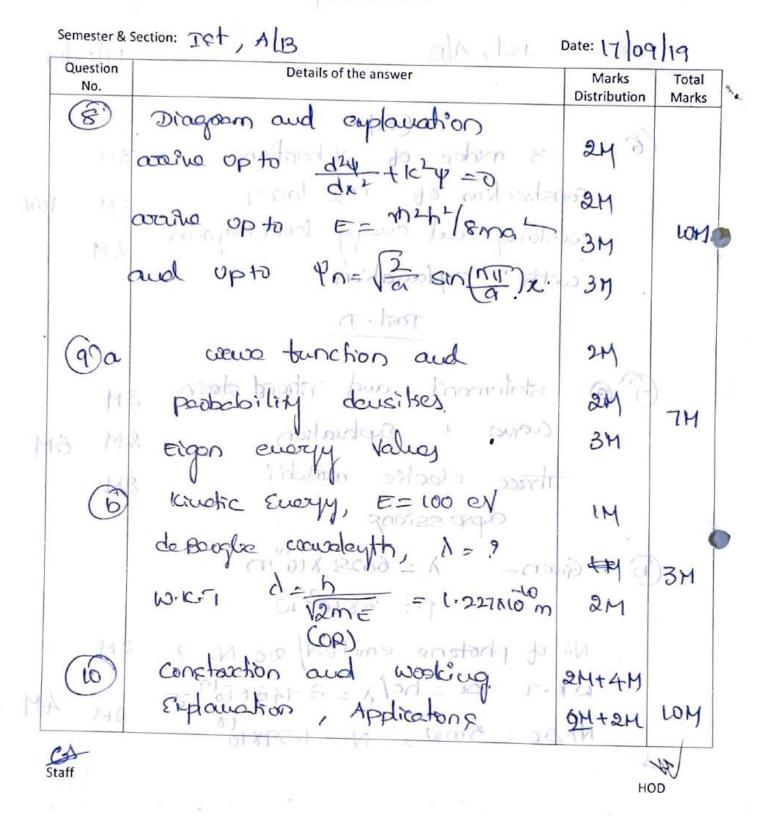
Internal Test

ala tor Date: 17/09/19 Semester & Section: IST, AB Question Details of the answer Total Marks No. Distribution Marks a (81) is bus magas 6 MB 3 made of vibrations anosh Construction of co2 lason LOY. 3M wooking and everyy level dagoon C NO 4M NIN with maxplaughon gigu Post-D where function and 190 statement and stopp storn 2M Esphiation 6M three clackic moduli? expressions Given - $\lambda = 6328 \times 10^{10}$ 5(6) monnec.) p= 5×103 W 1201 No of photons emitted sec. No ? 21 DE= hc/2 = 3.143xid9 W.K.T AM NYDE = 5mw N= 1.59×10 Staff

DEPARTMENT OF PHYSICS

SCHEME FOR VALUATION

Internal Test



Bra	CITY ENGINEERING COLLEGE II Internal b:- Engg Physics 18PHY12 anch:- CS n&Sec:- I, A/B Date:- 05/11/2 Time:-10:30 to Max.Marks-5	o-12.00	P.M	
Q.No.	ANSWER ALL QUESTIONS	MARKS	·· CO.	BT
	ANGWER ALL QUESTIONS		8	Level
	PART-A	· .		
1.	What is Torsional pendulum. Derive the expression for Couple per unit twist for a solid cylinder	10	COI	BT:
	OR			140
2.a)	Derive the expression for Fermi energy at zero kelvin.	7	CO5	BT
b)	Calculate the probability of an electron occupying an energy level 0.02 eV above the Fermi level at 200 K and 400 K in a material.	3	CO5	BTS
	PART-B			
3.a)	Explain in detail Hall Effect with a neat diagram? Obtain the expression for Hall voltage in terms of Hall coefficient .	10	ĊO5	BT2
14 a .	OR			2 8 4
4.a)	Discuss Fermi Factor and the variation of Fermi Factor on different conditions		12.	3.12
	of temperature and energy.	6	CO5	BT1
b)	The Hall co-efficient of a material is $-3.68 \times 10^{-5} \text{ m}$ m3/C. What is the type of charge carriers? Also calculate the carrier concentration.	4	CO5	BT5
**	PART-C.	1.1		
5.a)·	Derive the relation between Y,n and σ .	6	COI	BT6
b)	An increment in length by 1mm was observed in a gold wire of diameter 0.3mm, when it was subjected to a longitudinal force of 2 Newtons ,and a twist			
	of 0.1 radian was observed in the same wire when its one end was subjected to	4	CO1	BT5
	a torque of 7.9×10^{-7} nm, while its other end was fixed. Calculate the value of Poisson's ratio for gold.			
2.5	OR .			1
5.a)	Discuss the success of Quantum free electron theory.	6	CO5	B76
b) :	Define Beam and explain different types of beams and mention their engineering applications.	. 4	CO4	BT2

PART-D

· · ·		· · ·
6	CO5	BT3
n^{3} , 4	CO5	BT5
	. 4	. 4 CO5

	Define Bending moment and derive the expression for bending moment in terms of moment of inertia. Mention the expression for bending moment for rectangular and circular cross section.	10	CO1	BTO
. 5	PART-E			<u> </u>

9.a)	What is polarization in dielectrics. Explain different polarization mechanisms			
b)	Find the polarization produced in a constal being polarization mechanisms	• 7	CO5	BT5
<u> </u>	Find the polarization produced in a crystal by an electric field of strength 500- V/mm if it has a dielectric constant of 6?		CO5	BT2

10.	Define internal fields in case of solids and liquids and mention its	· · · · ·		0.2
4		4		-
	Derive Clasius-Mossotti equation.	6	CO5	BT3

Course outcomes:-

8.

CO1--- Understand various types of oscillations and their implications, the role of shock waves in various fields and recognize the elastic properties of materials for engineering applications.

CO5---Understand various electrical and thermal properties of materials like conductors, semiconductors and dielectrics using different theoretical methods.

Blooms Taxanomy:-

BT1—Knowledge BT2---Understand BT3---Apply BT4---Analyzing BT5----Evaluate BT6----Creating

.....

SCHEME FOR VALUATION

Semester & Section: I & A, B.

Date: 04/11/2019

Question No.	Details of the answer	Marks Distribution	Total Marks
0	Poat-A		
()	Togsional pendulum Explusion	1	100
		2M	* * .
an 10. Ng 10.4 - 15 - 1	with diagram		
	$upto \tau = n\phi = ng\theta$	0.1	IOM
	upto t = np = ngo	24	1910
			•
	avoue up to Twisty coople = TINR 4		
	100 S 10 /21	3M	
1,291			•
*	avoire upto c= TIMR4	3M	1 1 1 1
<i>t</i>	21_	1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -	
(2)a			
ee	NCEL dE = gleidex flej	im	
	upto gueldE = 8/2 Im 312 1		
10	$opto$ guide = $\frac{8\sqrt{2} \sqrt{10}}{13} E^{1/2} dE$	SM .	
		×.	GM
	course up to EFO = BD 2/3	2M	
1 A 1		-11	
1	where $B = \left(\frac{h^2}{8m}\right) \left(\frac{3}{\pi}\right)^{2/3}$	2M	
5	(IT) (8m)		
6	Write τ $f(e) = \frac{1}{ e + e }$		
		M	
	Case(i) - C + 1	IM	
	Caseci) - fce)=0.24 at 200.12		3M
	fcel = 0.36 at 400K	I M	
1		Jus .	1 /

SCHEME FOR VALUATION

Internal Test

Semester & Section: I A.B Date: 4/11/2019 Question Details of the answer Marks Total No. ×.e. Distribution Marks Post -B 3 @ Hall ebbect explanation with 3M Lagram arrive upto Firs EH 2M $Y = \frac{1}{P\omega d}$ $P = \frac{BI}{V_{H}\omega}$ IOM 2M Hall coefficient , RH = 1 $\wedge \quad V_{H} = R_{f_{1}} \left(\frac{BT}{\omega} \right)$ 3M (8) (4) @ Formi tacto explanation a equation three cases of Fermi factor 2M when 6M ELEF 2M 2M E=EF 6 W.K.T RH = = ne 2M n= 1.7×1023 /m3 4M 2M Staff

0

SCHEME FOR VALUATION

Internal Test

Semester & Section: Ist / AXB Date: 4 11 2019 Question Details of the answer . Marks Total No. Distribution Marks Past-C 50 dagen & explanation 2M avaive up to px = 2 $up to n = \frac{1/\alpha}{\alpha(1+\sigma)}$ 2M 6M 0ph ... Y = 2n (1+5) 2M D $W = \frac{FL}{0} + \frac{FL}{TR^2 x}$ IM $\Lambda C = \frac{\pi n R^4}{2L}$ IM 4M Y= 2.848 , 0= =0.424 24 (OR) (6)a TWO SUCCEOPE OF QFET O Temp dependence of électercal anductivity 3M. 6M @ dependerie of o on 'n' 31 G W Staff HED

CITY ENGINEERING COLLEGE DEPARTMENT OF Phylics SCHEME FOR VALUATION Internal Test Ist Semester & Section: Date: 411 2019 AB Question Details of the answer Marks Total No. **Distribution** Marks Detinition of Beam 66 IM for Types of beam 41 · 3M diagram and explanation Pagt -D 66 Explanation of semiconductop 2M W.K.T I= NeAV arrive upto J= OE 6M 21 avoire upto = e (Neple + Nh Hh) σ = nie (μe+μh) aM 6 or = nie (Met Mh) IM Pr= 1M 41 21 1? = 0.449 m Staff

CITY ENGINEERING COLLEGE DEPARTMENT OF PHYSICS SCHEME FOR VALUATION Internal Test Semester & Section: Ist/ AIB Date: 4 11 2019 Question Details of the answer No. Marks Total Distribution (OR) Marks 8 Bendry moment definition QM Lapson X explanation Upto F= Yag arrive 2M Moment of tace = 4 Zag12 IOM 2M B.M = YIg 2M Appetauquity beam, B.M. = 4 (bd3) s section M Acquiles cross section, B-M= Y PAT <u>Post-E</u> Explanation of Polarization 90 IM 77 Three types of polarization 3×2M 6 WIKIT P= Eo (Eg-1) E IM = R.21×105 C/m2 3M 2M Staff

CITY ENGINEERING COLLEGE DEPARTMENT OF Physics SCHEME FOR VALUATION

luestion No.	Section: $D_{8} + \int A_{1} B$ Details of the answer	Date: 4 (Marks	Total
		Distribution	Marks
a. 1. 1.	(OR)	1. A.	
(10)		a	1.1
C	Explanation & Expression top	IM	
	Internal tiolds in one dimension	3M	4 M
	and three dimensions	31-1	
	inter and international second	an an a' 🔒	
	clasius - Mossotti equation		1 × 1
· · .			e a 1
	arrive opto $E = \frac{P}{E_0(E_q - 1)}$		
e	$E = \frac{1}{1}$	3M	
	الم		
•			6M
	arrive up to $(E_{3}-1)$ $N\alpha_{e}$ ($E_{3}+2$) $3E_{0}$	3M	
	(-17) Nue	1 1 A 3	28.14
	· (Eq+2) 3E		· •2
2 E			1
			- C. 🔍
		2 E	
			1.1.1
		· · · · ·	l on si s
			Sec.
			6 - 14 -
90 1			a a second
°			
1 2 2 1			
		. 1	S. also
1			· · ·
iff .		V	K
		fit	OC

1 CE

III Internal

Sub:- Engg Physics 18PHY12 Branch:- CS Sem&Sec:- I, A/B

Date:- 12/12/2019 Time:-10:30 to-12.00 P.M Max.Marks-50

Q.No.	ANSWER ALL QUESTIONS	MARKS	CO' S	BT Level
	PART-A			
1.	What are Damped Oscillations, give the theory. Discuss the case of underdamping.	10	COI	BT2
	OR			

2.a)	State and explain the law of conservation of mass, momentum and energy with expressions.	6	COI	BT3
b)	The distance between two pressure sensors in a shock tube is 150 mm. The time taken by a shock wave to travel this distance is 0.3 ms. If the velocity of sound under the same condition is 340 m/s. Find the Mach number of the shock wave.	4	CO1	BT5

PART-B

3.a) Expalin Gauss theorem in electrostatics. Derive Gauss Divergence theorem.	10	CO2	ET2
--	----	-----	-----

0

OR

4.a)	Discuss Maxwells-Ampere law and Biot Savarts law.	6	CO2	BT1
b)	Find the divergence of the vector field \vec{A} given by $\vec{A} = 6x^2 \hat{a}_x + 3xy^2 \hat{a}_y + xyz^3 \hat{a}_z$ at a point p (1 3 6)	4	CO2	BT5
	PART-C			

5.a)	Define Simple Harmonic Motion. Derive the equation of motion for SHM.	7	COI	ET6
b)	A man weighing 600 N steps on a spring scale machine. The spring in the machine is compressed by 1 cm. Find the force constant of the spring	3	CO1	BT5

OR

6.a)	Distinguish between Acoustic, Ultrasonic, Subsonic and Supersonic waves	6	CO1	BT6
b)	Define Mach number, Mach cone and Mach angle.	4	COI	BT2

USN

5

PART-D

7.a)	Explain the concepts of gradient, divergence and curl along with physical significance	6	C02	BT3
b)	Calculate the curl of \vec{A} Given $\vec{A} = (1+yz^2)\hat{a}_x + xy^2\hat{a}_y + x^2y\hat{a}_z$	4	CO2	BT5
	OR			
8.	Derive the expressions for equivalent force constants for two springs connected in series and parallel with suitable diagrams.	10	CO2	BT3
	PART-E			
9.	What are forced Oscillations . Derive the expressions for amplitude and phase of the forced vibrations.	10	COI	BT?
	OR			
10.	What are Shock Waves . Describe the construction and working of Reddy			

Course outcomes:-

CO1--- Understand various types of oscillations and their implications, the role of shock waves in various fields and recognize the elastic properties of materials for engineering applications.

CO2---Realize the interrelation between time varying electric field and magnetic field, the transverse nature of the EM waves and their role in optical fibre communications.

CO5---Understand various electrical and thermal properties of materials like conductors, semiconductors and dielectrics using different theoretical methods.

Blooms Taxanomy:-

BT1—Knowledge BT2---Understand BT3---Apply BT4---Analyzing BT5----Evaluate BT6----Creating

DEPARTMENT OF physics

SCHEME FOR VALUATION

Internal Test

No.	Details of the answer	Marks Distribution	Total Marks
1.24	Post-A	135	
\odot	Damped ascillations detenition theory	2M	
fint	avoine up to md2x +8 dx +kx=0	am	
	up to x= ce toto b2-w-)t + (-b-15-with +De	2M	
	(10to x - 20 (1. b] (-b+ 12-w).t+	(4) -	lor
145	upto $x = \frac{x_0}{2} \left[\left[1 + \frac{b}{\sqrt{b^2 - w^2}} \right] \left[\left(-b + \sqrt{b^2 - w^2} \right) + \frac{b}{2} \right] \left(-b - \sqrt{b^2 - w^2} \right] + \frac{b}{2} \right]$	am	
× og	Supern underdamping case with	am	
		$(r_{ij})^{ij}$	
48	another (a) a strange in Million		
2 9)	statement a suplanation obvierpossion	3X2M	GM
i = 2	of conservation laws		
ь)	$M = \frac{Us}{a}$, $Us = \frac{d}{t} z$	2M	
14	M = 1.47	2M	41
	Poot - B		
3 00	Statement	2M	
8	averue upto & D. de = JV. D. dv	4M	lom
1 e	with poort	4M	

Question No.Details of the answerMarks DistributionAExplor NoticeMaxwellor AmpereAmpere LawImAExplor NMaxwellor NAmpere LawImAExplor NBiot StributionXH=ImAExplor NBiot StributionStribution NImAExplor NBiot StributionStribution NImBTA=ImImBTA=ImImBTA=ImImBTA=ImImBTA=ImImBTAImImBKImImImCKImImCKImImCKImImCKImImCKImImCKImImCKImImCKImCKImCKImCKImCKImCKImCKImCKImCKImCKImCKImCKImCKImCKImCK	nal Test	Internal Test	
Question No.Details of the answerMarks Distribution IM 4 6 Explain UptoMarkwelle- VXH = $J + \partial J$ Marks Distribution IM 4 6 Explain UptoMarkwelle- VXH = $J + \partial J$ Marks Distribution IM 4 6 Explain UptoMarks VXH = $J + \partial J$ Marks Distribution IM 4 6 Explain UptoMarks VXH = $J + \partial J$ Marks Distribution IM 6 6 $7 \times H = J + \partial J$ $2M$ Marks Distribution IM 6 $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ Marks Distribution IM $2M$ 6 $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = \partial A_1 + \partial A_2$ $2M$ $2M$ $7 - A^2 = A_1 + A_2 + A_2$ $2M$ $2M$ $7 - A_2 + A_2 + A_2$ $A_1 + A_2$ $A_1 + A_2$ $7 - A_2 + A_2 + A_2$ $A_1 + A_2$ $A_1 + A_2$ $6 - A_2 + A_2 + A_2$			
Question No.Details of the answerMarks Distribution DistributionABExplain Markwalle- Ampesse lawIMareau upto $\nabla x H = \vec{J} + \partial \vec{J}$ 2MExplain Biot Savashe lawIMareau upto $dH = \vec{J}dlsin\theta$ 2Mareau upto $dH = \vec{J}dlsin\theta$ 2Mareau upto $dH = \vec{J}dlsin\theta$ 2M $\Delta T = \partial A_{1} + \partial A_{2} + \partial A_{3} + \partial A_{4} + \partial A_{5} + \partial $	Date: 10/12/19		
(4) (6) Explain Maxwelle Ampere law IM are upto $\forall x H = \vec{J} + \frac{\partial \vec{J}}{\partial T}$ 21M Explain Biot Sanadle law IM are up to $dH = \vec{J} dJ \sin \theta$ 2M $4\vec{u} a^2$ 2M $\vec{V} \vec{A} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M = 354 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_2}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_2}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M $\vec{J} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi} + \frac{\partial A_2}{\partial \xi} + \frac{\partial A_3}{\partial \xi} + \frac{\partial A_4}{\partial \xi} +$	f the answer Marks To Distribution M	Details of the ar	No.
(a) course up to $\nabla x H = \vec{J} + d\vec{D}$ Explain Biot Sanoshe law IM accure up to $dH = JdJsin\theta$ $4\vec{u}a^2$ 2M $4\vec{u}a^2$ 2M $\nabla \cdot \vec{A} = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_2}{\partial \xi}$ 2M = 354 past-C (3) (3) (3) (4) $dx = 0$ past-C past-C y = dx dx + dx = 0 past-C y = dx dx = 0 dx + dx	- Ampere law IM	D Explain Maxwelle-1	+) @
Explain Biot Screents law accure up to $dH = Idlsin\theta$ $40a^2$ $7 \cdot A^2 = \frac{\partial A_1}{\partial x} + \frac{\partial A_2}{\partial y} + \frac{\partial A_3}{\partial \xi}$ = 354 post-C SHM debinition A Supposition 2M $course up to \frac{d^2x}{dt^2} + w^2x = 0$ $w = \sqrt{\frac{K}{m}}$ $k = -\frac{F_x}{x} = \frac{w}{x} = 6x to Nlm, IM 3M$	$\vec{H} = \vec{J} + \partial \vec{D}$ 2M	avene upto VXH?	
(b) $\nabla \cdot \vec{A} = \frac{\partial A_{1}}{\partial x} + \frac{\partial A_{2}}{\partial y} + \frac{\partial A_{3}}{\partial \xi}$ 2M = 354 2M (c) (c) (c) (c) (c) (c) (c) (c) (c) (c)	sta law	Explain Biot Sandalla	5
(b) $\nabla \cdot \vec{A}^{2} = \frac{\partial A_{1}}{\partial x} + \frac{\partial A_{2}}{\partial y} + \frac{\partial A_{2}}{\partial \xi}$ = 354 post-C (5) (a) SHM debinition x Explanation 2M $arrow up to \frac{d^{2}x}{dt^{2}} + w^{2}x = 0$ $w = \sqrt{\frac{K}{m}}$ $k = -\frac{Fx}{x} = \frac{w}{x} = 6x10^{4} \text{ N/m}, \frac{1M}{2M}$	2M	and upto dH =	- 13
$= 354$ $\frac{post-C}{post-C}$ $SHM deternition a Explanation 2M$ $course up to \frac{d^2x}{dt^2} + w^2x = 0 \qquad 4M 7$ $w = \sqrt{\frac{K}{m}} \qquad 1M$ $W = \sqrt{\frac{K}{m}} \qquad 1M$	lingt		6
$= 354$ $\frac{post-C}{post-C}$ $SHM deternition a Explanation 2M$ $course up to \frac{d^2x}{dt^2} + w^2x = 0 \qquad 4M 7$ $w = \sqrt{\frac{K}{m}} \qquad 1M$ $W = \sqrt{\frac{K}{m}} \qquad 1M$	aty, dts an	$\nabla \cdot A' = \frac{\partial A_{1}}{\partial x} + \frac{\partial A_{2}}{\partial x}$	1.1
$= 354$ $\frac{post-C}{post-C}$ $SHM detrinition a Explanation 2M$ $arrow up to \frac{d^2x}{dt^2} + w^2x = 0 4M 7$ $w = \sqrt{\frac{K}{m}} 1M$ $W = \sqrt{\frac{K}{m}} 1M$ $K = -\frac{Fx}{x} = \frac{W}{x} = 6x10^{5} \text{ N/m}, \frac{1M}{2M} = 3$	24 08.	Or J	
SHM debinition a supplication 24 supplier op to $\frac{d^2x}{dt^2} + w^2x = 0$ 4M 7 $w = \sqrt{m}$ $k = -\frac{Fx}{x} = \frac{w}{x} = 6x10^2 \text{ N/m}, \frac{1M}{2M}$	21	= 354	100
SHM debinition a supplication 24 supplier op to $\frac{d^2x}{dt^2} + w^2x = 0$ 4M 7 $w = \sqrt{m}$ $k = -\frac{Fx}{x} = \frac{w}{x} = 6x10^2 \text{ N/m}, \frac{1M}{2M}$	<u>-Ci</u>	Past-C	20
(b) $k = -\frac{F_x}{x} = \frac{w}{x} = 6x10$ N/m. $\frac{1M}{2M}$ 3		SUM debinition	3)a
(b) $k = -\frac{F_x}{x} = \frac{w}{x} = 6x10$ N/m. $\frac{1M}{2M}$ 3	$\frac{2\chi}{12} + \omega^2 \chi = 0 \qquad 4M 7$	our up to der	0 8 4
$k = -\frac{\pi}{x} = \frac{\omega}{x} = 6 \times 10^{\circ} \text{ N/m}, \text{IM}$		ω_	6
a a an a	= W - GXIO N/m IM	k= - Fx = h	6
	2M S	~ ^	
(3) Distinguish all the wave	-the wave o	- /	Ga
(6) Noch no. Neet are Mach cyle 4M 4	OF OF		0

DEPARTMENT OF ... Physica

SCHEME FOR VALUATION

Internal Test

Question No.	Details of the answer	Marks Distribution	Total Marks
(†) (©)	Explanation of gradient 1 divergence 1 cerel with	2 M	6M
	divergence 1 cuel with physical significance and	24	
6	Eupracsion c Eupracsion c $\nabla x \vec{A} = \frac{1}{2} \vec{J} \vec{J} \vec{J} \vec{J} \vec{J} \vec{J} \vec{J} J$	2M	
	VXA' = You alog alog An Ay Ag	2M	4M
	$- 2^{-} \alpha_{11} - 2(x - y_{3}) \alpha_{1} + (y - s) \alpha_{3}$	2M	.,
~	(OR)		
8	explaination & 1 expressions	4M	
	d'agrams of sease 1 populles craits	2M	10 M
	around up to $K_s = \frac{K_1 K_2}{K_1 + K_2}$	2M	
	and Kp = K1+K2 (post E)	2 M	
9	Explanation a = P[m accue up to a = V4b2p2+(w2pt) ~	.4M	
	$\Lambda q = h = 1/2bp$	4M 2M	LOM
staff	(10) Explanation ob shock waves Rodoly tube empt. Suplanation with Lingrams	2M 8M	1 way

Year: 2019 - 2020

SI SI SELED DO

13.15 13.20.10 13

Semester : Odd / Even

Name of the Teacher : Da K. Sujatha, Nagashace. G Designation : Paol: X Hop, Act. paol Department : Physics

9.9

Salbrid

notori

or administration

		Initials at th	e End of the	
	1st Month	2nd Month	3rd Month	Semester
Staff		- stata y	31619	Elintua,
HOD	W	MAR	dzuanti.	ad !
Principal		pourly d.	1 popular	

CITY ENC AG SOULEGENT AND PRIN

CITY ENGINEERING COLLEGE

ATTENDANCE

1.				-	-	-	-	-	-	-		-	-	T	T	T	T	—
_	SI. No.	Reg.No.	Name	08/08	09 08 2	13	14	10/80 5	17 08 6	19 08 7	20/08	21 08 9	22 08 10	- <u>23</u> 08 11	26 08 12			8
_	X	19 0500)	Aakash TE!	14	2	3	4	5	6	7	8	9	10	a	12	13	14	-V
	2		Achyuth Mahesh Hegde -	1:	ł	2	3	4	4	5	6	7	8	9	10	10	10	R
-	3	1905003	Afrid pasha HP	1	2	2	3	4	5	6	٦	8	9	10	(1	12	13	
-	AX		Aishwasya B M 1	1	2	3	4	5	6	7	8	9	Ø	11	12	13	14	-
-	5	C 5005	Aishwazya C //	1	10	1.	.2	3	4	5	6	7	8	9	10	11	12	
-	A		Ananya Bhomboge. //	12	2	3	4	5	6	6	7	8	9	10	11	12	13	
. –	A		Apposiva R shot /	ι.	2	3	4	5	6	7	8	9	to	u	12	13	14	1.01
· · -	st		Agishad ulla 7 /18	1	2	3	4	5	6	7	8	9	10	11	12	13	14	CIT
61	et	CSOIL	Agitee Kumai R 1/	1	2	3	4	5	6	7	8	9	10	11	12	13	14	N.
-	105		Ashwini B 11	1	1	2	3	4	5	6	Г	8	9	10	ų	12	13	5
-	1	C S016	Bholay Noth singh	t	2-	З	4	5	6	7	8	9	10	11	12	13	14	Un l
	12		Chandan Kumpy C	1	ł	10	2	3	3	4	0	6	7	8	9	10	11	6.2
^_	13		chandini RP	1 :	1 %	2	3	4	4	5	5	7	8	9	10	11	12	5
-	14		chazansimba .D	1	2	3	4:	5	6	7	8	9	10	11	12	13	14	10
- -	15	1	chetan s	1.	2	3.	4	5	5	6	7	8	9	0	:1	12	3	5
-	10 10 M		chetan R	1	1 :-	2		4	5	-5	7	8	9	10	и	11	12	5
-	_17	CS024	chetanpaj H	. (2	2	3	4		6	.7	8	9	10	(1	12-	13	5
-	19		Chizonjeevi V	1.	2.	3	4.	-	6	7	8	9	10	11	12	13	14	12
· -	201	and the second second	Daspan K	. (2	-	4	-	6	7	8	9	10	u	12	13	14	12
cot	21		Deepak Jadon	1	2		4	5	6	7	8	9	10	10	11	12	B	34
19:5N	22		Jhaoush s /	1	2	3	4	5		7	8	9	(0	11	11	11	12	142-5
-	23		Divya SA	15	2	3	4			7	8	9	10	11-				39
-	24	<u>CS031</u>		1	2		4	-	1	7	8	9	10	11	-	13	14	10-11
1	25		Gestanch P	1		2	3		1	5	6	77	8	9	10			B
· 、 —		No. of Abs.	Hoashith G R	1	1	1	2	3.	3 1	E	4	5	6	7	7	8	8	53
-	. * -	Initials		GI-	Cad	GA (CH .	GI I	34 4		<u></u>	GA	Cat	CA	A	50	Ø	1
_		initiatio		Car I	9	000	an a		-	-	Gt-	en	et		P		_	

ATTENDANCE

				-	-	-		-	-				-	-		No. Carry	
	isno.	extreM test	in c	KB (9	12						-	02	03	26.	26-	28
SI. No.	Reg.No.	- Strate il 6	1	2/20	9/8	10/18	14 18	16/08	17 108	19	20/08	21/08	22/08	2/8	26	26	25
140.	CH IN		33 83	1	2	3	4	5	6	7	8	9	10	11	12	13	14
26	CS035	Hemanth V	20 1:	U	2	3	4	5	6	7	8	19	10	U :	12	131	14
21	C 5037	Taga Fathing	91 I I	1:1	2	3	4:	5	6	7	8	9	10	(1)	12	13	14
287	C \$038	Transhing DA!	Rei Xa	1:	2	3	4	5	6	7	8	9	10	u	12	13	14
297 -	0.5039	TEONAD M	20.2	t	2:	5	4	5	6	7	8	9	10	11	12	13	13
30	A DESCRIPTION OF TAXABLE PARTY OF TAXABLE PARTY.	Juothi shace SR/	1 de la	U	2	3	4	5	5	5	6	7	8	9	lo	- (1	12
at		Kavana B	12:41	1.	13	2	3	4:	5	5	6	71	8	9	10	u	12
327	C. SO 63	Kapothi Kumazi	行图	ŀ	2:	3	4	5	6	7	82	9	10	U	12	13	14
38	1	Kistan Gauda	1.	1:	2	3	4	5	6	7	-8	9	10	u	12	13	14
34	C 5045	Raithika N Koushik	1</td <td>L</td> <td>2</td> <td>3</td> <td>4</td> <td>15</td> <td>6</td> <td>7</td> <td>8</td> <td>9</td> <td>0</td> <td>ar</td> <td>12</td> <td>13</td> <td>14</td>	L	2	3	4	15	6	7	8	9	0	ar	12	13	14
63 35	CSOG2	Keesthi chardsa N L	1			1	-,	12	1	2	32	4	5	6	7	8	9.
36		M N Rachana	teres.	-		-in	-			A.	-	-			1	1	-
37		Mahaday A C	te .	5		-		1-		14		-	100		•	1	
_ 385	CSOLT	Manasa R	1. 1.	1:	10	ų	3	4 F	15	6	1.1768	8	9	10	dt	12:	13
392	C SO48	Manchaz M (1	2	3	4	.5	6	7	8	9.	ιö	11	12	13	14
402	C 5049	Maroj MK	1.10	ŀ	10	2	3	4	5	6	173	8	9	10	14	12	13
AT	CS050	Maroj R	P P	H	10	4	2	3:	3	4	35	6	7	7	8	9	10
42	CS05	Maria Monica P/	10-19	1:	21	2	3:	4	5	6	+27-	8	9.	10	-it	12+	13
-43	CS085	Spoosthi H.M.V		1:	2	3	4	5	6	17	: 8	9	10	u	12	18	14
44		- The	1.1		1	5 00	9.1	18	· fr	12	6000	62	1	Contraction of the	21		200
45		Antipe Inthe	10	1	-	2.0	3 8.	- 2+	- 1	1		D	The second	2		No.	1
46			1-1-1-1	1.5	- 3	14	64	Ar	J.	(A)	at in	14 J			The second	-	a free
47	5	1218-11	100-		-	ee	- 4	18	2	and I		14			4		
48		A Starter	102	115	Q.	5 B	* 0	之前	1	1 THE	-				1	in the second	N.
49		and the second	<u>D</u> I :	25	3.6	45 6	Å. 1	112 8	· 4	114	aure -		1		214	+	
50		A CARGON S	137 1	1 L	1 4	4 .2	14	1 1	13	1		135	1		14.00		+
	No. of Abs.	and the state of the			t yr		1	+	100				1	14		1	
	Initials		11-	G	G	G	G	G	G	G	CH-	G	- 61	G	V	10	25
													-				

(Doddakallsandra, Off Kanakapura Road, Bangalore-560061)

Department of ____ Chemistry



Faculty Academic File	
NAME SUNITRA-N	· · · · · ·
DESIGNATION: ASSE. Prof.	
semester: 01	
section.	
SUBJECT NAME & CODE Engy: Chu	nicity_18CHE12
ACADEMIC YEAR: 2019 - 20	Lodd SEM]

CONTENTS

1.	Individual Time Table
2.	Calendar of Events
3.	University Syllabus
4.	Below average Student's list and Topper's list
5	Lesson Plan
6	Record of Class Work - Section-wise (Xerox Copy of Attendance Format)
7	University Question Papers : Min 05
8	Unit-wise Assignment Question Bank(all units) : Min 08 Questions per Unit
9	Internal Test:
	9.1: Attendance Shortage List Test-1, Test -2 & Test-3
	9.2: Internal Question Paper & Scheme — Test-1, Test-2 & Test-3
	9.4: Counseling form
10	Result Analysis & Feedback 10.1: Final internal Test Marks List (University Copy) 10.2: Subject Result & student feed back





VISION

Making Remarkable Contribution by Disseminating Knowledge on Emerging Trends in Engineering and Technology through various Programmes, Innovation and Research so as to Excel in Quality both at National and International level and to provide Career Guidance & Training for Employment.

MISSION

M1- To encourage Knowledge Acquisition and Foster Innovation & Research.

M2- To Prepare Students for Immediate Employment, leading to Technological and Socio- economical growth.

M3- To Provide Guidance for a Productive Career under various programmes.





PROGRAM OUTCOMES (PO)

PO1 – Engineering knowledge: Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.

PO2 – Problem analysis: Identify, formulate, review research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.

PO3 – Design/development of solutions: Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations.

PO4 – Conduct investigations of complex problems: Use research-based knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.

PO5 – Modern tool usage: Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modeling to complex engineering activities with an understanding of the limitations.

PO6 – The engineer and society: Apply reasoning informed by the contextual knowledge to assess societal, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.

PO7 – Environment and sustainability: Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.

PO8 – Ethics: Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.

PO9 – Individual and team work: Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.

PO10 – Communication: Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, and give and receive clear instructions.

PO11 – Project management and finance: Demonstrate knowledge and understanding of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.

PO12 – Life-long learning: Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change.





DEPARTMENT OF CHEMISTRY

VISION

• To convey knowledge on engineering chemistry to stakeholders for engineering applications.

MISSION

- Facilitate the faculty to strengthen their knowledge and skills using ICT tools.
- Motivate and train students in theory and laboratory practices.
- Succeed to deal with societal issues like preserving green environment.

	I Sem B. E. / B. Tech. / B. Arch. (Tentative)	III, V & VII Sem B. E. /B. Tech. III, V,VII & IX Sem B. Arch.	III & V Sem MCA	III Sem MBA	III Sem M. Tech.	III Sem M. Arch.
Commencement of ODD Semester	01.08.2019	29.07.2019	29.07.2019	08.08.2019	26.08.2019	08.09.2019
Last Working day of ODD Semester	29.11.2019	30.11.2019	30.11.2019	05.12.2019	23.12.2019	06.01.2020
Practical Examinations	03.12.2019 To 13.12.2019	03.12.2019 To 13.12.2019	03.12.2019 To 07.12.2019	-		
Theory 16.12.2019 Examinations 04.01.2020		16.12.2019 То 07.02.2020	09.12.2019 09.12.2019 To To 28.12.2019 04.01.2020		27.12.2019 To 10.01.2020	08.01.2020 To 22.01.2020
nternship Viva-Voce	-	•	-		12.01.2020 To 19.01.2020	•
Professional training Organization study	-	-	•	-	-)=
Commencement of EVEN Semester	27.01.2020	10.02.2020	27.01.2020	27.01.2020	27.01.2020	01.02.2020

Academic Calendar of VTU, Belagavi for ODD Semester of 2019-2020 (Jul 2019 - Jan 2020)

Accul All Hode Crown NOTE

salocha.

- VII Semester B. E / B. Tech students shall have to undergo Internship for a period of four Weeks. ۰
- . I Semester B. E/ B. Tech / B. Arch Students shall compulsorily undergo Induction Program for a period of 3 Weeks (two phases) as per the schedule given by VTI First phase 11 days in first semester and second phase 10 days in second semester.
- College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notifie 1. separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.

PRINCIPAL TECHNO

- If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTR

Ģ		CITY ENG	NEERING C	OLLEGE	E, BENGALURU- 2019-2	560061. 020(OD	ACADEMIC CALENI D SEM)				and the second second second second
VISIT .	August	-2019	Se	ptembe	er-2019	0	October-2019	Nov	/ember-2019	December-2019	
DAY	DATE	EVENT		DATE	EVENT	DATE	EVENT	DATE	EVENT	DATE	EVENT
JUL	Y 28th M	IOM ON CURIC	JLLUM								
START	INGOFF	IGHER SEMES	TERS(3rd			1					
51	th& 7th	sem 29.7.2019 n	non)			2	GANDH JAYANTI				
THU	1	STATRTING OF F	-IRST SEM			3					
						3			KANAKADASA		
FRI	2					4		1	RAJYOTSVA(DH		
SAT	3					4 5		2)		
SUN	4			1		5		2		1	
					VINAYAKA	0	MAHALAYA	3		Least and	Contraction of the second
MON	5			2	CHATURTI	7	AMAVASYA(DH)	4		2	
TUE	6			3	FIRST	8	VIJAYA DASHAMI(DH)	5		3	
WED	7	FIRST SEM INDU	ICTION	4	INTERNAL ASSESSMENT	9		6	SECOND CIE	4	
THU	8			5	3rd, 5th, 7th				FOR 1st SEM		
	9				semester	10		7		5	
FRI	10	-		6		11		8		6	
SAT	11	2nd Satuarday I	noliday	7		12	2nd satuarday holida	9	2nd satuarday h	7	
SUN		1 1 1 1 1		8		13		10		8	
MON	12	bakrid(DH)		9		14		11		9	THIRD CIE
TUE	13			10	MOHARAM(DH)			12		10	FOR FIRST
WED	14			11		16		13		11	SEM
THU	15	INDEPENDENCE		12		17		14		12	
FRI	16			13		18		15	KANAKA JAYAN	13	
SAT	17			14	2nd Saturday	19		16		14	
SUN	18			15		20		17		15	
MON	19	TALENTSDAY		16		21	SECOND INTERNAL	18	THIRD		
TUE	20			17		22	ASSESSMENT	19	INTERNAL TEST _ ASSRSSMENT	16 17	
WED	21			18		23	3rd, 5th, & 7th semester	20	3rd, 5th, &7th	18	LAB INTERNALS FOR 1ST SEM
THU	22			19		24		21	semesters	19	
FRI	23			20		25		22		20	
					FIRST CIE FOR						
	24				FIRST SEM.		4th satuarday		4th satuarday		LAST WORKING
SAT		4th sataurday		21		26	holiday	23			DAY1ST
SUN	25			22		27		23		21	SEM(REVISED)
MON	26			23		28		24		23	
TUE	27			24		29	DEEPAVALI(DH)	26		 24	
WED	28			25		30		27	IAB TESTS		VTU PRACTICAL: 1st
THU	29			26		31		27	3rd,5th,&7th SEMs	25	SEMESTER: 23.1
FRI	30			27				20 29	Last working day	20 27	2.19 To 3.01.20 THEORY
								29	Last working day	2/	EXAMS 1st
	31								LAST WORKING		SEMESTERS 6.01.20to28.0
NT		Eth Osternal		28	4TH satuarday				DAY 3rd, 5th&	10000	.2020
SAT SUN		5th Satuarday		28	HOLIDAY			30	7th SEM	28	
/ON				30					nou		hur
UE								F		and a	un /



DEPARTMENT OF BASIC SCIENCE ACADEMIC YEAR 19-20 ODD SEMESTER CIRCULAR

Ref No: CEC/BS/DAC/ACY/2019-20/OR/01

Date: 25-07-2019

This is to inform the members of Department Advisory Committee that meeting is scheduled on 08-08-2019 at 10: 00 AM in Physics Laboratory.

Agenda:

- · Commencement of classes for 1st semester students
- Student Induction Programme for 1st semester students
- · Conduction of Talents day
- Organizing value added courses/ certificate courses, seminars & webinars in the curriculum.

SUJAITZ . K HOD

Rummeres

Principal City Engineering College, Bangalore-560.061



DEPARTMENT OF BASIC SCIENCE

Department Advisory Committee Meeting

Date: 08-08-2019 Time: 10:00 AM Venue: Physics Laboratory

DAC Members present in the meeting:

Sl. No	Member Name	Designation	Role	Signature
1	Dr. Rajasekar. P	HOD & Professor	Convener	DOBIE
2	Mrs.Sunitha.N	Assistant Professor	Member	B
3	Mrs. Anu Radha U	Assistant Professor	Member	Ann
4	Mrs. Sowmya P	Assistant Professor	Member	Soumya.
5	Dr.Sujatha	HOD & Professor	Member	B
6	Mrs.Nagashree. G	Assistant Professor	Member	GI
7	Mrs.Ashwini Hindiholi	Assistant Professor	Member	Ashin
8	Dr.Jyothi	Assosciate Professor	Member	Just
9	Vanitha G R	Assistant Professor	Member	Vanit
10	Mrs. Gayatri annasagaram	Assistant Professor	Member	Gart
11	Mrs.Kalavathi	Assistant Professor	Member	Krice
12	Mrs.Gana Priya	Assistant Professor	Member	Cian
13	Mrs.Reena Patro	Assistant Professor	Member	. heer

Agenda of the Meeting:

- Inauguration programme for 1st semester students on 25^h Sep 2019.
- Commencement of orientation Programme from 26th Sep 2019.
- Conduction of Talents day on 19th Aug 2019.
- · Classes for 1st semester students will be from 8th Aug 2019.
- · Organizing value added courses/ certificate courses in the curriculum like Entrepreneurship and innovation.
- · Organizing seminars and webinars.



Minutes of Meeting:

The members discussed suggestions for improvement and reviewed the meeting agenda.

- The committee decided to organize Certification course on "Communication Proficiency" It was discussed to conduct of Talents day on 19th Aug 2019.
- Committee decided to conduct webinar on Introduction to Research Methodology. Committee members agreed to conduct a seminar on environmental pollution.

are Sim Convener

Dr. Rajasekhar. P

Sujata·K

Department of Physics

Rummeres

Principal City Engineering College, Bangalore-560.061

CITY ENGINEERING COLLEGE TIME TABLE –FIRST SEMESTER AUG – 2019-20 CHEMISTRY CYCLE

SECTION:C

ROOM NO: A004

DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00	
MON	CHE	CPS		ELN	MAT		←CHEL/CPL/EGHL/C1/C2/C3→			
TUE	ELN	CPS	AK	EME	CHE	LUNCH	MAT	EGH	LIBARARY	
WED	CHE	MAT		ELN	EME		←CHEL/CPL/EGHL /C2/C3/C1→			
THU	MAT	CHE	BREAK	CPS	EGH		←CHEL/CPL/EGHL/C3/C1/C2→			
FRI	EME	ELN		CPS	MAT		EDUSAT/DEP/COLLEGE ACVIVITIES			
SAT	EME	ELN		CHE						

MAT- Dr. Jyothi.P & Prof. Gayathri A CPS - Prof. Deepak. N.S EME Prof. Shruthi CPL- Prof. Ramesh B CHE - Dr.Rajasekhar.P & Dr.Sunitha.N ELN-Prof. Arabindo Koti CHEL - Dr. Rajasekhar.P & Dr. Sunitha.N EGH- Dr.K.Sujatha & Prof. Nagashree G

PROCTORS - Prof. Sunitha. N & Prof. Gayathri A

P. Cai. S. Kum HOD

Ruchulans

PRINCIPAL

Rueaucipus

Principal City Engineering College, Bangalore-560 061

CITY ENGINEERING COLLEGE TIME TABLE -FIRST SEMESTER AUG - 2019-20 CHEMISTRY CYCLE

Mrs. Sunitha. N (SN)

DAY	9:00-10:00	10:00-11:00	11:00-11:15	11:15 -12:15	12:15-1:15	1:15-2:00	2:00-3:00	3:00-4:00	4:00-5:00
MON									
TUE					С	REAL ST			
WED	C		AK			LUNCH	←	-C2 lab SN+SWM	→
THU		×	BREAK				<i>←</i>	-C3 lab SN+ANU -	→
FRI									
SAT	Kannada (M	E, EC, CIVIL)		Ø					

P. Cai. Sunor

Russures

PRINCIPAL

Rummeres

Principal City Engineering College, Bangalore-560 061

HOD

DEPARTMENT OF CHEMISTRY

LESSON PLAN FOR ODD SEMESTER FOR ACADEMIC YEAR 2019-2020

NGINFFRRM

Course Title: Engineering Chemistry	Course Code : 18CHE12
Total contact hours: L:T:P:S :: 05 (3L+2T)	
Internal Marks : 40	End Term Marks : 100
Semester : 1	Academic year : 2019-20.
Lesson plan Author: Dr. P. Rajasekhar & Sunitha. N	Date :10/08/2019

Course Objective:

This course (18CHE12/22) will enable students to

- Master the basic knowledge of engineering chemistry for building technical competence in industries, research and development.
- To develop knowledge in the fields of use of free energy in chemical equilibrium, electrochemistry and energy storage systems, Corrosion and metal finishing.
- To understand the importance of energy systems, environmental pollution, waste management, water chemistry, Instrumental methods of analysis and Nanomaterials.

Course Outcomes:

On completion of this course, students will have knowledge in:

- CO1: Use of free energy in equilibria, rationalize bulk properties and processes using thermodynamic considerations, electrochemical energy systems.
- CO2: Causes & effects of corrosion of metals and control of corrosion. Modification of Surface properties of metals to develop resistance to corrosion, wear, tear, impact etc. by electroplating and electroless plating.
- CO3: Production & consumption of energy for industrialization of country and living standards of people. Electrochemical and concentration cells. Classical, modern batteries and fuel cell. Utilization of solar energy for different useful forms of energy.
- CO4: Environmental pollution, waste management and water chemistry.
- CO5: Different techniques of instrumental methods of analysis. Fundamental principles of nanomaterials.

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
1	1	Thermodynamic functions: Definitions of free energy and entropy. Cell potential, derivation of Nernst equation for single electrode potential	L.3	COL
500 a 14 16 a 16	2	Numerical problems on E, E0, and Ecol.	R,U	COI
×	3	Reference electrodes: Introduction. construction, working and	R,U .	CO1.

MODULE-1

а к к	16	electrode, and determination of pH using glass electrode.		
2	1	Electrolyte concentration cells, numerical problems.	R.U	CO1
	2	Energy storage systems: Introduction. classification - primary, secondary and reserve batteries.	R,U	COI
* * * *	3	Construction, working and applications of Ni-MH and Li-ion batteries.	R.U	COL

MODULE-2

Week .	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
	·		Lével	(CO)
4.	- 1	Corrosion	R.U	·CO2
		Introduction. Electrochemical theory	R,O	.002
		of corrosion		
м И	2	Factors affecting the rate of .	, R.U	CO2
		corrosion rațio of anodic to cathodic	. N.U	02
	2	areas, nature of metal, nature of	22	1.00
•	2	corrosion product, nature of medium	84) Form	
2 4 15 //	9	– pH, conductivity and temperature.		
	3	Types of corrosion - Differential		
с. ÷	0		R.U	CO2
		metal and Differential aeration -		
	1	pitting and water line)	his in	
1	4	Corrosion control: Anodizing -	R.U	CO2
10	<u> </u>	Anodizing of aluminium, Cathodic	3	
a se de ser e	f	protection	<u> </u>	0.000
· · ·		sacrificial anode and impressed	R,U	CO2
		current methods. Metal coatings -		11 A.
	2	Galvanization.		0.00
li ne ne li	2	Metal finishing: Introduction,	R.U	CO2
2) 20		Technological importance,	· · · · · ·	
s - 1		Electroplating: Introduction,		
<u>80</u>		principles governing electroplating- Polarization.		
10 ¹¹	3			000
	3	decomposition potential and	R.U	CO2
		overvoltage		000
	4	Electroplating of chromium (hard and	·R.U.	CO2
6	1 2	decorative).	р. 11	
0		electroless plating of copper	R,U	CO2
£	2	Electroless plating; Introduction.	.R.U	CO2
2 1.51 N		electroless plating of nickel	المستستقوين ورب	
	3 '	distinction between electroplating	·R.U ·	CO2
	ļ.	and electroless plating processes.	· · · · · ·	,
	4	Chemical Fuels: Introduction,	R,U	CO3
		classification, definitions of CV.	21 	
		LCV. and HCV. determination of		· •
14		calorific value of solid/liquid fuel		1
:	-	using bomb calorimeter .		
82	5	numerical problems	R:U	CO3

MODULE-3

Week	Days/	Contents of Module	Bloom's	Course
	Date		Taxonomy	Outcome
	10		Level	(CO)
7 .	1 14	Knocking of petrol engine	R.U	CO3
		Definition, mechanism, ill effects and	a 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975 - 1975	
		prevention.		
	2 .	Power alcohol, unleaded petrol and	'R.U	CO3
		biodiesel	•	
	3	Solar Energy: Photovoltaic cells-	, R.U.E .	CO3
	- E	introduction. construction and:	·	jas -
ĸ		working of a typical PV cell.		
	4	Fuel Cells: Introduction. differences	'R.U	CO3
	1	between conventional cell and fuel	•	
	-4	cell, limitations & advantages.	<u></u>	
8	1	Construction, working & applications	·R,U	CO3
	8	of methanol-oxygen fuel cell with	10 N	
	~~~~~~	H2SO4 electrolyte	. · ·	<u>.</u>
	2	solid oxide fuel cell (SOFCs).	R.U	CO3
	3	Solar Energy: Photovoltaic cells-	R,U	CO3
19		introduction, construction and		
		working of a typical PV cell		
8	.4	Preparation of solar grade silicon by	R,U	CO3 .
1		Union Carbide Process/Method.		14
n all		Advantages & disadvantages of PV		
· · · · · ·		cells.	DELC	(27)1
	1	Environmental Pollution: Air.	R.U.C	CO4
		pollutants: Sources, effects and control of primary air pollutants:		
		Carbon monoxide.		
	2	Oxides of nitrogen and sulphur.	R:U, A1	CO4
	3	hydrocarbons. Particulate matter	R.U	CO4
· · ·	4	Carbon monoxide, Mercury	R.U	CO4
	5	the statement and an	R.U	CO4
	2	Lead. Secondary air pollutant: Ozone. Ozone depletion.	K.U	C ()+

MODULE-4

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
10		Waste Management: Solid waste, e-, waste & biomedical waste	R.U.	CO4
	2	Sources, characteristics & disposal methods (Scientific land filling, composting, recycling and reuse).	R.U	CO4
	3	Water Chemistry: Introduction, sources and impurities of water	R.U	ĊO4 ·
	4	boiler feed water, boiler troubles with disadvantages	·R.U.	CO4
11	1	scale and sludge formation	R,U	CO4
	2	boiler corrosion (due to dissolved O2: CO2 and MgCl2)	R,U .	CO4
	3	Sources of water pollution. Sewage	R.U ·	CO4

- * *	4	Definitions of Biological oxygen . demand (BOD) and Chemical .	.R.U	CO4
a ⁿ	б	Oxygen Demand (COD),		
	have wellen	determination of COD	3 N	
12 .	1	numerical problems on COD	R,U-	CO4
	2	Chemical analysis of water: Sulphates (gravimetry)	R,U	CO4
10700 #3	3	Fluorides (colorimetry).	.R.U ·	CÓ4
2 2 8	4.	Sewage treatment: Primary, secondary (activated sludge) and	R.U	CO4
.*		tertiary methods	э н	

### MODULE-5

Week	Days/ Date	Contents of Module	Bloom's Taxonomy	Course Outcome
			Level	(CO)
13	. 1 .	Softening of water by ion exchange process	R,U,A2	CO4
	•2	Desalination of sea water by reverse. osmosis.	R,U	CO4 '
	3	Instrumental methods of analysis: Theory, Instrumentation and applications of Colorimetry	R,U	CO5
	4	Flame Photometry	,R,U	CO5
14 ·	1	Atomic Absorption Spectroscopy	R.U.E	CO5
	2	Potentiometry	RU	CO5
(@) 1911	3	Conductometry (Strong acid with a -	R.U	(05
- - 4		strong base, weak acid with a strong base		
4 <u>.</u>	4	mixture of strong acid and a weak acid with a strong base	R.U ·	CO5
15 .	1	Introduction, size dependent properties (Surface area, Electrical, Optical, Catalytic and Thermal properties)	R.U	ÇO5
8 A	2	Synthesis of nanomaterials: Top down and bottom up approaches	R,U,A1,C	CO5
81 - 193, ¹⁰	3	Synthesis by Sol-gel	R,U	CO5
	4	precipitation	R.U	CO5 ·
16	1	chemical vapour deposition	·R.U	<u>CO5</u>
	2	Nanoscale materials: Fullerenes	R.U	CO5
	3	Carbon nanotubes	R.U	CO5
	.4 	graphenes – properties and applications	R.U.ALC	CO5

Bloom's Taxonomy Level R-Remembering U-Understanding A1-Applying A2-Analysing E-Evaluating C-Creating

#### Text Books:

1. P.C. Jain & Monica Jain. "Engineering Chemistry", Dhanpat Rai Publications, New Delhi (2015 Edition).

2. S. S. Dara. A textbook of Engineering Chemistry, 10th Edition. S Chand & Co., Ltd., New Delhi, 2014.

3. Physical Chemistry, by P. W. Atkins, Oxford Publications (Eighth edition-2006).

Reference books:

1. O.G. Palanna. "Engineering Chemistry", Tata McGraw Hill Education Pvt. Ltd. New Delhi. Fourth Reprint (2015- Edition).

2. R.V. Gadag & A. Nityananda Shetty., "Engineering Chemistry", I K International Publishing House Private Ltd. New Delhi (2015- Edition).

3. "Wiley Engineering Chemistry", Wiley India Pvt, Ltd.:New Delhi. Second Edition-2013.

**4.** B. Jaiprakash, R. Venugopal, Sivakumaraiah and Pushpa Iyengar, Chemistry for Engineering Students, Subhash Publications, Bengaluru, (2015- Édition).

Principal City Engineering Ca Bangalore-560.061

#### VISVESVARAYA TECHNOLOGICAL UNIVERSITY, BELAGAVI

#### B.E.SYLLABUS FOR 2018-2022

#### Engineering Chemistry

(Common to all branches) [As per Choice Based Credit System (CBCS) scheme] (Effective from the Academic Year 2018-19)

Course Code: 18CHET2/22 Contact Hours/Week: 05 (3L+2T) Total Hours: 50 (8L+2T per module) Semester: I/II CIE Marks: 40 SEE Marks: 60 Exam. Hours: 03 Credits: 04(3:2:0)

Course Learning Objectives: This course (18CHE12/22) will enable students to

- Master the basic knowledge of engineering chemistry for building technical competence in industries, research and development.
- To develop knowledge in the fields of use of free energy in chemical equilibrium, electrochemistry and energy storage systems, Corrosion and metal finishing.
- To understand the importance of energy systems, environmental pollution, waste management, water chemistry, Instrumental methods of analysis and Nanomaterials.

#### MODULES

#### MODULE- I: Electrochemistry and Energy storage systems

Use of free energy in chemical equilibria: Thermodynamic functions: Definitions of free energy and entropy. Cell potential, derivation of Nernst equation for single electrode potential, numerical problems on E,  $E^0$ , and  $E_{cell}$ .

Electrochemical Systems: Reference electrodes: Introduction, construction, working and applications of Calomel electrode. Ion-selective electrode – Definition, construction and principle of Glass electrode, and determination of pH using glass electrode. Electrolyte concentration cells, numerical problems. Energy storage systems: Introduction, classification - primary, secondary and reserve batteries. Construction, working and applications of Ni-MH and Li-ion batteries.

(RBT Levels: L3)

#### MODULE-II: Corrosion and Metal finishing

**Corrosion:** Introduction, Electrochemical theory of corrosion, Factors affecting the rate of corrosion: ratio of anodic to cathodic areas, nature of metal, nature of corrosion product, nature of medium – pH, conductivity and temperature. Types of corrosion - Differential metal and Differential aeration - pitting and water line). Corrosion control: Anodizing – Anodizing of aluminium, Cathodic protection - sacrificial anode and impressed current methods, Metal coatings - Galvanization.

Metal finishing: Introduction, Technological importance. Electroplating: Introduction, principles governing electroplating-Polarization, decomposition potential and overvoltage. Electroplating of chromium (hard and decorative). Electroless plating: Introduction, electroless plating of nickel & copper, distinction between electroplating and electroless plating processes. (RBT Levels: L1 & L2)

#### **MODULE-III : Energy Systems**

12.2.2

aladi yika zira Galiz Kristovic

**Chemical Fuels**: Introduction, classification, definitions of CV, LCV, and HCV, determination of calorific value of solid/liquid fuel using bomb calorimeter, numerical problems. Knocking of petrol engine – Definition, mechanism, ill effects and prevention. Power alcohol, unleaded petrol and

Page 1 of 3

#### biodiesel.

Fuel Cells: Introduction, differences between conventional cell and fuel cell, limitations & advantages. Construction, working & applications of methanol-oxygen fuel cell with H2SO4 electrolyte, and solid S'.ide fuel cell (SOFCs).

Solar Energy: Photovoltaic cells- introduction, construction and working of a typical PV cell. Preparation of solar grade silicon by Union Carbide Process/Method. Advantages & disadvantages of PV cells. (RBT Levels: L3)

MODULE IV: Environmental Pollution and Water Chemistry

Environmental Pollution: Air pollutants: Sources, effects and control of primary air pollutants: Carbon monoxide, Oxides of nitrogen and sulphur, hydrocarbons, Particulate matter, Carbon monoxide, Mercury and Lead. Secondary air pollutant: Ozone, Ozone depletion.

Waste Management: Solid waste, e-waste & biomedical waste: Sources, characteristics & disposal methods (Scientific land filling, composting, recycling and reuse).

Water Chemistry: Introduction, sources and impurities of water; boiler feed water, boiler troubles with disadvantages -scale and sludge formation, boiler corrosion (due to dissolved O2, CO2 and MgCl₂). Sources of water pollution, Sewage, Definitions of Biological oxygen demand (BOD) and Chemical Oxygen Demand (COD), determination of COD, numerical problems on COD. Chemical analysis of water: Sulphates (gravimetry) and Fluorides (colorimetry). Sewage treatment: Primary, secondary (activated sludge) and tertiary methods. Softening of water by ion exchange process. Desalination of sea water by reverse osmosis. (RBT Levels: L3)

MODULE-V: Instrumental methods of analysis and Nanomaterials

Instrumental methods of analysis: Theory. Instrumentation and applications of Colorimetry, Flame Photometry, Atomic Absorption Spectroscopy, Potentiometry, Conductometry (Strong acid with a strong base, weak acid with a strong base, mixture of strong acid and a weak acid with a strong base).

Nanomaterials: Introduction, size dependent properties (Surface area, Electrical, Optical, Catalytic and Thermal properties). Synthesis of nanomaterials: Top down and bottom up approaches, Synthesis by Solgel, precipitation and chemical vapour deposition, Nanoscale materials: Fullerenes, Carbon nanotubes and graphenes - properties and applications.

(RBT Levels: L1 & L2)

AND AL filican's

 $([a])^{a')} =$ 

1.100/113

Course Outcomes: On completion of this course, students will have knowledge in:

CO1: Use of free energy in equilibria, rationalize bulk properties and processes using thermodynamic considerations, electrochemical energy systems.

CO2: Causes & effects of corrosion of metals and control of corrosion. Modification of surface

properties of metals to develop resistance to corrosion, wear, tear, impact etc. by electroplating and electroless plating.

CO3: Production & consumption of energy for industrialization of country and living standards of people. Electrochemical and concentration cells. Classical, modern batteries and fuel cells. Utilization of solar energy for different useful forms of energy.

CO4: Environmental pollution, waste management and water chemistry.

CO5: Different techniques of instrumental methods of analysis. Fundamental principles of nanomaterials. • ...

City Engineering Co

Page 2 of 3

### Assignment -1

### <u>Module -1</u> Electrochemistry & Energy Storage Systems Electrochemistry:-

1.Derive Nernst Equation for Single electrode potential?

2.Define reference electrode and Ion selective electrode?

3.Explain construction & working of calomel electrode?

3.Explain construction & working of concentration cells?

4.Explain the construction & working of Glass electrode?

5.Explain the determination of pH using Glass electrode?

### **ENERGY STORAGE SYSTEMS:-**

1. Write a note on classification of batteries?

2. Explain the construction & working of Ni-MH battery?

3. Write a note on Li-ion batteries?

### Assignment -2

### Module -2 Corrosion & Metal finishing

Corrosion:-

1.Explain the electrochemical theory of corrosion taking Fe as example?

2. Write a note on factors affecting the rate of corrosion

i) Ratio of anodic to cathodic areas ii) pH

3. Write a note on factors affecting the rate of corrosion

i) Nature of corrosion product ii)conductivity iii) Temperature

4. Explain about Differential metal corrosion?

5.Explain about Differential aeration corrosion? (pitting & Water-line)

6. Write a note on Anodizing?

7. Write a note on galvanization?

8.Define cathodic protection? Explain about sacrificial anodic method?

9. Explain about impressed current method?

### Metal Finishing:-

1. Write a note on

i)polarization ii) Decomposition potential iii) over-voltage

2. Write a note on Technological importance of Metal Finishing?

3. Explain the electroplating of Chromium?

4. Mention the differences between between electroplating & electroless plating?

5. Explain the electrolessplating of Copper?

6. Explain the electrolessplating of Nickel?

### Assignment -3

### Module -3

### Fuels & Solar Energy

### Fuels:-

1.Explain the classification of fuels?

2.Explain the determination of calorific value of fuels using Bomb calorimeter?

3.Define octane number & cetane number?

4.Explain the mechanism of knocking?

5. Write a note on unleaded petrol?

6. Write a note on power alcohol?

7.Write a note on biodiesel?

### FUEL CELLS:-

1. Explain the construction & working of CH₃OH –O₂ fuel cell?

2.Mention the differences between conventional cell and fuel cell?

3. Write a note on solid oxide fuel cell?

### 0

### Solar Energy:-

1. Explain construction & working of photovoltaic cell?

2. Explain preparation of solar grade cell by union carbide process?

3. Write a note on advantages and disadvantages of fuel cell?

### Assignment -4

### .Water Chemistry:-

1.Explain scale & sludge formation in boilers?

2.Define COD? Explain the determination of COD of waste water sample?

3.Explain softening of water by Ion -exchange method?

4. Explain desalination of water by Reverse Osmosis?

5. Write a note on colorimetry analysis of fluorides?

6. Write a note on gravimetric estimation of sulphates?

7. Write a note on boiler corrosion?

8. Write a note on activated sludge method?

### **Environmental Pollution:-**

- 1. Write a note on carbon dioxide?
- 2. Write a note on carbon mono oxide?
- 3. Write a note on oxides of nitrogen?
- 4. Write a note on oxides of sulphur?
- 5. Write a note on ozone depletion?
- 6. Write a note on e-waste management?
- 7. Write a note on mercury?
- 8. Write a note on lead?
- 9. Write a note on biomedical waste management?
- 10. Write a note on lead?

### Assignment -5

### Module-5

### Instrumental method of analysis:-

- 1. Explain instrumentation and application of flame photometry?
- 2. Explain instrumentation and application of potentiometry?
- 3. Explain instrumentation and application of conductometry?
- 4. Explain instrumentation and application of Atomic absorption spectroscopy?

### Nano Materials:-

- 1. Explain the sysnthesis of nanomaterials by sol-gel method?
- 2. Explain the sysnthesis of nanomaterials by precipitation method?
- 3. Explain the sysnthesis of nanomaterials by chemical vapour deposition?
- 5. Write a note on graphene?
- 6. Write a note on carbon Nano tubes?
- 7. Write a note on Fullerenes?

inure

USN

1

### CITY ENGINEERING COLLEGE

### I Internal

### Sub:- Engg. Chemistry 18CHE22 Branch:- CS, ME, EC, CV Sem & Sec:- I & C

CE

Date:- 19/09/2019 Time:-10.30-12.00 P.M Max.Marks-50

NY

Q.No.	ANSWER ALL QUESTIONS	MARKS	CO' S	BT Level
	PART-A			
1.a)	What is single electrode potential? Derive Nernst equation for single electrode potential?	6	COI	BT'I
b)	Outline construction & working of calomel electrode?	4	COI	BT2
	OR	<b>1</b>		
2.a)	Build construction & working of Ni-MH battery?	4	COI	BT3
b)	Build construction & working Li-Ion battery?	6	COI	BT3
	PART-B			1
3.	Build construction and working of Glass electrode?	10	CO1	BT2
	OR			
4.a)	Electrochemical cell consists of Cu electrode dipped in 0.5M CuSO ₄ & Ag ¢lectrode dipped in 0.25M AgNO ₃ . Write cell scheme, half cell and net cell reactions. Also calculate emf. SRP of Cu & Ag are 0.34&0.8V	6	COI	BT5
b)	The EMF of the cell Ag/AgCl _(0.1M) /AgCl _(XM) /Ag is 0.07V. Find X at 298 K?	4	CO1	BT5
	PART-C			
5.a)	Define Concentration cell? Calculate the potential of the cell at 298K $Ag/AgCl_{(0.005M)//}AgCl_{(0.5M)/}Ag$ .	6	CO1	BT5
b)	Define reference electrode and Ion selective electrode?	4	COI	BTI
~)	OR			
6.a)	Write a note on factors affecting the rate of corrosion i) Ratio of anodic to cathodic areas ii) PH	6	CO2	BT2
b)	Write a note on factors affecting the rate of corrosion i) Nature of corrosion product ii)Temperature	4	CO2	BT2

### **P.T.O**

	PART-D			
7.a)	Explain about Differential aeration corrosion?	4	CO2	BT2
b)	Explain galvanization process of alumimium?	6	CO2	BT2
	OR			
8.	What is metallic corrosion? Describe the electrochemical theory of corrosion taking iron as an example	10	CO2	BTI
	PART-E			
9.a)	Explain sacrificial anodic method and impressed current method?	7	CO2	BT2
b)	Summarize on Anodizing of aluminium?	3	CO2	BT2
	OR			
10.	Explain: (i) Differential metal corrosion & (ii) Water-line corrosion	10	CO2	BT5

#### Course outcomes:-

CO1--- Use of free energy in equilibria, rationalize bulk properties and processes using thermodynamic considerations, electrochemical energy systems.

CO2-- Causes and effects of corrosion of metals and control of corrosion.

Blooms Taxanomy:-

BT1-Knowledge BT2---Understand BT3---Appiy BT5----Evaluate.

Russurepus

Principal City Engineering College, Bangalore-560.061

DEPARTMENT OF .... Chemistry

SCHEME FOR VALUATION

Semester & Section: I, C.

Date: 199119.

Question	Details of the answer		<b>r</b>
No.		Marks Distribution	Total Marks
l a.	Def:	IM	IVIAIRS
1.7	Du=-nFE	an an an an an	
		2M	
	$\Lambda a^{\circ} = - n F E^{\circ}$		6M .
	De= De + Riln ke + Substitution	1+1.	
	E= E+ 0.0591 log [M"+]		
1 N	C CT Control Control Internet	IM	
			- di
ь.			
100	Anode: 249 + 201" +1920/2+ 2e	1+1+1+1	ЧM
	Calhode: Hg2U2+ 20 24g+20-	j <b>n</b> n	
	$E = E' - 0.0591 \cdot 109[a]$		3
	0		
2- 4:			
	Anode. MH2 + OH M+ H20+ 2e	1+1+2	um
	Califode: NiO(OH) + Hotae = NiLOH) + OH-		s 1
6			
ь.	Fig. + Expl. + reactions + Apply		
	$Li-C_6 \rightleftharpoons Li^+ + lc + bc$		
i arri - Xini Ri	COO2+ Cit+le = LiCOO2	e. 1	
3.	Fig. + Equar # Expl. + Eb.	1+2+2	lom
1	V Ceau		LU M
	EXAME the Eq = Eb + EAPLARD + Earym.	IM	5
X	이 이 이 이 이 이 이 이 이 이 이 이 이 이 이 이 이 이 이	200	Ċ.
Staff		)) ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~	
6 ⁷⁷		, п	

DEPARTMENT OF

SCHEME FOR VALUATION

Internal Test

Semester & Section:

Date:

Question Details of the answer No. $E_{G} = L_{1} - 0.05$	Marks Distribution	Total Marks
E = L1-0.0591 pH		IVIDIKS
	2M .	
constantion fig. + Expl	1 M + 1 M	
4. 9. E - passi log (metal im at cala)		. 0
Cell = Cell + Orosi ( [melas in al-anode]	Im.	
$= 0.46 + 0.0591 \log \frac{(0.25)^2}{(0.5.)}$		
· 0.46 + 0.02955 (- 0.90.30)	2m	6M
= 0.46 = 0.0266 = 0.433V Anode $cut = cut + 2e^{-1}$		611
Calibra 2 Agt+2e - s 2 Ag.	IM	
cell Rep. culleu ²¹ Agt Ag.	1M-	2 4
$E_{\alpha U}^{2} = E_{c}^{2} - E_{A}^{2}$ = 0.8-0.34 - 0.46v.	IM	
b. $E_{cell} = \frac{0.0591}{0} \log \left(\frac{C_2}{C_1}\right)$		
$0.07 = 0.0571 \log(\frac{x}{2})$	1 M.	
$\frac{0.07}{0.0591} = 109 \times -10.901$	1 M.	

DVDG los 200 HOD

## DEPARTMENT OF

## SCHEME FOR VALUATION

Internal Test .....

Semester & Section:

	Date:	
on Details of the answer	Marks	Total
	Distribution	Marks
1.1844 = 10JX - (-1)	im	
1-15-44-1 = 10g x		UM
103x = 0.16uy		
x = 1.5289 M	Ing	
Det	2m	ка к
$E = \frac{0.0591}{2} \log\left(\frac{C_{L}}{C_{1}}\right)$ = $\frac{0.0591}{1} \log\left(\frac{C_{L}}{C_{1}}\right)$ (0.005)	IM 2M	6m
= 0.1182V. Def	1M 2×2	YM ·
Empl. (i) Empl.	3×2	6m
Eupl. 11) Eupl.	242	Чм
	No	Л

Date:

DEPARTMENT OF

Internal Test .....

2020

• 

Semester & Section:

Date:

Question No.	Details of the answer	Marks	Total
NO	· · · · · · · · · · · · · · · · · · ·	Distribution	Marks
7-9-	Fig-+ Eupl	2.12	Um.
<i>b</i> -	Fig. + Eupl.	3+3	6 m.
8:	$\frac{evpl}{Re} - \frac{1}{Re^{2f}} + \frac{2e^{-1}}{1}$	SM	
	02+2H20+4e 4041		юм
	21-20 + 2e + H2 + 2011	SM	
	2H++2e- H2.		
	R(04)2+02+(n-2)H20 R203. NH20.		
9 9.	Fig. + Expl. + fig. + Expl.	2+2 lt2	7m.
۶	Fig. + Eup).	1+3	YM.
•	Eupl + Fig. + reaction		
rain an M	Ren Ret pre-	2+2+1	
	02+ 2H20+ 4e 014	EM.	
n).	Expl. + fig + reaction	2+2+1	lom.
1.		xi-ti	a *
/ )			*

Principal City Engineering College, Bangalore-560.061

R

USN

- 1	1000	- E -
-1		
-1		- F 1

### C E

## **CITY ENGINEERING COLLEGE**

### II Internal

### Course:- Engg. Ghemistry 18CHE12 Programme:- CS, ME,CV,EC Sem & Sec:- I, C

### Date:- 05/10/2019 Time:-10.30-12.00 Max.Marks-50

Q.No.	ANSWER ALL QUESTIONS	MARKS	CO.	BT Level
·	PART-A	I		
1.a)	Outline technological importance of metal finishing?	4	CO2	B1.
b)	Develop electroplating process of hard chromium with reactions?	6	CO2	BIC
r==	OR	L	1002	
2.a)	Create electroless plating of nickel with suitable reactions?	6	CO2	BTO
b)	In a COD test 30.2 cm ³ and 14.5 cm ³ of 0.05N FAS solution are required for	4	102	BT5
	blank and sample titration respectively. The volume of test sample used was 25 cm ³ . Calculate COD of sample titration?		CO2	
	PART-B		1	<u></u>
3.a)	Explain desalination of water by reverse osmosis?	4	CO4	TBT5
b)	Explain procedure, principle & Calculation for COD estimation?	6	0.04	B15
	OR	L		
4.a)	Summarize on Activated studge method?	4	CO4	B12
b)	Write 6 Differences between electroplating and electroless plating process?	6	CO4	BIS
r	PART-C			1
5.	Summarize principles governing electroplating process such as polarization, over potential and decomposition potential?	10	CO2	B12
<u> </u>	OR	•		
6.a)	Define knocking & its mechanism with ill effects?	6	CO3	BH
b)	Outline on biodiesel?	4	CO3	B12
	PART-D	100		
7.a)	Brief power alcohol?	4	CO3	BTT
b)	When 0.935g of fuel is subjected for complete combustion in excess of oxygen the increase in temperature of water in a calorimeter containing 1240g of water was $2.35^{\circ}$ C.Evaluate HCV. LCV of the fuel, if water equivalent of calorimeter is 130g. Given specific heat of steam=2454J./Kg, specific heat of water is 4.187 J/g?K and % of H ₂ in coal sample is 5.8	6	CO3	BT2

# **P.T.O**

	OR			T
8.	Build determination of calorific value of solid fuel using bomb calorimeter with	10	CO3	B13
- j	formula and mention the terms used in the formula?	008 <u></u>		

	PARI-E			
9.a)	Define NCV & GCV	6	CO4	BTI
b)	Write a note on anti knocking agents?	4	CO4	BT2
	OR			T
10.	Define Solar cell and Build construction and working of photovoltaic cell with its advantages and disadvantages?	10	CO3	BT3

#### Course outcomes:-

CO2-- Modification of surface properties of metals to develop resistance to corrosion, wear. Tear, impact etc. by electroplating and electrolessplating.

CO3 – Production and comsumption of energy for industrialization of country and living standards of people. Utilization of solar energy for different useful forms of energy.

CO4- Water chemistry

#### **Blooms Taxanomy:-**

BT1--Knowledge. BT2---Understand. BT3---Apply, BT4--Analyzing, BT5----Evaluate.

BT6-- creating.

Rume

Principal City Engineering College, Bangalore-580.061

DEPARTMENT OF Chemicing

## SCHEME FOR VALUATION

## Internal Test

Semester & Section:  $\mathcal{I}$  , C.

Question

No.

1. a.

	Date: 5/10/1	9.
Details of the answer	Marks Distribution	Total Marks
Any 4 technological importance pre treating of object.	1×4	4M.
Fie filled Object	100	

	V	1 1 × 4	YUM.	
þ,	Pre treating of object. Composition of plating bats wills reaction	IM -		
	Application	нм IM	бм	
2. a.	Catalylic activation of Object composition of plating bats with reactions	IM SM	Ġη.	
Р.	1 ml of 1 N FAS = Ring of 0,. (30.2-14.5) ml of 0.05N FAS = ?.	2M		
	25mi of waster water = 6.28 mg oto_		HM.	
	1000ml of waster water = $?$ . $\frac{1000 \times 6.28}{25} = 251.2 \text{ mgoto}/L$	ам		
3. a,	Det. of desalization. Fig. + Expl.	1M. 2+1 M	um.	
ь.	procedure, principle + cal.	2+2+2	6 M.	
ң.	Fig. + Expl.	2+2	un	
0 /				

mpl

### DEPARTMENT OF .....

### SCHEME FOR VALUATION

### Internal Test .....

Semester & Section;

Date:

Question No.	Details of the answer	Marks Distribution	Total Marks
b.	6 differences bit electroplating 2 electrotess plating	1×6	6M.
ς.	Expl. Decomposition potential + over voltage	4+3+3	IOM.
	+ polarization.		
6. a,	Deb. + Mechanism + ill ebbects	2+3+1	6M
b۰	Expl.	4	чм
f∙ Q,	Expl.	1	UM.
<u></u> Ь.	HCV = [W+N+) XJ X (t2-t1)	<b>N</b>	
	= (1240+130) × 2.35 × 4.187 0.935 × 10=3 = 14417.16 K5/kg.	чм	6M
	= 19411.00 m1.71. LCV > 14417.76 - 0.09x S. 8x 2454 = 13136.174 K5/Kg.	2M	
		in 114	
		u)	

610 HOD YOU.

DEPARTMENT OF .....

### SCHEME FOR VALUATION

Internal Test .....

Semester & Section:

Date:

•

Question		Date:		
No.	Details of the answer	Marks	Total	1
		Distribution	Marks	
8.	Fig. + Expl. + formula + lerms	2+H+2+2		-
9. a	Definitions.	3Mx2	ъм.	
в	. , , ,	н	HM.	
	importante.			
10.	Fig. F Eupl. F Advantages + disadvantages	2+4+2+2	IOM	
			0	
	0			
			•	1000
	а. До стана стан			
aff		20	lei; Se	~
		HOD		
	Principal City Engineering College, Bangalore-560 761		5 B 6	

USN

## **CITY ENGINEERING COLLEGE**

**III** Internal

Course:- Engg. Chemistry 18CHE12 Programme:- CS, ME, CV, EC

C E

Sem & Sec:- I, C

1

Date:- 12/12/2019 Time:-10.30-12.00 PM Max.Marks-50

Q.No	ANSWER ALL QUESTIONS	MARKS	CO'S	BT Leve
	PART-A	1		Leve
1.a)	Show properties and application of fullerene?			-1
b)	Explain the sources, effects and control of Hg pollution?	4	CO5	BT
	OR	6	CO4	BT2
2.a)	Relate about scale and abudas 6			
b)	Relate about scale and sludge formation in boilers?	6	CO4	BT
	Explain the sources, effects and control of Pb pollution?	4	CO4	BTI
3.a)	PART-B			
	Elaborate properties and application of carbon nano tubes?	4	CO5	BT6
b)	Explain synthesis of nano materials by chemical vapour deposition?	6	CO5	BT2
	OR		1000	
4.a)	Explain the causes, effects and disposal methods of e-waste?	5	CO4	D.1.5
b)	Explain the sources, effects and control of CO ₂ pollution?	5		BT2
	DADTE C		<u>_CO4</u>	B16
5.	Explain synthesis of nano materials by sol-gel method?			<del>.</del>
	j our ger method.	10	× 17 × 7	
	OR	10	CO5	B12
6.a)	Build the construction & working of $CH_3OH - O_2$ fuel cell?	1	()() >	
b)	Recall the differences between conventional cell and fuel cell?	6	<u>CO3</u>	BT3
	PART-D	4	CO3	BT1
7.a)				
b)	Build the construction & working of solid oxide fuel cell?	4	CO3	BT3
	Outline instrumentation of potentiometry?	6	CO5	BT2
8.	OR OR			
	Explain the theory and instrumentation of conductometry?	10	CO5	BT2

P.T.O

	PART-E	1	5 U. B	19 (S
9.a)	Write a note on properties of nano particles	!	CO5	DTO
	a) Electrical property b) Optical property?	5	COS	BIZ
b)	Elaborate properties and application of graphene?	5	CO5	BT6
11	OR		1	1
10.		10	COF	DTO
	Explain the theory and instrumentation of colorimetry?		CO5	BI7

#### Course outcomes:-

CO4-- waste management, water chemistry

0

CO5 – Fundamental principles of nano materials, different techniques of instrumental methods of analysis.

### Blooms Taxanomy:-

BT1-Knowledge, BT2---Understand, BT3---Apply, BT4-Analyzing, BT5----Evaluate,

BT6-- creating.

Rummer

Principal City Engineering College, Bangalore-560.061 CITY ENGINEERING COLLEGE DEPARTMENT OF <u>Chemistry</u> SCHEME FOR VALUATION Internal Test <u>III</u>

-

N	stion lo.	Details of the answer	Marks Distribution	Total Marks
01 1.	a.)	properties, application	272	Um.
12	b.	sources, effect, control of Hg.	372	6m.
2.	a.	pef. + formation + Disadvantages	3x2	6m.
10	b.	to be a second sec	1+2+1	Lem.
3	a.	Siructure + propulies + application.	1+1+2	um.
	b-	Synthesis + tig.	5+1	6 m.
Ч.	a.	causes + ebbeuls + disposal e-wade	1+2+2	ξm.
	Ь.	source + effect + control coz.	1+2+2	5m.
5.		Syntisciis + fig + reactions.	21+2+4	iom.
6.	a٠	Fig. + Expl. + reactions	2+2+2	6M.
	Ь.	Any 4 diffuences	ixu	UM
7.	a.	Fig. + Expl. + realtions Instrumentation	2+2+2	UM.
	Ь	Instrumentation		6M

HOD

DEPARTMENT OF .....

### SCHEME FOR VALUATION

### Internal Test .....

Semester & Section:

Question No.	Details of the answer	Marks Distribution	Total Marks
	+ Instrumentation.		IOM
9. q. Electrica	l property, optical property	每24×2	5M
# 5. properties	+ application	21/2×2	Sm.
	- impentation.	SX2	10 m.
	+ Instrumentation.		E
5 1+2	fit + when the	12 1	
1+2+2 5	uses + ebbeuts + disposal e-wade	a. Ca	ч.
1+2+2 51	unce + Effect + Contral Coz.	b. 50	
A+2+4 10	methode + fit + acadiens	142	2
2+2+2 61	+ Expl. + seachians	4 FM	9
1×4 a	4 differences	ura d	
2+2+2 u	t expi + readians	a Fig	۲
9	divinent at m	6 In	

Russureres

Principal City Engineering College, Bangalore-560.061

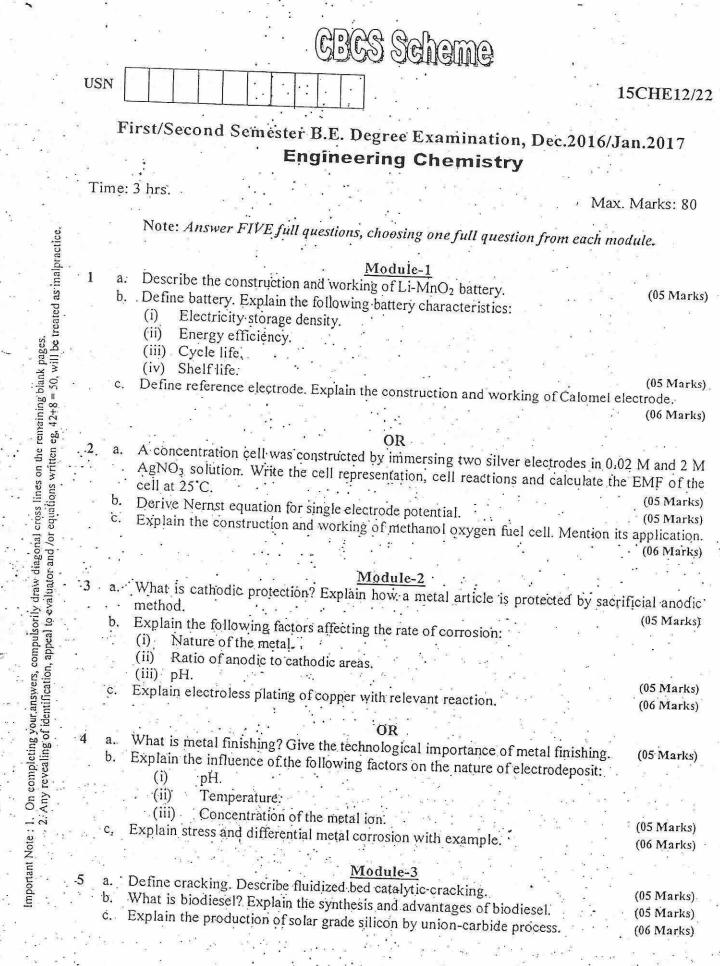
### Model Question Paper-2 with effect from 2018-19 (CBCS Scheme)

	Engineering Chemistry (Common to all Branches) Max.Marks:100 full questions, choosing one full question from each module Module-I	
USN		
	18CHE12/22	
	2451 12451	
First/Second Semester B.E.Degree Examination	on	
Engineering Chemistry		
	May Markey 100	
Time: 3 Hrs	Max.Marks.100	
Note: Answer any FIVE full questions, choosing one full question from	each module	
	*	
Module-I		
1. a. What is single electrode potential? Derive Nernst equation for single electrode potential?	ectrode potential.	
b. Calculate the emf of a Cd-Cu cell in which Cd is in contact with 0.002	M CdSO a and	
298 K		
c. Explain the construction and working of 141-1411 battery, mention its app		
	(/ Marks)	
OR		
Ŭ.	4	
2. a. Explain the construction and working of Li-ion battery. Mention their a	dvantages and	
applications.	(7 Marks)	
b. What are primary and secondary batteries? Explain with examples.	(6 Marks)	
c. A concentration cell was constructed by immersing two silver electrod	· · · · · · · · · · · · · · · · · · ·	
1M AgNO ₃ solutions. Give the cell representation, write the cell reaction	*	
the emf of the cell	(7 Mårks)	
	.(/ 4viai Ks)	
Module-II		
3. a. Explain: (i) Water-line corrosion & (ii) Pitting corrosion.	(6 Marks)	
b. Explain the process of (i) galvanization & (ii). Anodizing	(7 Marks)	
c. What is electrolessplating? Explain the electrolessplating of nickel.	(7 Marks)	
	(, , , , , , , , , , , , , , , , , , ,	
OR		
. On		
4. a. What is meant by metal finishing? Mention (any 6) technological impo	rtance .	
of metal finishing.	(7 Mårks)	
b. Define the terms (i) Polarization, (ii) Decomposition potential & (iii) C		
b. Denne the terms (i) i blanzation, (ii) Decomposition potential & (iii) C	(6 Marks)	
c. What is cathodic protection? Explain (i) Sacrificial anodic & (ii) Impres		
current methods	· .(7 Marks)	
	.(/ 1/1/1/1/1/5)	
	8. 	

a	Module-111	
	5. a. What are chemical fuels? How are they classified?	(6 Marks)
	b. What are fuel cells? How does a fuel cell differ from a battery? Give their a	0422
	disadvantages.	· ·(7 marks)
	c. Explain the preparation of solar grade silicon by union carbide process.	(7 marks)
	OR	
8	6. a. What are PV cells? Mention their advantages and limitations.	(6 marks)
	b. 0.85 g of coal sample (carbon 90%, $H_2$ 5% and ash 5%) was	
ě	subjected to combustion in 'a Bomb calorimeter. Mass water taken in	
	the calorimeter was 2000 g and the water equivalent of calorimeter	a 1000 11
		8
8	was 600 g. The rise in temperature was found to be 3.5°C. Calculate	
	gross and net calorific values of the sample. Latent heat of steam	1 a 2 a 1
	=2457KJ/Kg.	
	(8 Marks)	
	c. Write a note on (i) Power alcohol & (ii) Unleaded petrol	5
		(6 Marks)
		(a)
	Module-IV	
		· · · · · · · · · · · · · · · · · · ·
	7 a. What are the causes, effects and disposal methods of e-waste?	(7 Marks)
	b. What are the sources, effects and control of mercury pollution?	(7 Marks)
X	c. In a COD test 30.2 cm ³ and 14.5 cm ³ of 0.05 N FAS solution are required	
	for blank and sample titration respectively. The volume of the test sample u	sed was 25
	cm ³ . Calculate the COD of the sample solution.	(6 Marks)
	OP.	(0
	8. a. Explain the softening of water by ion exchange method.	(C Manler)
		(6 Marks)
	b. Explain the activated sludge treatment of sewage of water.	· (7 Marks)
	c. Explain the mechanism of photochemical smog.	(7 Marks)
		Josef
	Module-V	
•		. ·
	9. a. Explain the theory, instrumentation and applications of atomic absorption s	55 S. S. S.
		(7 Marks)
	b. Explain the theory and instrumentation of potentiometry	(7 Marks)
	c. Explain the synthesis of nano-material by sol-gel technique.	(6 Marks)
		()
	OR	
11		(7 NA 1-)
		<u>(</u> 7 Marks)
	b. What are nano-materials? Explain the synthesis of nano-materials by	
	chemical vapor deposition.	(7 Marks)
	c. Explain the theory and instrumentation of colorimetry.	(6 Marks)
12		3.1
		10
		8
		8
8	the second se	, 9. <b>x</b>
	la de	
	multiply	
0877	Ruin	1 <b>2</b>
	Principal	2
	City Engineering College, Bangalore-560.061	19 10
8		8

. .

	80
Model Question Paper-1 with effect from 2018-19	2000 2000
(CBCS Scheme)	
USN	а 1 т.
18CHE	10/00
	12/22
First/Second Semester B.E.Degree Examination	2000 E
Engineering Chemistry	
(Common to all Branches) Time : 3 Hrs Max.Mar	40.100
Max.Mar	KS.100.
Note: Answer any FIVE full questions, choosing one full question from each mode	ule .
	41 353
Module-1	C, 2 7
1. a. Define the terms: (i) Free energy, (ii) Entropy & (iii) Cell potential (6 M	(Salar)
b. What are concentration cells? The cell potential of Cu concentration cell	larks)
Cu/CuSO ₄ (0.005M) // CuSO ₄ (X)/ Cu is 0.0295 V at 25° C.	б К
Write the cell reaction and calculate the value of $X$ . (7 N	larks)
c. What are batteries? Explain the construction and working of Li-ion battery, mention its applications. (7 M	larks)
	ai K5j
OR	
2: a. Write short notes on primary; secondary and reserve batteries. (6 N	larks)
b. Explain the construction and working of Ni-MH battery. Mention its applications	
c. For the cell, $Fe/Fe^{2}$ (0.01M)//A $\sigma$ (0.1M)/A $\sigma$ write the cell reaction and calculate	Marks)
child of the cent at 290K, it standard electrode potentials of Fe and Ag electrodes a	re
-0.44 V and 0.8 V Tespectively.	Marks)
<u>Module-2</u>	
3. a. What is metallic corrosion? Describe the electrochemical theory of corrosion	· ·
	larks)
b. Explain: (i) Differential metal corrosion & (ii) Water-line corrosion (6 N	larks)
	larks)
	10 20
OR	
4. a. What is meant by metal finishing? Mention (any five) technological importance	8
	larks)
b. What is electrolessplating? Explain the electrolessplating of copper. (8 N	larks)
c. Explain the factors affecting the rate of corrosion (i) Nature of corrosion product, (ii) Ratio of anodic to cathodic areas & (iii) pH	larks)
	12 18
	T.
	2 ² 13
이 집에 많은 것이 같이 많은 것이 같은 것이 같이 많은 것이 없는 것이 같이 많은 것이 없는 것이 없는 것이 없는 것이 없다.	n 1 a 1 a



. 1 of

(06 Marks)

6 a.

8

- Define photo voltaic cell. Explain the construction and working of photo voltaic cell.
- b. Explain the purification of silicon by zone refining.
- c. A 0.6 g of coal sample (carbon 90%, H₂ 3% and ash 7%) was subjected to combustion in a (04 Marks) bomb calorimeter. Mass of water taken in the calorimeter was 2000 g and the water equivalent of calorimeter was 400 g. The rise in temperature was 3'C. Calculate the gross and net calorific value of the sample. Given, specific heat of water is 4.187 KJ/kg/°C and latent heat of steam is 2454 KJ/kg, (06 Marks)

#### Module-4

- a. Explain the free radical mechanism for addition polymerization by taking vinyl chloride as an example. (06 Marks) ! Explain the synthesis, properties and applications of epoxy resin. b.
- . (04 Marks) What is glass transition temperature? Explain the following factors affecting glass transition .·C. temperature.
  - Chain flexibility and (i)
  - Intermolecular forces. (ii)

(06 Mar

#### OR

- a. Explain structure property relationship of polymers with respect to, Crystallinity . (i)(ii) Tensile strength
  - (05 Marks) What is polymerization? Explain addition and condensation polymerization with example. What are polymer composite? Explain the synthesis, properties and application of Kevlar (05 Marks) fibre. (06 Marks)

#### Module-5

Write a note on fullerenes. Mention its application. (05 Marks) Discuss the synthesis of nanomaterials by gas condensation method and chemical vapour condensation processes. . . . • , . • • (05 Marks) Discuss the experimental determination of Dissolved Oxygen (DO) of waste water. Mention the reactions involved in it. (06 Marks)

#### OR.

- What is desalination? Discuss the desalination of sea water by ion exchange process. 10 · a.
  - (05 Marks) What is boiler feed water? Explain the scale and sludge formation in boilers. . b. (05 Marks) Explain any three size dependent properties of nanomaterials. C.

(06 Marks)

### 18CHE12/22

#### Module

a. Define the term Calorific value of fuel. Explain the experimental determ	ination
of calorific value of solid/liquid fuel using Bomb calorimeter.	(8 Marks)
b. What are fuel cells? Describe the construction and working of CH ₃ OH-C	$D_2$ fuel cell.
	(6 marks)
c. What are solar cells? Explain the construction and working of a typical I	V cell.
	(6 marks)
	8

a. Explain the production solar grade Si by union carbide process b. 0.75 g of coal sample (carbon 90%,  $H_2$  5% and ash 5%) was 6: (6 marks)

subjected to combustion in Bomb calorimeter. Mass water taken in the calorimeter was 2.5Kg and the water equivalent of calorimeter is 0.65Kg. The rise in temperature was found to be 3.2°C. Calculate gross and net calorific values of the sample. Latent heat of steam =2457KJ/Kg and specific heat of water = 4.187KJ/ Kg/°C: (8 Marks)

c. What is knocking? Explain its mechanism. Mention its ill effects.

0

(6 Marks)

### Module-4

7	a. Explain the mechanism of photochemical smog?	. (7.Marks)	
	b. What are the sources, effects and control of lead pollution?	(7 Marks)	
	c. Define COD. In COD test 27.5 cm ³ and 13.2 cm ³ of 0.05 N FAS solution		
*	for blank and sample titration respectively. The volume of the test sample	used is 25	02
	cm ³ . Calculate the COD of the sample solution.	(6 Marks)	
	OR	(81) -	
8.	a. Define the term COD. Explain the determination of COD.	(6 Marks)	
	b. What is potable water? Describe the process of reverse osmosis process of	of water.	
		(7 Marks)	
	c. What are the causes, effects and disposal methods of e-waste?	(7 Marks)	

### Module-5

9	9. a. Explain the theory, instrumentation and applications of flame photometry.	8 ° .
, ,		(7 Marks)
	b. Explain the theory and instrumentation of conductometry.	(7 Marks)
8	c. Explain the synthesis of nano-material by sol-gel technique.	(6 Marks)
े इ		

10. a.	Write a note on graphenes. Mention its applications.	(7 Marks)
b.	What are nano-materials? Explain the synthesis of nano-materials by	
	precipitation method	(7 Marks)
c.	Explain the theory and instrumentation of potentiometry.	(6 Marks)

Principa City Engine 580



### DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

### CIRCULAR

### Ref. No: CEC/CSE/DAC/2019-2020/02

Date: 31/01/2020

All the members of Department Advisory Committee are informed to attend a meeting which will be held as follows

Date: 03/02/2020 Time: 11.30 AM Venue: LAB C107

#### Agenda:

- AICTE Internship policy
- Lab in-charge and class teacher allotment
- Rubrics for project and technical seminar
- · Activities planned for even semester
- Introducing ICT tools in teaching methodology

Mr. Vivekavardhana Reddy

HOD



### DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

### **Department Advisory Committee Meeting**

Date: 03-02-2020 Time: 11:30 AM

### **DAC Members Present:**

Sl. No	Member Name	Designation	Role
1	Mr. Vivekavardhana Reddy	HOD	Convenor
2	Dr. Nandakumar A N	Professor	Member
3	Dr. Sowmya Naik P T	Professor	Co-Convenor
4	Mr. Deepak N R	Assistant Professor	Member
5	Mr. Girish G A	Assistant Professor	Member
6	Mrs. Ambika P R	Assistant Professor	Member
7	Mrs. Laxmi M C	Assistant Professor	Member
8	Mrs. Archana Bhat	Assistant Professor	Member
9	Mr. Vinodh Kumar S	Assistant Professor	Member
10	Mr. Vivekraj G K	Technical Product Manager, Sabre India	Industry Expert
11	Mr. Devraj K	Founder & CEO, EtherScale	Alumni

The Department Advisory Committee meeting was conducted at Department of CSE, on 3rd of February 2020, at 11:30 AM.

### Agenda of the Meeting:

- AICTE Internship policy
- Lab in-charge and class teacher allotment
- Rubrics for project and technical seminar
- Activities planned for even semester
- Introducing ICT tools in teaching methodology



### **Minutes of Meeting:**

The following points were discussed in the meeting:

- The HOD discussed about internship guidelines and procedures proposed by AICTE for 2019 batch. He suggested different activities which can be carried out by the students. The proctors were informed to mentor the students in this regard.
- Lab in-charge and class teachers were identified and their duties and responsibilities were briefed by the HOD.
- Encourage final year students to attend inter collegiate events where they can exhibit their project or present technical paper. It was decided that such participation by the students will carry 40 marks out of 100 during project evaluation.
- The activities planned for even semester such as guest lecture, industrial visit, poster presentation was discussed in the meeting.
- It was discussed to inculcate ICT tools in their teaching method. All the members
  were agreed to use Google class room on which syllabus, lesson plan, lecture notes,
  question papers, assignments and quiz shall be posted. It was informed that the
  faculties handling laboratories shall use flipped classrooms to explain lab programs.
- The HOD suggested to create programming aptitude tests in Moodle to increase the competency among students.

HOD

cc to Principal

	II Sem B. E. / B. Tech. / B. Arch	IV & VI Sem B. E. /B. Tech. IV, VI&VIII Sem B. Arch.	VIII Sem B.E / B.Tech & X Sem B. Arch	IV Sem MCA	VI Sem MCA	IV Sem MBA	IV Sem M. Tech.	IV Sem M. Arch.	II Sem M. Tech.	II Sem MCA	II Sem MBA	II Sem M. Arch.
Commencement of EVEN Semester	10.02.2020	10.02.2020	10.02.2020	27.01.2020	27.01.2020	10.02.2020	27.01.2020	27.01 2020	05.03.2020	05.03.2020	14.02.2020	14.02.2020
Last Working day of EVEN Semester	01.96.2020	01.06.2020	01.06.2020	20.05.2020	20.05.2020	01.06.2020	20.05.2020	20.05.2020	22.06.2020	22.06.2020	05.06.2020	05.06.2020
Practical Examination	03.06.2020 To 13.06.2020	03.06.2020 To 13.06.2020	-	26.05.2020 To 30.05.2020				×	25.06.2020 To	25.06.2020 To	-	
Theory Examinations	15.06.2020 To 04.07.2020	15.06.2020 To 20.07.2020	03.06.2020 To 11.06.2020	03.06.2020 To 18.06.2020		03.06.2020 To 28.06.2020	03.06.2020 To 10.06.2020		30.06.2020 01.07.2020 To 11.07.2020	30.06.2020 01.07.2020 To	08.06.2020 To	09.06.2020 To
Viva Voce			15.06.2020 To 20.06.2020	•			-	- -	-	11.07.2020	20.06.2020	20.06.2020
Summer Project / Professional training	5	-		-	22.05.2020 To 30.05.2020 (Submission of report to VTU)	01.04.2020 To 15.04.2020 (Submission of report to VTU)	12.06.2020 To 25.06.2020 (Submission of report to VTU)		13.07.2020 To 31.07.2020	-	23.06.2020 To 21.07.2020	01.07.2020 To 25.08.2020
Commencement of ODD Semester	27.07.2020	27.07.2020	27.07.2020	27.07.2020	•	-	-		03.08.2020	27.07.2020	27.07.2020	28.08.2020

Academic Calendar of VTU, Belagavi for EVEN Semester of 2019-2020 (Jan 2020 – July 2020)

NOTE

1. College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notified separately.

2. The faculty/staff shall be available to undertake any work assigned by the university.

3. If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day.

4. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTRAR

	1	СІТҮ І	ENGIN	EERING COLLEGE, BEN	GALUR	U-560061. ACADEMIC	CALE	NDAD 2010 20 /51/5		
DAY	1 Post Second	2010/111 2020	2. 2 M	MARCH 2020		APRIL 2020		MAY 2020	SEM)	JUNE 2020
DAT	Date	EVENT	Dat	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
WED					1					
THU					2		_			
FRI					3					
SAT	1				4		1	MAY DAY GH	2	
SUN	2		1		5	the factor called and the state of the	2		_	
MON	3		2		6		3			
TUE	4		2			MAHAVIRA JAYANTHI GH	4		1	LAST WORKING DAY OF
WED	5		3		7		5		2	2 nd , 4 ⁿ , 6 ⁱⁿ & 8 ⁱⁿ SEMS
THU	6		4 5		8		6	ETHNIC DAY	3	THEORY EXAMS 8" SEN
FRI	7		6		9		7	SPORTS DAY	4	03.6.20 to 11.06.20
	8				10	GOOD FRIDAY-GH	8		5	
SAT	9	2 ND SATURDAY HOLIDAY	7		11	2™ SATURDAY HOLIDAY	9	CHRONICLES	6	VIVA VOCE 8 th SEM 15.06.20 to 20.06.20
and	10	CTADTING OF	8		12		10		-	the second s
NON	10	STARTING OF 2™, 4 th , 6 th & 8 th SEMESTERS	9		13		11		7	
TUE	11	, ye at stricters	10				11		8	
WED	12		11		14	AMBEDKAR JAYANTI-GH	12		9	THEORY EXAMS
ТНО	13	PHASE-2 INDUCTION	12		15		13		10	4** & 6* SEMs 15.06.20 to 20.07.20
FRI	14	PROGRAMME	13		16		14		11	10.00.2010 20.07.20
SAT	15	10.2.2020 to 20.2.20	14		17		15		12	
SUN	16			2™ SATURDAY HOLIDAY	18		16	OPENDAY/EXHIBITIONS (Higher Semesters)	13	
ION	17	and the second second second second	15		19		17	(ingher bernesters)	14	15.06.20 to 04.07.20
UE	18	PHASE-2 INDUCTION	16	Piper in measure	20		18		15	
/ED	19	PROGRAMME	17	FIRST INTERNAL ASSESSMENT 2 nd , 4 th , 6 th & 8 th Semesters	21		19		16	PRACTICAL EXAMS
	20	10.2.2020 to 20.2.20	18	2 ", 4", o" & 8" Semesters	22		20		17	2nd,4th & 6th SEMESTERS
HU		0 2012.20	19		23		21		18	03.06.20 to 13.06.20
RI	21	MAHASHIVARATHRI-GH	20		24	BATTLE OF SCIENCE EVENT (First	22	THIRD INTERNAL ASSESSMENT 2nd, 4th , 6th & 8th Semesters	19	GRADUATION DAY AFTER 20.7.2020
AT	22	4™ SATURDAY HOLIDAY	21	Alumni Day (Tentative)	25	Year)			1.5	
	23		22		26	4 TH SATURDAY HOLIDAY	23	4 [™] SATURDAY HOLIDAY	20	
	24		23		27		24		21	
	25		24		28		25	RAMJAN GH	22	
	26		25	UGADI-GH	29	SECOND INTERNAL ASSESSMENT	26		23	
	27	C.C.M.	26		30	2 nd , 4 th , 6 th & 8 th Semester	27		24	
	28		27		30		28	LAB TESTS	25	
12.5	29		28	41 SATURDAY HOLIDAY			29	2rd,4th,6th & 8th SEMs	26	Color-
JN			29				30	1 15 0 0 SEMI	27	C.T.M.C.
N			30				31		28	
E			31		- Lore - Pro-				29	

		DEPARTMENT OF		UTER SCIENCE AND ENGI	NEERIN	G	ACA	DEMIC CALENDAR 2019-2	20 (EVE	N SEM)
		FEBRUARY 2020		MARCH 2020		APRIL 2020		MAY 2020		JUNE 2020
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
WED					1					
THU					2					
FRI					3		1	MAY DAY GH		
SAT	1				4		2			
SUN	2		1		5		3			
MON	3		2		6	MAHAVIRA JAYANTHI GH	4		1	LAST WORKING DAY OF 2 nd , 4 th , 6 TH & 8 TH SEMS
TUE	4		3		7		5		2	
WED	5		4		8		6	ETHNIC DAY	3	THEORY EXAMS 8 th SEM
THU	6		5		9		7	SPORTS DAY	4	03.6.20 to 11.06.20
FRI	7		6	Guest Lecture	10	GOOD FRIDAY-GH	8		5	VIVA VOCE 8 th SEM
SAT	8	2 ND SATURDAY HOLIDAY	7		11	2 ND SATURDAY HOLIDAY	9	CHRONICLES	6	15.06.20 to 20.06.20
SUN	9		8		12		10		7	
MON	10	STARTING OF 2 nd , 4 th , 6 TH & 8 TH SEMESTERS	9		13		11		8	THEORY EXAMS
TUE	11		10		14	AMBEDKAR JAYANTI-GH	12		9	4 th & 6 th SEMs
WED	12	PHASE-2 INDUCTION	11		15		13		10	15.06.20 to 20.07.20
THU	13	PROGRAMME	12		16		14		11	
FRI	14	10.2.2020 to 20.2.20	13		17		15		12	THEORY EXAMS
SAT	15		14	2 ND SATURDAY HOLIDAY	18		16	OPENDAY/EXHIBITIONS (Higher Semesters)	13	SECOND SEM 15.06.20 to 04.07.20
SUN	16		15		19		17		14	19.00.20 to 0 1.07.20
MON	17		16		20		18		15	
TUE	18	PHASE-2 INDUCTION	17	FIRST INTERNAL ASSESSMENT	21		19		16	PRACTICAL EXAMS 2 nd ,4 th & 6 th SEMESTERS
WED	19 20	PROGRAMME 10.2.2020 to 20.2.20	18	2 nd , 4 th , 6 th & 8 th Semesters	22 23	Workshop/ Technical Activities	20		17	03.06.20 to 13.06.20
THU	20	10.2.2020 (0 20.2.20	19		23		21	THIRD INTERNAL ASSESSMENT 2 nd , 4 th ,6 th & 8 th Semesters	18	GRADUATION DAY AFTER
FRI	21	MAHASHIVARATHRI-GH	20		24	BATTLE OF SCIENCE EVENT (First Year)	22		19	20.7.2020
SAT	22	4 TH SATURDAY HOLIDAY	21	Alumni Day (Tentative)	25	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	20	
SUN	23		22		26		24		21	
MON	24		23		27		25	RAMJAN GH	22	
TUE	25		24		28	SECOND INTERNAL ASSESSMENT	26		23	
WED	26		25	UGADI-GH	29	2 nd , 4 th , 6 th & 8 th Semester	27		24	
THU	27		26		30		28	LAB TESTS	25	
FRI	28		27			29 2'	2 nd ,4 th ,6 th & 8 th SEMs	26		
SAT	29		28	4 [™] SATURDAY HOLIDAY			30		27	
SUN			29				31		28 29	
MON TUE			30 31						29 30	
TUE			31						30	



# ACADEMIC YEAR : 19-20

# DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

## COURSE PREFERNCE

Name of the Faculty: AMBIKA PR.

Designation: ASST. PROF-

Year / Semester:

Sl.No	Course Code and N	ame	new	Year/Semester	0
1.	180542 - DAD			2nd 14m	
2.	18CSL47-DAALAB	1	4	2nd 14th .	
3.	150561- IOT			4th 18th	
			3		-
		(*		· · · ·	
•					1

1

Signature of faculty





# ACADEMIC YEAR : 19 -2 0

# DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

## COURSE PREFERNCE

Name of the Faculty: MS Deepika R

Designation: ASSI, PROD.

Year / Semester:

SI.No	Course Code and Name		Year/Semester
1 -	18CS45-00C	i.	2 hd 14th .
2.	ISCSLU7 - DAA Lab	. 1	and 14th.
3.	ICCS664 - PAP		3rd/6Hh.
4	17CSL68 -CGLab	•	3rd 1644
		1	

Signature of faculty



# ACADEMIC YEAR: 2019 - 2020(Even)

# DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

# COURSE ALLOCATION

SI.No	Name of the Faculty	Course Code and Name	Year/ Semester	Signature
1	Mrs. Sowmya Naik	17CS832 – User Interface Design	4 th / 8 th	Lib
2	Dr. Nandakumar A N	17CS81 – Internet of Things and Applications 15CSP85 – Project Work Phase – II 15CSS86 – Seminar	2 ⁴⁴ y 8 th 4 th / 8 th 4 th / 8 th 4 th / 8 th	NK.
3	Mr. Vivekavardhana Reddy	18CS46 – Data Communication 17CS61 – Cryptography, Network Security and Cyber Law	2 nd / 4 th 3 rd / 6 th	3
4	Mr. Nandish A C	18CS44 – Microcontrollerand Embedded Systems18CSL48MicrocontrollerandEmbedded Systems Lab	2 nd /4 th	R.
5	Mr. Girish G A	<ul> <li>17CS63 - System Software and Compiler Design</li> <li>17CSL67 – System</li> <li>Software and Operating</li> <li>System Lab</li> <li>15CSP85 – Project Work</li> <li>Phase II</li> <li>10CS85 – Project work</li> </ul>	4 th /8 th (OTE)	A
6	Mr. Surendranath Gowda	18CSL48–MicrocontrollerandEmbedded Systems Lab17CS65317CS653–OperationResearch15CS81–UserInterfaceDesign	$3^{rd} / 6^{th}$	Suunder





				1
7	Mr. Vinod Kumar	15CS82- Big Data Analytics 17CSL67 – System Software and Operating System Lab 15CSS86 – Seminar 10CS86 - Seminar	$3^{rd} / 6^{th}$ $4^{th} / 8^{th}$	S.Vit
8	Mrs. Ambika P R	18CS42- Design and Analysis of Algorithms 18CSL47 – Design and analysis of algorithms Lab	$4^{th}/8^{th}$ (OTE) $2^{nd}/4^{th}$ $2^{nd}/4^{th}$	d
9	Mrs. Laxmi M C	18CS43 – Operating Systems 17CS664 – Python Application Programming 17CSL68 – Computer Graphics Lab 15CS84 – Internship	$2^{nd} / 4^{th}$ $3^{rd} / 6^{th}$ $3^{rd} / 6^{th}$ $4^{th} / 8^{th}$	two
10	Mr. B. Ramesh	17CS62 – Computer Graphics and Visualization 17CSL68 – Computer Graphics Lab	$3^{rd} / 6^{th}$ $3^{rd} / 6^{th}$	Jel -
11	Mrs. Punitha P	15CS81 – Internet of Things and Applications	4 th / 8 th	P
12	Mrs. Archana Bhat	18CS44 – Microcontrollerand Embedded Systems18CSL48MicrocontrollerandEmbedded Systems Lab	$2^{nd} / 4^{th}$ $2^{nd} / 4^{th}$	Au
13	Ms. Deepika R	18CS45 – Object Oriented Concepts 18CSL47 – Design and analysis of algorithms Lab	$2^{nd} / 4^{th}$ $2^{nd} / 4^{th}$ $4^{th} / 8^{th}$	DL
14	Mrs. Sriraksha S	17CS664 – Python Application Programming	3 rd / 6 th	Sm





15	Ms. Pushpa	15CS81 – Internet of Things and Applications	4 th / 8 th	fueles
16	Mrs. Sreevidya	17CS61 – Cryptography, Network Security and Cyber Law 17CSL67 – System Software and Operating System Lab		Sent.
17 ¢	Ms. Sowbhagya M P	18CS42- Design and Analysis of Algorithms 18CSL47 – Design and analysis of algorithms Lab	$2^{nd} / 4^{th}$ $2^{nd} / 4^{th}$	Southag
18	Mrs. Nagashree	17CS64 – Operating Systems	3 rd / 6 th	Q
19	Ms. Sowmya L D	17CS653 – Operation Research	3 rd / 6 th	Im
20	Mr. Gangappa D	10IS81 – Software Architecture	4 th / 8 th (OTE)	legenomawas
21	Mr. Suhas	10CS82 – System Modelling and Simulation	$4^{\text{th}}$ / $8^{\text{th}}$ (OTE)	
22	Mr. Doreswamy	10CS834 – Network Management System	4 th / 8 th (OTE)	Dolesiony
23	Ms. Tejaswini	Software Testing	$4^{\text{th}}$ / $8^{\text{th}}$ (OTE)	Jy7.
24	Mr. Channabasappa	101S846 – Decision Support Systems	4 th / 8 th (OTE)	Claugh.



Dept of Computer Science & Engineering CITY ENCLUEDE Doddakato and a Dept of Could Road Dangelore Déceb L



# Department Of CSE

## Feb - May 2020

# Time Table for IV Sem A Section

Room: C-203

DAY	9:00 - 10:00	10:00 - 11:00	1	11:15 - 12:15	12:15-1:15		2.00. 2.00			
MONT	DII				14.10-1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00	
MON	DAA	OS		MES	DC		MATAI	-		
TUE	OS	MES	~	MAT41			MAT41	OOC	Kannada	
WED	MES		ca –		OOC		I –DAA LAB / A2- MES LAB			
and the second second	Cathole Sector	MAT41	Br	OOC	DAA	Bre	OS	DC		
THU	DC	DAA	÷	MAT41	OS			Dist for	Kannada	
FRI	OOC	DC	0			2	A	MES LAB		
	DAA / MES LAB		S Dim		MES	E.	MAT41	EDUSAT/ LIBRARY		
SAT				MES .	DAA		and a second second			

Sl.No	Course Code	Course Name	Can	
1	18CS42	Design and Analysis of Algorithm	Course	Faculty Name
2	18CS43		DAA	Prof. Ambika P R / Prof. Sowbhagya M P
		Operating Systems	OS	Prof. Laxmi M C
2	18CS44	Microcontroller and Embedded Systems	MES	Prof. Nandish A C / Prof. Archana Bhat
4	18CS45	Object Oriented Concepts	OOC	
5	18CS46	Data Communication		Prof. Deepika R
6	18CSL47		DC	Dr. A N Nanda Kumar
7		Design and Analysis of Algorithm Laboratory	DAA LAB	Prof. Ambika P R/ Prof. Deepika R /Prof. Sowbhagya
1	18CSL48	Microcontroller and Embedded Systems Laboratory	MES LAB	Prof. Nandish A C/ Prof. Archana Bhat/ Prof. Surendranath
8	18MAT41	Complex Analysis. Probability and Statistical Methods		
		, and statistical Methods	MAT41	Prof. Gayathri A

Class Teacher: Prof. Archana Bhat

HOD

Romencelan

Principal



-

# **CITY ENGINEERING COLLEGE**

Department Of CSE

Feb - May 2020

Time Table for IV Sem B Section

Room: C-204

DAY	9:00 - 10:00	10:00 - 11:00		4							
		10.00 - 11.00	1	11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00		
MON	MES	OOC		DAA	00			1.00	4.00 - 5:00		
TUE	DAA	MAT41			OS	_	B1 – DAA LAB/ B2 – MES LAB				
WED	OS		cak		MES	cak	OS	OOC	Kannada		
THU	ooc	DAA	Br	DC	MAT41	Bre					
and the second		OS	+ MES DO		- DAA LAB / B1 - MES LAB						
FRI	DC	MES	Sho	MAT41	OOC		The second second second	DAA	Kannada		
SAT	MES	DAA		000		2	MAT41	EDUSAT/ LIBRARY			
		DAA		DAA/	MES LAB						

		67	
18CS42	Course Name Design and Analysis of Algorithm	Course	Faculty Name
		DAA	Prof. Ambika P R / Prof. Sowbhagya M P
and the second second second		OS	Prof. Laxmi MC
	Microcontroller and Embedded Systems	MES	Prof. Nandish A C / Prof. Archana Bhat
		OOC	Prof. Deepika R
	Data Communication	DC	Prof. Vivekavardhana Reddy
18CSL47	Design and Analysis of Algorithm Laboratory		
18CSL48	Microcontroller and Embedded Systems Laborator		Prof. Ambika P R/ Prof. Deepika R /Prof. Sowbhagya
18MAT41	Complex Analysis Brabability		Prof. Nandish A C/ Prof. Archana Bhat/ Prof. Surendranath
	Somplex Analysis, Probability and Statistical Methods	MAT41	Prof. Nagendra Naik
	18CS43 18CS44 18CS45 18CS46 18CSL47	18CS43Operating Systems18CS44Microcontroller and Embedded Systems18CS45Object Oriented Concepts18CS46Data Communication18CSL47Design and Analysis of Algorithm Laboratory18CSL48Microcontroller and Embedded Systems Laboratory	18CS43Operating SystemsDAA18CS43Operating SystemsOS18CS44Microcontroller and Embedded SystemsMES18CS45Object Oriented ConceptsOOC18CS46Data CommunicationDC18CSL47Design and Analysis of Algorithm LaboratoryDAA LAB18CSL48Microcontroller and Embedded Systems LaboratoryMES LAB18MAT41Complex Analysis ProbabilitiesIOurie interform

Class Teacher: Prof. Ambika P R

HOD

Renequerelans

Principal

- Contraction of the second				Γ	CNGINEERI Department Of ( Feb – May 2020 Table for VI Sem	CSE		LEGE		Room: C-201
DAY	9:00 - 10:00	10:00 - 11:00	1	11:15-12:15	12:15 - 1:15		2:00 -	2:00 - 3:00 3:00 - 4:00		4:00-5:00
MON	CGV	OS	1	SSCD	CNECI					
TUE	CNSCL	CGV	k	SSCD	CNSCL			A.	1 - SSOS/ A2 - C	GLAB
WED	OR	CNSL	3rcak	PYTHON	PYTHON	Break	OR		OS	
THU	SSCD	OS	t m	OR	OS				-SSOS / A1 - C	G LAB
FRI	PYTHON	SSCD	Shor	- Contraction of the second	CGV	nch		CNSCL PYTHON		
SAT	MINI PI		S		CGV OR MINI PROJECT		EDU	SAT/ LIBRA	L ACTIVITIES	
SI . No	Course Code		-	Course Name		T	urse			
1	17CS61	Cryptography, N	Cryptography, Network Security and Cyber Law						Faculty N	
2	17CS62						CNSCL Prof. Vivekavardha		and the second se	Prof. Sreevidya
3	17CS63		Computer Graphics and Visualization System Software and Compiler Design					CGV Prof. Ramesh B		
4	17CS64			omptter Design		SS	CD	Prof. Girisl	n G A	
5	110007	Operating System	15			0	DS	Dr.Sowmy	a Naik / Prof Naga	shree

SL. NO	Course Code	Course Name		
1	17CS61	Cryptography, Network Security and Cyber Law	Course	Faculty Name
2	17CS62		CNSCL	Prof. Vivekavardhana Reddy / Prof. Sreevidya
		Computer Graphics and Visualization	CGV	Prof. Ramesh B
3	17CS63	System Software and Compiler Design	SSCD	
4	17CS64	Operating Systems		Prof. Girish G A
5	17CS653		OS	Dr.Sowmya Naik / Prof. Nagashree
-		Operations Research	OR	Prof. Surendranath Gowda / Prof. Sowmya L D
0	17CS664	Python Application Programming	Python	
7	17CSL67	System Software and Operating System Laboratory		Prof. Laxmi M C / Prof. Sriraksha S
8	17CSL68		SSOS LAB	Prof. Girish G A/ Prof. Vinod Kumar /Prof. Sreevidya
	The SEO8	Computer Graphics Laboratory with mini project	CG LAB	Prof. Ramesh B/ Prof. Laxmi M C/ Prof. Sriraksha S

Class Teacher: Prof. Girish G A

Z HOD

Remembergan

Principal



Department Of CSE Feb – May 2020 Time Table for VI Sem B Section

Room: C-202

DAY	9:00 - 10:00	10:00 - 11:00		11/15 10.10	M. alt i				
				11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4.00 = 00
MON	CNSCL	SSCD		COV		_		0.00 4.00	4:00 - 5:00
TUE	SSCD	PYTHON		CGV	PYTHON		OS	OR	
WED	Contract Contract	and the second s	- la	OR	CGV	ak			0.1.10
	PYTHON	OS	Src	CGV	SSCD	rei		B1 – SSOS/ B2 – C	GLAB
THU	CGV	CNSCL		PYTHON		2	OR	CNSCL	
FRI	OS	OR			OS	Ich		B2 - SSOS/ B1 - C	GLAB
SAT	MIN	1		SSCD	CNSCL	'n,		T/LIBRARY/TECHNICAL ACTIVITIES	
	MINI PROJECT			MINI PROJECT				In a contract of the contract	L ACTIVITIES

Sl.No	Course Code	Course Name		
1	17CS61		Course	Faculty Name
2	17CS62	Cryptography, Network Security and Cyber Law	CNSCL	Prof. Vivekavardhana Reddy / Prof. Sreevidya
3	17CS63	Computer Graphics and Visualization	CGV	Prof. Ramesh B
4	17CS64	System Software and Compiler Design	SSCD	Prof. Girish G A
5	17CS653	Operating Systems	OS	Dr.Sowmya Naik / Prof. Nagashree
6		Operations Research	OR	Prof. Surendranath Gowda / Prof. Sowmya L D
7	17CS664	Python Application Programming	Python	Prof. Donaille B. (B. 6.0.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.
/	17CSL67	System Software and Operating System Laboratory	SSOS LAB	Prof. Deepika R / Prof. Sriraksha S
8	17CSL68	Computer Graphics Laboratory with mini project		Prof. Girish G A/Prof. Vinodh Kumar S/ Prof. Sreevidya
			CG LAB	Prof. Ramesh B/ Prof. Laxmi M C/ Prof. Sriraksha S

Class Teacher: Prof. Ramesh B

HOD

Renequerary

Principal

Sec.
Č,

## Department Of CSE Feb – May 2020 Time Table for VIII Sem A Section

Room: C-303

DAY	9:00 - 10:00	10:00 - 11:00		11:15-12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
MON	IOT	BDA		UID	BDA			Destant WI 1 /C	A STATE AND A STAT
TUE	BDA	UID	¥	IOT	UID	- 4	Project Work / Seminar		
WED	UID	IOT	rc:	BDA	IOT		Project Work / Seminar		
THU			- = = = = = = = = = = = = = = = = = = =	bbrt	101	р В		Project Work / Se	minar
FRI			- lou			Inc			
SAT			_ s			<u> </u>			

Course Code	Course Name	Course	P 1 N
15CS81			Faculty Name
15CS82			Dr. Nanda Kumar / Prof. Pushpa
15CS832			Prof. Vinodh Kumar S
15CS84			Dr.Sowmya Naik
15CSP85			Prof. Laxmi M C/ Prof. Deepika R
15CSS86	Seminar		Dr. A N Nanda Kumar / Prof. Girish G A Dr. A N Nanda Kumar / Prof. Vinodh Kumar S
	15CS81 15CS82 15CS832 15CS84 15CSP85	15CS81Internet of Things and Applications15CS82Big Data Analytics15CS832User Interface Design15CS84Internship / Professional Practice15CSP85Project Work Phase II	15CS81Internet of Things and ApplicationsIOT15CS82Big Data AnalyticsBDA15CS832User Interface DesignUID15CS84Internship / Professional Practice15CSP8515CSP85Project Work Phase II15CSP85

Class Teacher: Prof. Vinodh Kumar S

HOD

Remancharg

Principal



Department Of CSE Feb – May 2020

# Time Table for VIII Sem B Section

Room: C - 304

DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12.15 1.15		1		
MON			1		12:15 - 1:15	1.0	2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
MON	BDA	UID		IOT	UID				
TUE	UID	IOT						Project Work / Seminar	
WED	IOT	and the second s	8	BDA	IOT	al	Project Work / Seminar		
	101	BDA	Br	UID	BDA	Src.			
THU			- <del>-</del>					Project Work / Se	minar
FRI									
SAT			S			Lu			

SI.No	Course Code	Course Name	500				
1	15CS81						
2	15CS82	Internet of Things and Applications	IOT	Faculty Name Dr.A N Nanda Kumar / Prof. Pushpa			
3		Big Data Analytics	BDA	Prof. Vinodh Kumar S			
4	15CS832	User Interface Design	UID	Prof. Surendranath Gowda			
4	15CS84	Internship / Professional Practice					
5	15CSP85	Project Work Phase II		Prof. Laxmi M C/ Prof. Deepika R			
6	15CSS86	Seminar		Dr.A N Nanda Kumar / Prof. Girish G A			
				Dr.A N Nanda Kumar / Prof. Vinodh Kumar S			

Class Teacher: Prof.Surendranath Gowda

Russing

HOD

Principal

	<b>N</b>		C	Departi Feb	NEERING ( ment Of CSE – May 2020 le for OTE Batch	COLI	LEGE		Room: C - 302	
DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00	
MON	SA	SMS		NMS	ST/DSS				50000000 C (0000000000	
TUE	ST/DSS	NMS		SMS	and conversion and and			minar		
WED	NMS	SA			SA	cak	J	Project Work/ Seminar		
THU	NMS	SMS	Bre	ST/DSS	SMS	Bre		Project Work/ Se	minar	
INU		0110	ort	ST/DSS	SA	lch		7		
						- 5				
FRI			Sh			5				

Sl.No	Course Code	Course Name		
1	10/581	SOFTWARE ARCHITECTURE	Course	Faculty Name
2	10CS82	SYSTEM MODELLING & SIMULATION	SA	Prof. Gangappa
3	10CS834		SMS	Prof. Suhas
4		NETWORK MANAGEMENT SYSTEMS	NMS	Prof. Doreswamy
4	4 10CS842	SOFTWARE TESTING	ST	
	10/5846	DECISION SUPPORT SYSTEMS		Prof. Tejaswini
5	10CS85	PROJECT WORK	DSS	Prof. Channabasappa
6	10C586			Prof. Girish G A
	100300	SEMINAR		Prof. Vinodh Kumar S

Remember

Principal

HOD

Z

Sec. Sec. Sec. Sec. Sec. Sec. Sec. Sec.				Construction and the second	GINEERIN Department Of C Feb – May 2020	CSE	OLLEGE		
~3	- <b>e</b> - Fac	culty Name: Dr. Sov	wmya N	aik	Sem: VI – A &	B, VIII	[-A]	Subject	: OS, UID
DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
MON		VI - A		UID - A					
TUE		UID - A	ak		UID - A	reak		VI - A	
WED	UID - A		Break			2 m			
Constant Constant			ort		VI - B	hoh			
THU			ŭ				3		
THU FRI	VI - B	1	Sh						

OS	BE [CSE] VI SEM A Section	2 Hours/ Week	$2 \times 2 = 4$
OS	BE [CSE] VI SEM B Section	2 Hours/ Week	2 x 2 = 4
UID	BE [CSE] VIII SEM A Section	4 Hours/ Week	$4 \ge 2 = 8$
Executive Officer			10
Work load			26

3 HOD

Romeneulon

[As per Choice ] (Effective fro	PERATING SY Based Credit Sy om the academi SEMESTER	/stem (CBCS) scheme c year 2017 - 2018)		
Subject Code	17CS64	IA Marks	140	
Number of Lecture Hours/Week	4		40	
Total Number of Lecture Hours	50	Exam Marks	60	
	CREDITS -	Exam Hours	03	
Module – 1	CILIDITIS -	04		1
Introduction to operating systems. do; Computer System operation	, System struct	Ires: What operating a		Teaching Hours 10 Hours
do; Computer System organization System structure; Operating System management; Storage management; Special-purpose systems; Computin User - Operating System interface; programs; Operating system desig structure; Virtual machines; Operatin <b>Management</b> Process concept; Pro Inter process communication <b>Module - 2</b>	r, Computer Sy n operations; Pr Protection and g environments. System calls; T m and implem	stem architecture; Ope ocess management; Me Security; Distributed sy Operating System Ser ypes of system calls; Sy entation; Operating System	rating emory ystem; vices; ystem ystem	
Multi-threaded Programming: C Libraries; Threading issues. Process Criteria; Scheduling Algorithms; scheduling. Process Synchronizati problem; Peterson's solution; Synchronization; Monito. problems of synchronization; Monito. Module – 3	s Scheduling: Multiple-proc on: Synchroniz	Basic concepts; Sched essor scheduling; Th	uling pread	10 Hours
Deadlocks : Deadlocks; System mod handling deadlocks; Deadlock pre detection and recovery from dead hanagement strategies: Background; Paging; Structure of page table; Segm Module – 4	dlock. Memor	ock avoidance; Dead	lock	10 Hours
Virtual Memory Management: Bac Page replacement; Allocation of Implementation of File System: Fi Directory structure; File system mplementing File system: File syste Directory implementation; Allocation Module – 5	of frames; T le system: File mounting; F em structure; Fi methods; Free s	hrashing. File Syst concept; Access meth ile sharing; Protect le system implementat pace management.	tem, ods; ion: ion;	10 Hours
Secondary Storage Structures, Pr tructure; Disk attachment; Disk sel nanagement. Protection: Goals of prot rotection, Access matrix, Implement evocation of access rights, Capability Operating System: Linux history; D nanagement; Scheduling; Memory Matrix	tection, Principle tection, Principle tation of acces y- Based system	management; Swap sp es of protection, Domain s matrix, Access cont s. Case Study: The Lin	n of rol, nux	10 Hours

Inter-process communication.

Course outcomes: The students should be able to:

- Demonstrate need for OS and different types of OS .
- Discuss suitable techniques for management of different resources .

Illustrate processor, memory, storage and file system commands .

Explain the different concepts of OS in platform of usage through case studies

## Question paper pattern:

The question paper will have TEN questions.

There will be TWO questions from each module.

Each question will have questions covering all the topics under a module.

The students will have to answer FIVE full questions, selecting ONE full question from each module.

## Text Books:

1. Abraham Silberschatz, Peter Baer Galvin, Greg Gagne, Operating System Principles 7th edition, Wiley-India, 2006.

## **Reference Books**

- 1. Ann McHoes Ida M Fylnn, Understanding Operating System, Congage Learning, 6th
- 2. D.M Dhamdhere, Operating Systems: A Concept Based Approach 3rd Ed, McGraw-Hill, 2013.
- 3. P.C.P. Bhatt, An Introduction to Operating Systems: Concepts and Practice 4th Edition, PHI(EEE), 2014.
- 4. William Stallings Operating Systems: Internals and Design Principles, 6th Edition,

Faculty Name: Sowmya Naik

# **CITY ENGINEERING COLLEGE**

# DEPARTMENT OF CSE

# **LESSON PLAN FOR EVEN SEMESTER FOR ACADEMIC YEAR 2019-20**

Course Title: OPERATING SYSTEMS	Course Code : 17CS64	
Total contact hours: L:T:P:S :: 3:1:0:0	End Term Marks : 60	
Internal Marks : 40		
Semester: VI SEM A	Academic year : 2019-20	
Lesson plan Author: SOWMYA NAIK P T	Date :7/02/2020	
in the second		

### Course Objective:

This course will enable students to:

- Introduce concepts and terminology used in OS
- Explain threading and multithreaded systems
- Illustrate process synchronization and concept of Deadlock
- Introduce Memory and Virtual memory management, File system and storage techniques.

## Course Outcomes:

After studying this course, students will be able to:

- Demonstrate need for OS and different types of OS
- Apply suitable techniques for management of different resources
- Use processor, memory, storage and file system commands
- Realize the different concepts of OS in platform of usage through case studies

Week	Days	Contents of Module	RBT	Course Outcome (CO)
1	1	What operating systems do; Computer System organization	L1,L2,L3	CO1,CO2
	2	Computer System architecture; Operating System structure	L1,L2,L3	CO1,CO2
	3	Operating System operations; Process management	L1,L2,L3	CO1,CO2
	4	Memory management; Storage management	L1,L2,L3	CO1,CO2
2	1	Protection and Security; Distributed system	L1,L2,L3	CO1,CO2
	2	Special-purpose systems; Computing environments.	L1,L2,L3	CO1,CO2
	3	Operating System Services, User - Operating System interface; System calls	L1,L2,L3	CO1,CO2
	4	Types of system calls; System programs	L1,L2,L3	C01,C02

Faculty Name: Sowmya Naik

0

# LESSON PLAN

ACADEMIC YEAR: 2019-20

3	1	Operating system design and implementation; Operating System structure	L1,L2,L3	C01,C02
	2	Virtual machines; Operating System structure generation; System boot	L1,L2,L3	C01,C02
	3	Process concept; Process scheduling	L1,L2,L3	C01,C02
	4	Operations on processes; Inter process communication	L1,L2,L3	C01,C02

## MODULE 2

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
-	1	Multi-threaded Programming: Overview; Multithreading models	L1,L2,L3	C01,C02
	2	Thread Libraries; Threading issues.	L1,L2,L3	C01,C02
	3	Process Scheduling: Basic concepts; Scheduling Criteria	L1,L2,L3	C01,C02
	4	Scheduling Algorithms; Multiple-processor scheduling; Thread scheduling	L1,L2,L3	CO1,CO2
5	1	Process Synchronization: Synchronization	L1,L2,L3	C01,C02
	2	The critical section problem; Peterson's solution	L1,L2,L3	C01,C02
	3	Synchronization hardware; Semaphores;	L1,L2,L3	C01,C02
	4	Classical problems of synchronization; Monitors	L1,L2,L3	C01,C02

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome
6	1	INTERNAL ASSISMENT 1	Level	(CO)
	2	INTERNAL ASSISMENT 1		
	3	INTERNAL ASSISMENT 1		
	4	Deadlocks : Deadlocks; System model	L1,L2,L3	CO3
7	1	Deadlock characterization, Methods for handling deadlocks;	L1,L2,L3	CO3
	2	Deadlock prevention; Deadlock avoidance	L1,L2,L3	CO3
	3	Deadlock detection and recovery from deadlock.	L1,L2,L3	CO3
8	1	Memory Management: Memory management strategies: Background	L1,L2,L3	CO3
	2	Swapping; Contiguous memory allocation	L1,L2,L3	CO3
	3	Paging; Structure of page table	L1,L2,L3	CO3

Faculty Name: Sowmya Naik

LESSON PLAN

ACADEMIC YEAR: 2019-20

4	Segmentation			
	Segmentation.	L1,L2,L3	CO3	
1	problems			
	problems	L1,L2,L3	CO3	
2	problems			
	problems	L1,L2,L3	CO3	
3	3 problems			
1.000	problems	L1,L2,L3	CO3	
	4 1 2 3	protients	1problemsL1,L2,L32problemsL1,L2,L33problemsL1,L2,L3	

Week	Days/ Date	Contents of Module	Bloom's Taxonomy Level	Course Outcome
10	1	Virtual Memory Management: Background; Demand paging	L1,L2,L3	(CO) CO4
	2	Copy-on-write; Page replacement	L1,L2,L3	CO4
	3	Allocation of frames; Thrashing, File system: File concept	L1,L2,L3	CO4
11	1	Access methods; Directory structure; File system mounting;	L1,L2,L3	CO4
	2	File sharing; Protection: Implementing File system: File system structure	L1,L2,L3	CO4
	3	File system implementation; Directory implementation	L1,L2,L3	CO4
	4	Allocation methods; Free space management.	L1,L2,L3	CO4

## MODULE4

Week	Days/ Date		Bloom's Taxonomy Level	Course Outcome (CO)
12		Secondary Storage Structures, Protection: Mass storage structures; Disk structure; Disk attachment;	L1,L2,L3	CO5
	2	INTERNAL ASSISMENT 2	L1,L2,L3	CO5
	3	INTERNAL ASSISMENT 2	L1,L2,L3	CO5
	4	INTERNAL ASSISMENT 2	L1,L2,L3	CO5
13	1	Disk scheduling	L1,L2,L3	CO5
	2	Disk management	L1,L2,L3	CO5
	3	Swap space management.	L1,L2,L3	CO5
	4	Protection: Goals of protection,	L1,L2,L3	CO5
4	1	Principles of protection, Domain of protection	L1,L2,L3	CO5
	2	Access matrix, Implementation of access matrix	L1,L2,L3	CO5

LESSON PLAN

	3	Access control, Revocation of access rights,	L1,L2,L3	CO5
	4	Capability- Based systems.		
15	1	Case Study: The Linux Operating System: Linux history; Design principles	L1,L2,L3	CO5
	2	Kernel modules; Process management;	L1,L2,L3	CO5
	3	INTERNAL ASSISMENT 3	L1,L2,L3	CO5
	4	INTERNAL ASSISMENT 3	L1,L2,L3	CO5
16	1	Scheduling; Memory Management; File systems.	L1,L2,L3	CO5
	2	Input and output; Inter-process communication.	L1,L2,L3	CO5
	3	Problems	L1,L2,L3	CO5

### **Text Books:**

1. Abraham Silberschatz, Peter Baer Galvin, Greg Gagne, Operating System Principles 7th edition, Wiley-India, 2006

### **Reference Books:**

- 1. Ann McHoes Ida M Fylnn, Understanding Operating System, Cengage Learning, 6th Edition
- D.M Dhamdhere, Operating Systems: A Concept Based Approach 3rd Ed, McGraw-Hill, 2013.
   P.C.P. Bhatt, An Introduction to Operating Systems: Concepts and Practice 4th Edition PHI (EEE), 2014.
- 4. William Stallings Operating Systems: Internals and Design Principles, 6th Edition, Pearson.

Signature of Faculty

Signature of HOD

## DEPARTMENT OF CSE

SUB: OPERATING SYSTEM SEM: VI SEC: A& B

SUBCODE: 17CS64

## <u>ASSIGNMENT – 1</u>

- 1. Define Operating System. Explain 2 view of Operating system. Explain abstract view of the components of the operating system.
- What network configuration would best suite the following: i) Dormitory Floor ii) University Floor iii) A State iv) A Nation.
- Define the essential Properties of the following types of the system: i) Batch ii) Time Sharing iii) Network iv)Real Time v) Interacting vi) Distributed vii) Parallel viii) Clustered ix) Handheld.

4. Briefly Describe the concept of Storage Management System.

# CITY ENGINEERING COLLEGE DEPARTMENT OF CSE/ISE <u>Assignment 2</u>

## SUBJECT: OPERATING SYSTEM SEMESTER: VI

## SUB CODE:17CS64 SECTION: A & B

Q.no	Questions
1.	Discuss any 4 treading issues that come with multithreaded programs.
2.	Explain the critical section problem. List and explain the requirement to be met by a solution to critical section problem.
3.	Explain Peterson's solution to critical section problem
4.	What are semaphores? Explain any three use cases of semaphores
5.	Explain how it can be used to solve the producer-consumer problem
6.	What are monitors? Explain its usage and implementation.
7.	Describe the monitor solution to the classical dining -philosopher's problem.
8.	What is busy waiting in a critical section concept? How semaphore is used to solve critical section problem? What are the advantages of semaphore?
9.	What are deadlocks? Explain the necessary conditions for its occurrence.
10.	Explain the process of recovery from deadlock.
11.	Using Banker's algorithm. Determine whether the system is in a safe state.
12.	What is Belady's anomaly? Explain with an example.
13.	Discuss paging with an example
14.	Distinguish between: i) Logical address space and physical address space. ii) Internal fragmentation and external fragmentation. iii) Paging and segmentation.
15.	Explain with the help of supporting hardware diagram how the TLB improves the performance of a demand paging system.

# CITY ENGINEERING COLLEGE DEPARTMENT OF CSE/ISE <u>ASSIGNMENT 3</u>

## SUBJECT: OPERATING SYSTEM SEMESTER: VI

# SUB CODE:17CS64 SECTION: A & B

Q.no	Questions		
1.	What is thrashing? How does the system detect thrashing?		
2.	Discuss on the performance of demand paging.		
3.	Explain the various access method of files.		
4.	Explain different approaches to managing free space on disk storage.		
5.	Compare contiguous and linked allocation methods for disk space.		
	Explain the various Disk scheduling algorithms with example.		
	Describe the various directory structures.		
1999 B	Write a note on any four different methods for managing free space.		
	Explain various directory structures		
1000	Explain the various storage mechanisms available to store files, with neat diagram.		

## CITY ENGINEERING COLLEGE DEPARTMENT OF CSE/ISE <u>QUESTION BANK</u>

## SUBJECT: OPERATING SYSTEM SEMESTER: VI

'n

SUB CODE: 17CS64 SECTION: A & B

Q.no	Questions	
1.	Define an operating system. Explain two view points of OS role. Also explain abstract view of the components of a computer system?	
2.a.	What are OS operation? Explain.	
b.	Give a note on Distributed Systems?	
3.	Discuss the operating system functions or services.	
4.	What are the major activities of OS with regards to process and memory Managment?	
5.	What are system calls? Explain different types of system calls?	
6.	Explain the types of multiprocessor systems and the types of clustering.	
7.	Explain different categories of system programs.	
8.	Differentiate between multiprogramming and multi tasking systems.	
9.	Explain the advantages of layered approach with a neat diagram.	
10.	What are virtual machines? Explain its advantages with a neat diagram.	
11.	Explain the just-in-time(JIT) compiler, used in java virtual machine.	
12.	With a diagram of VM-WARE architecture, Explain the concept of virtual machine(VM and main advantages of using VM architecture.	
13.	What is process? With a state diagram, explain states of a process.	
4.a.	Write a note on context switch.	
b.	What is PCB? Enumerate and explain various fields in PCB.	
15.	Explain direct and indirect communication with respect to message passing systems.	
16.	Explain the difference between long term and short term and medium term schedulers.	
17.	Describe implementation of IPC using shared memory and message passing.	

MAG	DT	
MO	DU	LE 2

1			Ques	tions		
1.	What are the d	ifferences betwe	en user level a	nd kernel leve	l threads?	
2.	Discuss comm	on ways of estab	lishing relation	shin between	a unedus?	
3.	Discuss common ways of establishing relationship between user and kernel thread. Differentiate between 1.process and thread 2.short term and medium term scheduler 3.user level and kernel level threads 4.waiting and turnaround time				user and kernel thread.	
4.	Define the five scheduling criteria considered in Process scheduling					
5.	Discuss any 4 tr	reading issues the	teria consider	ed in Proces	s scheduling	
6,	Consider the fol in milliseconds	reading issues the llowing set of pro	at come with n	nultithreaded particulation in the length of	programs. of the CPU burst time is giv	
	Process	Arrival time	Burst time	priority	7	
	p1	0	10	3	-	
	p2	0	1	1		
	p3	3	2	3	-	
	p4	5	1	4	-	
	p5	10		1.1.1		
	Draw gantt chart emptive priority priority=4.also ca algorithms	s illustrating the	5 execution of th ithm. assume h waiting time a	2 nese processes nighest priorit; nd average tur	s using FCFS and pre- y=1 and lowest in around time of both the	
	priority=4.also ca algorithms. Following is the s	s illustrating the scheduling algor alculate average	execution of th ithm. assume h waiting time an	iese processes	s using FCFS and pre- y=1 and lowest in around time of both the	
	priority=4.also ca algorithms. Following is the s process	s illustrating the scheduling algor alculate average	execution of th ithm. assume h waiting time an	iese processes	s using FCFS and pre- y=1 and lowest in around time of both the	
	priority=4.also ca algorithms. Following is the s process p1	s illustrating the scheduling algor alculate average	execution of th ithm. assume h waiting time an	nese processes highest priorit	s using FCFS and pre- y=1 and lowest in around time of both the	
	priority=4.also ca algorithms. Following is the s process	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b	execution of th ithm. assume h waiting time an	nese processes highest priorit; nd average tur rrival time	s using FCFS and pre- y=1 and lowest in around time of both the	
	priority=4.also ca algorithms. Following is the s process p1	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10	execution of th ithm. assume h waiting time an	nese processes highest priorit; nd average tur rrival time	s using FCFS and pre- y=1 and lowest in around time of both the	
7.	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07	execution of th ithm. assume h waiting time an urst A	rrival time	y=1 and lowest in around time of both the	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms	rrival time 0 1 2 3 rnaround time	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follo	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al wing set of proce	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms	rrival time 0 1 2 3 rnaround time	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follor process	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms	nese processes highest priorit nd average tur rrival time 0 1 2 3 rnaround time 1 burst time(ir	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follor process p0	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al wing set of proce	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms esses with CPU	nese processes highest priorit nd average tur rrival time 0 1 2 3 rnaround time 1 burst time(ir	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follor process p0 p1	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al wing set of proce arrival	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms esses with CPU Burst	nese processes highest priorit nd average tur rrival time 0 1 2 3 rnaround time 1 burst time(ir	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follo process p0 p1 p2 p2	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al wing set of proce arrival 0 1 2	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms esses with CPU Burst 6	nese processes highest priorit nd average tur rrival time 0 1 2 3 rnaround time 1 burst time(ir	y=1 and lowest in around time of both the e using FCFS,SJF and RR	
7. [[w 8. C	priority=4.also ca algorithms. Following is the s process p1 p2 p3 p4 Draw gantt chart a with time quatum Consider the follor process p0 p1	s illustrating the scheduling algor alculate average snapshot of a cpu CPU b 10 29 03 07 and calculate the 10 scheduling al wing set of proce arrival 0 1 2 3	execution of the ithm. assume he waiting time and urst A waiting and tu gorithms esses with CPU Burst 6 3 1 4	nese processes highest priorit; nd average tur rrival time 0 1 2 3 rnaround time 1 burst time(in time	y=1 and lowest in around time of both the e using FCFS,SJF and RR n m sec)	

Q.no Questions What are deadlocks? Explain the necessary conditions for its occurrence. 1. 2.a. Dead lock exists if a cycle exists. Yes or no. Justify your answer with a suitable example. b. What is Resource Allocation Graph(RAG)? Explain how RAG is very useful in describing deadly embrace (dead lock )by considering your own example For the following resource-allocation graph write the corresponding wait-for graph. 3. 4. Explain the process of recovery from deadlock. 5. Using Banker's algorithm determine whether the system is in a safe state. Consider the following snapshot of a system: 6. Answer the following questions using the Banker's algorithm: i) What is the content of matrix need? ii) Is the system in a safe state? iii) If a request from process P1 arrives for(0,4,2,0) can the request be granted immediately?(10) iv) Is the system in a safe state? System consists of five jobs (J1,J2,J3,J4,J5) and three resources (R1,R2,R3) . Resource 7. type R1 has 10 instances, resource type R2 has 5 instances and R3 has 7 instances. The following snapshot of the system has been taken: Find need matrix and calculate the safe sequence by using Banker's algorithm. Mention the above system is safe or not safe. Using Banker's algorithm determine whether the system is in a safe state. 8. If a request from process P2 arrives for (0 0 2), can the request be granted immediately? 9. Consider the following snapshot of a system.

	Answer the questions using Banker's algorithm. i) What is the content of the matrix need ii) Is the system is safe state? iii) If a request P1 arrives for (1,0,2), can the request be granted immediately?	
10		
11.	Distinguish between internal and external fragmentation.	
12.	Explain with a diagram, how TLB is used to solve the problem of simple paging scheme.	
13.	Discuss paging with an example.	
15.a.	What is Belady's anomaly? Explain with an example.	
b.	Distinguish between: i) Logical address space and physical address space. ii) Internal fragmentation and external fragmentation. iii) Paging and segmentation.	
17.	With a supporting paging hardware, explain in detail concept of paging with an examp for a 32-byte memory with 4-type pages with a process being 16-bytes. How many bit are reserved for page number and page offset in the logical address. Suppose the logical address is 5, calculate the corresponding physical address, after populating memory and page table.	
18.	Given memory partitions of 100K,500K,200K,300K and 600K, apply first fit and best fit algorithm to place 212K,417 K,112 K and 426 K.	
19.	Explain with the help of supporting hardware diagram how the TLB improves the performance of a demand paging system.	
	What are the draw backs of contiguous memory allocation?	
	What is swapping? Does this increase the operating systems overhead? Justify your answer.	

Q.n	Questions
1.	What is thrashing? How does the system detect thrashing?
2.a.	Discuss on the performance of demand paging.
b.	, a demand paging.
3.	. Short notes on: a. Page replacement algorithms b. Steps in handling page fault.
4.	What do you mean by a copy on write? What do you mean by a copy on write? What do you mean by a copy on write?
5.	What do you mean by a copy-on-write? Where is it used? Explain in brief.
1000	Consider the following page reference string 1,2,3,5,2,3,5,7,2,1,2,3,8,6,4,3,2,2,3,6. Assuming there are three memory frames, how many faults would occur in the case of i) LRU ii) Optimal algorithm. Note that initially all frames are empty.
6.	10,11,104,170,73,309,185,245,246,434,458,364 i) Show the reference string assuming page size of 100 words ii) Find page fault rate for the above reference string assuming 200 words of primary memory available and FIFO and LRU replacement elements.
7.	Explain briefly the various operations performed on files.
8.	Explain the various access method of files.
9.	. Explain various allocation methods in implementing file systems.
10.	Explain different approaches to managing free space on disk storage.
1.	Describe the various directory structures
2.a.	With supporting diagrams distinguish between single-level and two-level directory structure.
).	Compare contiguous and linked allocation methods for disk space.
2.	Explain bit vector free-space management technique
3.	Explain various file protection mechanisms.

#### Q.no Questions Explain the various Disk scheduling algorithms with example. 1. 2.a. Point out and explain briefly the problems with RAID Explain Access Matrix method of system protection. b. What is disk scheduling? Explain the following with diagram: i) FCFS ii) SSTF iii) 3. SCAN. 4. What is an access matrix? Explain the following operations in access matrix with an example for each: i) Copy ii) Transfer iii) Limited copy Suppose the position of cylinder is at 53. The disk drive has cylinders numbered from 0-5. 199. The queue of pending requests in FIFO order is: 98,183,37,122,14,124,65,67. Starting from the current head position, what is the total distance travelled (in cylinders) by the disk arm to satisfy the requests using algorithms FCFS, SSTF, SCAN and LOOK. Illustrate with figures in each case. Describe the access matrix model used for protection purpose. 6. What are boot block and bad blocks? Explain. 7.a. Explain the goals and principles of protection. b. Explain the difference between protection and security? Describe the scheme of 8. capability lists to implement protection Write short notes on: i) Swap space management ii) Revocation of access rights. 9. A drive has 5000 cylinders numbered 0 to 4999. The drive is currently serving a request 10. at 143 and previously serviced a request at 125. The queue of pending requests in FIFO order is : 86, 1470, 913, 1774, 948, 1509, 1022, 1750, 130 starting from current head position, what is total distance travelled(in cylinders) by disk arm to satisfy the requests using FCFS,SSTF,SCAN and look algorithms. 11. Explain SCAN and C-SCAN disk scheduling. Explain the various components of a Linux system. 12.a. Explain process scheduling in a Linux system. b. Explain file systems implementation in Linux. C. 13. Discuss how memory management is dealt with in Linux operating system. 14. Write short note on: a) process management in Linux. b) Linux files system. c) Benefits of multi- threading. d) Inter-process communication. Write a short note on Linux virtual memory system. 15. Write short notes on: a. Linux history b. Components of a Linux system. 16. Explain the Linux device drive block structure. 17. What are the design principles of Linux operating systems? Explain 18.

# CITY ENGINEERING COLLEGE DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

# SUBJECT: OPERATING SYSTEMS

## SUBJECT CODE:18CS43

## **Quiz Questions** Module 1

1. What is operating system?

a) collection of programs that manages hardware resources

b) system service provider to the application programs

c) link to interface the hardware and application programs

d) all of the mentioned

#### Answer:d

2. To access the services of operating system, the interface is provided by the

a) System calls

b) API

c) Library

d) Assembly instructions

#### Answer:a

3. Which one of the following is not true?

a) kernel is the program that constitutes the central core of the operating system

b) kernel is the first part of operating system to load into memory during booting

c) kernel is made of various modules which can not be loaded in running operating system

d) kernel remains in the memory during the entire computer session

#### Answer:c

4. Which one of the following error will be handle by the operating system?

a) power failure

b) lack of paper in printer

c) connection failure in the network

d) all of the mentioned

#### Answer:d

5. What is the main function of the command interpreter?

a) to get and execute the next user-specified command

b) to provide the interface between the API and application program

c) to handle the files in operating system

d) none of the mentioned

### Answer:a

6. By operating system, the resource management can be done via a) time division multiplexing

b) space division multiplexing

c) time and space division multiplexing

d) none of the mentioned

#### Answer:c

7. If a process fails, most operating system write the error information to a _

a) log file

b) another running process

c) new file

d) none of the mentioned

#### Answer:a

8. In operating system, each process has its own _

a) address space and global variables

b) open files

c) pending alarms, signals and signal handlers

d) all of the mentioned

#### Answer:d

9. In Unix, Which system call creates the new process?

- a) fork
- b) create
- c) new
- d) none of the mentioned

### Answer:a

10. A process can be terminated due to ____ a) normal exit

- b) fatal error
- c) killed by another process
- d) all of the mentioned

#### Answer:d

11. What is the ready state of a process?

a) when process is scheduled to run after some execution

b) when process is unable to run until some task has been completed

c) when process is using the CPU d) none of the mentioned

#### Answer:a

12. A set of processes is deadlock if ____

a) each process is blocked and will remain so forever

b) each process is terminated

c) all processes are trying to kill each other

d) none of the mentioned

#### Answer:a

13. A process stack does not contain

a) Function parameters

b) Local variables

c) Return addresses

d) PID of child process

### Answer:d

14. Which system call returns the process identifier of a terminated child?

- b) exit
- c) fork
- d) get

## Answer:a

15. A Process Control Block(PCB) does not contain which of the following?

b) Stack

c) Bootstrap program

## d) Data

### Answer:c

16. The number of processes completed per unit time is known as

a) Output

- b) Throughput
- c) Efficiency
- d) Capacity

#### Answer:b

17. The state of a process is defined by _

a) the final activity of the process

b) the activity just executed by the process

c) the activity to next be executed by the process

d) the current activity of the process

#### Answer:d

18. Which of the following is not the state of a process?

a) New

b) Old

c) Waiting

d) Running

### Answer:b

19. What is the degree of multiprogramming?

a) the number of processes executed per unit time

b) the number of processes in the ready queue

c) the number of processes in the I/O queue

d) the number of processes in memory

#### Answer:d

20. What will happen when a process terminates?

a) It is removed from all queues

b) It is removed from all, but the job queue

c) Its process control block is de-allocated

d) Its process control block is never de-allocated

## Answer:a

21. What is a long-term scheduler?

a) It selects which process has to be brought into the ready queue

b) It selects which process has to be executed next and allocates CPU

c) It selects which process to remove from memory by swapping d) None of the mentioned

### Answer:a

22. If all processes I/O bound, the ready queue will almost always be _____ and the Short term Scheduler will have a _____ to do.

a) full, little

b) full, lot

c) empty, little

d) empty, lot

#### Answer:c

23. The primary distinction between the short term scheduler and the long term scheduler is

a) The length of their queues

b) The type of processes they schedule

c) The frequency of their execution

d) None of the mentioned

#### Answer:c

24. The context of a process in the PCB of a process does not contain _____

a) the value of the CPU registers

b) the process state

c) memory-management information

d) context switch time

### Answer:d

25. Round robin scheduling falls under the category of ____

a) Non-preemptive scheduling

b) Preemptive scheduling

c) All of the mentioned

d) None of the mentioned

#### Answer:b

26. The strategy of making processes that are logically runnable to be temporarily suspended is

- a) Non preemptive scheduling b) Preemptive scheduling
- c) Shortest job first
- d) First come First served

#### Answer:b

22. Which is the most optimal scheduling algorithm? a) FCFS - First come First served b) SJF - Shortest Job First c) RR - Round Robin d) None of the mentioned

#### Answer:b

27. Consider the following set of processes, the length of the CPU burst time given in milliseconds.

Process	Burst time	
P1	6	
P2	8	
P3	7	
P4	3	

Assuming the above process being scheduled with the SJF scheduling algorithm.

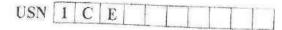
a) The waiting time for process P1 is 3ms

b) The waiting time for process P1 is 0ms

c) The waiting time for process P1 is 16ms

d) The waiting time for process P1 is 9ms

#### Answer:a



Kanakapura Road, Doddakallasandra, Bengalura - 560062

### FIRST INTERNAL TEST

Programme: CSE Course Name: OPER ATING SYSTEMS Sem:VI(A,B) MAX MARKS: 50

Date: 17/03/2020 Time: 2:30-4:00PM Duration: 1 %Hrs

Note: Answer any FIVE questions choosing at least ONE from each Part.

			CO'S	BT'S
-	Part - A			
1.	Explain the role of operating system from different viewpoints. Explain dual mode operation of an operating system.	10	CO1	BT1
-				
2.	Demonstrate the operations of process creation and process termination in UNIX.	10	CO1	BT1
	Part – B		1	
3.	Briefly describe the process of Storage Management in detail	10	CO1, CO3	BT2,BT3
-	Or		1-170703	
4.	Write short notes on : i) Single processor system ii) Multiprocessor system iii)Clustered systems	10	CO1, CO3	BT2,BT3
	Part-C		1	
5.	Illustrate with a neat sketch, the process states and process control block.	10	CO2	BT3
-	Or			015
6.	Define System Calls. With example, Explain different categories of system calls.	10	CO2	BT3
-	Part-D			
7.	Describe the implementation of IPC using shared memory and message passing	10	CO1, CO2	BT3
-	<u>Or</u>			
3.	List the different services that an operating system provides.	10	CO1, CO2	BT3
	Part-E			·····
•	Discuss the threading issues that come with multithreaded program.	10	CO1, CO2	BT2,BT3
1	Or		004	
0	Discuss the benefits of multithreaded programming, Explain different threading models with neat diagram.	10	CO2	BT2,BT3

Blooms Taxonomy Levels (BTL): BT2- Understanding BT4 - Analyzing

Course Outcomes (CO's):

- CO1: Demonstrate need for OS and different types of OS
- CO2: Apply suitable techniques for management of different resources
- CO3: Use processor, memory, storage and file system commands
- CO4: Realize the different concepts of OS in platform of usage through case studies

CITY ENGINEERIN COLLEGE DEPARTMENT OF ..... CSE SCHEME FOR VALUATION Semester & Section: I 'A' & 'B' Internal Test _____ Date: 17-03-2020 Details of the Answer Marks Total-Distribution Marks 8. Services provided by the OS 1. Vser ontespace 2. command there Interface (CLI) Batch onterface Graphical User Interface (GUE). * program Execution IOM 10m Ilo operation file systèm manipulation ¥ communication * * Emor detection Resource Allocation. × Accounting * protection and Security Threading Issues 9. 1) forkel) and Exec() system call Cervellation LOM Signal handling 4) Threads Pool 5) Thread - Specific data 6) Schedular activation

Depails of the Distribution Marks Benefite of Multi Threading 10. 1. Responsiveness 2. Lesource sharing. 3. Economy 4. Utilization of Multiprocessor Archilichires SM Threading Models 1. Many - to - one one-to-one 10M d. 3 - Many - to - Many Ş Ş \$ \$ 50 5 5M R  $(\mathbf{R})$ 

CITY ENGINEERIN COLLEGE DEPARTMENT OF ..... CSE SCHEME FOR VALUATION Internal Test _ I ↓ 'B' Semester & Section: 🗹 ໍ A' Date: 17 - 03-2020 Question Details of the Answer Marks No Total Distribution Marks 5. new Inited Exit Ferminated Intern Related ninning Scheduler 5M dispatch Ilo Tlo waiting IOM Process Control Block Process state number counter 5m regista menony limit open files : Systèm calle poovides interfaces to the services made available 6. by an 05 HO

0

Details of the Answe Distribution Marks 1) process control 2) File management 3) Device Management A) Information Maintainance SM 5) communication (User application 10m open User Mode 5m System call interface Keinel open() Mode open() 0 system call Selum 7. Ipc mechanisms 1. shared memory 5m 2. neering preeing Process A process A M shared PROCEY B [M lom proces B 5M 2 ۱ keenel [m] Keenel

**CITY ENGINEERIN COLLEGE** DEPARTMENT OF ... CSE SCHEME FOR VALUATION Internal Test I_ 'A' & 'B' Semester & Section: VI Date: 17-03-2020 Question No: Details of the Answer. Marks Total Distribution Marks Different view of DS 1. User View * Ease of use * Resource utilization 5m compromise bln ondividualusuability × System View Resource allocator * * control program Dual mode of objection lom User process sehim from System calls system Uner process calls Exempine mpmodebit=0 medbif=1 Execute system calls kemel 5M Transition from User to kernel Mode. HIC

Details of the An 2. Operation of process creation and Process fermination in UNIX Process creation > parent Executes concurrently with its children > pacent waits till child terminates 5M program Proceer Termination -> The child had Exceeded its neuroge of 10 M resources -> Taste assigned to child 1x over 5m -> If parent Exist, os does not 0 allow other process to continue there Execution 3. i). File-systems management ii) Mares - Storage Management 10 M iii) (aching iv) Ilo system. 4. i) Single processor system 3M ii) Multiprovelor system IOM An creased Throughput *) Fromomy of Scale iii) Increased re liability 4 M iii) clustered system 3M

13-54	-	ATTENDANCE														
CI			10/2	11/2	12/2	13	2 17/2	18/2	-19/2	20/2	29/2	25/2	27/2	023	33	q12
SI. No.	Reg.No.	Name ,	E	VII	II	I	I	T		T	T	TE	T	T	TH	12
	and approve	and a second	1	2	3	4	5	6	7	8	9	10	11	12	13	14
1	ICEI705003	Авнізнек · в	l	2	3	4	5	6	7	8	9	9	10	10	10	10
2	ICE 17 ( 5004		1	2	3	4	5	6	7	8	9	10	11	12	12	12
3	06		0	1	2	3	4	5	6	7	8	8	9	٩	9	10
4	07		1	2	3	4	5	6	7	7	8	9	10	11	12	13
5	08		1	2	3	4	5	6	7	8	9	9	10	11	12	13
6	09		1	2	3	4	5	6	7	7	8	9	10	10	10	10
7	013	Anusha	1.	2	3	4	5	6	7	8	9	10	11	12	13	14
8	015	Anushree K.R	1	2	3	4	5	6	7	8	9	9	10	11	12	12
9	016	and the second	1	2	3	4	5	6	3	8	9	10	11	12	17	12
10	018	Arvind Kumar. G	1	2	3	4	5	6	7	8	9	10	11	12	13	14
11	022		1	2	2	3	4	5	6	7	8	9	10	11	12	13
12	023	a second s	D	1	2	3	4	5	6	7	8	9	10	11	12	13
13	024	Rhuvaneshwazi · M	1	2	3	4	5	6	7	8	9	10	1)	12	13	14
14	029	Deetshark	1	2	3	4	5	6	7	8	9	10	11	12	13	14
15	032	Dikshita Jain	1.	2	2	3	4	5	6	7	8	9	10	11	12	II
16	0.33	Eesanna. T	1	2	3	4	5	6	7	8	9	9	10	11	11	12
17	035	Gayathai, B	1	2	3	4	5	6	7	8	9	0)	11	12	13	14
18	036	10	1	2	3	4	5	6	7	8	9	ID	11	12	13	14
19	037	1	0	1	2	3	4	5	6	7	8	9	(0)	11	12	13
20	0.38	H. Pawan kumas	1	2	3	4	5	6	7	8	9	10	11	12	12	13
21	041	Hasshitha.L	1	2	3	3	4	5	6	7	8	9	10	11	-	
22		Hitha · S	1	2	3	4		6	7	8	2	10		12		13
23	and the second se	Jahnavi · B	1	2	3	ч	5	6	7	8	9	9	10			13
24	the second se	Jasir Ahmad	1	2	3	4	5	6	Z	8	9	10				12
25		k. Mallikasjun	1	2	3	4	5	6	7	8	9	9				12
1922	No. of Abs.	. 0						_	T							
	Initials		4	4	4	4	9	4	4	4	4	4	4	4	5	h.

" OPERATING SYSTEM - 170564 " A SEC



### ATTENDANCE

			T	F	F			_	14							
1			10/2	· · ·		13/2	17/2	18/2	19/2	20/2	24/2	10/2	22/-	2/3	330	13
SI.	Reg.No.		I	VI	T	T		1	THE IS		T	TY	T	/	E .	2
No.			1	2	3	4	5	6	7	8	9	10	11	12	13	14
26	ICFITCS047	K. Pavithra	1	2	3	4	5	6	+	8	9	10	11	12	13	13
27	048		1	2	З	3	4	5	6	7	8	9	ID	11	12	13
28	049		1	2	3	4	5	6	7	8	9	10	10	11	12	13
29	050	Karyashree · S.B	0		2	3	4	5	6	7	8	9	10	11	12	13
30	0.52		1	2	3	4	5	6	7	8	9	10	11	12	13	14
31	054		0	1	2	3	4	5	6	7	8	9	10	11	11	12
32	058		1.	2	3	4	5	6	7	7	8	8	9	10	11	12
33	059	1	D	1	2	3	Ч	5	6	7	8	9	10	11	12	13
34	062	Mohammed Ali Baig	1	2	3	4	5	6	7	8	9	10	11	12	12	13
35		Mohammad Faidal	1	2	3	4	5	6	7	8	8	9	10	11	11	12
36	064		1	2	3	4	5	6	7	8	9	9	10	17 -	12	13
37	065		1	2	3	4	5	6	7	8	9	9	10	()	12	13
38	066	Monika R	1	2	3	4	5	6	7	8	9	10	11	12	13	14
39	067		1	2	3	4	5	6	7	8	9	10	10	11	12	13
40	068		D	1	2	3	4	5	6_	7	8	9	0)	11	12	13
41	074		1	2	3	4	5	6	7	8	9	10	11	12	13	14
42	075		11	2	3	4	5	6	7	8	.9	10	11	12	13	13
43	080	THE PARTY AND A REPORT OF A DATA OF	0	1	2	3	4	5	6	7	8	9	10	10	10	10
44	094		1	2	3	4	5	6	7	8	8	9	10	10	10	10
45	097		1	2	3	4	5	6	7	8	9	9	10	11	12	13
46		Shantha Kunga: M.V.	T	2	3	ÿ	5	6	7	8	9	10	11	12	13	1.4
47	130	the second se	1,	2	3	4	4	5	6	7	8	9	ID	11	12	13
48	146	Vishal Kunnas,	1	2	3		4	5	6	7	8	9	10	11	1	11
49		Vasavi . D. g	1	2		4		6	7	8	9	9	10	10	10	11
50		Ababishek · P.V	1,	2	3		5	6	7	8	9	10	11	12	12	12
	No. of Abs.	1. J.	+	1	1		T		L	-						
1.1.1	Initials		٨.	0.	10.	0.	T.	I.	9	14	17	4	4	14	14	8

# ATTENDANCE

		ATTEND		-	-	-	-									
_	-		10/2		12/2	13/2	Ala	18/2	19/2	20/2	2410	26/2	22/2	2/3	23	43
SI.	Reg.No.	Name	I	VI	TIL	II	TI	13	E I		I	-	-	R		N
No.	Rogino		1	2	3	4	5	6	7	8	9	10	11	12	13	14
		the standard Beared	0	1	2	3	4	-	-	-	8	8	9	10	10	10
51	1CE16 CS006	Allam Nagendra Prasad	1	2	3	4	5	5	6.	7	9	10	11	11	11	12
52	25	Chethan B.G	1	2	3	4	5	6	7	8	9	9	10		11	12
53	25	Chethan . B.G	1,	2	3	4	5	1-	7	8	1	10	-	12	13	1,4
54	41			-	3	<u> </u>	-	6	7	8	9	-	10	11	12	12
55	52	Mohammed Bushan	1	2	-	4	5	6	7	8	9	9	10	11	12	13
56	74	Rakshitha B	1	2	3	4	5	6	7	8	9	10	10	-	12	
57	79	Reenea R. Khaswi	1	R	.3		5	6	7	8	9	9	-	1.	12	-
58	81		1	2	3	4	5	6	7	8	9	10	-	11	-	
59	97	Sucesh	0	1	2	3	4	5	6	7	8	8	9	10	10	10
60		Mahasudra =	1	2	3	4	5	6	7	8	٩	9	(0)	11	12	
61	093		1	2	3	4	5	6	7	8	9	9	10	10	11	12
62		Roopashree . R. V	1	2.	3	4	5	6	7	8	9	10	11	11	12	12
63		in the second				1.	1				1			-		-
64		No. 2 Martin 1 and Mile		•	1							1			-	-
65	1.1.1.1	The state of the second second	1					1						-	-	-
66	12.33	in the state of the second			1	1		14	1						-	-
67	14.500							1.5							_	
68		Sand States and States	13.8							i de statu					-	-
69			1							1.1		-				
70			30.			40		3		all all			-			
71			1		12	1		1		14-17						
72	1						ine.							1		
73	12000	And the second s			1	12	12									_
74						Sec.				5- 1						
75				1	1.00		1.					1	-			
	No. of Abs.				-		1		-			1				
2.2	Initials		4	4	4	7	4	4	4	G	4	4	12	4	4	4

### CITY ENGINEERING COLLEGE DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING LESSON PLAN 2019-20

### SUBJECT: OPERATING SYSTEMS SUBJECT CODE: 17CS64

FACULTY NAME:DR.Sowmya SEM: VI SEC : A& B

Week	D	ate	Topics Planned
	From	To	
I	10/02/2020	15/02/2020	MODULE 1: Introduction to operating systems, System structures: What operating systems do; Computer System organization; Computer System architecture; Operating System structure; Operating System operations; Process management; Memory management
п	17/02/2020	22/02/2020	Storage management; Protection and Security; Distributed system; Special-purpose systems; Computing environments Operating System Services; User - Operating System interface; System calls; Types of system calls; System programs; Operating system design and implementation
ш	24/02/2020	29/02/2020	Operating System structure; Virtual machines; Operating System generation; System boot. Process Management Process concept; Process scheduling; Operations on processes; Inter process communication
IV	02/03/2020	07/03/2020	MODULE 2: Multi-threaded Programming: Overview; Multithreading models; Thread Libraries; Threading issues. Process Scheduling
v	09/03/2020	14/03/2020	Basic concepts; Scheduling Criteria; Scheduling Algorithms Multiple-processor scheduling; Thread scheduling.
VI	16/03/2020	21/03/2020	FIRST INTERNAL TEST - 16,17,18/03/2020 Process Synchronization: Synchronization: The critica section problem; Peterson's solution;
VII	23/03/2020	28/03/2020	Synchronization hardware; Semaphores; Classical problems of synchronization; Monitors <b>MODULE 3: Deadlocks</b> : Deadlocks; System model; Deadlock characterization;
VIII	30/03/2019	04/04/2020	Methods for handling deadlocks; Deadlock prevention; Deadlock avoidance; Deadlock detection and recovery from deadlock. Memory Management: Memory management strategies:
IX	06/04/2020	11/04/2020	Background; Swapping; Contiguous memory allocation; Paging; Structure of page table; Segmentation. MODULE 4: Virtual Memory Management: Background; Demand paging;

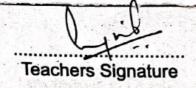


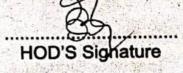
#### CITY ENGINEERING COLLEGE DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING LESSON PLAN 2019-20

#### SUBJECT: OPERATING SYSTEMS SUBJECT CODE: 17CS64

FACULTY NAME: DR.Sowmya SEM: VI SEC: A& B

Veek	Da	ite	Topics Planned
	From	То	
x	13/04/2020	18/04/2020	Copy-on-write; Page replacement; Allocation of frames; Thrashing. File System, <b>Implementation of File System</b> : File system: File concept; Access methods; Directory structure; File system mounting; File sharing; Protection:
XI	20/04/2020	25/04/2020	Implementing File system: File system structure; File system implementation; Directory implementation; Allocation methods; Free space management.
XII	27/04/2020	02/05/2020	SECOND INTERNAL TEST – 28,29,30/04/2020 Secondary Storage Structures, Protection: Mass storage structures;
XIII	04/05/2020	09/05/2020	Disk structure; Disk attachment; Disk scheduling; Disk management; Swap space management. Protection: Goals o protection, Principles of protection, Domain of protection Access matrix, Implementation of access matrix,
XIV	11/05/2020	16/05/2020	Access control, Revocation of access rights, Capability- Based systems. <b>Case Study</b> : The Linux Operating System: Linux history; Design principles;
XV	18/05/2020	23/05/2020	Kernel modules; Process management; Scheduling; Memory Management; THIRD INTERNAL TEST -20,21,22/05/2020
XVI	25/05/2020	30/05/2020	File systems, Input and output
XVII	01/06/2020	06/06/2020	CASE STUDY : Operating Systems





Scanned with OKEN Scanner

# RECORD OF CLASS WORK

Date	Period	Topics Covered
10/2/2020	I	MODULEI : Introduction to operating system
		system shullyres: what operating
11/2/2020	The	Système do:
	VII	computer System Organization
12/2/2020	<u> </u>	computer System architecture
13/2/2020	I	Operating System Structure
17/2/2020	II	operating System operations
18/2/2020	VII	Process Management,
19/2/2020	<u> </u>	Memory Management, Storage Management
20/2/2020	TT	Protection and Security Dishibuted Systems
24/2/2020	<u> </u>	Special puspose systems computing
26/2/2020	IV	Environments, operating System Seenices
27/2/2020	TI-	Operating System Services
		User-operating system Interface
		System calle; Types of system calle
2/3/2020	I.	System program &: operating Systems
		design and implementation
		operating system smultire
3/3/2020	IV	Vistual machines operating Sylinigeneration
Section States		System boot proces Management
4/3/2020	TV_	PROCESS creation process Scheduling
		Context Switch, PCB process Termination
5/3/2020	I	P.P. message - passing systems, Buffering
	I	Sockete, Reniete procedure calls
 Tea	chers Signature	HOD'S Signature

# **RECORD OF CLASS WORK**

Date	eriod	Topics Covered
6/3/2020	Ţ	MODULE 2: MULTI-THREADED PROGRAMMING
913/2020	Ш	Overview Multithreading Modele Thread Libraries: Pthread, WIN, Tava
11/3/2020	I	Thread James, process Scheduling
		Baric concepti, Scheduling interio
		Multiple - proceeser scheduling.
		Thread scheduling proces supernonization: The critical
		section problem, peterson's solution
		Synchronization Hardware Semaphores,
		Claeural problems of Synchronization Morallons
		Monitors
		e de la companya de la

Teachers Signature

HOD'S Signature

O Scanned with OKEN Scanner



#### **DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING**

### CIRCULAR

#### Ref. No: CEC/CSE/DAC/2019-2020/01

Date: 17/01/2019

All the members of Department Advisory Committee are informed to attend a meeting which will be held as follows

Date: 20/07/2019 Time: 3:00 PM Venue: LAB C104

Agenda:

- Seventh Sem Internship and Project related
- Innovation in Teaching Methods
- Conduction of student development programme

HOD

Dept of Computer Science & Engineering CITY ENGINEELTING COLLECT Deddakallosandru of Academputa Road Bangalore 560061



#### DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

### **Department Advisory Committee Meeting**

Date: 20-07-2019 Time: 03:00 PM

#### **DAC Members Present:**

S1. No	Member Name	Designation	Role	Sign
1	Mr. Vívekavardhana Reddy	HOD	Convenor	S
2	Dr. Nandakumar A N	Professor	Member	al
3	Dr. Sowmya Naik P T	Professor	Co-Convenor	A
4	Mr. Deepak N R	Assistant Professor	Member	But
5	Mr. Girish G A	Assistant Professor	Member	a.
6	Mrs. Ambika P R	Assistant Professor	Member	due
7	Mrs. Laxmi M C	Assistant Professor	Member	Kun
8	Mrs. Archana Bhat	Assistant Professor	Member	Aur
9	Mr. Vinodh Kumar S	Assistant Professor	Member	S.Vit
10	Mr. Vivekraj G K	Technical Product Manager, Sabre India	Industry Expert	Uge.
11	Mr. Devraj K	Founder & CEO, EtherScale	Alumni	Elev

The Department Advisory Committee meeting was conducted at Department of CSE, on 20th of July 2019, at 03:00 PM.

#### Agenda of the meeting:

- Seventh Sem Internship and Project related
- Innovation in Teaching Methods
- Conduction of student development programme



#### Minutes of meeting:

The following points were discussed in the meeting:

- Mrs. Laxmi M C and Ms. Deepika R will be coordinating the internships for finalyear students, with the evaluation of their work to be completed by the end of September.
- Prof. Sowmya Naik, Mr. Siddaramappa V, and Mr. Girish G A have been designated to oversee the final-year project work.
- The HOD recommended using Google Classroom for faculty members to approve students' synopses, presentations, and reports, as well as to conduct online tests and share study materials.
- Mr. Vivekaraj suggested conducting training on cloud computing and soft skills to third- and fourth-year students to keep them updated with industry advancements.



cc to Principal

	I Sem B. E. / B. Tech. / B. Arch. (Tentative)	III, V & VII Sem B. E. /B. Tech. III, V,VII & IX Sem B. Arch.	III & V Sem MCA	III Sem MBA	III Sem M. Tech.	III Sem M. Arch.
Commencement of ODD Semester	01.08.2019	29.07.2019	29.07.2019	08.08.2019	26.08.2019	08.09.2019
Last Working day of ODD Semester	29.11.2019	30.11.2019	30.11.2019	05.12.2019	23.12.2019	06.01.2020
Practical Examinations	03.12.2019 To 13.12.2019	03.12.2019 To 13.12.2019	03.12.2019 To 07.12.2019			-
Theory Examinations	16.12.2019 To 04.01.2020	16.12.2019 To 07.02.2020	09.12.2019 To 28.12.2019	09.12.2019 To 04.01.2020	27.12.2019 To 10.01.2020	08.01.2020 To 22.01.2020
nternship Viva-Voce	-	-	-	-	12.01.2020 To 19.01.2020	
Professional training Organization study	-	-	•	-	-	-
Commencement of EVEN Semester	27.01.2020	10.02.2020	27.01.2020	27.01.2020	27.01.2020	01.02.2020

# Academic Calendar of VTU, Belagavi for ODD Semester of 2019-2020 (Jul 2019 - Jan 2020)

NOTE

- VII Semester B. E / B. Tech students shall have to undergo Internship for a period of four Weeks.
- I Semester B. E/B. Tech / B. Arch Students shall compulsorily undergo Induction Program for a period of 3 Weeks (two phases) as per the schedule given by VTU. First phase 11 days in first semester and second phase 10 days in second semester.
- 1. College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notified separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.
- 3. If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day.
- 4. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTRAR 28/c/19

1.52	· · · Δ!	UGUST 2019	Des autor	SEPTEMBER 2019	2. 1. 28	OCTOBER 2019		NOVEMBER 2019	DE	CEMBER 2019
DAY	Date	EVENT STAR	Date	STREAM STREAM	Date	ALCON OF EVENT	Date	WALLARD EVENT SALVIN	(Date)	1 GALVENIES
and the	A DTING	OF HIGHER SEMESTERS	South Males	The state of the s	1	245.0-95.00.0077095943458005215292	THE LOC	12) Martin Stratter with the Construction	-	1201042003204000000020
		Semesters 29.7.2019 MON)		and the second	2	GANDHI JAYANTI(DH)	初始推荐		-	Carl Million State
THU	1 - 1 - 1	STARTING OF FIRST SEM			3	292	1.9448	和 经生	1	and type and the set
FRI	2	STATUTO OF THE COM	1 W.L. 201-	- internet and the second s	4		1412-0	KANNADA RAJYOTSAVA(DH)	23/200	
SAT	3		1.52.451		5		12213	Semantic a State of the	27.52	
SUN	4 4	0. 258	.1	1 - Martin Martin - Ch	6	MITTER MARKENART	3	CONTRACTOR AND	1	Service Street Service
MON	5	20 CR. O.	-1.4 ⁻¹ .2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		1941.21 11	a negative law
TUE	. 6	And the second second second	3	FIRST INTERNAL	18	VIJAYA DASHAMI(DH)	115-11	SECOND CIE FOR	- 3	
NED	7	FIRST SEM INDUCTION	· 4.	ASSESSMENT	9		6.2	FIRST SEM.	1.4.	1.0000000000000000000000000000000000000
THU	8	Contractor of Academic State	5 × 5 + 1*	3rd, 5th & 7th Semesters	10	the second second second	Same?		1-5-1	
FRI	9	and a second	6		11		1. B.		1	Contraction (State
SAT	10	2ND SATURDAY HOLIDAY	7	the second s	12	2ND SATURDAY HOLIDAY	9 1	2ND SATURDAY HOLIDAY	71	Y
SUN	11	a de tracer de las deserredas	-8	a a chanaicean an a ch	13	werden in weekendere en	. 10 .	a the second and the second	8	al states in the second
MON	12	BAKRID(DH)	9.00	and the second secon	14	and the second second second second second second	bir t		2:9	and the court in the
TUE	13	2000年月一天 安吉 日日	**10 ^{***}	MOHARAM (DH)	15		37723-		5 10 TE	THIRD CIE FOR
NED	14-1	网络马马克马马马马 医中心	11		16	1 b d	13	Contract of the March State	211	FIRST SEM
THU	15	INDEPENDENCE DAY(DH)	12	and the second second second	1.17	NAME OF A DESCRIPTION OF A	134		12	
FRI	16	网络马马马莱马马马 医外外	13	一 计按数据分子的	18	the way of the second second	15	KANAKA JAYANTHI(DH)	5a13	
SAT	17 %	计算行通过 化二乙酸 化化化	14	2ND SATURDAY HOLIDAY	19	かがきるとうたちしてい	15:5	방법 동물이 가 같은 것이다.	2114	
SUN	18		15	Contraction of the second second	20	A state and a state of the state of the	17	State March State State State	15 .	A CARLES AND A CARLES AND
MON	19	The second sector as the	16		21	2. 公司	18	S 2 PAN A COMPANY	16	a server a
TUE	20	化合成的 医乙烯基 人名	17		22	SECOND INTERNAL	19	THIRD INTERNAL	17	LAB INTERNALS
WED	21	的时候,你就是我们的人。" 这时间,我们还是你的问题。	18		23	ASSESSMENT 3rd,5 th & 7 th Semesters	20	ASSESSMENT 3rd,5th & 7th Semesters	18	FIRST SEM
тни	22	all all a second and a second	19	しんのうたう ちき かまりつ	24	with the set of the set of the	21	The second second second	19	
FRI	23	The second second	20	FIRST CIE FOR	25	12 101 E 19 12 E	22		20	a standard
SAT	24	4TH SATURDAY HOLIDAY	21	FIRST SEM.	26	4TH SATURDAY HOLIDAY	23	4TH SATURDAY HOLIDAY	21	LAST WORKING DAY
SUN	25	THE STREET	22		27		24	a state of the second	. 22	
NON	26	网络拉拉拉 新教师 机	23	and the state of the second	28	医骨骨骨骨骨骨 的复数	25		23	
TUE	27	and the second	24	1 - L Martin and Martin Street	29	DEEPAVALI(DH)	26	and a second of the second	- 24	FIRST SEMESTER
WED	28		25		30	NEERIA	27	LAB INTERNALS FOR	25	VTU PRACTICALS
THU	29		26		31	She	28	3rd, 5th & 7th SEMESTERS	26	23.12.19 TO
RI	30		27			Bungstore 62	29	1. A. S. M	27	03.01.2020 THEORY EXAMS
SAT	31		28	4 TH SATURDAY HOLIDAY	1.1	Figure 5	30	LAST WORKING DAY	28	06.01.2020 TO 28.01.2020
UN	h.R. A. E.	and the state of the state of the	29	and the second second second		. 7	1000	3AD ,STH &7th SEM	29	
ION		and the second s	30	- martine		La de la construir de la const	CALL C	the standers.	30	
UE									31	
1	TU PRA	CTICAL FXAMS: 280 8 CTH CF	MESTER	· 2 12 10 TO 12 12 10 2""CC		6.12.19 TO 14.12.19, VTU THEO		10.382 FM 0.319 CELESTER		0 10 7 2 1010



CITY	ENG	INEERING COLLEGE	DE	PARTMENT OF COMP	UTER	SCIENCE ENGINEERING	A	CADEMIC CALENDAR	2019-	20 (ODD SEM)
	А	UGUST 2019		SEPTEMBER 2019		OCTOBER 2019		NOVEMBER 2019	DE	CEMBER 2019
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
		OF HIGHER SEMESTERS			1					
(3 rd ,5	5 th & 7 th	Semesters 29.7.2019 MON)			2	GANDHI JAYANTI(DH)				
THU	1	STARTING OF FIRST SEM			3					
FRI	2				4		1	KANNADA RAJYOTSAVA(DH)		
SAT	3				5		2			
SUN	4		1		6		3		1	
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		2	
TUE	6		3		8	VIJAYA DASHAMI(DH)	5	SECOND CIE FOR FIRST SEM.	3	
WED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9		6		4	
THU	8		5	3 rd ,5 th & 7 th Semesters	10		7	WORKSHOP	5	
FRI	9		6		11		8		6	
SAT	10	2 ND SATURDAY HOLIDAY	7	INDUSTRIAL VISIT	12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7	
SUN	11		8		13		10		8	
MON	12	BAKRID(DH)	9		14		11		9	
TUE	13		10	MOHARAM (DH)	15		12		10	THIRD CIE FOR FIRST
WED	14		11		16		13		11	SEM
THU	15	INDEPENDENCE DAY(DH)	12		17		14		12	
FRI	16		13		18		15	KANAKA JAYANTHI(DH)	13	
SAT	17		14	2 ND SATURDAY HOLIDAY	19		16		14	
SUN	18		15		20		17		15	
MON	19		16		21		18		16	
TUE	20		17	Technical Activities	22	SECOND INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	19	THIRD INTERNAL ASSESSMENT	17	LAB INTERNALS FOR
WED	21		18		23	5.4,5 w & 7 w Semesters	20	3 rd ,5 th & 7 th Semesters	18	1 st SEMESTERS
THU	22		19		24		21		19	
FRI	23		20	FIRST CIE FOR FIRST SEM.	25		22		20	
SAT	24	4 [™] SATURDAY HOLIDAY	21		26	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	LAST WORKING DAY 1 ST SEM
SUN	25		22		27		24		22	
MON	26	PTM	23		28		25		23	
TUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR	24	VTU PRACTICAL: 1 ST
WED	28		25		30		27	3 rd ,5 th &7 th SEMESTERS	25	SEMESTER: 23.12.19
THU	29		26		31		28		26	TO 3.1.20
FRI	30		27				29	LAST WORKING DAY 1 st SEM	27	THEORY EXAMS : 1 ST SEMESTERS : 6.1.20
SAT	31		28	4 TH SATURDAY HOLIDAY			30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	TO 28.1.2020
SUN			29						29	
MON			30						30	
TUE									31	
VTU PI	RACTICA	L EXAM : 3 RD & 5 TH SEMESTER	: 3.12.19	TO13.12.19,7 TH SEMESTER: 6.12	2.19 TO1	4.12.19, THEORY EXAMS : 3 RD ,5 ^T	^H &7 TH SI	EMESTERS : 16.12.19 TO 7.2.20	020	



# ACADEMIC YEAR : 2019 - 20'

### DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

COURSE PREFERNCE

Name of the Faculty: Mas. Mala P

Designation: A.P

Year / Semester:

SI.No	Course Code and Name	Year/Semester
1.	18 CS 35 - SE	2nd 3rd
2,	17 cs52 - CN	3 sid 15th
3.	150871 - Web	4th 17th
	4	
•		

Signature of faculty



# ACADEMIC YEAR: 2019-20 (oold)

### DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

### COURSE PREFERNCE

Name of the Faculty: Vivekavaedhana Reddy

Designation: - Asst. Professor

Year / Semester:

SI.No	Course Code and N	ame	Year/Se	emester
1.1	180932 - DS		2nd (31	d :
2.	15 (SA) - Web		dith/7	th .
3'	170352- CN	· · ·	320 15	fth.
3		2		+
				¥
1.	¹² I			· · · · · · · · ·

Signature of faculty



### ACADEMIC YEAR: 2019 - 2020(Odd)

# DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

### COURSE ALLOCATION

SI.No	Name of the Faculty	Course Code and Name	Year/ Semester	Signature
1	Mrs. Sowmya Naik	15CS73 – Information and Network Security 17CS551 - Artificial Intelligence	$4^{th} / 7^{th}$ $3^{rd} / 5^{th}$	lib
2	Dr. Nandakumar A N	15CS754 – Storage Area Network	4 th / 7 th	Nh
3	Mr. Vivekavardhana Reddy	18CS32 – Data Structure and Its Application 18CSL38 – Data Structure Lab	2 nd / 3 rd	3
4	Mr. Deepak N R	18CS33 – Analog and Digital Electronics	2 nd / 3 rd	Dit
5	Mr. Nandish A. C	17CS53 – Database Management System 17CSL58 – DBMS Lab	3 rd / 5 th	18
6	Mr. Girish G A	15CS72 – Advanced Computer Architecture	4 th / 7 th	Di
7	Mr. Surendranath Gowda	15CS71 – Web Technologies 15CSL77 – Web Technologies Lab	4 th / 7 th 4 th / 7 th	Swiendaa
8	Mr. Vinod Kumar	17CS551 – Object Oriented Modelling and Design	3 rd / 5 th	S. Ilas
9	Mr. Siddaramappa V	18CS35 - Software Engineering 15CS73 - Machine Learning 15CSL76 - Machine Learning Lab	2 nd / 3 rd 4 th / 7 th 4 th / 7 th	Stolv.



10		15CS73 - Information and	4 th / 7 th	
	Mrs. Ambika P R	Network Security 18CS34 – Computer Organization		d
11	Mrs. Laxmi M C	17CS54 – Automata Theory and Computation 15CS71 – Web Technologies 15CSL76 – Machine Learning Lab	3 rd / 5 th 4 th / 7 th 4 th / 7 th	due.
12	Ms. Savitri Kulkarni	18CS32 – Data Structure and Its Application 18CSL38 – Data Structure Lab	2 nd / 3 rd	St
13	Mr. B. Ramesh	17CS51 - Management & Entrepreneurship 18CPS13 - Problem solving using C	$3^{rd} / 5^{th}$ $1^{st} / 1^{st}$	Val
14	Mrs. Punitha P	18CS33 – Analog and Digital Electronics	2 nd / 3 rd	Pre
15	Mrs. Archana Bhat	17CS53 – Database Management System 17CSL58 – DBMS Lab 18CS35 – Software Engineering	$3^{rd} / 5^{th}$ $3^{rd} / 5^{th}$ $2^{nd} / 3^{rd}$	Aue
16	Ms. Deepika R	17CS52 – Computer Networks 17CSL57 – Computer Networks Lab	3 rd / 5 th 3 rd / 5 th	De
17	Mrs. Mala P	18CS35 – Software Engineering	2 nd / 3 rd	neitor
18	Mrs. Sriraksha S	17CS551 – Object Oriented Modelling and Design	3 rd / 5 th	Sm
19	Mrs. Manjula S	18CS32 – Data Structure and Its Application 18CSL38 – Data Structure Lab	2 nd / 3 rd	Me
20	Ms. Pushpa	15CS71 – Web Technologies	4 th / 7 th	bulo
21	Mrs. Sreevidya	17CS52 – Computer Networks 17CSL57 – Computer	3 rd / 5 th 3 rd / 5 th	Sort



		Networks Lab		
22	Mrs. Kavyashree Yadav	15CS754 – Storage Area Network	4 th / 7 th	Lyn
23	Ms. Sowbhagya M P	15CSL77 – Web Technologies Lab	4 th / 7 th	Southage





# **CITY ENGINEERING COLLEGE**

### Department Of CSE

Aug - Nov 2019

Time Table for III Sem A Section

Room No: C203

DAY	9:00 - 10:00	10:00-11:00		11:15 - 12:15	12:15-1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
MON	CO	DSA		MATHS	ADE	-			
TUE	DSA	DMS	-	and the second se				A1-ADE/ A2 - DS	S LAB
				MATHS	ADE	ah	CO	SE	Tutorial
WED	SE	CO	Sr.	ADE	DMS	- 2	The second s	A1- DS/ A2 - ADI	
THU	DSA	SE	11	MATHS	DMS	- B			S LAB
FRI	DMS	SE	- 10			ach	ADE	CO	Tutorial
- Contraction			Sh	MATHS	DSA	(III)		EDUSAT/LIBR	ARY
SAT	CPH	DSA		ADE	E/DS LAB		Status participation		

SI.No	Course Code	Course Name	Course	P. L. M
1	18MAT31	Transform Calculus, Fourier Series and Numerical Techniques	MAT-3	Faculty Name Mrs. Gayathri
2	18CS32	Data Structures and Applications	DSA	Mr. Vivekavardhana Reddy
3	18CS33	Analog and Digital Electronics	ADE	Mr. Deepak N R
4	18CS34	Computer Organization	CO	Mrs. Ambika P R
5	18CS35	Software Engineering	SE	
6	18CS36	Discrete Mathematical Structures	DMS	Mr. Siddaramappa Mr. Narendra
7	18CSL37	Analog and Digital Electronics Laboratory	ADE LAB	
8	18CSL38	Data Structures Laboratory	DS LAB	Mr. Deepak/ Mrs. Punitha P Mr. Vivekavardhana Reddy/ Ms. Savitri K
9	18CPC29	Constitution CL P. D. C. L. B. C.	- C DILD	Mil. Viverava dilalia Reudy/ Mis. Savitri K
	1001029	Constitution of India, Professional Ethics and Cyber Law	CIP	Dr. Rajasekhar



Romencelars

Principal

				r	GINEERIN Oepartment Of C Aug – Nov 2019 Table for III Sem B	CSE		R	oom No: C204
DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12:15 -1:15		2:00 - 3:00	3:00 - 4:00	4:00-5:00
MON	MATHS	SE		ADE	DMS		ADE	СО	Tutorial
TUE	DMS	MATHS	res CO DSA res	eak	Contraction of the second s	B1-ADE / B2 - DS	and the second second second		
WED	SE	DSA	Bre	MATHS	ADE	Bre	СО	DSA	Tutorial
THU	ADE	DMS	T	SE	DSA		1	B1-DS / B2 - ADE	
FRI	MATHS	SE	Sho	DMS	СО	Lunch		EDUSAT/ LIBRA	
SAT	ADF	E/DS LAB		СРН	DSA	P		LOCULIT LIDIO	

Sl.No	Course Code	Course Name	Course	Faculty Name
1	18MAT31	Transform Calculus, Fourier Series and Numerical Techniques	MAT-3	Mrs. Gayathri
2	18CS32	Data Structures and Applications	DSA	Mrs. Manjula S
3	18CS33	Analog and Digital Electronics	ADE	Mrs. Punitha P
4	18CS34	Computer Organization	СО	Mrs. Ambika P R
5	18CS35	Software Engineering	SE	Mrs. Mala
6	18CS36	Discrete Mathematical Structures	DMS	Mr. Nagendra
7	18CSL37	Analog and Digital Electronics Laboratory	ADE LAB	Mrs. Punitha P/ Mr. Deepak N R
8	18CSL38	Data Structures Laboratory	DS LAB	Mrs. Manjula S/ Ms. Savitri K
9	18CPC29	Constitution of India, Professional Ethics and Cyber Law	CIP	Dr. Rajasekhar

нор

Principal

				I	CNGINEERI Department Of ( Aug – Nov 2019 Table for V Sem 2	CSE			Room No: C201
DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00-5:00
MON	CN	AI		OOMD	ATC	-	DBMS	MC	
TUE	ME	ATC			ME	Tutorial			
WED	OOMD	CN	Break	DBMS			- CN / A2 - DBN		
THU	CN	ME		AI	ATC		OOMD	ATC	Tutorial
FRI	ME	AI				nch	A2	-CN/A1 - DBN	
SAT		ni Project	Sh	DBMS Min	OOMD ni Project	Lu	Teleford and a second se	EDUSAT/ LIBRA	ARY

17CS51 17CS52 17CS53	Course Name Management and Entrepreneurship Computer Networks and Security	Course ME	Faculty Name Mr. B Ramesh
			MI. D Kamesn
170853		CNS	Mrs. Deepika R
170000	Database Management System	DBMS	Mrs. Archana Bhat
17CS54			Mrs. Laxmi M C
17CS562			Mr. Vinodh Kumar S
17CS5	Artificial Intelligence		Mrs. Sowmya Naik
17CSL57	Computer Network Laboratory		Mrs. Deepika R/ Mrs. Shrividya
17CSL58	DBMS Lab with Mini project	DBMS LAB	
	17CS562 17CS5 17CSL57	17CS562     Object Oriented Modeling and Design       17CS5     Artificial Intelligence       17CSL57     Computer Network Laboratory	17CS54Automata Theory and ComputabilityATC17CS562Object Oriented Modeling and DesignOOMD17CS5Artificial IntelligenceAI17CSL57Computer Network LaboratoryCN LAB17CSL58DPMS Laborative MinimumCN LAB



Principal

Ç			Âuş	INEERING rtment Of CSE g – Nov 2019 e for V Sem B Secti		Ε		Room No: C202
DAY	9:00 - 10:00	10:00 - 11:00	11:15-12:15	12:15 - 1:15	2:00 -	- 3:00	3:00 - 4:00	4:00 - 5:00
MON	OOMD	ME	DBMS	CN		I	31- CN/ B2- DBM	S LAB
TUE	DBMS	AI	OOMD	ATC	ak	ME	CN	Tutorial
WED	AI	ATC	ME	DBMS	Break	Ι	32- CN/ B1- DBM	S LAB
THU	OOMD	DBMS	ME	CN	ch	AI	ATC	Tutorial
FRI	ATC	OOMD	CN	AI	Lunch		EDUSAT/ LIBRA	ARY
SAT	Mini P	Project	Mi	ni Project				
SI.No	Course Code		Course Name		Course	1	Faculty N	lame
1	17CS51	Management and	l Entrepreneurship		ME	Mr. B Ra	umesh	
2	17CS52	Computer Netwo	orks and Security		CNS	Mrs. Shri	ividya	
3	17CS53	Database Manag	ement System		DBMS	Mr. Nand	lish A C	

1	17CS51	Management and Entrepreneurship	ME	Mr. B Ramesh
2	17CS52	Computer Networks and Security	CNS	Mrs. Shrividya
3	17CS53	Database Management System	DBMS	Mr. Nandish A C .
4	17CS54	Automata Theory and Computability	ATC	Mrs. Laxmi M C
5	17CS562	Object Oriented Modeling and Design	OOMD	Mrs. Shriraksha
6	17CS5	Artificial Intelligence	AI	Mrs. Sowmya Naik
7	17CSL57	Computer Network Laboratory	CN LAB	Mrs. Deepika R/ Mrs. Shrividya
8	17CSL58	DBMS Lab with Mini project	DBMS LAB	MR. Nandish A C/ Mrs. Archana Bhat

3

Principal

HOD

Ç				Depa Au	GINEERING artment Of CSE g – Nov 2019 e for VII Sem A Se		LEGE		Room No: C303
DAY	9:00 - 10:00	10:00 - 11:00		11:15 - 12:15	12:15 - 1:15		2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
MON	ACA	WEB		ML	INS				
TUE	A1-ML/A2	- WEB LAB	ak	LAB	ACA	ak	ML	WEB	SAN
WED	SAN	ACA	Break	INS	WEB	Break			1
THU	A2-ML/A1	- WEB LAB	L L	LAB	INS		ACA	SAN	ML
FRI	ML	INS	Short	WEB	SAN	Lunch			
SAT	Projec	t Work		Pro	ject Work		antes antes antes	diana managana	ANN AND STATE OF A CARACTER STATE

Sl.No	Course Code	Course Name	Course	Faculty Name
1	15CS71	Web Technologies	WEB	Ms. Pushpa
2	15CS72	Advanced Computer Architectures	ACA	Mr. Girish G A
3	15CS73	Machine Learning	ML	Mr. Siddaramappa V
4	15CS743	Information and Network Security	INS	Mrs. Sowmya Naik
5	15CS754	Storage Area Network	SAN	Dr. Nandakumar A N
6	15CSL76	Machine Learning Lab	ML Lab	Mrs. Ambika P R/ Mr. Siddaramappa V
7	15CSL77	Web Technologies Laboratory with Mini Project	WEB Lab	Mrs. Sowbhagya/ Mrs. Laxmi M C
8	15CSP78	Project Work - Phase I + Seminar	Project	Mr. Siddaramappa/ Mr. Girish G A

-HOD

Principal

			1	Aug – Nov 2019				Room No: C304
9:00 - 10:00	10:00 - 11:00	1	11:15 - 12:15	12:15 - 1:15	1	2:00 - 3:00	3:00 - 4:00	4:00 - 5:00
B1-ML/	B2 – WEB LAB		LAB	INS		ACA	ML	SAN
ACA	WEB	ak	INS	SAN	ak			10001000000
B2 – ML /	B1 – WEB LAB	Sre	LAB	ACA	Bre	INS	WEB	ML
SAN	INS		WEB	ML				
WEB	ACA	Sho	SAN	ML				
Proj	ect Work		Pro	ject Work		12- 1- 1-1-1-5-640	S A STREET	Sector Property and the sector
A	B1 – ML / ACA B2 – ML / SAN WEB	0:00 - 10:00       10:00 - 11:00         B1 - ML / B2 - WEB LAB         ACA       WEB         B2 - ML / B1 - WEB LAB         SAN       INS	D:00 - 10:00       10:00 - 11:00         B1 - ML / B2 - WEB LAB       WEB         ACA       WEB         B2 - ML / B1 - WEB LAB       MEB         SAN       INS         WEB       ACA	D:00 - 10:00       10:00 - 11:00       11:15 - 12:15         B1 - ML / B2 - WEB LAB       LAB         ACA       WEB         B2 - ML / B1 - WEB LAB       INS         SAN       INS         WEB       ACA         WEB       SAN	Aug – Nov 2019 Time Table for VII Sem B         D:00 – 10:00       10:00 – 11:00       11:15 – 12:15       12:15 – 1:15         B1 – ML / B2 – WEB LAB       LAB       INS         ACA       WEB       INS       SAN         B2 – ML / B1 – WEB LAB       ML       KeB       ML         SAN       INS       SAN       ML         WEB       ACA       WEB       ML	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Aug – Nov 2019 Time Table for VII Sem B Section0:00 – 10:0010:00 – 11:0011:15 – 12:1512:15 – 1:152:00 – 3:003:00 – 4:00B1 – ML / B2 – WEB LABLABINSACAMLACAWEBINSSANINSACAMLB2 – ML / B1 – WEB LABINSSANMLINSWEBSANINSWEBMLINSWEBWEBACAMLINSWEB

Sl.No	Course Code	Course Name	Course	Faculty Name
1	15CS71	Web Technologies	WEB	Mr. Surendranath Gowda
2	15CS72	Advanced Computer Architectures	ACA	Mr. Rakesh R
3	15CS73	Machine Learning	ML	Mrs. Ambika P R
4	15CS743	Information and Network Security	INS	Mrs. Sowmya Naik
5	15CS754	Storage Area Network	SAN	Mrs. KavyaShree Yadav
6	15CSL76	Machine Learning Lab	ML Lab	Mr. Siddaramappa/ Mrs. Laxmi M C
7	15CSL77	Web Technologies Laboratory with Mini Project	WEB Lab	Mrs. Sowbhagya/ Mrs. Deepika R
8	15CSP78	Project Work - Phase I + Seminar	Project	Mr. Siddaramappa/ Mr. Girish G A



Romenelan

Principal

HOD

Sec.				ENGIN					
		Name: Mrs. A	rchana Bhat	~	[ov 2019 [ – B, V – A, ]	В			05/08/2019 t: SE, DBMS
DAY	9:00 - 10:00	10:00 - 11:00	11:00 - 11:15	11:15 - 12:15	12:15 - 1:15	1:15 - 2:00	2:00-3:00	3:00 - 4:00	4:00 - 5:00
MON		III- B		V - B			V - A	DBMS	LAB (B2)
TUE	V-B		ak	V-A		ak	I	BMS LAB	(A2)
WED	III - B		Short Break	V - A	V - B	Bre	I	BMS LAB	(B1)
THU		V - B	L L	III - B		definition of the second secon		(A1)	
FRI		III - B	Sho	V-A		In			aconcosta e i
SAT						F		1	



	[As per Choice ]	SE MANAGEM Based Credit Sys om the academic SEMESTER -	tem (CBCS) scheme] c year 2017-2018)		
Subject Code		17CS53	IA Marks	40	
Number of Lectu	re Hours/Week	4	Exam Marks	60	10 Stander
Total Number of	Lecture Hours	50	Exam Hours	03	ALL STREET
		CREDITS -	04	1.1	CHU ADARS
Module – 1			ristics of database app		Teaching Hours
Advantages of u Overview of Dat and Instances. T languages, and in Modelling using attributes, roles, examples, Special	sing the DBMS abase Languages hree schema arc terfaces, The Data g Entities and	approach, Histor and Architectu chitecture and dubase System env Relationships: nstraints, Weak alization.	ry of database applic res: Data Models, Scl ata independence, da ironment. Conceptua Entity types, Entity entity types, ER dia	ations. hemas, itabase I Data sets,	
Relational Mode and relational dat with constraint v operations, addition of Queries in rela- Design: Relation SQL data definit queries in SQL, Additional feature Textbook 1: Ch4.	tabase schemas, U iolations. Relation onal relational operational algebra. M al Database Desi ion and data type INSERT, DEL	Update operation onal Algebra: Uperations (aggregations (aggregations) apping Conception gn using ER-to- es, specifying conception of the top of top of the top of t	elational Model Cons s, transactions, and d Inary and Binary rela- te, grouping, etc.) Exa- tual Design into a L Relational mapping. Onstraints in SQL, re OATE statements in Textbook 2: 3.5	lealing ational amples ogical SQL: trieval	10 Hours
onstraints as ass tatements in SQI rom applications, tored procedures. The three-Tier app 'extbook 1: Ch7.	ertions and action <b>Database App</b> An introduction to Case study: The	n triggers, View lication Develop o JDBC, JDBC o internet Booksh re, The presentat	etrieval queries, Spec s in SQL, Schema of ment: Accessing dat lasses and interfaces, top. Internet Application ion layer, The Middle 5 to 7.7.	change abases SQLJ, ations:	10 Hours
Functional and Melation schema, I Keys, Second and Dependency and I Form. Normalizat Cover, Properties Database Schema	fultivalued Deper Functional Depen Third Normal For Fourth Normal For ion Algorithms: of Relational D Design, Nulls, discussion of M	ndencies: Information dencies, Normations, Boyce-Codd orm, Join Deper Inference Rules, Decompositions, Dangling tuples	ction to Normalization mal design guidelin l Forms based on P l Normal Form, Multi indencies and Fifth N , Equivalence, and M Algorithms for Rel s, and alternate Rel indencies and 4NF,	es for rimary valued Normal inimal ational ational	10 Hours

Textbook 1: Ch14.1 to 14.7, 15.1 to 15.6 Module - 5	Sector St.
Transaction Processing: Introduction to Transaction Processing, Transaction and System concepts, Desirable properties of Transactions, Characterizing schedules based on recoverability, Characterizing schedules based on Serializability, Transaction support in SQL. Concurrency Control in Databases: Two-phase locking techniques for Concurrency control, Concurrency control based on Timestamp ordering, Multiversion Concurrency control techniques, Validation Concurrency control techniques, Granularity of Data items and Multiple Granularity Locking. Introduction to Database Recovery Protocols: Recovery Concepts, NO-UNDO/REDO recovery based on Deferred update, Recovery techniques based on immediate update, Shadow paging, Database backup and recovery from catastrophic failures Textbook 1: 20.1 to 20.6, 21.1 to 21.7, 22.1 to 22.4, 22.7.	10 Hours
Course outcomes: The students should be able to:	You all all
<ul> <li>database using RDBMS.</li> <li>Use Structured Query Language (SQL) for database manipulation.</li> <li>Design simple database systems</li> <li>Design code for some application to interact with databases.</li> </ul>	
Question paper pattern:	
The question paper will have TEN questions. There will be TWO questions from each module.	
Each question will have questions rour each module. The students will have to answer FIVE full questions, selecting ONE full question f module.	rom each
Text Books:	Service Providence
<ol> <li>Fundamentals of Database Systems, Ramez Elmasri and Shamkant B. Navat Edition, 2017, Pearson.</li> <li>Database management systems, Ramakrishnan, and Gehrke, 3rd Edition, 201 McGraw Hill</li> </ol>	
Reference Books:	1967
<ol> <li>Silberschatz Korth and Sudharshan, Database System Concepts, 6th Edition, GrawHill, 2013.</li> <li>Coronel, Morris, and Rob, Database Principles Fundamentals of Design.</li> </ol>	Mc-

Coronel, Morris, and Rob, Databa se Principles Fundamentals of Design, Implementation and Management, Cengage Learning 2012.

5

### **CITY ENGINEERING COLLEGE** Department of CSE

		Aug - Nov 2019
		V SEM 'A'Section
SI No.	USN	Student Name
1	1CE17CS003	ABHISHEK S
2	1CE17CS004	ADITYA PRASAD
3	1CE17CS006	AISHWARYA S
4	1CE17CS007	AKANKSHA GOWRI
5	1CE17CS008	AKSHAY AMRUT MORAB
6	1CE17CS009	ANANDESHWAR. C
7	1CE17CS013	ANUSHA
8	1CE17CS015	ANUSHREE K R
9	1CE17CS016	APEKSHA BHARADWAJ .M
10	1CE17CS018	ARVIND KUMAR G
11	1CE17CS019	BELLARY NITIN PRASAD
12	1CE17CS021	BHARATH KUMAR S 🖌
13	1CE17CS022	BHAVANAK
14	1CE17CS023	BHAVYA AGGARWAL
15	1CE17CS024	BHUVANESHWARI M
16	1CE17CS029	DEEKSHA R
17	1CE17CS032	DIKSHITA JAIN
18	1CE17CS033	EERANNAT
19	1CE17CS035	GAYATHRI B
20	1CE17CS036	GAYATHRI B M
21	1CE17CS037	GEETHA S
22	1CE17CS038	H PAWAN KUMAR
23	1CE17CS040	HARSHITH S +
23	1CE17C5041	HARSHITHA L
24	1CE17CS042	HITHA. S
	1CE17CS044	JAHNAVI B
26	1CE17CS045	JASIR AHMAD
27 28	1CE17CS046	K MALLIKARJUN
28	1CE17CS047	K PAVITHRA
	1CE17CS048	KALPANA GJ
30	1CE17CS049	KAVANA D
31	1CE17CS050	KAVYASHREE S B
32	1CE17CS052	KRUPA D
33	1CE17CS052	MADAN THARU
34	1CE17CS058	MANORANJINI
35	1CE17CS059	MEGHANA G



37	1CE17CS062	MOHAMMED ALI BAIG
38	1CE17CS063	MOHAMMAD FAIZAL
39	1CE17CS064	MOHAMMED SHAHID ULLA
40	1CE17CS065	MOHAMMED TAUSIF PASHA
41	1CE17CS066	MONIKA R
42	1CE17CS067	MUAAZ MERAZ
43	1CE17CS068	MUJTABA NAYAZ
44	1CE17CS072	NANDIKA M J
45	1CE17CS074	NISCHAL KOTHARI M
46	1CE17CS075	NITHESH S
47	1CE17CS080	PAVAN KUMAR S
48	1CE17CS094	RAJATH DEEP SINGH
49	1CE17CS113	SHANTHA KUMARI M V
50	1CE17CS125	SOUNDARYAR 🖌
51	1CE17CS130	SUMIT SAURAV
52	1CE17CS146	VISHAL KUMAR
53	1CE16CS003	ABHISHEK
54	1CE16CS006	NAGENDRA PRASAD
55	1CE16CS024	CHETHAN B.G
56	1CE16CS025	CHETHAN B
57	1CE16CS029	BHOOMIKA D K
58	1CE16CS041	KARTHIK KUMAR .P
59	1CE16CS052	MOHAMMED BURHAN
60	1CE16CS074	RAKSHITHA .B
61	1CE16CS079	REEMA R KHARVI
62	1CE16CS081	ROOPITHA
63	1CE16CS097	SURESH
64	1CE15CS069	MAHARUDRA
65	1CE15CS093	PANCHAMI .B
66	Repair of the	vasavi
67	Service Contractor	Roopashree



## **CITY ENGINEERING COLLEGE**

### Department of CSE

V SEM 'B'Section							
SI No.	USN	Student Name					
1	1CE17CS005	AISHWARYA B R					
2	1CE17CS014	ANUSHA HIREMATH					
3	1CE17CS053	LATHA L					
4	1CE17CS057	MANOJ KUMAR T					
5	1CE17CS070	MUSKAN K					
6	1CE17CS076	PALLAVI K R					
7	1CE17CS077	PALLAVIMC					
8	1CE17CS078	PALLAVIR					
9	1CE17CS079	PARVATHI N K					
10	1CE17CS081	PAVAN V					
11	1CE17CS082	POKALA SESHA SAI POOJA					
12	1CE17CS083	POLICE PATEL SAINATH REDDY					
12	1CE17CS084	POOJAK					
14	1CE17CS085	POOJASHREE A					
15	1CE17CS086	PRAJWAL V					
16	1CE17CS087	PRASHANTH H K					
17	1CE17CS088	PRASHANTH KUMAR N					
18	1CE17CS089	PRERANA P					
19	1CE17CS090	PRERANA PRASAD					
20	1CE17CS091	PRIYA G					
20	1CE17CS092	PRIYANKA S MARELLAVAR					
Provide the	1CE17CS093	RAHUL KARMAKAR					
22	1CE17CS095	RASHMIKA C P					
23	1CE17CS097	ROOPA M					
24	1CE17CS098	S BHAVYASRI					
25	1CE17CS101	SAGAR M					
26	1CE17CS102	SAHANA M R					
27	1CE17CS103	SAHANA N					
28	1CE17CS104	SAHANA S V					
29	1CE17CS105	SAI NITHIN G					
30	1CE17CS106	SANDHYA P					
31	1CE17CS107	SANEETH BANIK					
32	ICEI7CS108	SANGEETHA N					
33	1CE17CS109	SANJANA R					
34	1CE17CS111	SHALINI G					
35	1CE17CS112	SHANMUGA PRIYA G					
36	1CE17CS112	SHASHIDHARA S					



38	1CE17CS115	SHAZIYA KOUSAR
39	1CE17CS118	SHRAVANI J
40	1CE17CS119	SHREYAS R GOWDA
41	1CE17CS120	SHUBHAM KUMAR
42	1CE17CS122	SIMRAN BANU A
43	1CE17CS123	SINCHANA B G
44	1CE17CS124	SINDHU P PAI
45	1CE17CS126	SOUNDARYA RAJ G
46	1CE17CS127	SRIDHAR D N
47	1CE17CS128	SRI LAKSHMI B A
48	1CE17CS129	SUMAIYA ARA KHANUM
49	1CE17CS132	SWATHI P
50	1CE17CS133	SYED HASNAIN RAZA
51	1CE17CS134	TARIQ MOHAMMED SARFARAZ
52	1CE17CS136	THANUSHREE B M
53	1CE17CS137	THEJAS MURTHY R
54	1CE17CS138	THEJESHWARI S
55	1CE17CS139	UMAA MAHESHWARI S V
56	1CE17CS141	VANDANA M
57	1CE17CS143	VIDHYADHAR JOSHI
58	1CE17CS144	VINDYA SHREE P
59	1CE17CS145	VINUTHA D B
60	1CE17CS150	ZAIBA BEGUM
61	1CE16CS040	JAYA SHANKAR
62	1CE16CS051	MANOHAR
63	1CE16CS056	MUJEER AHMED
64	1CE16CS096	SUHAS S
65	1CE16CS103	TEJAS K S



#### CITY ENGINEERING COLLEGE "ACCREDITED BY NAAC"



#### DEPARTMENT OF CSE

#### LESSON PLAN FOR ODD SEMESTER FOR ACADEMIC YEAR 2019 - 2020

Course Title: Database Management System	Course Code : 17CS53
Total contact hours: L:T:P:S :: 4:0: 0:0	End Term Marks :60
Internal Marks: 40	
Semester : V - 'B'	Academic year : 2019-20
Lesson plan Author: Mrs. Archana Bhat	Date : 29/07/2019

Course objectives: This course will enable students to

- 1. Provide a strong foundation in database concepts, technology, and practice.
- 2. Practice SQL programming through a variety of database problems.
- 3. Demonstrate the use of concurrency and transactions in database
- 4. Design and build database applications for real world problems.

Course Outcomes: The students shall able to:

- 1. Summarize the concepts of database objects; enforce integrity constraints on a database using RDBMS.
- 2. Use Structured Query Language (SQL) for database manipulation
- 3. Design simple database systems
- 4. Design code for some application to interact with databases

Mod	n	le	1
TTIOU			-

Week	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
	Introduction to Databases: Introduction, Characteristics of database approach	L1,L2	COI
	Advantages of using the DBMS approach, History of database applications.	L1,L2	CO1
1	Overview of Database Languages and Architectures: Data Models, Schemas, and Instances	L1,L2	CO1
	Three schema architecture and data independence, database languages, and interfaces	L1,L2	COI
	The Database System environment	L1,L2	CO1
2	Conceptual Data Modeling using Entities and Relationships: Entity types, Entity sets, attributes	L1,L2	CO1, CO3
	roles, and structural constraints	L1,L2	CO1, CO3
	Weak entity types	L1,L2	CO1, CO3
120.48	ER diagrams. examples	1.2.1.3	CO1. CO3



## Module 2

Week	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
	<b>Relational Model: Relational Model Concepts</b>	L1,L2,L3	COI
	Relational Model Constraints and relational database schemas	L1,L2,L3	CO1
4	Update operations, transactions, and dealing with constraint violations	L1,L2,L3	CO1, CO2
	Relational Algebra: Unary and Binary relational operations	L1,L2,L3	COI
5	Additional relational operations (aggregate, grouping, etc.) Examples of Queries in relational algebra	L1,L2,L3	COI
	Mapping Conceptual Design into a Logical Design: Relational Database Design using ER- to-Relational mapping	L2,L3	CO1, CO3
1 2	SQL: SQL data definition and data types	L1,L2	CO2
	Specifying constraints in SQL	L1,L2	CO2
7	Retrieval queries in SQL,	L2,L3	CO2
	INSERT, DELETE, and UPDATE statements in SQL	L1,L2	CO2
	Additional features of SQL	L1,L2	CO2
8	Additional features of SQL	L1,L2	CO2

## Module 3

Week	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
	SQL : Advanced Queries: More complex SQL retrieval queries	L2, L3	CO2
8	Specifying constraints as assertions and action triggers	L2, L3	CO2
	Views in SQL, Schema change statements in SQL	L2, L3	CO2
	Database Application Development: Accessing databases from applications	L2, L3	CO4
9	An introduction to JDBC, JDBC classes and interfaces	L1, L2	CO4
	SQU	L1, L2	CO2, CO4
1	Stored procedures	L1, L2	CO2, CO4
10.10	Case study: The internet Bookshop	L2, L3	CO4
10	Internet Applications: The three-Tier application architecture	L1, L2	CO4
	The presentation layer, The Middle Tier	L1, L2	CO4

## Module 4

Week	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
11	Normalization: Database Design Theory – Introduction to Normalization using Functional and Multivalued Dependencies: Informal design guidelines for relation schema	L2, L3	CO3
	Functional Dependencies, Normal Forms based on Primary Keys	L2, L3	CO3
	Second and Third Normal Forms, Boyce-Codd Normal Form	L2, L3	CO3
12	Multivalued Dependency and Fourth Normal Form, Join Dependencies and Fifth Normal Form.	L2, L3	CO3
	Normalization Algorithms: Inference Rules, Equivalence, and Minimal Cover,	L2, L3	CO3
13	Properties of Relational Decompositions	L2, L3	CO3
14	Algorithms for Relational Database Schema Design, Nulls, Dangling tuples and alternate Relational Designs	L2, L3	CO3
	Further discussion of Multivalued dependencies and 4NF	L2, L3	CO3
	Alternate Relational Designs	L2, L3	CO3

## Module 5

Week	Contents of Module	Bloom's Taxonomy Level	Course Outcome (CO)
14	Transaction Processing: Introduction to Transaction Processing, Transaction and System concepts	L1, L2	CO1, CO4
	Desirable properties of Transactions, Characterizing schedules based on recoverability	L1, L2	CO1, CO4
15	Desirable properties of Transactions, Characterizing schedules based on recoverability	L1, L2	CO1, CO4
	Transaction support in SQL	L1, L2	CO1, CO4
	Concurrency Control in Databases: Two- phase locking techniques for Concurrency control, Concurrency control based on Timestamp ordering		CO1, CO4
17.54	Multi version Concurrency control techniques, Validation Concurrency control techniques	L1, L2	CO1, CO4
16	Granularity of Data items and Multiple Granularity Locking	L1, L2	CO1, CO4
	Introduction to Database Recovery Protocols: Recovery Concepts, NO- UNDO/REDO recovery based on Deferred update	L1, L2	CO1, CO4



16	Recovery techniques based on Immediate update, Shadow paging	L1, L2	CO1, CO4
17	Database backup and recovery from catastrophic failures	L1, L2	CO1, CO4

#### **RBT** Level

L1-Remembering L2-Understanding L3-Applying L4-Analysing L5-Evaluating L6-Creating

#### Text Books:

1. Fundamentals of Database Systems, Ramez Elmasri and Shamkant B. Navathe, 7th Edition, 2017, Pearson.

2. Database management systems, Ramakrishnan, and Gehrke, 3rd Edition, 2014, McGraw Hill

#### **Reference Books:**

1. Silberschatz Korth and Sudharshan, Database System Concepts, 6th Edition, McGrawHill, 2013.

2. Coronel, Morris, and Rob, Database Principles Fundamentals of Design, Implementation and Management, Cengage Learning 2012.

Arel

Signature of Faculty

### Signature of HOD



## Department of Computer Science and Engineering

#### Question Bank - Module 1

#### Subject: Database Management Systems

#### Sub Code: 17CS53

- 1. Define DBMS. Discuss the advantages of DBMS over the traditional file system.
- 2. Explain the component modules of DBMS and their interaction with the help of a diagram.
- 3. Define the following with an example: Weak entity type, Participation constraints, Cardinality ratio, and Recursive relationship with example.
- 4. Draw an ER diagram of Banking System taking into account at least five entities; indicate all keys, constraints and assumptions that are made.
- 5. Discuss the main characteristics of the database approach and how it differs from traditional file systems.
- 6. Describe three schema architecture. Why do we need mappings among schema levels?
- 7. Define an Entity and attribute. Explain the different types of attributes that occur in ER diagram model, with an example.
- 8. Draw an ER diagram of an airline reservation system, taking into account at least five entities. Indicate all keys, constraints and assumptions that are made.
- 9. Define snapshot, metadata, intention and database.
- 10. Design an ER diagram for an employee database with at least four entities considering all the constraints.
- 11. What are the structural constraints on a relationship type? Explain with examples.
- Explain additional implications of using database approach.
- 13. Write an ER diagram for hospital management considering at least four entities.
- 14. What are the responsibilities of the DBA and Database Designer?
- 15. Discuss the different types of user friendly interfaces and the types of user who typically use each.
- 16. Explain with block diagram the different phases of database design.
- 17. Draw an ER diagram of movie database. Assume your own entities attributes and relationships.



## Department of Computer Science and Engineering

#### Question Bank - Module 2

#### Subject: Database Management System

#### Sub Code: 17CS53

- 1. What is NULL? What is its importance? How are these values handled in relational model?
- 2. Discuss in detail the operators SELECT, PROJECT, UNION with suitable example?
- 3. Explain about different DML operations.
- 4. By considering an example describe various data update operations in SQL
- 5. Explain in detail about various key constraints used in database system.
- 6. What are the basic operations that can change the states of relations in the database? Explain how the basic operations deal with constraint violation.
- 7. Explain briefly violation in entity integrity constraint, key and referential integrity constraints, with example.
- 8. In SQL which command is used for table creation? Explain how constraints are specified in SQL during table creation with suitable example.
- Describe the steps of an algorithm for ER to Relational mapping.
- 10. Explain the data types available for attribute specification in SQL.
- 11. Give an example of mapping of generalization or specialization into relational schema.
- 12. Consider the following tables: works (Pname, Cname, Salary) lives (Pname, Street, City) located-In (Cname, City)

Write the following queries in SQL:

i) List the names of the people who work for the company 'Wipro' along with the cities

they live in.

ii) Find the names of the persons who do not work for 'Infosys'.

- iii) Find the people whose salaries are more than that of all of the 'oracle' employees.
- iv) Find the persons who work and lives in the same city
- 13. Define the following:

i) Relation state ii) Relation schema iii) Arity iv) Domain



## **Department of Computer Science and Engineering**

**Question Bank - Module 3** 

## Subject: Database Management Systems

Sub Code: 17CS53

- How triggers and assertions defined in SQL? Explain. 1.
- How are views created and dropped? Explain how the views are implemented and 2. updated.
- Explain the single tier and client server architecture with a neat diagram. 3.
- With the program segment, explain retrieving of tuples with embedded SQL in C. 4.
- Discuss how each of the following constructs is used in SQL and discuss the various 5. options for each construct:

Nested queries ii) aggregate functions iii) Schema change statements iv) Group by and Having clause

- Draw and explain 3-tier architecture and technology relevant to each tier. Write the 6. advantages 3-tier architecture.
- What is CGI? Why was CGI introduced? What are the disadvantages of an 7. architecture using CGI scripts?
- What is Dynamic SQL and how it is different from Embedded SQL? 8.
- 9. What is SQLJ and how is it different from JDBC?
- Define stored procedure. Explain the creating and calling of stored procedure with 10. suitable example.
- What is cursor? Explain with example, retrieving multiple tuples with embedded 11. SQL.



## Department of Computer Science and Engineering

#### Question Bank - Module 4

#### Subject: DBMS

#### Sub Code: 17CS53

- 1. Define normal form. Explain 1NF, 2NF and 3NF with suitable examples for each.
- 2. Which normal form is based on the concept of transitive functional dependency? Explain the same with an example.
- 3. What is the need for normalization?
- 4. What is Functional Dependency?
- 5. Define Multivalued dependency. Explain fourth normal form, with an example.
- 6. Define non-additive join property of decomposition and write an algorithm of testing for non-additive join property.
- 7. Explain the informal guidelines used as measures to determine the quality of relation schema design.
- 8. Define minimal cover. Write an algorithm for finding a minimal cover F for a set of functional dependencies E.
- 9. What is functional dependency? List the conditions for a set of functional dependencies to be minimal.
- 10. Which normal form specifies multivalued functional dependency? Explain it with examples.
  - 11. Consider the relation:

EMP PROJ={SSN, Pnumber, Hours, Ename, Pname, Plocation} Assume {SSN, Pnumber} as primary key.

The dependencies are:

{SSN, Pnumber} -> Hours

SSN->Ename

```
Pnumber->{Pname, Plocation}
```

Normalize the above relation to 3NF.

- 12. Find the minimal cover for the following dependency.F={AB->D, B->C, AE->B, A ->D, D->EF}
- 13. Consider two sets of functional dependency: F={A->C, AC->D, E->AD, E->H} and G={A->CD, E->AH} Are they equivalent?
- 14. Consider the universal relation R = {A, B, C, D, E, F, G, H, I, J} and the set of functional dependencies  $F = \{ \{A, B\} \rightarrow \{C\}, \{A\} \rightarrow \{D, E\}, \{B\} \rightarrow \{F\}, \{F\} \rightarrow \{G, H\}, \}$  $\{D\} \rightarrow \{I,J\}\}$ 
  - a. What is key of R? Decompose R into 2NF and then 3NF relations.
  - b. Determine whether the decomposition has the lossless join property with respect to F.

 $D1=\{R1,R2,R3\}; R1=(A,B,C,D,E); R2=(B,F,G,H); R3=(D,I,J)$ 



#### Department of Computer Science and Engineering

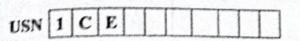
#### **Question Bank – Module 5**

## Subject: Database Management Systems

#### Sub Code: 17CS53

- 1. Discuss the ACID properties of a database transaction. Or Discuss the desirable properties of transaction.
- 2. Why concurrency control is needed? Demonstrate with an example.
- Discuss the UNDO and REDO operations and the recovery techniques that use each. 3.
- Discuss the time stamp ordering protocol for concurrency control. 4.
- Explain how shadow paging helps to recover from transaction failure. 5.
- Explain the transaction support in SQL. 6.
- What is two-phase locking protocol? How does it guarantee serializability? 7.
- What is serializability? How can serializability be ensured? Do you need to restrict 8. concurrent execution of transaction to ensure serializability? Justify your answer.
- 9. When deadlock and starvation problem occurs? Explain how these problems can be resolved.
- 10. Briefly explain the recovery process.
- 11. Explain transition diagram of a transaction.
- 12. Explain the principles used in ARIES algorithm.
- 13. What is a schedule? Explain conflict serializable schedule with example.







#### CITY ENGINEERING COLLEGE FIRST INTERNAL TEST

Programme: CSE Course Name: Database Management System Sem & See: V SEM A, B

Date: 07/09/2019 Time: 10:30AM-12:00PM Duration: 1 1/2 hrs.

Max Marks: 50 Note: Answer all Questions selecting any ONE FULL question from each part.

2	Sub O No.	Questions	Marks	CO's	BT's
	- C	PART -A	1		
1	2	Discuss the main characteristics of the database approach and how it differs from traditional file systems.	10	COI	L1, L2
		Or			
2		Explain the component modules of DBMS and their interaction with the help of a diagram	10	COI	L1, L2
		PART-B			1
	a	Describe three schema architecture. Why do we need mappings among schema levels?	5	COI	L1, L2
3	b	Discuss the different types of user friendly interfaces and the types of user who typically use each.	5	COI	L1, L2
-	-	Or		1	IT1
4	14	Explain with block diagram the different phases of database design.	10	CO1	L1, L2
1		PART-C			
5		Design an ER diagram for hospital management considering at least four entities	10	CO1	L3, L4
		Or			
6	1	Draw an ER diagram of movie database. Assume your own entities attributes and relationships	10	CO1	L3, L4
-	1	PART - D		1.72	
		What are the basic operations that can change the states of relations in What are the basic operations deal with constraint			L2
7		the database? Explain now the case of	10	CO1,2	L3
23.	1	violation. Or		-	-
	1	In SQL which command is used for table creation? Explain how constraints are specified in SQL during table creation with suitable	4	CO2	L2 L3
8	a	constraints are specified in a	6	CO2	LI L2
	b	example         Explain the data types available for attribute specification in SQL         PART -E			
			1.20	1 22	
5	,	Write SQL Queries for following set of tables: EMPLOYEE (EmpNo, Name, DoB, Address, Gender, Salary, DNumber) DEPARTMENT (DNumber, Dname, ManagerEmpNo,	10	CO2	L3 L4
No.		DEPARTMENT (Diverse).			

	<ul> <li>i) Display the DoB of "male" employees.</li> <li>ii) Display all employees in Department named "Marketing".</li> </ul>	2.21
17 85	iii) Display the maximum salary in each department.	81.1
	iv) Display Manager Name along with the department name which	6.5
19	they manage.	-,003
Station!	v) Display the name of department of the employee "SMITH".	L

Or

	Consider the following Schema:		1	
	Emp(name, id, age, salary)			
	Works_for(pid,eid, #hrs)			1
	Proj(pid, name)		Sec.	
10.0	Write the relational algebra for the following.	10	CO2	L3,
10	i. Retrieve employee name and employee id who works for all the	10	002	LA
	projects.			
	ii. Retrieve employee name and age whose salary > 1000		11-5-5-5	1.
1.5	iii. For each employee, get the number of projects and number of		1.	
	hours worked on projects		1 Mars	
	iv. Retrieve the employee name who is working for "CSE" project			-

Blooms Taxonomy Levels: L1: Remembering L2: Understanding L3: Applying L4: Analyze L5: Evaluate L6: Create

#### **Course Outcomes:**

CO1: Summarize the concepts of database objects; enforce integrity constraints on a database using RDBMS. CO2: Use Structured Query Language (SQL) for database manipulation.



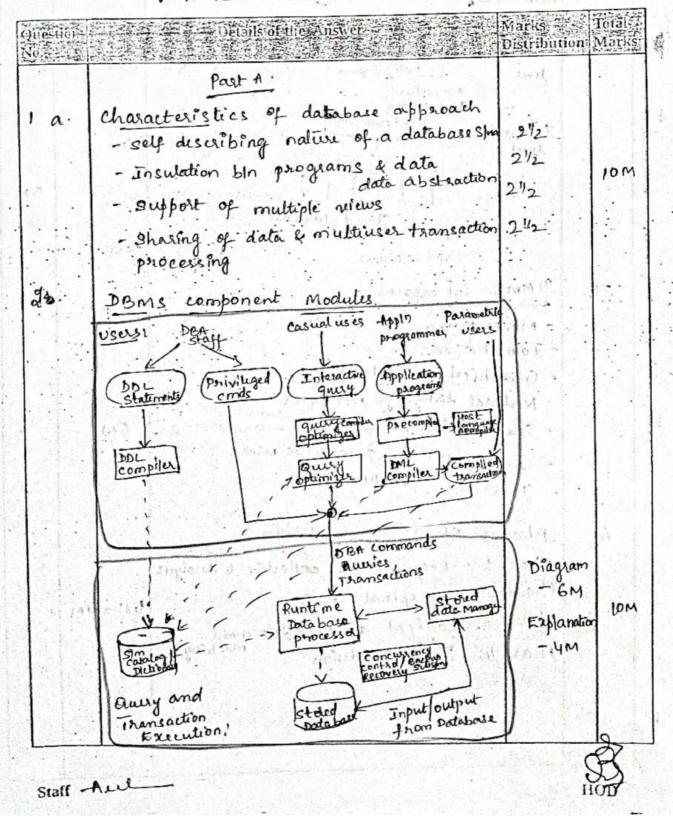
## CITY ENGINEERIN COLLEGE DEPARTMENT OF ...CSE

#### SCHEME FOR VALUATION

Internal Test ____

Date: 04/09/19

Semester & Section: V A &B



Part - B. Three Schema-Architecture 3.a External External External view level External conceptu mapping Conceptual su Conceptual Mappin level conceptual/ Internalmappi Internal schem Dragram - 2M Internal livel 51 Stored Database Explanation DBMS. interfaces 36. - Menu driven. - Form based - Goraphical user interface - Natural language Interfaces 5M - speech alp ofp - Interfaces for parametric users Interfaces for DBA Phases of database design 4. phase 1 : Requirements collection & analysis phase 2 : conceptual design 4x1 = 4Mphase 3: Logical design (data makil mapping) Phase 4: Physical design

Scanned with OKEN Scanner

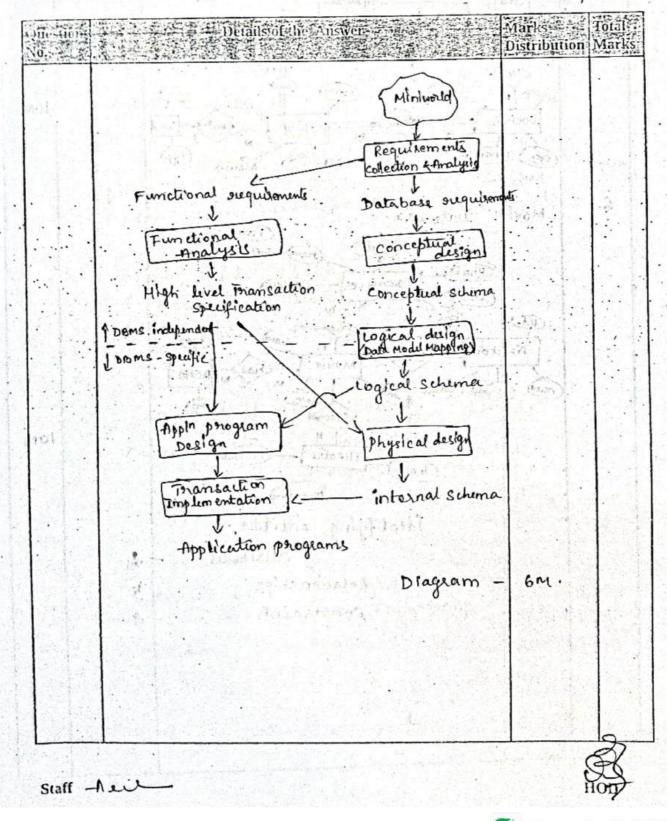
## CITY ENGINEERIN COLLEGE DEPARTMENT OF .. CSE

#### SCHEME FOR VALUATION

Internal Test T

Semester & Section: V A LB

Date: 04 09 19



Scanned with OKEN Scanner

Part-c. E.R diagram foi Hospital Management 5. sname Sino 5 Job Com-Subo Staff BND Bant Phone Age Bil M Hel IOM pham spic pre Solary N War Admit atient reat Doctor N typ 000 name Address Phone Dho 6. : Moirie Databas Fnan Pid tan nam Phont Produces Addree Pdob Pit nar Disector Movie has Actol R alali Adres ANO nam -Adda SURCED IOM id Tlocation Theatre Inamle (Tower name identifying entities, attributes 4 Relationships 4 constraints 2

O

## CITY ENGINEERIN COLLEGE DEPARTMENT OF .....

#### SCHEME FOR VALUATION

Internal Test _]

Semester & Section: V A& B

Date: 04/09/19

	Part-D.	•
4.	Insert, Delite, Updalt Insert-Domain, key, Entilg Integrily and sugerential Integrily - 4 M. Delite - Only sufferential integrily - 2 M Updale - All 4 constraints 4 M	10M
8a	Coreate table C Attainame datatype, Attainame datatype,	
	Syntax of create table - 1M constrainte - primary key - 1 foreign key - 1 not null, unique - 1	414
i - j _{Obe}	Datatypus in squ chasacter string	
89	- Numerie - characterstring - Numerie - Time, Timestamp - Dati - Boolean - BLOB - 6 M	60

O Scanned with OKEN Scanner

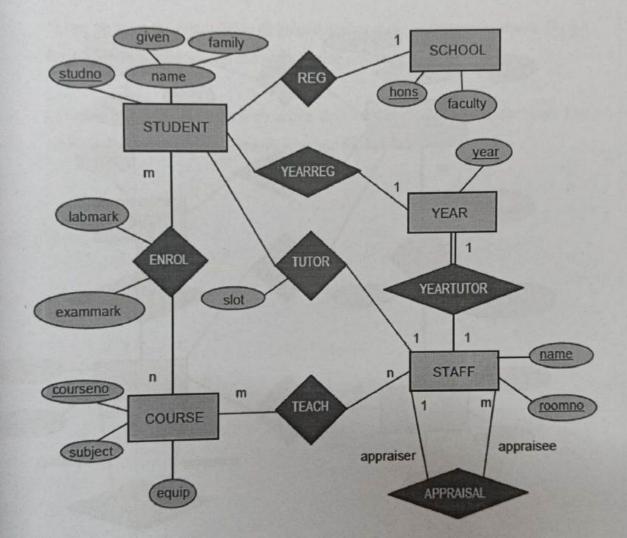
Part-E. select î) Name, DoB 9. 2M Employees From where gender = 'male'; i Select Emp No, Name 2M forom Employee, Department hehere Department. Dnumber = Employee. Dnumber and Dname - Marketing' 10 M in) select DNumber, MAX (Salary) am From employee group by Dnumber select e. Name, d. DNumber from employee e, Department d aM where e. DNumber = d. DNumber and e. Empro : d. ManagerEmpro; Select D'name. as Drame-of-smith Department natural join Employee 2M Friom hohere . Name = 'SMITH' is Re- (Thid, end (Worksfor) + Tipid (Proj) 10 am Finame, Id (Emp Mid-eld R) i) II name, age ( Salary >1000 (EMP)) M 2 in (wolks-for) IOM ed count pid, sum #has 3 M iv) Tempic- O (Works.for * Paroj) 3M Temps - TTeid (Temp1) ·Tiname ( Emp M Tempe)

Scanned with OKEN Scanner

#### ER TO RELATIONAL SCHEMA MAPPING

#### **Exercise Questions**

1. Based on the ER-diagram given below, develop a relational database schema. Identify the missing cardinalities. List tables with their attributes. Identify keys and foreign keys.

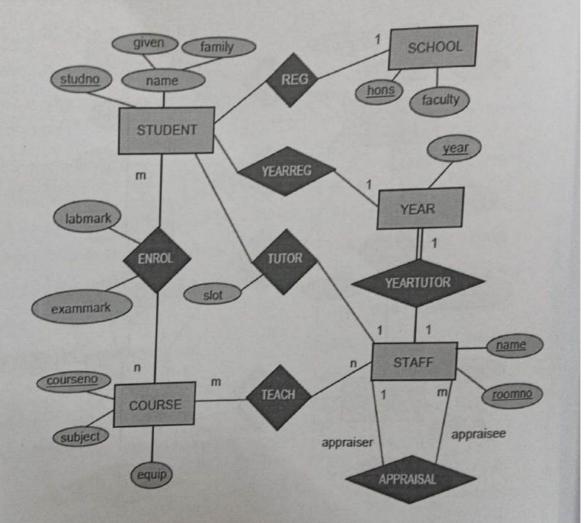


- 2. A database needs to be developed that keeps track of PhD students:
- For each student store the name and matriculation number. ۲
- Matriculation numbers are unique. .
- Each student has exactly one address. An address consists of street, town and post . code, and is uniquely identified by this information.



## ER TO RELATIONAL SCHEMA MAPPING **Exercise Questions**

1. Based on the ER-diagram given below, develop a relational database schema. Identify the missing cardinalities. List tables with their attributes. Identify keys and foreign keys.



- 2. A database needs to be developed that keeps track of PhD students:
- For each student store the name and matriculation number. .
- Matriculation numbers are unique. .
- Each student has exactly one address. An address consists of street, town and post . code, and is uniquely identified by this information.



- For each lecturer store the name, staff ID and office number. Staff ID's are unique. .
- Each student has exactly one supervisor. A staff member may supervise a number of students.
- The date when supervision began also needs to be stored. .
- For each research topic store the title and a short description. Titles are unique. .
- Each student can be supervised in only one research topic, though topics that are . currently not assigned also need to be stored in the database.

a) Design an entity relationship diagram that covers the requirements above. Do not forget to include cardinality and participation constraints.

b) Based on the ER-diagram from above, develop a relational database schema. List tables with their attributes. Identify keys and foreign keys.



## SQL - PRACTICE QUESTIONS

Consider the following schema:

EMPLOYEE( EName, ENum, JoinDate, Job, Salary, Commission, DNum) DEPARTMENT(Dno, DName, Location)

- Select the employees in department 30.
- List the names, numbers and departments of all clerks.
- Find the department numbers and names of employees of all departments with deptno greater than 20.
- Find employees whose commission is greater than their salaries.
- 5. Find employees whose commission is greater than 60 % of their salaries.
- 6. List name, job and salary of all employees in department 20 who earn more than 2000/-.
- 7. Find all salesmen in department 30 whose salary is greater than 1500/-.
- 8. Find all employees whose designation is either manager or president.
- 9. Find all managers who are not in department 30.
- 10. Find all the details of managers and clerks in dept 10.
- 11. Find the details of all the managers (in any dept) and clerks in dept 20.
- 12. Find the details of all the managers in dept. 10 and all clerks in dept 20 and all employees who are neither managers nor clerks but whose salary is more than or equal to 2000/-.
- 13. Find the names of anyone in dept. 20 who is neither manager nor clerk.
- 14. Find the names of employees who earn between 1200/- and 1400/-.
- 15. Find the employees who are clerks, analysts or salesmen.
- 16. Find the employees who are not clerks, analysts or salesmen.



- 17. Find the employees who do not receive commission.
- 18. Find the different jobs of employees receiving commission.
- 19. Find all the employees whose total earning is greater than 2000/- .
- 20. Find all the employees whose name begins or ends with 'M'
- 21. Find all the employees whose names contain the letter 'M' in any case.
- 22. Find all the employees who were hired in the month of February (of any year).
- 23. Find the managers hired in the year 2003.
- 24. Display the details of all the employees sorted on their names.
- 25. Display the names of the employees, based on the tenure with the oldest employee coming first.
- 26. Display the names, jobs and salaries of employees, sorting on job and salary.
- 27. Display the names, jobs and salaries of employees, sorting on descending order of job and within job sorted on salary.
- 28. List the employee names, department names and salary for those employees who are earning 0 commission or commission is null. Sort your output in the order of department name.
- 29. List the employee names, department names and hiredate for those employees who have joined in 2003. Sort your output in the order of joining date.
- 30. List all the department names along with the names of employees in them, irrespective of the fact whether any employee is there or not.





#### DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

### CIRCULAR

#### Ref. No: CEC/ECE/DAC/2019-2020/02

Date: 05-02-2020

All the members of Department Advisory Committee are informed to attend a meeting which will be held as follows

Date: 6-02-20 Time: 03.30 PM Venue: LAB A206

#### Agenda:

- Certification course for 3rd year
- Organizing workshop for final year
- Conduction of Project Exhibition
- Industrial Visit
- Conduction of guest lectures/ workshops

(.s. malite

Prof. Mallikarjuna G S

HOD



#### DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

#### **Department Advisory Committee Meeting**

Date: 06-02-2020 Time: 03.30 PM Venue: LAB A206

DAC Members Present:

Sl. No	Member Name	Designation	Role	Signature
1	Prof. Mallikarjuna G S	HOD	Convenor	Asnals Kugh
2	Dr. Shalini Prasad	Professor	Co-Convenor	S. Prasud
3	Prof. Shylaja K	'Assistant Professor	Member	sum
4	Prof. Ravindra S	Assistant Professor	Member	R.
5	Prof. Aurobindo Koti	Assistant Professor	Member	Kuta
6	Prof. SKL Narayana	Assistant Professor	Member	sKlu

The Department Advisory Committee meeting was conducted at Department of ECE, on  $06^{TH}$  April 2020, at 03:30 PM.

#### Agenda of the Meeting:

- Conducting Certification courses
- Organizing workshop for final year
- · Conduction of Project Exhibition
- Faculty development program
- · Conduction of guest lectures/ workshops



#### **Minutes of Meeting:**

In the Department Advisory Committee meeting, an overview of the department was presented, emphasizing student achievements, result analysis, and faculty accomplishments. The members discussed various suggestions for improvement and reviewed the meeting agenda.

The Committee proposed the following items for inclusion in the agenda:

- A Value added course has been recommended by the convener.
- Second-year students are encouraged to participate in technical activities and to attend guest lectures or seminars to broaden their knowledge.
- A project exhibition has been proposed, offering final-year students a platform to showcase their work.
- To keep students and faculty updated with current technologies, the committee suggested organizing workshops, guest lectures, and hands-on sessions.

( .s. malithe

Prof. Mallikarjuna G S

HOD

# Academic Calendar of VTU, Belagavi for EVEN Semester of 2019-2020 (Jan 2020 – July 2020)

	II Sem B. E. / B. Tech. / B. Arch	IV & VI Sem B. E. /B. Tech. IV, VI&VIII Sem B. Arch.	VIII Sem B.E / B.Tech & X Sem B. Arch	IV Sem MCA	VI Sem MCA	IV Sem MBA	IV Sem M. Tech.	IV Sem M. Arch.	II Sem M. Tech.	II Sem MCA	II Sem MBA	II Sem M. Arch.
Commencement of EVEN Semester	10.02.2020	10.02.2020	10.02.2020	27.01.2020	27.01.2020	10.02.2020	27.01.2020	27.01.2020	05.03.2020	05.03.2020	14.02.2020	14.02.2020
Last Working day of EVEN Semester	01.06.2020	01.06.2020	01.06.2020	20.05.2020	20.05.2020	01.06.2020	20.05.2020	20.05.2020	22.06.2020	22.06.2020	05.06.2020	05.06.2020
Practical Examination	03.06.2020 To 13.06.2020	03.06.2020 To 13.06.2020	-	26.05.2020 To 30.05.2020		4	-		25.06.2020 To	25.06.2020 To	_	
Theory Examinations	15.06.2020 To 04.07.2020	15.06.2020 To 20.07.2020	03.06.2020 To 11.06.2020	03.06.2020 To 18.06.2020		03.06.2020 To 28.06.2020	03.06.2020 To 10.06.2020	~	30.06.2020 01.07.2020 To	30.06.2020 01.07.2020 To	08.06.2020 To	09.06.2020 To
Viva Voce	-	_	15.06.2020 To 20.06.2020	-	-	-	-	2	-	-	-	20.06.2020
Summer Project / Professional training	-	-	-	-	22.05.2020 To 30.05.2020 (Submission of report to VTU)	01.04.2020 To 15.04.2020 (Submission of report to VTU)	12.06.2020 To 25.06.2020 (Submission of report to VTU)	-	13.07.2020 To 31.07.2020	-	23.06.2020 To 21.07.2020	01.07.2020 To 25.08.2020
Commencement of ODD Semester	27.07.2020	27.07.2020	27.07.2020	27.07.2020	-	-	-	-	03.08.2020	27.07.2020	27.07.2020	28.08.2020

NOTE

- 1. College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notified separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.
- 3. If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day.
- 4. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTRAR

	e Fl	EBRUARY 2020	-	MARCH 2020		APRIL 2020	100	MAY 2020		JUNE 2020
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
/ED					1					
THU					2					
FRI					3		1	MAY DAY GH		
SAT	1				4		2			
SUN	2		1		5		3			
MON	3		2		6	MAHAVIRA JAYANTHI GH	4		1	LAST WORKING DAY OF 2 nd , 4 th , 6 TH & 8 TH SEMS
TUE	4		3		7	A	5		2	muranumus atters
WED	5		4		8		6	ETHNIC DAY	3	THEORY EXAMS 8 th SEN 03.6.20 to 11.06.20
THU	6		5		9		7	SPORTS DAY	4	05.0.20 10 11.00.20
FRI	7		6		10	GOOD FRIDAY-GH	8		5	VIVA VOCE 8 th SEM
SAT	8	2 ND SATURDAY HOLIDAY	7		11	2 ND SATURDAY HOLIDAY	9	CHRONICLES	6	15.06.20 to 20.06.20
SUN	9		8		12		10		7	
MON	10	$\begin{array}{c} \text{STARTING OF} \\ \textbf{2}^{nd}, \textbf{4}^{th}, \textbf{6}^{TH} & \textbf{8}^{TH} \text{SEMESTERS} \end{array}$	9		13		11		8	THEORY EXAMS
TUE	11		10		14	AMBEDKAR JAYANTI-GH	12		9	4 th & 6 th SEMs
WED	12	PHASE-2 INDUCTION	11		15		13		10	15.06.20 to 20.07.20
THU	13	PROGRAMME	12		16		14		11	
FRI	14	10.2.2020 to 20.2.20	13		17		15		12	THEORY EXAMS
SAT	15		14	2 ND SATURDAY HOLIDAY	18		16	OPENDAY/EXHIBITIONS	13	SECOND SEM
SUN	16		15		19		17		14	15.06.20 to 04.07.20
MON	17		16	•	20		18		15	DRACTICAL EVALUE
TUE	18	PHASE-2 INDUCTION	17	FIRST INTERNAL ASSESSMENT	21		19		16	2 nd ,4 th & 6 th SEMESTER
WED	19	PROGRAMME	18	2 nd , 4 th ,6 th & 8 th Semesters	22		20		17	03.06.20 to 13.06.20
THU	20	10.2.2020 to 20.2.20	19		23		21	THIRD INTERNAL ASSESSMENT 2 nd , 4 th ,6 th & 8 th Semesters	18	GRADUATION DAY AFTER 20.7.2020
FRI	21	MAHASHIVARATHRI-ĠH	20		24	BATTLE OF SCIENCE EVENT (First Year)	22	1	19	ATTER 2017.2020
SAT	22	4 TH SATURDAY HOLIDAY	21	Alumni Day (Tentative)	25	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	20	
SUN	23		22		26		24		21	
MON	24		23		27		25	RAMJAN GH	22	
TUE	25		24		28	SECOND INTERNAL ASSESSMENT	26		23	
WED	26		25	UGADI-GH	29	2 nd , 4 th , 6 th & 8 th Semester	27		24	
THU	27		26		30	- 400 ATO THE CONTRACTOR	28	LAB TESTS	25	00
FRI	28		27				29	2 nd ,4 th ,6 th & 8 th SEMs	26	on and
SAT	29		28	4 TH SATURDAY HOLIDAY			30	an to the second second	27	PRINCIPAL
SUN			29				31		CIT28E	IGINEERING COLL
MON	a		30					×	ar ak 29ra	Main Road, BANGALORE
TUE		11-	31						30	

a contractor

		CITY EN	GINEE	RING COLLEGE, BENG		U-560061. ACADEMIC	CALE	NDAR 2019-20 (EVEN	SEM)	
						DEPT OF E&CE		•		
37 (2	FE	BRUARY 2020		MARCH 2020		APRIL 2020		MAY 2020		JUNE 2020
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
WED					1					
THU					2					
FRI					3		1	MAY DAY GH		
SAT	1				4		2			
SUN	2		1		5		3			
MON	3		2		6	MAHAVIRA JAYANTHI GH	4		1	LAST WORKING DAY OF 2 nd , 4 th , 6 TH & 8 TH SEMS
TUE	4		3		7		5		2	
WED	5		4		8		6	ETHNIC DAY	3	THEORY EXAMS 8 th SEM
THU	6		5	PCB WORKSHOP	9		7	SPORTS DAY	4	03.6.20 to 11.06.20
FRI	7		6		10	GOOD FRIDAY-GH	8		5	VIVA VOCE 8 th SEM
SAT	8	2 ND SATURDAY HOLIDAY	7		11	2 ND SATURDAY HOLIDAY	9	CHRONICLES	6	15.06.20 to 20.06.20
<mark>SUN</mark>	9		8		12		10		7	
MON	10	STARTING OF 2 nd , 4 th , 6 TH & 8 TH SEMESTERS	9		13		11		8	
TUE	11		10	GUEST LECTURE 1	14	AMBEDKAR JAYANTI-GH	12		9	THEORY EXAMS 4 th & 6 th SEMs
WED	12	PHASE-2 INDUCTION	11		15		13		10	15.06.20 to 20.07.20
THU	13	PROGRAMME	12		16		14	INDUSTRIAL VISIT	11	
FRI	14	10.2.2020 to 20.2.20	13		17		15		12	THEORY EXAMS
SAT	15		14	2 ND SATURDAY HOLIDAY	18		16	OPENDAY/EXHIBITIONS (Higher Semesters)	13	SECOND SEM
SUN	16		15		19		17		14	15.06.20 to 04.07.20
MON	17		16		20		18		15	
TUE	18	PHASE-2 INDUCTION	17	FIRST INTERNAL ASSESSMENT	21		19		16	PRACTICAL EXAMS
WED	19	PROGRAMME	18	2 nd , 4 th ,6 th & 8 th Semesters	22	GUEST LECTURE 2	20		17	2 nd ,4 th & 6 th SEMESTERS
THU	20	10.2.2020 to 20.2.20	19		23		21	THIRD INTERNAL ASSESSMENT 2 nd , 4 th ,6 th & 8 th Semesters	18	03.06.20 to 13.06.20
FRI	21	MAHASHIVARATHRI-GH	20		24	BATTLE OF SCIENCE EVENT (First Year)	22		19	GRADUATION DAY AFTER 20.7.2020
SAT	22	4 TH SATURDAY HOLIDAY	21	Alumni Day (Tentative)	25	4 TH SATURDAY HOLIDAY	23	4 [™] SATURDAY HOLIDAY	20	
SUN	23		22		26		24		21	
MON	24		23		27		25	RAMJAN GH	22	
TUE	25		24		28		26		23	
WED	26		25	UGADI-GH	29	SECOND INTERNAL ASSESSMENT 2 nd , 4 th ,6 th & 8 th Semester	27		24	
THU	27		26		30		28	LAB TESTS	25	
FRI	28		27				29	2 nd ,4 th ,6 th & 8 th SEMs	26	
SAT	29		28	4 TH SATURDAY HOLIDAY		0 0 .	30		27	
SUN			29			C.s. walniberjus_	31		28	(9) Swamp
MON			30			U. ,			29	CITY ENGINEERING COLLEGE
TUE			31						30	



# **Department of Electronics and Communication Engineering**

## **COURSE ALLOCATION**

ACY: 2019-20 (even)

SI No	Name of the Faculty	Course code and Name	Year& Semester	Signature
1	Prof. Mallekarjuna.G.S	ITECHS MP ITECLAT MP Lab	卫/亚	Ps
2	Prof. Shalini Prasad	1950.44 PCS 17 Срнз9 СІР 17 ЕССАР УР Саб	11回 11回 11回	S. Prus
3	Prof. Rowindra. S	ISEC82 FON	121	galas
4	Prof. Shylaja. K	17EC43 CS ISECLOS CN'Lab	回过	Stork U.
5	Prof. Madhavi. J Kullcarni	ISECGSI Cellular mobile commin ISEC833 Rodon Eng.	and a second	insk
b	Prof. Gopskishan. J	17ECL48 LIC LAS	可)可 可(12	AR.
7	Prof. Vishva Lian, RC	ISECG63 DSDN 17ECL47 SUP GB	回 11 卫110	A
8	Prof. Deepa Mathews. K	17EC42 StS 15EC168 CN66	<u>ছ</u> । ভা	pp



Department of Electronics and Communication Engineering

SI No	Name of the Faculty	Course code and Name	Y: 2019 - Year& Semester	Signature
09.	Proj. Radhie Ka. T.S	ISEC64 CEN 17ECL47 SUP 65	回 回 回 回	Rodhel
10.	S.K.L. Narayan	ISEC61 DC ISEC835 Network4 CS		sklurr
[].	Prof. Kreishing - K.S	15EC63 VLSI design 15ECS86 Semidran 10ECS86 Seminar		Kall.
2.	Proj. Chandra Noiele-G	15EC62 Arm controller 15EC84 Intenship 10ECP85 Project Word	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	chard
13.	Dr. Sridhar. S.B	ISECOI Litrelus cellular	<b>逊</b> /亚	Sb
14.1	Roy Ranguath - S. L	10EC81 Wireless Lounds	छ । र्गेष	Rat.
15	Geethanjali	IDEC 82 DSS	R/VIII	huntur
16	Prof. Nanditha-H.G	IDEC832 NS	JE [VII]	Buoll
IJ.	Prof. Szavanthi Rowi	IDEC843 GSM		SB.

HOD, ECE Professor & Head Dept. of Electronics & Communication Engineering City Engineering College, Doddatalescendre, Kenckspura Main Rosc Remain musication 51



## **Department of Electronics and Communication Engineering**

COURSE PREFERENCE

ACY: 2019-20 (BVEN)

Name of the Faculty: Shalin Plasad

Designation: Asst- Profeesor,

SI No	Course code and name	Year/Semester
۱	17EC44 - PCS	近)45
2	17 EC CPH 29 - CIP	D/ 4th
3	MECL 47 - MP lab	II   wth
4	17ECL 47 - MP lab 15EC82 - Fiber optie Networks	Ju   ett.

S. Prasad Faculty

iconjus .S.ma

Professor & Head Dept. of Electronics & Communication Engineering City Engineering College, Ovdelatelassidra, Karakapura Main Bosw⁴ Bengshun-580 061,

# 4TH SEM

Dept. of E&CE				<b></b>					A107
	1	2	TEA BREAK	3	4	LUNCH BREAK	5	6	7
	9:15 10:10	10:10 11:05	11:05 11:20	11:20 12:15	12:15 13:10	13:10 14:00	14:00 14:50	14:50 15:40	15:40 16:30
Мо	18EC44	18MAT4 1		18EC45	18EC42		18ECL4 Batch 1	VIX	/ GSM
	Vanitha	Gayathri		Ravi	MJK	-	18ECL4 Batch 2	¹⁸ Koti / S	Shylaja
Tu	18MAT4	18EC45		18EC46	18EC43		18ECL4 Batch 1	¹⁸ Koti	/ Ravi
TU	Gayathri	Ravi		VKI	SRK	×	18ECL4 Batch 2	¹⁷ VK /	Deepa
	18EC42	18EC46	AK	18EC44	18EC43	BREAK	18EC46	18EC43	18EC45
We	MJK	VKI	BREAK	Vanitha	SRK	B B B B B B	VKI	SRK	Ravi
Th	18EC46	18MAT4 1		18EC43	18EC45	Т С	18EC44	18EC42	18EC43
	VKI	Gayathri	TEA	SRK	Ravi	LUNCH	Vanitha	MJK	SRK
Fr	18MAT4 1	18EC42		18EC44	18EC45		Dept /(	Club/Edu	Sat Act
	Gayathri	MJK		Vanitha	Ravi				Satriot
	18EC43	18EC46		18EC42	18EC44				
Sa	SRK	VKI		MJK	Vanitha				aSc Timetables

# **6TH SEM**

Dept. of E&CE				••••					A106
	1	2	TEA BREAK	3	4	LUNCH BREAK	5	6	7
	9:15 10:10	10:10 11:05	11:05 11:20	11:20 12:15	12:15 13:10	13:10 14:00	14:00 14:50	14:50 15:40	15:40 16:30
Мо	17EC64	17EC65 4		17EC62	17EC66 3		17EC63	17EC61	17EC64
	Ranga	GK		Shalini	VK		SKLN	Radhika	Ranga
Tu	17EC66 3	17EC64		17EC62	17EC61		17EC63	17EC64	17EC65 4
	VK	Ranga		Shalini	Radhika	X	SKLN	Ranga	GK
We	17EC61	17EC65 4	AK	17EC66 3	17EC64	BREAK	17ECL6 Batch 1	³⁷ Shali	ni / VK
	Radhika	GK	BREAK	VK	Ranga		17EC Batch 2	èepa / S	Shylaja
Th	17EC63	17EC61		17EC66 3	17EC62	Н С	17EC Batch 1	èepa / S	Shylaja
	SKLN	Radhika	TEA	VK	Shalini	-UNCH	17ECL6 Batch 2	³⁷ Shalini	/ Ravi
Fr	17EC65 4	17EC61		17EC62	17EC63		Dept./(	Club/Edu	Sat Act
	GK	Radhika		Shalini	SKLN				
Sa	17EC62	17EC63		17EC66 3	17EC65 4				
	Shalini	SKLN		VK	GK				aSc Timetables

# 8TH SEM

Dept. of E&CE									A105	
	1	2	TEA BREAK	3	4	LUNCH BREAK	5	6	7	
	9:15 10:10	10:10 11:05	11:05 11:20	11:20 12:15	12:15 13:10	13:10 14:00	14:00 14:50	14:50 15:40	15:40 16:30	
Мо	15EC81 Geetha	15EC83 5 Shylaja		15EC82 Krishna	15EC83 5 Shylaja			Semina	r	
Tu	15EC82 Krishna	15EC81 Geetha		15EC83 5 Shylaja	15EC82	×	Seminar			
We	15EC83 5 Shylaja	15EC81 Geetha	REAK	15EC82 Krishna	15EC81 Geetha	BREAK	Internship			
Th	Projec	t Work	TEA BREAK	Projec	t Work	LUNCH		ork		
Fr	Project Work		Projec	t Work			Project Wo	ork		
Sa	Project Work			Projec	t Work			Project W	ork	

Timetable generated:05-02-2020

WEF: 10TH FEB 2020

# Prof. Vishvakiran

Dept. of E&CE			110	I. VIOI	Ivani				
	<b>1</b> 9:15 - 10:10	<b>2</b> 10:10 - 11:05	TEA BREAK 11:05 - 11:20	<b>3</b> 11:20 - 12:15	<b>4</b> 12:15 - 13:10	LUNCH BREAK 13:10 - 14:00	<b>5</b> 14:00 - 14:50	<b>6</b> 14:50 - 15:40	<b>7</b> 15:40 - 16:30
Мо									
Tu				18EC46 <b>4EC</b>		¥			
We		18EC46 <b>4EC</b>	REAK			BREA	18EC46 <b>4EC</b>		
Th	18EC46 <b>4EC</b>		TEA BREAK			LUNCH BREAK			
Fr			•						
Sa Timetable genera		18EC46 <b>4EC</b>							aSc Timetables

Timetable generated:05-02-2020

.S. malilconjus

Professor & Head Dept. of Electronics & Communication Engineering City Engineering College, Ocodatellas andra, Kanakapura Main Ross Bengsium-580 061,

aSc Timetables

#### B. E. (EC / TC) Choice Based Credit System (CBCS) and Outcome Based Education (OBE) SEMESTER – IV

MICROCONTROLLER			
Course Code	18EC46	<b>CIE Marks</b>	40
Number of Lecture Hours/Week	03	SEE Marks	60
Total Number of Lecture Hours40 (8 Hours per Module)Exam Hours03			
CREDITS – 03			

Course Learning Objectives: This course will enable students to:

- Understand the difference between a Microprocessor and a Microcontroller and embedded microcontrollers.
- Familiarize the basic architecture of 8051 microcontroller.
- Program 8051 microprocessor using Assembly Level Language and C.
- Understand the interrupt system of 8051 and the use of interrupts.
- Understand the operation and use of inbuilt Timers/Counters and Serial port of 8051.
- Interface 8051 to external memory and I/O devices using its I/O ports.

1
RBT Level
L1, L2
•
L1, L2
·
L1, L2, L3
L1, L2, L3
1
L1, L2, L3
of 8051 1.

- Write 8051 Assembly language programs to generate square wave on 8051 I/O port pin using interrupt and C Programme to send & receive serial data using 8051 serial port.
- Interface simple switches, simple LEDs, ADC 0804, LCD and Stepper Motor to 8051 using 8051 I/O ports.

#### **Question paper pattern:**

- Examination will be conducted for 100 marks with question paper containing 10 full questions, each of 20 marks.
- Each full question can have a maximum of 4 sub questions.
- There will be 2 full questions from each module covering all the topics of the module.
- Students will have to answer 5 full questions, selecting one full question from each module.
- The total marks will be proportionally reduced to 60 marks as SEE marks is 60.

#### **Text Books:**

- 1. "The 8051 Microcontroller and Embedded Systems using assembly and C", Muhammad Ali Mazidi and Janice Gillespie Mazidi and Rollin D. McKinlay; PHI, 2006 / Pearson, 2006.
- 2. "The 8051 Microcontroller", Kenneth J. Ayala, 3rd Edition, Thomson/Cengage Learning.

#### **Reference Books:**

- 1. "The 8051 Microcontroller Based Embedded Systems", Manish K Patel, McGraw Hill, 2014, ISBN: 978-93-329-0125-4.
- 2. "Microcontrollers: Architecture, Programming, Interfacing and System Design", Raj Kamal, Pearson Education, 2005.

#### **DEPARTMENT OF ELECTRONICS & COMMUNICATION**

#### LESSON PLAN FOR EVEN SEMESTER FOR ACADEMIC YEAR 2019-20

Course Title: Microcontroller Course Code : 18E		
Total contact hours: L:T:P:S :: 5:1:0:1	End Terry Mader (0	
Internal Marks : 40	End Term Marks : 60	
Semester : IV	Academic year : 2019-20	
Lesson plan Author: Vishva Kiran RC	Date :06/02/2020	

#### PREREQUISITES:

Logic gates, Memory module, Hexa decimal number system, ALP programming concepts, C programming, and serial communication.

#### COURSE OBJECTIVE:

Introduction to microprocessor and micro controller, learning basic features, architecture, addressing modes, instruction sets of 8051, programming concepts ALP, interfacing with memory and peripheral

#### **COURSE OUTCOMES:**

At the end of the course students will be able to:

- 1. Understand features and architecture of 8051
- 2. Explain various addressing modes and instruction sets of 8051
- 3. Write ALP and C programs for 8051 based systems
- 4. Interface various peripherals to 8051
- 5. Design and implement microcontroller-based embedded system
- 6. Know different versions of 8051 microcontroller

#### MODULE-1: 8051 MICROCONTROLLER

Week	Days/ Date	Contents of Unit	Bloom's Taxonomy Level	Course Outcome (CO)
1	1	Introduction to Subject	U, R	CO1
	2	Historical background	U, R	CO1
	3	Microprocessor Vs Microcontroller	U, R	CO1
	4	Embedded System	U, R	CO1
	5	Embedded Microcontrollers	U, R	CO1
2	1	Salient features	U, R	CO1
	2	Pin diagram	U, R	CO1
	3	8051 Architecture block diagram1	U, R	CO1
	4	8051 Architecture block diagram2	U, R	CO1
	5	Registers	U, R	CO1
3	1	SFR Registers	U, R	CO1
	2	I/O ports functions	U, R	CO1
	3	Internal Memory organization- reg banks	U, R	CO1
	4	Internal Memory organization - BAR	U, R	CO1
	5	External Memory (ROM & RAM) interfacing	U, R	CO1

Week	Days/ Date	Contents of Unit	Bloom's Taxonomy Level	Course Outcome (CO)
4	1	Addressing Modes	U, R, A1, A2	CO1
	2	Addressing Modes	U, R, A1, A2	CO1
	3	Data Transfer instructions	U, R, A1, A2	CO1
	4	Data Transfer instructions	U, A1, A2	CO1
	5	Data Transfer instructions	U, A1, A2	CO1
5	1	Arithmetic instructions	U, A1, A2	CO1
	2	Arithmetic instructions	U, A1, A2	CO1
	3	Arithmetic instructions	U, A1, A2	CO1
	4	Logical instructions	U, A1, A2	CO1
	5	Logical instructions	U, A1, A2	CO1
6	1	Branch instructions	U, A1, A2	CO1
	2	Branch instructions	U, A1, A2	CO1,CO4
	3	Bit manipulation instructions	U, A1, A2	CO1,CO4
	4	Simple ALP examples	U, A1, A2	CO1,CO4
	5	Simple ALP examples	U, A1, A2	CO1,CO4

#### MODULE-2: 8051 INSTRUCTION SET

MODULE-3 : 8051 STACK, I/O PORT INTERFACING AND PROGRAMMING

Week	Days/ Date	Contents of Unit	Bloom's Taxonomy Level	Course Outcome (CO)
7	1	8051 Stack	U, <b>R</b> ,A1,A2,E	CO2
	2	Stack and Subroutine instructions	U, <b>R</b> ,A1,A2,E	CO2
	3	Assembly language program examples on subroutine	U,R,A1,A2,E	CO2
	4	and involving loops - Delay subroutine	U, <b>R</b> ,A1,A2,E	CO2
	5	Factorial of an 8 bit number (result max 8 bit)	U,R,A1,A2,E	CO1,CO2
8	1	Block move without overlap	U, <b>R</b> ,A1,A2,E	CO1,CO2
	2	Addition of N 8 bit numbers	U,R,A1,A2,E	CO1,CO2
	3	Picking smallest/largest of N 8 bit numbers	U,R,A1,A2,E	CO1,CO4
	4	Interfacing simple switch to I/O ports	U,R,A1,A2,E	CO1,CO4
9	1	Interfacing simple LED to I/O ports	U,R,A1,A2,E	CO1,CO4
	2	to switch on/off LED with respect to switch status	U,R,A1,A2,E	CO1,CO2
	3	Example programs	U, <b>R</b> ,A1,A2,E	CO1,CO2
	4	Example programs	U,R,A1,A2,E	CO1,CO2

#### MODULE-4: 8051 TIMERS AND SERIAL PORT

Week	Days/ Date	Contents of Unit	Bloom's Taxonomy Level	Course Outcome (CO)
10	1	8051 Timers and Counters Operation	U, A1, A2	CO1,CO3
	2	8051 Timers and Counters Operation CNTD	U, A1, A2	CO1,CO3
	3	ALP to generate a pulse using Mode-1	U, A1, A2	CO1,CO3
	4	square wave using Mode-2 on a port pin	U, A1, A2	CO1,CO3
	5	8051 Serial Communication- Basics of Serial Data Communication,	U, A1, A2	C01,C03
11	1	RS-232 standard	U, A1, A2	CO1,CO3
	2	9 pin RS232 signals	U, A1, A2	CO2
	3	Simple Serial Port programming in Assembly	U, A1, A2	CO2
	4	Simple Serial Port programming in C	U, A1, A2	CO1,CO3
	5	Transmit a message and to receive data serially	U, A1, A2	CO1,CO3

#### MODULE-5: 8051 INTERRUPTS AND INTERFACING APPLICATIONS

Week	Days/ Date	Contents of Unit	Bloom's Taxonomy Level	Course Outcome (CO)
12	1	8051 Interrupts	U,R, A1	CO5
	2	Types of interrupts	U,R, A1	CO5
	3	8051 Assembly language programming to generate an external interrupt using a switch	U,R, A1	CO5
	4	8051 C programming to generate a square waveform on a port pin using a Timer interrupt	U,R, A1	C01,C05
	5	Interfacing 8051 to ADC-0804	U,R, A1	CO1,CO5
13	1	LCD 8051 Assembly language interfacing programming	U,R, A1	C01,C05
	2	Stepper motor and their 8051 Assembly language interfacing programming	U,R, A1	CO6
	3	Example programs	U,R, A1	CO6
	4	Example programs	U,R, A1	CO6
	5	Example programs	U,R, A1	CO6

#### **Bloom's Taxonomy Level**

R-Remembering U-Understanding A1-Applying A2-Analysing E-Evaluating C-Creating

#### TEXT BOOKS:

- 1. "The 8051 Microcontroller and Embedded Systems using assembly and C "-, Muhammad Ali Mazidi and Janice Gillespie Mazidi and Rollin D. McKinlay; PHI, 2006 / Pearson, 2006.
- 2. "The 8051 Microcontroller", Kenneth J. Ayala, 3rd Edition, Thomson/Cengage Learning.

#### **REFERENCE BOOKS:**

- 1. "The 8051 Microcontroller Based Embedded Systems", Manish K Patel, McGraw Hill, 2014,
- 2. "Microcontrollers: Architecture, Programming, Interfacing and System Design", Raj Kamal, Pearson, 2005.

#### List of URLs-Text Books, Notes, Multimedia Content, etc

http://nptel.ac.in/courses/Webcourse-contents/IIT-KANPUR/microcontrollers/micro/ui/Course_home2_5.htm https://www.youtube.com/watch?v=pA6K5NgWTow http://nptel.vtu.ac.in/VTU-NMEICT/MC/weblinks.pdf

@ Visha Winaw

**Signature of Faculty** 

Ce.s. malithenjus

Signature of HOD

	Module Wise Assignment Questions – 18EC46 MICROCONTROLLER
	1. What is an embedded system and embedded microcontroller? List its applications.
	2. Differentiate between microprocessor and microcontroller with respect to their architecture and instructions.
	3. Describe the hardware features of 8051 microcontrollers, with a neat architecture block diagram.
<b>H</b>	4. Show how to interface external PROM and external RAM to 8051. Explain how 8051 access them.
Module	5. Explain how 4K×8 bit RAM and 8K×8 bit EPROM can be interfaced to 8051 with necessary control signal consider external memory such that the starting address of ROM is 1000H and RAM is C000H.
M	6. Briefly discuss the uses of A, B and PSW registers. Write bit pattern of PSW register and explain the conditional flags present in PSW.
	7. How many SFR's present in 8051 and write the bit addressable SFR's present in 8051 with its address?
	8. Explain the organization of internal RAM memory of 8051.
	9. Explain the oscillator circuit and a machine cycle of 8051 microcontroller.
	10. Sketch the neat diagram of 8051 PIN-OUT and explain its pins: ALE, RST,
	PSEN, EA, RD, WR, TXD & RXD

1. Explain the different addressing mode of 8051. Give an example for each one of
them.
2. Discuss the address ranges that are utilized by jump and call instructions.
3. Explain byte and bit level logical OR operation with examples.
4. Explain how MUL and DIV instruction works with an example in 8051
microcontroller.
5. Explain all the format of XOR and AND operations in 8051.
6. Explain how the following instructions works with an example
a. MOVC A, @A+DPTR
b. DA A
c. SJMP rel
d. DJNZ Rn, rel.
e. JNC rel
f. ANL A, Rn
g. XCHD A, @R0
h. SWAP A
i. CJNE A, 10H LOOP
j. MOVX A, @DPTR
k. MOVC A, @A+PC
7. Which of the following 8051 instructions are wrong and why?
a. MOV A,@R3
b. MOV R1,R2
c. ADD 10H, 11H
d. INC DPTR.

	1. With a neat diagram, explain the sequence of events of PUSH, POP, ACALL and RET instructions stack area of internal RAM with an example.
	-
	2. What are the benefits of subroutines? Mention the advantages of subroutine.
	3. Discuss two instructions used to call subroutines with their ranges and write the
	significance of stack with respect to all instructions.
	4. Find the time required to execute the following instructions if AT89C51
	microcontroller is used:
	a. ADDC A,#54 if XTAL frequency is 12 MHz
	b. XRL 35, #47h if XTAL frequency is 11.0592
	c. MUL AB if XTAL frequency is 12 MHz
	d. NOP if XTAL frequency is 11.0592MHz
~	
	5. Calculate the delay produced in the program shown and XTAL used is of value
l l	11.0592 MHz.
lp	MOV R2, #250
Module 3	LOOP: NOP
$\mathbf{N}$	NOP
	NOP
	NOP
	DJNZ R2, LOOP
	RET
	6. For an 8051 system of 11.0592 MHz. Find the time delay for the following
	•
	subroutine Delay :
	MOV R3, #250
	BACK: NOP
	NOP
	DJNZ R3, BACK
	RET

	1. Describe the various modes of operation of 8051 Timers. Explain TMOD register format of 8051.
4	
lle	2. List the advantages of serial data communication over parallel and explain briefly
Module	details of SCON register. Explain the procedure 8051 follows to transmit and receive characters serially.
Ň	3. Distinguish between counter and timers of 8051. Explain the mode 1 and mode 2
	operation of timer/counter of 8051. How to start/stop timers of 8051.
	4. Explain the functions of RS232 pins of DB-9 connector.

	1. Briefly explain the software interrupts of 8051. Discuss the role of TCON register
<b>N</b>	in handling interrupts giving its bit details.
-	2. Explain 8051 interrupts (both external & internal) and the procedure to enable/disable/mask them.
Module	3. Bring out the difference between interrupts and polling. Explain interrupt priority register of 8051 microcontroller.
	4. Explain the bit pattern of IE register and how (i) to enable the serial interrupt, time R0 interrupt and external hardware interrupt in 8051.

#### Assembly Language Programs (ALP) and C Programs from Last Three Modules

#### Module 3, Module 4, Module 5

- ALP or C Programs
- All the Non-Interfacing Lab Experiments are *Important. Additionally Some ALP which occurred in the Previous Papers.
  - 1. Write a program to copy the value 55H into RAM location 40H to 45H using
    - Direct addressing, without using loop.
    - *Register indirect addressing, without using loop.*
  - 2. Assume that register A has packed BCD, Write an 8051 ALP program to convert packed BCD to two ASCII numbers and place them in address 60H and 61H.
  - 3. Write a program to add the BCD numbers 99 and 85 present in RAM address 32 and 33. Store the BCD result in memory location 34 and 35. Also show how the BCD instruction works.
  - 4. Write an ALP to find the value of an expression S = [(M/N)+30H] of M and N are stored in the internal memory locations 22H and 23H respectively. Store the result in 24H.
  - 5. Write an 8051 subroutine program to initialize 8051 serial port to operate in the mode 0 transmission.
  - 6. Write a C program using interrupts to do following.
    - *Receive data serially and send it to P0.*
    - *Read Port P1, transmit data serially and give a copy to P2.*
    - *Make timer 0, to generate a square wave of 5 KHz frequency on P0.1.*

Assume XTAL = 11.0592 MHz with baud rate at 4800.

- 7. A switch is connected to pin P2.7 and a stepper motor to port 1. Write a program to monitor the status as of switching and
  - If SW = 0, Stepper motor should rotate clock wise, continuously.
  - If SW = 1, Stepper motor should rotate anti clock wise, continuously.
- 8. Interface 8051 to a stepper motor and write an ALP to rotate it 64° in clockwise direction. Step  $Angle = 2^{\circ}$ .
- 9. Show an interface of 8051 microcontroller with a stepper motor drive circuit and write an ALP to rotate it 5 steps counter clockwise.
- 10. Interface ADC 0804 to 8051 and write an ALP to convert the analog input to digital value. Display the converted data at Port 2.
- 11. Write an ALP to switch on LED connected on P1.3 for 500µSec when INT 1 is activated. XTAL used 12MHz.
- 12. Name the 14 pins present in LCD and show how it can be interfaced to microcontroller 8051 with P1 connected to data lines.
- 13. Write an 8051 C program the send letters 'M', 'D' and 'E' to the LCD using delays.
- _____
  - Ten 8-bit numbers are stored in RAM locations 40H onwards. Write an ALP to find the Largest number and store it in memory location 50H.
     Or

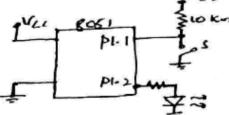
Write an ALP to find largest of five 8 bit numbers (without sorting) stored from location 20_H.

2. Write a program to find the smallest number of an array of N-8 bit unsigned numbers. The starting address is at 2000H and store the result in 2500H.

#### Assembly Language Programs (ALP) and C Programs from Last Three Modules

#### Module 3, Module 4, Module 5

- 3. Write an ALP to read the number from P1 if it is odd find the compliment of the number send it through P2 otherwise send it through P3.
- 4. Write and ALP to verify whether the data present in location 1000H is odd/even. If odd store 00H in location 2000H. Otherwise store EEH in 2000H.
- 5. Write a program to arrange the numbers in ascending order.
- 6. Write an ALP to read switch given in figure. If switch is closed turn ON the LED else turn OFF the LED.



#### 0r

Write an ALP to read the status of witch S connected to P1.2 if it is in the on condition switch on the LED connected P2.2 otherwise off LED connected P2.2.

7. Write an ALP to find factorial of an 8-bit number N. Assume value of N! does not exceed 8-bit. Or

Use subroutine to find the factorial of a number stored in memory location 45H. Assume that the number stored in memory location is  $\leq 05$ .

#### Or

Write a program to find the factorial of a number.

- 8. Write an ALP to find sum of ten 8-bit numbers, stored in the internal memory block starting with 30H. Store the 16 bit sum at locations 40H and 41H.
- 9. Write an ALP to find average of 10 numbers stored in external memory from 1000_H. Store result at 2000_H. Assume sum of those 10 numbers does not exceed 8 bits.
- 10. Write an ALP to move block of 10 data from internal data memory 30_H to external data memory 9000_H.
- 11. Write an ALP to transfer 10 bytes of data from location starting with 8030H to location starting with 8041H without overlap.

0r

Write a program to move a block of data stored in external memory location 9000H to a location staring from F000H (without overlapping).

12. Write a program to count the numbers of 1's and 0's in 8 bit data stored.

- _____
- 1. Write the steps to be followed for using timer 1 in mode 2 and also find the value to be stored in reg. TH1 and get a delay of 100  $\mu$ S when XTAL frequency is 11.0592MHz.
- 2. Write a program to create a delay of 1 sec. assume that the oscillator frequency is 1.2MHz.
- 3. Write an ALP to create a pulse width of 50ms on P2.3 using Timer '0' operating in Mode 1. Assume crystal frequency = 11.0592MHz.
- 4. Write and ALP to generate square wave a frequency of 100 KHz on Pin P1.1. Assume crystal frequency, XTAL = 12 MHz. Use Timer 1 in Mode 1.
- 5. Using time 0 write a program to generate a square wave on P1.4 of frequency of 2KHz in model. Assume XTAL frequency is 11.0592MHz.
- 6. Write an ALP to generate a square wave of frequency 1KHz on P1.3 using Mode 2. Timer 0. Assume crystal frequency = 22 MHz.

#### Assembly Language Programs (ALP) and C Programs from Last Three Modules

#### Module 3, Module 4, Module 5

- 7. Write a program using interrupts to get data from P1.0 and send it to P2.0, while timer 0 is generating a square wave of 4 KHz, on P2.4. Assume XTAL frequency as 11.0592 MHz.
- 8. Write a C-program that continuously gets a single bit of data from P1.7 and sends it to P1.0, while simultaneously creating a square wave of  $200\mu s$  period on pin P2.5. Use timer 0 to create the square wave. Assume XTAL = 11.0592 MHz
- 9. Write an ALP to generate a rectangular wave with an ON time of 3ms and an OFF time of 10ms on all pins of port 0. Assume XTAL of 22MHz. Use timer 0 in mode 1.
- 10. Write a C Program for 8051 to transfer the letter 'V' serially at 9600 baud continuously use 8bit data and 1 stop bit.
- 11. Write an 8051 'C' program to receive data bytes serially and put them in P1. Set the baud rate at 4800, 8 bit data and 1 stop bit. Assume XTAL frequency as 11.0592 MHz.
- 12. Write an ALP to transfer a 'M' serially at 9600 baud rate continuous by through P3.1. Assume XTAL frequency as 11.0592 MHz.
- 13. Write a program to transfer the message 'HELLO' serially at 4800 baudrate with 1 stop bit.
- 14. Write a program for 8051 to transfer the message "GOOD LUCK" serially at baud rate of 9600, 8 bit data with 1 stop bit. Do this continuously, use assembly language?
- 15. Write an 8051 C program to transfer the message 'GOD' serially at 9600 baud rate with XTAL = 11.0592 MHz.
- _____

		Module – 1 Questions Bank MICROCONTROLLER – 18EC46	
		1a. Compare and contrast microprocessors and microcontrollers.	04
	Jan 2018	1b. What does the term Embedded system mean?	02
		1c. Describe the hardware features of 8051 microcontrollers, with a neat internal	
		block diagram.	10
	2010	2a. Briefly discuss the uses of A, B and PSW registers.	06
		2b. Show how to interface external PROM and external RAM to 8051. Explain	
		how 8051 access them.	10
2		1a. Differentiate between microprocessor and microcontroller with respect to	
E		their architecture and instructions.	06
II	Jun	1b. With a diagram, explain the architecture and features of 8051	
RO	2018	microcontroller.	10
E	2010	2a. What is an embedded system and embedded microcontroller?	02
õ		2b. Explain the oscillator circuit and a machine cycle of 8051 microcontroller.	06
2015 SCHEME – 15EC563 8051 - MICROCONTROLLER		2c. Explain the internal memory organization in 8051.	08
RC		1a. What is a micro controller? Mention its applications.	04
		1b. With a neat block diagram explain the features of 8052 microcontroller.	06
	Jan	1c. Mention the internal RAM organization in 8051	06
12	2019	2a. With a neat functional block diagram explain the architecture of 8051.	08
80		2b. Design a microcontroller system using 8051 microcontroller, 4kbytes of ROM	
63		and 8k bytes of RAM interface the external memory such that the starting	00
CS		address of ROM is 1000H and RAM is C000H	08
SE		1a. i) Differentiate between microprocessor and microcontroller.	04
		ii) What is an Embedded Microcontroller and What is an Embedded System?	02
E	Jun	1b. Sketch the neat diagram of 8051 PIN-OUT and explain its pins:	10
E	2019	ALE, RST, PSEN, EA, RD, WR, TXD & RXD	10
H		2a. Explain the organization of internal RAM memory of 8051.	08
SC		2b. show the interfacing connections of external EPROM and RAM to the 8051	00
15		Microcontroller and explain how 8051 access them.	08 04
20		1a. Compare microprocessor and microcontroller.	04 04
		1b. Explain the internal organization of 8051 microcontroller RAM.	04 08
		<ul><li>1c. Write the block diagram of 8051 and explain its features.</li><li>2a. Write bit pattern of PSW register and explain the conditional flags present in</li></ul>	Vð
	Jan	PSW.	04
	2020	2b. How many SFR's present in 8051 and write the bit addressable SFR's present	04
		in 8051 with its address.	04
		<b>2c. Explain how 4K×8 bit RAM and 8K×8 bit EPROM can be interfaced to 8051</b>	<b>VT</b>
		with necessary control signal.	08
<u> </u>		with necessary control signal.	00

		Module – 2 Questions Bank MICROCONTROLLER – 18EC46	
		3a. Explain any 4 data addressing modes of 8051 with an example for each mode. 3b. Show the status of CY, AC and P flags after execution of following instructions.	06
	Jan 2018	<ul> <li>i) MOV A, #9CH</li> <li>ii) ADD A, #64H</li> <li>3c. Write a program to copy the value 55H into RAM location 40H to 45H using</li> <li>i) Direct addressing, without using loop.</li> <li>ii) Register indirect addressing, without using loop.</li> </ul>	04 06
		4a. Discuss the three address ranges that are utilized by jump and call	
		<ul><li>instructions.</li><li>4b. Explain byte and bit level logical OR operation with examples.</li><li>4c. Write and ALP to verify whether the data present in location 1000H is</li></ul>	06 04
		odd/even. If odd store 00H in location 2000H. Otherwise store EEH in 2000H.	06
LER		<ul> <li>3a. Explain the different addressing mode of 8051. Give an example for each one of them.</li> <li>3b. Mention the function of the following instructions of 8051 CPU : <ul> <li>i) MOVC A, @A+DPTR</li> </ul> </li> </ul>	08
NTROL		<ul> <li>ii) DA A</li> <li>iii) SJMP rel</li> <li>iv) DJNZ Rn, rel.</li> </ul>	05
CROCO	Jun	3c. Explain the functions of following pins of 8051 :         i)       ALE         ii)       EA	
III	2018	iii) RST	03
IE – 15EC563 8051 - MICROCONTROLLER		<ul> <li>4a. Explain all the format of XOR and AND operations in 8051.</li> <li>4b. Which of the following 8051 instructions are wrong and why? <ul> <li>i) MOV A,@R3</li> <li>ii) MOV R1,R2</li> <li>iii) ADD 10H, 11H</li> <li>iv) INC DPTR.</li> </ul> </li> <li>4c. Assume that register A has packed BCD, Write an 8051 ALP program to convert packed BCD to two ASCII numbers and place them in address 60H and</li> </ul>	06 04
HEN		61H.	06
2015 SCHEME	Jan	<ul> <li>3a. Explain any 4 different addressing modes used in 8051 microcontroller with suitable illustrations.</li> <li>3b. Explain the following instructions with examples. <ul> <li>i) DJNZ Rn, rel</li> <li>ii) JNC rel</li> <li>iii) ANL A, Rn</li> </ul> </li> </ul>	08
	2019	iv) DA A	08
-		<ul><li>4a. Write 8051 instruction to rotate the contents of A left by two positions.</li><li>4b. Write 8051 instructions to add two BCD numbers and store the result in BCD in register R1.</li></ul>	08 08
	Jun 2019	3a. Explain the four data addressing modes of an 8051 microcontroller with an example for each.         3b. Explain the following instructions:         i)       XCHD A, @R0         ii)       SWAP A         iii)       MOVC A, @A+DPTR         iv)       CINE A, 100 L OOD	06
		iv) CJNE A, 10H LOOP v) DA A	10

	4a. Explain Jump instructions of 8051 with their ranges of Jump.	06
	4b. Write an ALP to find the value of an expression $S = [(M/N)+30H]$ of M and N	
	are stored in the internal memory locations 22H and 23H respectively. Store the	
	result in 24H.	06
	4c. Explain the Logical OR instruction with all possible addressing modes.	04
	3a. Write the any four addressing modes present in 8051 and explain each one of	
	them with an example.	08
	3b. Write a program to add the BCD numbers 99 and 85 present in RAM address	
	32 and 33. Store the BCD result in memory location 34 and 35. Also show how the	
	BCD instruction works.	0
	4a. Explain how MUL and DIV instruction works with an example in 8051	
	microcontroller.	0
Jan	4b. Find the time required to execute the following instructions if AT89C51	
2020	microcontroller is used:	
	i) ADDC A,#54 if XTAL frequency is 12 MHz	
	ii) XRL 35, #47h if XTAL frequency is 11.0592	
	iii) MUL AB if XTAL frequency is 12 MHz	
	iv) NOP if XTAL frequency is 11.0592MHz	0
	4c. Explain how the following instructions works with an example.	
	i) MOVX A, @DPTR	
	ii) MOVC A, @A+PC	04

		Module 3 Questions Dearly MICDOCONTROLLED 19EC46	
		Module – 3 Questions Bank MICROCONTROLLER – 18EC46 5a. What are the benefits of subroutines?	02
		<b>5b.</b> Discuss two instructions used to call subroutines with their ranges and write	02
		the significance of stack with respect to all instructions.	06
	Jan 2018	5c. Ten 8-bit numbers are stored in RAM locations 40H onwards. Write an ALP	
		to find the Largest number and store it in memory location 50H.	08
		<ul> <li>6a. Write an ALP to read switch given in fig. Q6(a). if switch is closed turn ON the LED else turn OFF the LED.</li> <li>Fig.Q6(a)</li> <li>6b. For an 8051 system of 11.0592 MHz. Find the time delay for the following</li> </ul>	04
		subroutine Delay : MOV R3, #250	
		BACK: NOP	
~		NOP	
EE		DJNZ R3, BACK	
<b>DL</b> ]		<b>RET</b> 6c. Write an ALP to find factorial of an 8-bit number N. Assume value of N! does	06
<b>FR</b>		not exceed 8-bit.	0.6
<b>SEC563 8051 - MICROCONTROLLER</b>		5a. With a neat diagram, explain the sequence of events of PUSH, POP, ACALL	06
CC		and RET instructions stack area of internal RAM.	08
RC		5b. Write an ALP to find average of 10 numbers stored in external memory from	00
IIC	Iun	1000 _H . Store result at 2000 _H . Assume sum of those 10 numbers does not exceed 8	
N	Jun 2018	bits.	08
)51	2010	6a. Write an ALP to find largest of five 8 bit numbers (without sorting) stored	
3 8(		from location $20_{\rm H}$ .	08
563		6b. Write an ALP to move block of 10 data from internal data memory $30_{\rm H}$ to external data memory $9000_{\rm H}$ .	08
EC		5a. Write a program tofind the smallest number of an array of N-8 bit unsigned	00
1		numbers. The starting address is at 2000H and store the result in 2500H.	08
ا ل	Jan	5b. Write a program to count the numbers of 1's and 0's in 8 bit data stored.	08
SCHEME	2019	6a. Write a program to arrange the numbers in ascending order.	08
CH		6b. Write a program to create a delay of 1 sec. assume that the oscillator	00
S		frequency is 1.2MHz. 5a. Write an ALP to find the Largest number in an array of 10 bytes. Stored in	08
2015		the internal memory block starting with 20H. Store the result at 60H.	08
7		5b. Write an ALP to find sum of ten 8-bit numbers, stored in the internal memory	
	Jun	block starting with 30H. Store the 16 bit sum at locations 40H and 41H.	08
	2019	6a. Explain the operation of PUSP and POP and LCALL, ACALL and RET	
		instructions of 8051. Giving all the steps involved.	08
		6b. Write an ALP to transfer 10 bytes of data from location starting with 8030H to location starting with 8041H without overlap.	08
	l	5a. What is stack and explain PUSH and POP instruction works with an example.	06
		5b. Calculate the delay produced in the program shown and XTAL used is of	
		value 11.0592 MHz.	
	Icr	MOV R2, #250	
	Jan 2020	LOOP: NOP NOP	
	2020	NOP	
		NOP	
		DJNZ R2, LOOP	05
		RET	00

5c. Write an ALP to read the number from P1 if it is odd find the compliment of the number send it through P2 otherwise send it through P3.	05
<ul> <li>6a. Write an ALP to read the status of witch S connected to P1.2 if it is in the on condition switch on the LED connected P2.2 otherwise off LED connected P2.2.</li> <li>6b. What is subroutine and mention the advantages of subroutine.</li> <li>6c. Use subroutine to find the factorial of a number stored in memory location</li> </ul>	06 05
45H. Assume that the number stored in memory location is $\leq 05$ .	05

		Module – 4 Questions Bank MICROCONTROLLER – 18EC46	
			0.4
. I		7a. Describe the various modes of operation of 8051 Timers. 7b. Write on ALP to exceed a pulse width of 50ms on P2.3 using Timer (0)	04
		7b. Write an ALP to create a pulse width of 50ms on P2.3 using Timer '0' operating in Mode 1. Assume crystal frequency = 11.0592MHz.	06
		7c. Write an ALP to generate a square wave of frequency 1KHz on P1.3 using	VO
		Mode 2. Timer 0. Assume crystal frequency = 22 MHz	06
	Jan	8a. List the advantages of serial data communication over parallel and explain	00
	2018	briefly details of SCON register.	04
		8b. Write an ALP to transfer a 'M' serially at 9600 baud rate continuous by	
		through P3.1. Assume XTAL frequency as 11.0592 MHz	06
		8c. Write an 8051 'C' program to receive data bytes serially and put them in P1.	
		Set the baud rate at 4800, 8 bit data and 1 stop bit. Assume XTAL frequency as	
-		11.0592 MHz	06
		7a. Distinguish between counter and timers of 8051. Explain the mode 1 and	00
		mode 2 operation of timer/counter of 8051. How to start/stop timers of 8051. 7b. Write an ALP to generate a rectangular wave with an ON time of 3ms and an	08
~		OFF time of 10ms on all pins of port 0. Assume XTAL of 22MHz. Use timer 0 in	
ĽE		mode 1.	08
	Jun	8a. Explain the functions of RS232 pins of DB-9 connector.	04
	2018	8b. Explain the procedure 8051 follows to transmit and receive characters	
<b>N</b>		serially.	06
2		8c. Write a program for 8051 to transfer the message "GOOD LUCK" serially at	
õ		baud rate of 9600, 8 bit data with 1 stop bit. Do this continuously, use assembly	
SEC563 8051 - MICROCONTROLLER		language?	06
M		7a. Explain the JUMP and CALL program range with reference to 8051	06
1-		microcontroller. 7b. Write a program to find the factorial of a number.	06 06
805		7c. Write a program to move a block of data stored in external memory location	00
63	Jan	9000H to a location staring from F000H (without overlapping).	04
CS CS	2019	8a. Explain the role of CALL and subroutines in 8051 microcontroller	-
SE		programming.	04
- 1		8b. What are timers and counters? Explain its operations.	06
JE _		8c. Explain timer control register and timer mode control register.	06
2015 SCHEME		7a. Explain TMOD register format of 8051.	04
CH		7b. Explain MODE-1 programming of timers of 8051.	04
Ň		7c. Write and ALP to generate square wave a frequency of 100 KHz on Pin P1.1. Assume emoted frequency $XTAL = 12$ MHz Use Timer 1 in Mode 1	08
103	Jun	Assume crystal frequency, XTAL = 12 MHz. Use Timer 1 in Mode 1. 8a. Explain the principle of operation of serial port of 8051 to transmit and receive	00
	2019	a character serially.	06
		8b. Explain to following RS232 Handshaking signals: RTS and DTR.	02
		8c. Write an 8051 C program to transfer the message 'GOD' serially at 9600 baud	
		rate with XTAL = 11.0592 MHz.	08
		7a. Explain TMOD and SCON register with its bit pattern.	
		7b. Write the steps to be followed for using timer 1 in mode 2 and also find the	05
		value to be stored in reg. TH1 and get a delay of 100 $\mu$ S when XTAL frequency is	0.5
		11.0592MHz.	05
	Jan	7c. Using time 0 write a program to generate a square wave on P1.4 of frequency of 2KHz in model. Assume XTAL frequency is 11.0592MHz.	06
	2020	8a. What are advantages of serial communication over parallel communication?	00
		8b. Write a program to transfer the message 'HELLO' serially at 4800 baudrate	05
		with 1 stop bit.	05
		8c. Write a C Program for 8051 to transfer the letter 'V' serially at 9600 baud	
		continuously use 8-bit data and 1 stop bit.	06

		Module – 5 Questions Bank MICROCONTROLLER – 18EC46	
		9a. Briefly explain the software interrupts of 8051.	04
		9b. Discuss the role of TCON register in handling interrupts giving its bit details.	04
		90. Discuss the role of rCON register in handling interrupts giving its bit details. 9c. Write a program using interrupts to get data from P1.0 and send it to P2.0,	04
		while timer 0 is generating a square wave of 4 KHz, on P2.4. Assume XTAL	
		frequency as 11.0592 MHz.	08
	Jan	10a. A switch is connected to pin P2.7 and a stepper motor to port 1. Write a	00
	2018	program to monitor the status as of switching and	
		If SW = 0, Stepper motor should rotate clock wise, continuously.	
1		If $SW = 1$ , Stepper motor should rotate clock wise, continuously.	08
1		10b. Interface ADC 0804 to 8051 and write an ALP to convert the analog input	00
		to digital value.	08
		9a. Explain 8051 interrupts and the procedure to enable/disable/mask them.	08
		9b. Write a C-program that continuously gets a single bit of data from P1.7 and	00
		sends it to P1.0, while simultaneously creating a square wave of 200µs period on	
R	Jun	pin P2.5. Use timer 0 to create the square wave. Assume $XTAL = 11.0592$ MHz.	08
LE.	2018	10a. Show an interface of 8051 microcontroller with a stepper motor drive circuit	
TL		and write an ALP to rotate it 5 steps counter clockwise.	08
RC		10b. Interface ADC-0804 to 8051-Microcontroller and write a program in	
L		assembly level to read analog data and display the converted data at Port 2.	08
[O]		9a. Explain the 8051 SCON register.	08
00		9b. Write an 8051 subroutine program to initialize 8051 serial port to operate in	
<b>R</b>		the mode 0 transmission.	04
<b>15EC563 8051 - MICROCONTROLLER</b>	Jan	9c. Explain RS – 232 standards.	04
- 1	2019	10a. Bring out the difference between interrupts and polling.	04
51	-012	10b. Explain interrupt priority register of 8051 microcontroller.	04
80		10c. Write an 8051 C program the send letters 'M', 'D' and 'E' to the LCD using	
563		delays.	08
CC:		9a. Interface 8051 to a stepper motor and write an ALP to rotate it 64° in	
15F		clockwise direction. Step Angle = 2°.	08
Ι		9b. Explain the different interrupts of 8051 (both external and internal). How to	
Æ		enabled mask them?	08
SCHEME	Jun	10a. Write a C program using interrupts to do following.	
ΗC	2019	i. Receive data serially and send it to P0.	
S		ii. Read Port P1, transmit data serially and give a copy to P2.	
2015		iii. Make timer 0, to generate a square wave of 5 KHz frequency on P0.1.	
2(		Assume XTAL = 11.0592 MHz with baud rate at 4800.	08
		10b. Write a C Program to send 'M', 'D', 'E' to the LCD using delays.	08
		9a. Explain the bit pattern of IE register and how (i) to enable the serial interrupt,	
		time R0 interrupt and external hardware interrupt in 8051.	04
		9b. Write an ALP that continuously gets 8 bit data from P0 and sends it to P1	
		while simultaneously creating a square wave of 200us on pin P2.1 use timer 0 to	07
		create a square wave and XTAL frequency is 11.0592 MHz.	06
	Jan	9c. Explain how TCON can be used in handling the interrupts and also indicate	04
	2020	its bit pattern.	06
		10a. Write the name of the interrupt present in 8051 and also indicate the starting	05
		address reserved in ROM for each interrupt.	05
		10b. Write a ALP to switch on LED connected on P1.3 for 500µSec when INT 1 is activated. XTAL used 12MHz.	06
		10c. Name the 14 pins present in LCD and show how it can be interfaced to	00
		microcontroller 8051 with P1 connected to data lines.	05
	I	microcontroller ov51 with r 1 connected to data lines.	03



**18EC46** .....Online ....

#### **CITY ENGINEERING COLLEGE** FIRST INTERNAL TEST

Branch: EC Sub Name: Microcontroller Sem & Sec: IV Sem Duration: 1 ¹/₂ hrs.

Date:28/05/2020 Time: 3.30pm – 5.00pm Max Marks: 50

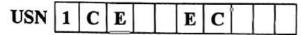
Qn.	Questions	Marks	CO's	BT's
No.	PART-A			
1.	Describe the hardware features of 8051 microcontrollers, with a neat architecture block diagram.	10	CO-2	BT1
	OR			
2.	Explain how MUL and DIV instruction works with an example in 8051 microcontroller.	10	CO-1	BT1
	PART-B			
3.	Explain the organization of internal RAM memory of 8051.	10	CO-2	BT4
	OR			
4.	How many SFR's present in 8051 and write the bit addressable SFR's present in 8051 with its address?	10	CO-2	BT1
	PART-C			
5.	Sketch the neat diagram of 8051 PIN-OUT and explain its pins: ALE, RST, PSEN, EA, RD, WR, TXD & RXD	10	CO-2	BT4
	OR			
6.	Explain the different addressing mode of 8051. Give an example for each one of them.	10	CO-2	BT1
	PART-D			
7.	<ul><li>a. What is an embedded system and embedded microcontroller? List its applications.</li><li>b. Differentiate between microprocessor and microcontroller with respect to their</li></ul>	05	CO-2 CO-1	BT4
	architecture and instructions.	05	0.1	
	OR			
8.	Discuss the address ranges that are utilized by jump and call instructions.	10	CO-2	BT1
	PART-E			
9.	Show how to interface external PROM and external RAM to 8051. Explain how 8051 access them	10	CO-3	BT4
	OR			
10.	Explain the following instructions:i)XCHD A, @R0ii)SWAP Aiii)MOVC A, @A+DPTRiv)CJNE A, 10H LOOPv)DA A	10	CO-3	BT1

**Course Outcomes (CO's):** 

CO1: Understand the difference between a Microprocessor and a Microcontroller and embedded microcontrollers.

CO2: Familiarize the basic architecture of 8051 microcontroller.

CO3: Program 8051microprocessor using Assembly Level Language



#### CITY ENGINEERING COLLEGE FIRST INTERNAL TEST

Branch: EC Sub Name: Microcontroller Sem & Sec: IV Sem Duration: 1 ½ hrs.

.

Date:28/05/2020 Time: 3.30pm – 5.00pm Max Marks: 50

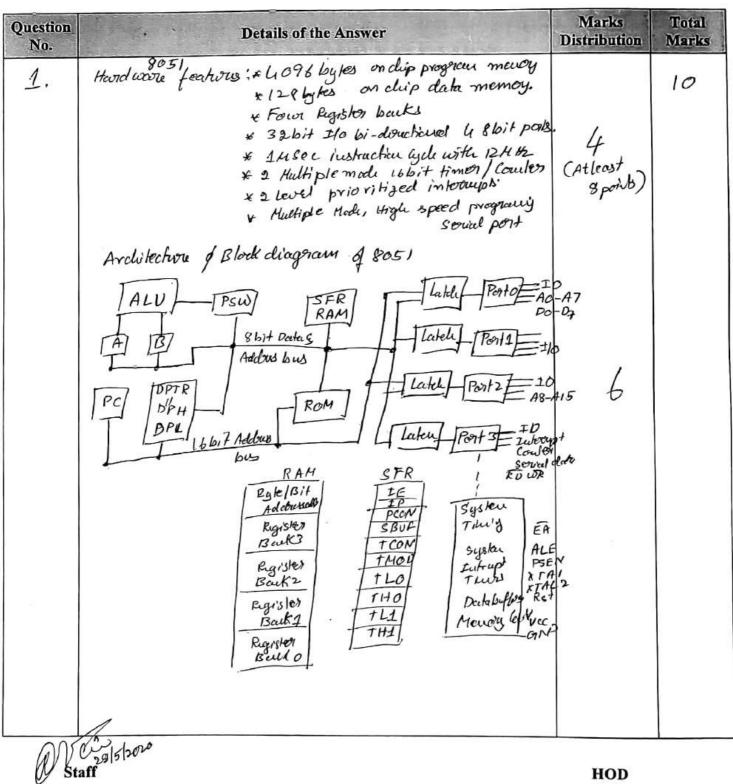
Qn. No.	Questions	Marks	CO's	BT's
	PART-A			
1.	Describe the hardware features of 8051 microcontrollers, with a neat architecture block diagram.	10	CO-2	BT1
	OR			
2.	Explain how MUL and DIV instruction works with an example in 8051 microcontroller.	10	CO-1	BT1
	PART-B		-	
3.	Explain the organization of internal RAM memory of 8051.	10	CO-2	BT4
	OR			
4.	How many SFR's present in 8051 and write the bit addressable SFR's present in 8051 with its address?	10	CO-2	BT1
	PART-C			
5.	Sketch the neat diagram of 8051 PIN-OUT and explain its pins: ALE, RST, PSEN, EA, RD, WR, TXD & RXD	10	CO-2	BT4
	OR			
6.	Explain the different addressing mode of 8051. Give an example for each one of them.	10	CO-2	BT1
	PART-D			
7.	a. What is an embedded system and embedded microcontroller? List its applications. b. Differentiate between microprocessor and microcontroller with respect to their	05	CO-2 CO-1	BT4
	architecture and instructions.	05		
	OR			
8.	Discuss the address ranges that are utilized by jump and call instructions.	10	CO-2	BTI
	PART-E		A	
9.	Show how to interface external PROM and external RAM to 8051. Explain how 8051 access them	10	CO-3	BT4
	OR			
10.	Explain the following instructions: i) XCHD A, @R0 ii) SWAP A iii) MOVC A, @A+DPTR iv) CJNE A, 10H LOOP	10	CO-3	BT
	v) DA A			
Bloo	ms Taxonomy Levels (BTL):BT1- Explain BT4 – Develop rse Outcomes (CO's):			

CO3: Program 8051 microprocessor using Assembly Level Language

## CITY ENGINEERING COLLEGE DEPARTMENT OF ELCECTRONICS & COMMUNICATION ENGINEERING SCHEME FOR VALUATION

INTERNAL TEST:  $\mathcal{I}$ 

28/5/2020 Sub Name: Micro Control ler Date: Sub Code: 18EC46 Semester & Section: IV A



Scheme of Valuation - 2019

HOD

1

Question No.	Details of the Answer	Marks Distribution	Total Marks
2.	MUL S DIV Instruction with examples <u>MUL AB</u> Multiply A × B The 8bit Cankerts of A-ragiston is Hultyphed with 8bit Context of B-ragiston. The 8bit Kultiplication rusults in 16-bit rusult. After Kultiplication the Lower byte of the rusult is available in A-Registon & Higher byte of the Result is available in B-Registon	Q	10
-	Byte: 1 Byte: 1 Cycle: 4 Operative: (A) × (B) -> { Lower byte of Rout in B Re Flags: CY; OV; Noc: Mov A, #05h Mov B, #07H MVL AB Before Neecution After neecution, A=05h B=00h	1 2	
	DIV AB Divide A/B Divide A/B Divide A/B Divide A/B Div AB divides the Carlers of accumulator by the Content of B-Register, The accamulator fucences the quotitient & B Register succeives the sumaculor Byte: 1 Cycles: 4 operative: (A)/B) ~ S.A=quotient B = Remained Flags: Cy; oV;	2	
Sta	1 ( 10/2020) Aff 28/5/2020	нор	

Scheme of Valuation - 2019

2

NV.

# 1CIE - 18EC46-MICROCONTROLLER

Question No.	Details of the Answer	Marks Distribution	Total Marks
	$\begin{aligned} & \mathcal{I}_{\mathbf{X}}: & MoV \ A, \#oFBH & FBL \rightarrow 951d \\ & MoV \ B, \#12H & 12L \rightarrow 18d \\ & DIV \ AB & 18) \frac{13}{951(2)} \\ & \frac{234}{17 \rightarrow (B)} \end{aligned}$	2	
	Before escention After escention, A = FBh (251d) = A = odh (13d) $B = 12h(18d) = 11h (17d)$		
	organization of internal RAM memory of 805)		10
3.	Soln: Internal RAM is also Called as deta memory. It has 128 byte RAM organised in to 3 types @ workling negister B 200 House He master	2	=
Boul Bou Boul Boul	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	<u>B</u> 4-	
	Registers Registers Lugistors, L Bit Aclobusetter herend purpor	4	
4.	SFR's of 8051 = 2/Nb,s Special function Registers are accessed by Using Addres from 804 to FFh	r A S	10

Staff

HOD

Scheme of Valuation - 2019

2

3

1.1	1.5	1		
		0.1	1.4	
A 11.0				
				1.1

Question No.	Details of the Answer	Marks Distribution	Total Marks
	Some location in SFR's on empty Reserved	*	
	Name function Internal Addresses	8	
	A ACCUMalator OEOL		
	DPL Adamsy Herey 824		
	IE IP INTOrryst Priority 088 h		
	PO PI J Input /output goh		
1	P2 little OAOh		
	PCON POWER Cartrol 1 871.		
	Devid Brazza status cold ODOh		
	SBUF Sourced poort Denter 99 h		
	SP stuck pointes 81h TMOD Trun/ Conter Hoch Cartol 89h		
	TCON Timor Coulor Control 884		
	TLO Timer o Lowbyte SAL		
	TII Tint Cow byte 8Bh		
5.	Pin-out of 8051.		10
5.	$P \downarrow O = \frac{1}{2}$ $LO = VCC = +5V$		
	$\begin{cases} p_{1,1} \\ p_{1,2} \\ p_{1,2} \\ q_{1,2} \\ q_{1,2} \\ q_{1,2} \\ q_{1,3} \\ q_$		
1	Porti Piis 4 31 - POIZ (ADZ) PIIS 6 36 - POIZ (ADZ) PIIS 6 36 - POIZ (ADZ) POIZ (ADZ) POITO	\$	
	B1.6 - 7 35 - PO.4 (ADu) (	<i></i> ,	
	RST -9 33 Poil (AD6)		
	$ \begin{pmatrix} (P \times D) & P 3 \cdot O & 10 \\ (T \times D) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I & 11 \\ (I \times T \circ) & P 3 \cdot I $		
Pont3	(INT2) P3.3 - 12 (INT2) P3.3 - 13 (TO) P3.4 - 14 28 - P2.7 (A15) 7		
101	(WR) P3.( 15 26 - 22.5 (413) ( p - 17)		
	$\begin{array}{c c} (PD) P3.7 \\ \hline (PD) P3.7 \\ \hline 17 \\ \hline 17 \\ \hline 24 \\ \hline 17 \\ \hline 23 \\ \hline 12 \\ 12 \\$		
ave	XTAL2 19 22 P2 (49)	HOD	
() ag151	$G_{NP} = 20$ $(4.8)$		,

4

Scheme of Valuation - 2019

# 1CIE - 18EC46- MICROCONTROLLER

Question No.	Details of the Answer	Marks Distribution	Total Marks
	Pins; ALE, RST, PSEN, EA, RD, WR, TXD, RXD ALE = 1 -> Porto is providing loworender Adda ALE = 0 > Porto is used as data lines. RST -> It is active trigh signal, loker a pulse is applied to thus phy the AC will terminate all its activities of Resets. program Gauter is loaded with 0000h PSEN -> Program store enable If the memory access is for the bayle of program Code in the ROM, then PSEN signal goes low of the data byte from the ROM is placed on the data byte from the EA -> Eschemal Accees feld, in internal ROM EA = 4 the Code is stored in internal ROM RD-3> Micro Controlor success the data bies. RD-3> Micro Controlor success the data from RD-3> Micro Controlor success the data into eschemal RAM UR-C-> MC writes the data into eschemal RAM ISD GRXD. The UC hous served data Commuccution concuts the data is Freesming the data from the data into the schemal RAM Iso Code is stored in the data into the code of the data from RD-3> Micro Controlor success the data into the schemal RAM INCOMENTION the data commuccution to the data of the data from RD-3> Micro Controlor success the data into the schemal RAM INCOMENTION the data Commuccution to the data of the	аН Ч	
6.	The dament Addressing Hoches of 8051 with Different Addressing Hoches of 8051 with Immediate Addressing Register Addressing Direct Addressing Register Inderet Addressing Traduced Addressing	At liast 4 with excay 2	10 10
@NE St	Sold/2020	HOD	

Scheme of Valuation - 2019

5

3

Question MERIC Total Details of the Answer No. MERKS Distation Discuss the Adobies stange ultilized 10 8. JAP Fump & Call Justice Her Replaces the contents of program Coulor (pc) with the New address of program escecution to start from theet new adobress. & The difference (in layles) of this New addres of frem address in program blove Funp of Call instruction is called Mango of Jump / Call. Types of Ranges No. of bytes wearples Ranges Relative -128d to+127d FG, FMC, FB, JNB 2 by le Fustricha JBC, JZ, JNZ, DJNZ CINE style with in a page ACALL zistriction Absolute gkbyte 3-byte menony (0-FFFF) Tustrution LCALL Long FFFFhTLADD Livit 1 Nose SADD Limit LIMP Relative hint bitowps AJMP PC+127d Rolatie Merza Ruge byteJugs PC Relatice lihet PC-128d SADD lint Start of this push LADD Court 00001 Staff 5/2020 HOD

Scheme of Valuation - 2019

6

1CIE - 18ECUS- MICROCONTROLLER

Question Marks Total **Details of the Answer** Distation Marks No. Embedded Systen . Embedded : HC 5 10 7. Alleast 8 differer Micro cantrolon Maroprocesson Atleast copuls 18 External PROM & External RAM espand 3 Darter 9, program Po PAM EA cli RD BP. ALE PSEN AO AT X (AO AT) Porto A8-A15 A8-A15 Pont2 RD suples AO AZ Dates A7 AD PO -AS-AIS PLH POTTIO AS A15 p2 eseptein instruction. 10. 10 XCHD A, QRO Lower of A-Reg tex exchange the nilsbes of A-Reg with Centert pointed by RO Addoms Lowen Nubble After execute Before exection HOV A=FFh 2 A= Foh Ro= 50h Ro= 504 50 h=00h 50h=OFh Staff

Scheme of Valuation - 2019

HOD

Question MARIA HOTER Details of the Answer No. Distrillation MERING Bytes: 1 Cegch: 1 SWAP A Scoop nibbles of Accumulater operation = (A3-A0) (A7-A4) Afton scectu Flegs: none Before execution A=59h | A=95h i.e. A=01011001 | i.e. A=10010101 MOVE A, @A+DPTR => Move Code This instruction loads the accurator with a Code byte of Carstant from program memory 1 Cyclis'-2 flegs'. None Beferre excentrer After escertu Byle : 1 A= FPh A = 00h A = FPh DPTR = 1234h DPTR = 1234h1234h = EPh / 1234h= FFh Cochimemery Allors Bater CJNE A, IGH LOOP JCJNE dusthyle, sychyle, horget Compare and Furp if not equal Byte: 3 Cyclus: 2 Florings : CY function PC + PC+ 3 If A = T?] PC - PC+ Hold LOOP else IA L [] there ese DA A -> decimal Adjust Acceleral Har 1 Fyr um Bytes: 1 Cycls: 1 aporation 1 A3-0>9 or Ac=1 In: Mov AF#lith Hen A3-0= A3-0+64 2 MOD A1#38h X-17 Az-4>9 or CY=1 DAA turk Az-4= A7-4+6h HOD

ALTER 2018 11 (1993) 2-2.1111

Scheme of Valuation - 2019



18EC46

#### CITY ENGINEERING COLLEGE SECOND INTERNAL TEST

Branch: EC Sub Name: Microcontroller Sem & Sec: IV Sem Duration: 1 ¹/₂ hrs. Date:10/06/2020 Time: 3.30pm – 5.00pm Max Marks: 50

<b>I</b> . <i>A</i>	PART-A			BT
<b>I</b> . <i>f</i>			L	
1	With a neat diagram, explain the sequence of events of PUSH, POP, LCALL, ACALL and RET instructions stack area of internal RAM.	10	CO-4	BT
1	OR			
	Distinguish between counter and timers of 8051. Explain the mode 1 and mode 2 operation of timer/counter of 8051. How to start/stop timers of 8051.	10	CO-5	BT
	PART-B			
336 L	Write an ALP to transfer 10 bytes of data from location starting with 8030H to location starting with 8041H without overlap.*	10	CO-3	BT
	OR			
- C.S.	a. Explain the functions of RS232 pins of DB-9 connector. b. Explain the procedure 8051 follows to transmit and receive characters	04	CO-5	BT
	serially.	06	005	
19 F	PART-C			
<b>N</b>	Ten 8-bit numbers are stored in RAM locations 40H onwards. Write an ALP to find the Largest number and store it in memory location 50H.*	10	CO-3	BT
	OR			
6. f	Write an ALP to find average of 10 numbers stored in external memory from 1000 _H . Store result at 2000 _H . Assume sum of those 10 numbers does not exceed 8 bits.	10	CO-3	BT
27	PART-D		N1 (8	
	a. What is subroutine and mention the advantages of subroutine.	05	CO-4	
	b. Use subroutine to find the factorial of a number stored in memory location 45H. Assume that the number stored in memory location is $\leq 05.*$	05	CO-3	BT
	OR			
c ł	a. Write an ALP to read the status of witch S connected to P1.2 if it is in the on condition switch on the LED connected P2.2 otherwise off LED connected P2.2. b. For an 8051 system of 11.0592 MHz. Find the time delay for the	05	со-з	
8.	following subroutine Delay : MOV R3, #250 BACK: NOP			BT
20	NOP DJNZ R3, BACK	05	00.5	
	RET PART-E	05	CO-5	

	OR			1
10.	Write a program to create a delay of 1 sec. assume that the oscillator frequency is 1.2MHz.	10	CO-3	BT1

Course Outcomes (CO's):

CO3: Program 8051microprocessor using Assembly Level Language

CO4: Understand the interrupt system of 8051 and the use of interrupts.

CO5: Understand the operation and use of inbuilt Timers/Counters and Serial port of 8051.

CO6: Interface 8051 to external memory and I/O devices using its I/O ports.

Year: 2019-2020

Semester : Odd / Even

Name of the Teacher :	VISHVA KIRAN	
Designation :	Asst. Prof.	
Department :	EÉCE	
Sem/Branch	Subject Code	Subject
14 <u>EC</u>	18EC46	Micro Controller
2		
3		

	Initials at the End of the							
	1st Month	2nd Month	3rd Month	Semester				
Staff	Vin	Uli						
HOD	Cs	ß						
Principal								

# I EC 18EC46 - Micro Controller

# ATTENDANCE

		a second s										T	T	T	T	T
SI.	Reg.No.	Name	10/2	1/2	12/2	13/2	17/2	18/2	29/2	24/2	27/2	26/2	27/2	28/2	2%	2/3
No.			1	2	3	4	5	6	7	8	9	10	11	12	13	14
2018SCH	ICE 16ECO15	INDIRESH . H. BHRAHMADES.	HAN I	2	3	3	4	5	6	1	8	9	10	11	12	13
2	17EC028	JYOTHESH KARNAM	l	2	3	4	5	6	7	2	9	10	4	12	13	14
3	18EC.001	A.T. HARSHITH	Ø	σ	1	2	3	4	5	6	7	g	9	10	11	12_
4	ISEC002	AKANKSHA .G. KULKARNI	1	2	3	Le	5	6	7	8	9	10	11	12	13	14
5	18FC003	AMARJITH .V.S.	1	2	3	4	5	6	7	8	9	10	11	12	13	14
6	18 EC004	ANKIT KUMAR	1	2	3	4	5	6	7	8	9	10	11	12	13	14
7	18EC005	GIANGADHAR P. UPAR	1	2	3	4	5	6	7	F	9	10	4	12	13	14
8	18 EC006	JOYEETA SARKAR	1	2	3	4	5	6	7	8	9	10	11	12	13	14
9	18 ECC07	KARTHIK . P.S	1	2	3	4	5	6	3	8	9	10	11	12	13	14
10	18 EC008	KRUTHIKA S.	t i	2	3	4	5	6	7	8	9	10	11	12	13	14
11	18 E. COO9	KUSHAL .V.V.	1	2	3	4	5	6	-	8	9	10	11	12	13	14
12	ISECOTO	MANOJ KUMAR .R.S.	l	2	3	4	5	6	T	8	9	10	()	12	13	14
13	18EC011	MD. IMRANULLA KHAN	l	2	3	4	5	6	72	8	9	10	ti	12	13	14
14	18 ECO12	NAYANA C.Y.	1	2	3	4	5	6	2	8	9	10	11	12	13	14
15		NOOR FATHIMA AFSAR	1	2	5	4	5	6	7	8	9	10	11	12	13	14
16	18EC014	D	1	2	3	4		6	10	8	9	10	11	12	13.	14
17	ISECOI5		1	2	3	4	5	6	=	8	7	10	11	12	13	14
18	ISE COIL		1	2	3	4	5	6	-	8	9	10	11	12	13	14
19	ISECOIT		1	2	3	4	5	6	T.	8	9	10	"	12	13	14
20	18EC018	The second the second sec	1	2	3	4	5	6	=	7	9	10	11	12	13	14
21	IBECOLO		)	2	3	4	5	6	77	8	9	10	()	12	13	14
22	ISEC020	0.115	1	2	3	4	5	5	77	8	9	10	11	12	13	14
23	18EC021		1	2	3	- <i>L</i> g	5	6	-	8	9	10	11	12	13	14
24	18EC022		1	2	3	4	5	4	-	9	9	10	61	12	13	14
25	18EC023		I	2	3	4	5	2	T		8	9	10	11	12	13
	No. of Abs.															
	Initials		Viei	phi	this	th	the	an a	12	h-	the.	U.	This	2ti	24.	



#### DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

### CIRCULAR

#### Ref. No: CEC/ECE/DAC/2019-2020/01

Date: 24-07-2019

All the members of Department Advisory Committee are informed to attend a meeting which will be held as follows

Date: 25-07-2019 Time: 03.30 PM Venue: LAB A206

#### Agenda:

- Conducting Add-on Course and soft skill training
- Faculty development programme
- Conducting coding, debugging events

C.s. maline

Prof. Mallikarjuna G S

HOD



## DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

#### **Department Advisory Committee Meeting**

Date: 25-07-2019 Time: 03.30 PM Venue: LAB A206

#### DAC Members Present: *

SI. No	Member Name	Designation	Role	Signature
1	Prof. Mallikarjuna G S	HOD	Convenor	Pr. Do u
2	Dr. Shalini Prasad	Professor	Co-Convenor	( Smalillant
3	Prof. Shylaja K	Assistant Professor	Member	aun
4	Prof. Ravindra S	Assistant Professor	Member	0-
5	Prof. Aurobindo Koti	Assistant Professor	Member	-11-to
6	Prof. SKL Narayana	Assistant Professor	Member	eklu

The Department Advisory Committee meeting was conducted at Department of ECE, on 25th July 2019, at

03:30 PM.

#### Agenda of the Meeting:

- · Conducting Add-on Course and soft skill training
- Faculty development programme
- · Conducting coding, debugging events



#### **Minutes of Meeting:**

In the Department Advisory Committee meeting, an overview of the department was presented, emphasizing student achievements, result analysis, and faculty accomplishments. The members discussed various suggestions for improvement and reviewed the meeting agenda.

The Committee proposed the following items for inclusion in the agenda:

- Second and Third year students are encouraged to participate in technical activities and to attend guest lectures or seminars to broaden their knowledge.
- A project exhibition has been proposed, offering final-year students a platform to showcase their work.
- The HOD also briefed about time table preparation, departmental activities.

S. mallithen

Prof. Mallikarjuna G S

HOD

	I Sem B. E. / B. Tech. / B. Arch. (Tentative)	III, V & VII Sem B. E. /B. Tech. III, V,VII & IX Sem B. Arch.	III & V Sem MCA	III Sem MBA	III Sem M. Tech.	III Sem M. Arch.
Commencement of ODD Semester	01.08.2019	29.07.2019	29.07.2019	08.08.2019	26.08.2019	08.09.2019
Last Working day of ODD Semester	29.11.2019	30.11.2019	30.11.2019	05.12.2019	23.12.2019	06.01.2020
Practical Examinations	03.12.2019 To 13.12.2019	03.12.2019 To 13.12.2019	03.12.2019 To 07.12.2019	-		
Theory Examinations	16.12.2019 To 04.01.2020	16.12.2019 То 07.02.2020	09.12.2019 To 28.12.2019	09.12.2019 To 04.01.2020	27.12.2019 To 10.01.2020	08.01.2020 To 22.01.2020
nternship Viva-Voce	-	•	-	a - <u>-</u>	12.01.2020 To 19.01.2020	•
Professional training Organization study	-		•	•	-	-
Commencement of EVEN Semester	27.01.2020	10.02.2020	27.01.2020	27.01.2020	27.01.2020	01.02.2020

#### Academic Calendar of VTU, Belagavi for ODD Semester of 2019-2020 (Jul 2019 - Jan 2020)

Accul All Hode Crown NOTE

- VII Semester B. E / B. Tech students shall have to undergo Internship for a period of four Weeks. .
- . I Semester B. E/ B. Tech / B. Arch Students shall compulsorily undergo Induction Program for a period of 3 Weeks (two phases) as per the schedule given by VTT First phase 11 days in first semester and second phase 10 days in second semester.
- College Time Table shall be arranged for five and a half week days and planned to accommodate EDUSAT transmission slots, the schedule of which will be notifie 1. separately.
- 2. The faculty/staff shall be available to undertake any work assigned by the university.

PRINCIPAL TECHNOS

- If any of the above date is declared to be a holiday then the corresponding event will come into effect on the next working day. Notification regarding Calendar of Events relating to the conduct of University Examination will be issued by the Registrar (Evaluation) from time to time.

REGISTR

	AL	JGUST 2019		SEPTEMBER 2019		OCTOBER 2019		NOVEMBER 2019	DEC	CEMBER 2019
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
S	ARTING	OF HIGHER SEMESTERS			1					
(3 rd ,5	th & 7th S	emesters 29.7.2019 MON)			2	GANDHI JAYANTI(DH)				
THU	1	STARTING OF FIRST SEM			3					
FRI	2				4		1	KANNADA RAJYOTSAVA(DH)		
SAT	3				5		2			
SUN	4		1		6		3		1	
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		2	
TUE	6		3		8	VIJAYA DASHAMI(DH)	5	SECOND CIE FOR FIRST SEM.	3	
WED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9		6		4	
THU	8		5	3 rd ,5 th & 7 th Semesters	10		7		5	
FRI	9		6		11		8		6	
SAT	10	2 ND SATURDAY HOLIDAY	7		12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7	
SUN	11		8		13		10		8	
MON	12	BAKRID(DH)	9		14		11		9	
TUE	13	as in the fact of	10	MOHARAM (DH)	15		12		10 THIRD CIE FOR FIR	
WED	14		11	, · · · · ·	16		13		11	SEM
THU	15	INDEPENDENCE DAY(DH)	12		17		14		12	
FRI	16		13		18		15	KANAKA JAYANTHI(DH)	13	
SAT	17		14	2 ND SATURDAY HOLIDAY	19		16		14	
SUN	18		15		20		17		15	
MON	19		16		21		18		16	
TUE	20		17		22	SECOND INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	19	THIRD INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	17	LAB INTERNALS FOR
WED	20		18		23	3 ,5 & 7 Semesters	20	- 3,5 & 7 Semesters	18	1 st SEMESTERS
THU	22		19		24		21		19	
FRI	23		20		25		22		20	
SAT	23	4 TH SATURDAY HOLIDAY	20	FIRST CIE FOR FIRST SEM.	26	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	LAST WORKING DAY
SUN	25		22		27		24		22	
MON	26		23		28		25		23	
TUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR	24	VTU PRACTICAL:
WED	28		25		30		27	3 rd ,5 th &7 th SEMESTERS	25	1 ST SEMESTER:
THU	29		26		31		28		26	23.12.19 TO 3.1.20
FRI	30		27				29	LAST WORKING DAY 1" SEM	27	THEORY EXAMS : 1 ST SEMESTERS :
SAT	31		28	4 TH SATURDAY HOLIDAY			30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	6.1.20 TO 28.1.2020
SUN			29						29	
MON			30						30	
TUE						4.12.19, THEORY EXAMS : 3 RD ,5			31	0-0-

	AUGUST 2019		SEPTEMBER 2019			OCTOBER 2019		NOVEMBER 2019		DECEMBER 2019	
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	
S	TARTIN	G OF HIGHER SEMESTERS			1						
		Semesters <b>29.7.2019</b> MON)			2	GANDHI JAYANTI(DH)					
THU	1	STARTING OF FIRST SEM			3						
-RI	2				4		1	KANNADA RAJYOTSAVA(DH)			
SAT	3				5		2				
SUN	4		1		6		3		1		
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		2		
ΓUE	6		3		8	VIJAYA DASHAMI(DH)	5	SECOND CIE FOR FIRST SEM.	3		
VED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9		6		4		
гни	8		5	3 rd ,5 th & 7 th Semesters	10		7		5		
R	9		6		11		8		6		
SAT	10	2 ND SATURDAY HOLIDAY	7	INDUSTRIAL VISIT	12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7		
SUN	11		8		13		10		8		
MON	12	BAKRID(DH)	9		14		11		9		
ΓUE	13		10	MOHARAM (DH)	15		12		10	THIRD CIE FOR FIRS	
NED	14		11		16	GUEST LECTURE 2	13		11	SEM	
гни	15	INDEPENDENCE DAY(DH)	12		17		14		12		
FRI	16		13		18		15	KANAKA JAYANTHI(DH)	13		
SAT	17		14	2 ND SATURDAY HOLIDAY	19		16		14		
SUN	18		15		20		17		15		
MON	19		16		21		18		16		
TUE	20		17	GUEST LECTURE 1	22	SECOND INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	19	THIRD INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	17	LAB INTERNALS FO	
NED	21		18		23		20	S ", S " & 7 " Semesters	18	1 st SEMESTERS	
гни	22		19		24		21		19		
FRI	23		20	FIRST CIE FOR FIRST SEM.	25		22		20		
SAT	24	4 TH SATURDAY HOLIDAY	21		26	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	LAST WORKING DAY 1 ST SEM	
SUN	25		22		27		24		22		
MON	26	PTM	23		28		25		23		
ΓUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR	24	VTU PRACTICAL: 1 ST	
NED	28		25		30		27	3 rd ,5 th &7 th SEMESTERS	25	SEMESTER: 23.12.1	
ΓHU	29		26		31		28		26	TO 3.1.20	
-RI	30		27			5	29	LAST WORKING DAY 1 st SEM	27	THEORY EXAMS : 1 ^s SEMESTERS : 6.1.20	
SAT	31		28	4 TH SATURDAY HOLIDAY		Duf Evany	30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	TO 28.1.2020	
SUN			29			CITY ENGINEERING COLLEGE Kanakapura Main Road, BANGALORE - 500 061		P.S. malutenjus			



# Department of Electronics and Communication Engineering

## COURSE ALLOCATION

ACY: 2019-20 (ODD)

SI No	Name of the Faculty	Course code and Name	Year& Semester	Signature
١	G-S. Mallikaljuna	18 ELE13-Babic Electrica Engineerin 17EC35-Nehrokand	63.	li
2	Shalini Prasad	15EC71 - Mil Landenna 10EC74 - ESD 105ECL57-DSP lab	12/74	Schus
3	Ravindea.8.	17EC36 - Enggielectro magnetics 10EC762 - KTS 18ELEL17 - Electrical	瓦17th 王114	Predes
4	Shylaja-K	15ES51 - Refectional Ethicsd Human ISEC755-Sat Common 15ECL76-Adv. Common Lab	IV/7th	548 K
5	Arabindo Koti .	15EC54- ITC 10ECL78-PE Labo 18ELEL17-Electrical	IV (ch IV (rth B(1st	k Koti
6	Madhavi J. Kulakami	17EC33-AELecleani 15EC553- DS 17ECL37-AELab	101502 1013-0	MUS
٩	SKL Narayan	15EC52 - DSP 16EC751- DSPA 10ECL77-V2616	11/5K 12/7K	Steller
8	Vestvallinen R.C.	15EC53 -VHDL 15EC663 - DSDV 15ECL77- VLSIL	前15th 国 15th	Vi



Department of Electronics and Communication Engineering

Sl No	Name of the Faculty	Course code and Name	CY: 2019-20 Year& Semester	Signature
9	Sheavanthi Rais	DEC35 - NA ISECL58 - HOLL	II   3nd Im   5th	S
10	Deepa Mathew. K	17EC34 - Dividad electronic 17ECL38 - DE Lab- 10EC73 - PE	El 224 El 22d El 22d El 47h	Þŧ
Ц	Kerishna, K-S.	10EC72 - DEC 18ELE13 - B. electeric 18ELEL17 - Belecteric	W [14th	18
12	Gopikishan. J.	15EC73 - PE 15EC176 - Adclab	IV 7th	AR.
13	Rangemath . S. L	17EC32 - Electro, Enetenmentati 17EC137-At lalo	of al id	Rat.
14	Geethenjali	18 ELN 14 -basic electr	onice Elist	beethys
15	Radhika . T. S.	15EC76 - DIP 15EC158-HDL lab	JV / 7th JU/5th	Redbird
			-	

(if mod sile HOD, ECE



## ACADEMIC YEAR:2019-20 (ODD)

# DEPARTMENT OF COMPUTER SCIENCE AND ENGINEERING

## COURSE PREFERENCE

Name of the Faculty: Aneobindo Koti Designation: Assorbant Professor

Sl. No	Course Code and Name	Year/Semester
l	ISEC54 - ITC	II / sth
2	15EC553- Operating System	团)5th
3	10ECL78 - PE lale	DInth
4	Basse Electrical Cab- 18ELEL17	211st

Aukot: Signature of Faculty

	AUGUST 2019		SEPTEMBER 2019			OCTOBER 2019		NOVEMBER 2019		DECEMBER 2019	
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	
S	TARTIN	G OF HIGHER SEMESTERS			1						
		Semesters <b>29.7.2019</b> MON)			2	GANDHI JAYANTI(DH)					
ГНО	1	STARTING OF FIRST SEM			3						
-RI	2				4		1	KANNADA RAJYOTSAVA(DH)			
SAT	3				5		2				
SUN	4		1		6		3		1		
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		2		
ΓUE	6		3		8	VIJAYA DASHAMI(DH)	5	SECOND CIE FOR FIRST SEM.	3		
VED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9		6		4		
гни	8		5	3 rd ,5 th & 7 th Semesters	10		7		5		
R	9		6		11		8		6		
SAT	10	2 ND SATURDAY HOLIDAY	7	INDUSTRIAL VISIT	12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7		
SUN	11		8		13		10		8		
MON	12	BAKRID(DH)	9		14		11		9		
ΓUE	13		10	MOHARAM (DH)	15		12		10	THIRD CIE FOR FIRS	
NED	14		11		16	GUEST LECTURE 2	13		11	SEM	
гни	15	INDEPENDENCE DAY(DH)	12		17		14		12		
-RI	16		13		18		15	KANAKA JAYANTHI(DH)	13		
SAT	17		14	2 ND SATURDAY HOLIDAY	19		16		14		
SUN	18		15		20		17		15		
MON	19		16		21		18		16		
TUE	20		17	GUEST LECTURE 1	22	SECOND INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	19	THIRD INTERNAL ASSESSMENT 3 rd ,5 th & 7 th Semesters	17	LAB INTERNALS FO	
NED	21		18		23		20	Jan & Am Semesters	18	1 st SEMESTERS	
гни	22		19		24		21		19		
FRI	23		20	FIRST CIE FOR FIRST SEM.	25		22		20		
SAT	24	4 TH SATURDAY HOLIDAY	21		26	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	LAST WORKING DAY 1 ST SEM	
SUN	25		22		27		24		22		
MON	26	PTM	23		28		25		23		
ΓUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR	24	VTU PRACTICAL: 1 ST	
NED	28		25		30		27	3 rd ,5 th &7 th SEMESTERS	25	SEMESTER: 23.12.1	
ΓHU	29		26		31		28		26	TO 3.1.20	
-RI	30		27			5	29	LAST WORKING DAY 1st SEM	27	THEORY EXAMS : 1 ^s SEMESTERS : 6.1.20	
SAT	31		28	4 TH SATURDAY HOLIDAY		Duf Evany	30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	TO 28.1.2020	
SUN			29			CITY ENGINEERING COLLEGE Kanakapura Main Road, BANGALORE - 500 061		P.S. malutenjus			



## **DEPARTMENT OF ELECTRONICS & COMMUNICATION ENGINEERING**

# **COURSE FILE**

NAME	Vishva Kiran R C
DESIGNATION	Asst. Prof.
SEMESTER	5 th EC
SECTION	"A"
SUBJECT NAME/CODE	17EC53 – Verilog HDL
ACADEMIC YEAR	Odd 2019-20

# CITY ENGINEERING COLLEGE DEPARTMENT OF ... Electronics & Communication Engg.

# CONTENTS

	Individual Time Table						
	Calendar of Events						
	University Syllabus						
	Below average Student's list and Topper's list						
; ]	Lesson Plan						
5	Record of Class Work - Section-wise (Xerox Copy of Attendance Format)						
7	University Question Papers : Min 05						
8	Unit-wise Assignment Question Bank(all units) : Min 08 Questions per Unit						
9	Internal Test:						
	9.1: Attendance Shortage List Test-1, Test -2 & Test-3						
	9.2: Internal Question Paper & Scheme - Test-1, Test-2 & Test-3						
(iii)	9.4: Counseling form						

CITY ENGINEERING COLLEGE

WEF 1ST AUG 2019

# Prof. Vishva Kiran RC

Dept. of E&CE			101. \						
	<b>1</b> 9:15 - 10:10	<b>2</b> 10:10 - 11:05	TEA BREAK 11:05 - 11:20	<b>3</b> 11:20 - 12:15	<b>4</b> 12:15 - 13:10	LUNCH BREAK 13:10 - 14:00	<b>5</b> 14:00 - 14:50	<b>6</b> 14:50 - 15:40	<b>7</b> 15:40 - 16:30
Мо	VERILOG A106								VERILOG A106
Tu					VERILOG A106	¥	VLSI LAB	7EC	
We			REAK			BREA	HDL LAB VLSI LAB	5EC ^{A1} 7EC	
Th		VERILOG A106	TEA BREAK			LUNCH BREAK	HDL LAB	5EC	
Fr		VERILOG A106				L			
Sa	ted:26.07-2019								aSc Timetables

Timetable generated:26-07-2019

aSc Timetables

S.malijcan, In

Professor & Head Dept. of Electronics & Communication Engineering City Engineering College, Ooddatalissandra, Kanakapura Main Rosu Bengsharu-580 061,

					JRU-560061. ACADEMIC CALENDA OCTOBER 2019		1 . 1	NOVEMBER 2019		DECEMBER 2019	
	A	UGUST 2019		SEPTEMBER 2019	1		-	EVENT	Date	EVENT	
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	, LVLNI	Date		
ST	ARTING	OF HIGHER SEMESTERS			1						
(3 rd ,5	th & 7th	Semesters 29.7.2019 MON)		•	2	GANDHI JAYANTI(DH)	-				
THU	1	STARTING OF FIRST SEM	•		3	-		KANNADA RAJYOTSAVA(DH)			
FRI	2				4		1	KANNADA KAJIGISAVA(DII)		10	
TA3	3			2	5		2		1		
EUN	4		1		6	· ·····	3		2		
U(N)	5	1	2	(H303774) ( H21041500 H)	7	(HOLAY ANALASALDH)		STOCKE CIEFCEF457 STM.	4		
1 k	- 17		3	-	8	$\chi_{1}(p, y_{i}) : : (+, +, +) \in \{1, +\}$	5	Streat Greener and the	4		
1 L D	7	F FST SEM INDUCTION	۵	FIFET INTEFICAL ASSESSMENT STILET & 71 Statementors	9		6		5		
* + + i	8		1	5 ,5 G / A / A / A	30				6		
11	51	1	6		11		8	2ND SATURDAY HOLIDAY	7		
TAB	10	21 SATURDAY HOLIDAY	7		12	2ND SATURDAY HOLIDAY	9	2" SATURDAT HOLIDAT	8	Contraction of the	
EUN	11		8		13		10	*	9		
MON	12	EAKRID(DH)	9		14		11		10	THIRD CIE FOR FIRST	
TUE	13		10	MOHARAM (DH)	15		12		11	SEM	
WED	14		11		16		13		12	and the second state	
THU	15	INDEPENDENCE DAY(DH)	12		17		14	KANAKA JAYANTHI(DH)	13		
FRI	16		13		18		15	NAMARA JALANTIN(DII)	14		
SAT	17		14	2ND SATURDAY HOLIDAY	19		16		15		
SUN	18		15		20		17		16		
MON	19		16		21	SECOND INTERNAL ASSESSMENT	18	THIRD INTERNAL ASSESSMENT	17	LAB INTERNALS FOR	
TUE	20		17		22	3rd,5th & 7th Semesters	19	3rd,5th & 7th Semesters	18	1st SEMESTERS	
WED	21		18		23		20				
THU	22		19		24		21		19		
FRI	23		20	FIRST CIE FOR FIRST SEM.	25		22		20	LAST WORKING DAY	
SAT	24	4 TH SATURDAY HOLIDAY	21		26	4 TH SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	1 st SEM	
SUN	25		22		27		24		22		
MON	26		23		28		25		23	VTU PRACTICAL:	
TUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR 3rd,5th &7th SEMESTERS	24	1 ST SEMESTER:	
WED	28		25		30		27	5",5" @/" SEMICSTERS	25	23.12.19 TO 3.1.20	
THU	29		26		31		28		26	THEORY EXAMS :	
FRI	30		27				29	LAST WORKING DAY 1st SEM	27	1 ST SEMESTERS :	
SAT	31		28	4™ SATURDAY HOLIDAY			30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	6.1.20 TO 28.1.2020	
SUN			29						29		
MON	-		30						30		
THE						4.12.19, THEORY EXAMS : 3 RD ,			31		

. 5

RE VSP	VERILOG HD		ooring/
	mester, Electronics & Com Telecommunication E er Choice Based Credit Sys	Engineering	
	17EC53	CIE Marks	40
Course Code		SEE Marks	60
Number of Lecture Hours/Week		SEE MAIRS	00
Total Number of Lecture Hours	50 (10 Hours / Module)	Exam Hours	03
*	CREDITS – C his course will enable stude	the second s	
<ul> <li>Learn different</li> <li>Familiarize the</li> <li>Understand Ve</li> <li>Understand tin</li> </ul>	etween Verilog and VHDL des Verilog HDL and VHDL cons different levels of abstractio crilog Tasks and Directives. ning and delay Simulation. design levels of data flow, b gital circuits.	structs. n in Verilog.	ctural for effective
A	Module-1		
Overview of Digital	Design with Verilog HDL		
Top-down and botton	in <b>g Concepts</b> m-up design methodology, di	ifferences between r	nodules and
Top-down and botton module instances, pa L1, L2, L3	m-up design methodology, di arts of a simulation, design b	olock, stimulus bloc	modules and ck. (Text1)
module instances, pa L1, L2, L3	m-up design methodology, di	olock, stimulus bloc	modules and ck. (Text1)
imodule instances, pa L1, L2, L3 Basic Concepts Lexical conventions, Modules and Ports	m-up design methodology, di arts of a simulation, design b Module-2 data types, system tasks, co oort declaration, connecting	olock, stimulus bloc ompiler directives. ( ports, hierarchical	Ck. (Text1) Text1)
<ul> <li>module instances, pa</li> <li>L1, L2, L3</li> <li>Basic Concepts</li> <li>Lexical conventions,</li> <li>Modules and Ports</li> <li>Module definition, p</li> </ul>	m-up design methodology, di arts of a simulation, design t Module-2 data types, system tasks, co	olock, stimulus bloc ompiler directives. ( ports, hierarchical	Ck. (Text1) Text1)
<ul> <li>module instances, particular instan</li></ul>	m-up design methodology, di arts of a simulation, design b <u>Module-2</u> data types, system tasks, co oort declaration, connecting <u>Module-3</u> g c Verilog gate primitives, de urn-off delays, min, max, an ments, delay specification 1) <b>L1, L2, L3</b>	olock, stimulus bloc ompiler directives. ( ports, hierarchical escription of and/o d typical delays. (To , expressions, op	r and buf/not type ext1)
<ul> <li>module instances, particular definition, particular definit</li></ul>	m-up design methodology, di arts of a simulation, design b <u>Module-2</u> data types, system tasks, co oort declaration, connecting <u>Module-3</u> g c Verilog gate primitives, de urn-off delays, min, max, an ments, delay specification 1) <b>L1, L2, L3</b> <u>Module-4</u>	olock, stimulus bloc ompiler directives. ( ports, hierarchical escription of and/o d typical delays. (To , expressions, op	r and buf/not type ext1)
<ul> <li>module instances, particular descent for the second seco</li></ul>	m-up design methodology, di arts of a simulation, design b <u>Module-2</u> data types, system tasks, co oort declaration, connecting <u>Module-3</u> g c Verilog gate primitives, de urn-off delays, min, max, an ments, delay specification <u>1) L1, L2, L3</u> <u>Module-4</u> g res, initial and always, blo rate statement, event contr	onpiler directives. ( ports, hierarchical escription of and/or d typical delays. (To , expressions, op ocking and non-bl rol, conditional sta	r and buf/not type ext1) erators, operands ocking statements atements, Multiway
<ul> <li>module instances, particular descent for the second seco</li></ul>	m-up design methodology, di arts of a simulation, design b <u>Module-2</u> data types, system tasks, co oort declaration, connecting <u>Module-3</u> g c Verilog gate primitives, de urn-off delays, min, max, an ments, delay specification 1) <b>L1, L2, L3</b> <u>Module-4</u> g res, initial and always, blo	onpiler directives. ( ports, hierarchical escription of and/or d typical delays. (To , expressions, op ocking and non-bl rol, conditional sta . (Text1) <b>L1, L2, L3</b>	rext1) rext1) rame referencing r and buf/not type ext1) erators, operands ocking statements atements, Multiwa
<ul> <li>module instances, particular descent for the second seco</li></ul>	m-up design methodology, di arts of a simulation, design b <u>Module-2</u> data types, system tasks, co oort declaration, connecting <u>Module-3</u> g c Verilog gate primitives, de urn-off delays, min, max, an ments, delay specification 1) <b>L1, L2, L3</b> <u>Module-4</u> g res, initial and always, blo rate statement, event contr quential and parallel blocks. <u>Module-5</u>	onpiler directives. ( ports, hierarchical escription of and/or d typical delays. (To , expressions, op ocking and non-bl rol, conditional sta . (Text1) <b>L1, L2, L3</b>	rext1) rext1) rame referencing r and buf/not type ext1) erators, operands ocking statements atements, Multiwa

Design tool flow, Font conventions.

Entities and Architectures: Introduction, A simple design, Design entities, Identifiers, Data objects, Data types, and Attributes. (Text 2) L1, L2, L3

- Course Outcomes: At the end of this course, students should be able to .
  - Write Verilog programs in gate, dataflow (RTL), behavioral and switch modeling levels of Abstraction.
  - Write simple programs in VHDL in different styles.
  - Design and verify the functionality of digital circuit/system using test benches.
  - Identify the suitable Abstraction level for a particular digital design.
  - Write the programs more effectively using Verilog tasks and directives.
  - Perform timing and delay Simulation.

### Text Books:

1. Samir Palnitkar, "Verilog HDL: A Guide to Digital Design and Synthesis", Pearson Education, Second Edition.

2. Kevin Skahill, "VHDL for Programmable Logic", PHI/Pearson education, 2006.

## **Reference** Books:

- 1. Donald E. Thomas, Philip R. Moorby, "The Verilog Hardware Description Language", Springer Science+Business Media, LLC, Fifth edition.
- 2. Michael D. Ciletti, "Advanced Digital Design with the Verilog HDL" Pearson (Prentice Hall), Second edition.
- 3. Padmanabhan, Tripura Sundari, "Design through Verilog HDL", Wiley, 2016 or

# CITY ENGNEERING COLLEGE

Doddakalsandra, Off kanakapura road, Bangalore 560 061.

Course Title: VERILOG HDL	Course Code: 17EC53		
Total contact hours: L:T:P:S :4:1:1:0	CREDITS – 04		
Internal Marks: 40	End Term Marks : 60		
Semester : V	Academic year : 2019-20		
Lesson plan Author: Vishva Kiran R C	Date : 31/07/2019		

### **Course Objective:**

This course will enable students to:

- Designing digital circuits, behavioral and RTL modeling of digital circuits using Verilog HDL.
- Verifying these models and synthesizing RTL models to standard cell libraries and FPGAs.
- · Students gain practical experience by designing, modeling,
- implementing and verifying several digital circuits.

## Course Outcomes:

After the completion of the course, the student would be able to

- Describe Verilog hardware description languages (HDL). Design Digital Circuits.
- Write behavioral models of digital circuits. Write Register Transfer Level (RTL) models of digital circuits.
- Verify behavioral and RTL models. Describe standard cell libraries and FPGAs.
- Synthesize RTL models to standard cell libraries and FPGAs. Implement RTL models on FPGAs and Testing & Verification.

We ek	Da ys	Mod ule	Main Topics	Sub Topics	Bloom's Taxonomy Level(L)	Course Outcome (CO)
	1	a.	Overview	Evolution of CAD,	U, A1	CO-1
	2		of Digital	emergence of HDLs,	U, A1	CO-1
1	3		Design	typical HDL-flow,	U, A1	CO-1
	4		with Verilog	why Verilog HDL?,	U, A1	CO-1
5	5		HDL	trends in HDLs.	U, A1	CO-1
•	1	I	Hierarchi	Top-down and bottom-up design methodology	U, A1	CO-1
2	2	1	cal Modeling	differences between modules and module instances	U, A1	CO-1
	3	1	Concepts	parts of a simulation	U, A1	CO-1
	4	1		design block, stimulus block.	U, A1	CO-1
	1		1	Lexical conventions,	A1,A2,E	CO-4
	2	1		data types	A1,A2,E	CO-4
3	3	1		Cont. data types	A1,A2,E	CO-4
	4	II I	Basic	system tasks	A1,A2,E	CO-4
÷	5	-	Concepts	Cont. system tasks	A1,A2,E	CO-4
	1	1	1.0	compiler directives	A1,A2,E	CO-4
4	2		147 1. 6	Cont. Compiler directives	A1,A2,E	CO-4

7	T	ī	1	I	Module definition	A1,A2,E	CO-4
	3	-		1 S 1 S -	Cont. module definition	A1,A2,E	CO-4
	4			Modules	port declaration	A1,A2,E	CO-4
21	5	5		and Ports	connecting ports	R,U, A1	CO3
	-	Ι.		a alterna	hierarchical name referencing	R, U, A1	CO3
	-	2.			Modeling using basic Verilog	R, U, A1	CO3
5		5		196 - S. 16	gate primitives Verilog primitives	R, U, A1	CO3
	-	4 5			description of and/or and	R, U, A1	CO3
	*	5		Gate- Level	buf/not type gates Cont. types of description	R, U, A1	CO3
	-	1		Modeling	rise, fall delays	R, U, A1	CO3
		2			turn-off delays	R, U, A1	CO3
6		3			min, max	R, U, A1	CO3
		4	Ш			R, U, A1	CO3
		5		· · · · ·	typical delays	A1,A2,E	CO2, CO4
		1		-	Continuous assignments	A1,A2,E	CO2, CO4
1		2		4	delay specification	A1,A2,E .	C02, C04
7	7	3	20	Dataflow	expressions	A1,A2,E	CO2, CO4
		4	1.1	Modeling	operators,	A1,A2,E	CO2, CO4
. 4		5	1		operands	A1,A2,E	C02, C04
		1			operator types	A1,A2,E	CO2, CO4
	-	2			Structured procedures	A1,A2,E	CO2, CO4
	8 · [	3			initial and always	AI,AZ,E	
		4	]		blocking and non-blocking statements	A1,A2,E	CO2, CO4
	ł	5	-		delay control,	A1,A2,E	CO2, CO4
-	-		1 IV 2 3 4 5	Behaviora	generate statement	R,U	CO5
				I Modeling		R,U	CO5
	9				conditional statements	R,U	CO5
	9				Multiway branching	R,U	CO5
	•				loops, sequential	R,U	CO5
H		1			parallel blocks	R,U	CO5
		2	-		Why use VHDL?,	R,U	CO5
		3	-		Shortcomings,	R,U	CO5
	10	4		Introduct on to		R,U	CO5
		5	-	VHDL	Design tool flow	R,U	CO5
H	-	1	-		Font conventions.	R,U	CO5
		2	-		Introduction	R,U	CO5
	11	3	-		A simple design	R,U	CO5
	11	4	_		Design entities	R,U	CO5
		5	_	Entities andArch		R,U	CO5
ŀ		1	-	ectures	I.C.	R,U	CO5
	10		_		Data types	R,U	CO5
	12	2		*	Attributes	R,U	. CO5
		3			Autouco		

.

4	Revision 01 – Programes in VHDL	R,U	CO1
5	Revision 02 – Programes in Verilog	R,U	CO1

#### Bloom's Taxonomy Level (L)

R-Remembering U-Understanding A1-Applying A2-Analysing E-Evaluating C-Creating

#### **Text Books:**

1. Samir Palnitkar, "Verilog HDL: A Guide to Digital Design and Synthesis", Pearson Education, Second Edition.

2. Kevin Skahill, "VHDL for Programmable Logic", PHI/Pearson education, 2006. Reference Books:

1. Donald E. Thomas, Philip R. Moorby, "The Verilog Hardware Description Language", Springer

Science+Business Media, LLC,

Fifth edition.

2. Michael D. Ciletti, "Advanced Digital Design with the Verilog HDL" Pearson (Prentice Hall), Second edition.

3. Padmanabhan, Tripura Sundari, "Design through Verilog HDL", Wiley, 2016 or earlier.

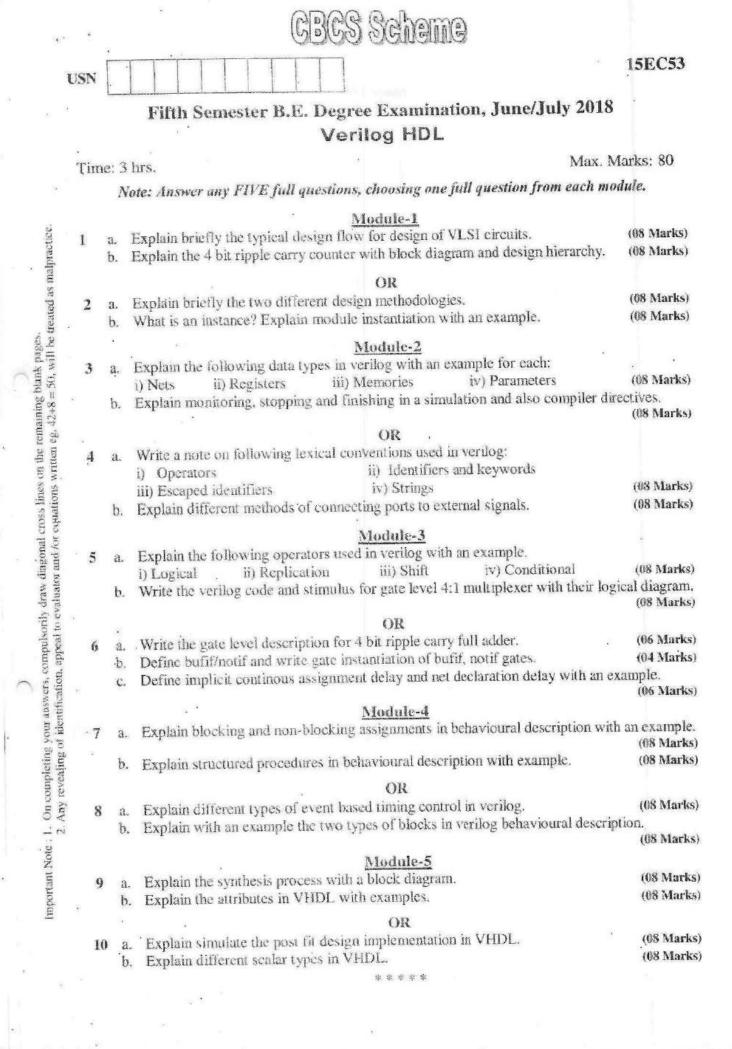
### CO-PO Mapping:

CO/PO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12
C508.1	1	2	3	2	3	1	1	1	2	1	· 1	1
C508.2	1	2	3	2	3	1	1	1	2	1	1	1
C508.3	1	3	3	1	2	1	1	1	1	2	1	1
C508.4	1.	2	3	2	3	1	1	1	2	1	1	1
MODAL VALUE	1	2	3	2	3	1	1	1	2	1	1	1

### List of URLs-Text Books, Notes, Multimedia Content, etc

- http://www.nptelvideos.in/2012/11/electronic-design-and-automation.html
- http://nptel.ac.in/courses/106105083/7
- https://sites.google.com/site/zakirsirece/verilog-hdl-notes
- http://www.satishkashyap.com/2013/12/lecture-notes-or-lecture-slides-on_6227.html
- https://www.smartzworld.com/notes/digital-design-through-verilog-hdl-notes-ddtv/
- http://d1.amobbs.com/bbs_upload782111/files_33/ourdev_585395BQ8J9A.pdf
- https://www.pdf-archive.com/2013/04/05/ebook-electronics-verilog-digital-designsynthesis/ebook- electronics-verilog-digital-design-synthesis.pdf

Wister Horew 31/7/2019



#### 15EC53 USN Fifth Semester B.E. Degree Examination, Dec.2018/Jan.2019 Verilog HDL Max, Marks: 80 Time Has Note: Answer any TWE full questions, choosing ONE full question from each module. Module-1 (06 Marks) a I xplain top-down design methodology with an example h Explain the typical design flow for designing VLSI IC crientits, with a near flow chart. (10 Marks) OR (06 Marks) Explain Bettom-up design methodology with an example. 2 41 Explara the different levels of abstraction used for programming in verilog (10 Marks) 12 Module-2 a Explain system tasks and compiler directives in verilog. (06 Marks) 3 What are the basic components of a module? Explain all the components of a verilog Te . (06 Marks) module with a neat block diagram. Wrue venlog description of SR Laich. Also write stimulus code. (04 Marks) 4.1 OR v) Vectors ii) Nets (iii) Arrays (v) Parameters 4 a Write a note on: i) Registers (12 Marks) vi) Memories b Declare a top-level module "Stimulus". Define Reg_in (4 bit) and Cik (1 bit) as register On completing your measure, computantly draw dur-2. Any reacting of identify along appeal to evaluation and variables and Reg_out (4 bits) as wire. Instantiate the module "shift-reg" in "stimulus" block and connect the ports by ordered list. Declare A (4 bit) and clock (1 bit) as inputs and B (4 bit) as output in "shift-reg" module. (No need to show internals). Write a verilog code (04 Marks) for the above. Module-3 5 a. Write the verilog description of 4 bit ripple carry adder at gate level abstraction, with a neat block diagram. Also, write stimulus block. (08 Marks) b. What would be the output of the following: a = 4'h1010, h = 4'h1111 ii) a && b iii) & a iv) a >> 1 v) a >>> 1 vi) $y = \{2\{a\}\}$ i) a & b vii) $a \wedge b$ (viii) $z = \{a, b\}$ . (08 Marks) OR 6 a. A full subtractor has three J-bit inputs x, y and z (previous borrow) and two 1-bit outputs D(Difference) and B(Borrow). The logic equations are nut Note D = xyz + xyz + xyz + xyzB = xy + xz + yzWrite verilog description using dataflow modeling. Instantiate the subtractor module inside astimulus block and test all possible combinations of inputs x, y and z, (08 Marks) 1 of 2

		6 ⁵ ¹	5EC53
	h	a count and the fire are undering to matching a contract white	stimulus 8 Marksi
		Module-4	1
	12	Explain structured procedure statements in verilog (0	6 Martes)
	2		6 Marks)
	8	Explain cases and cases statements in verilog.	4 Marks),
		OR .	
	a.	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	6 Marks)
	h. c	Write a venilog code to find the first bit with a value 1 in	6 Marks)
		Flag = 16'B 0010_0000_0000_0000, (0	4 Marks)
		Ca	
		Module-5	
	a F		9 Marks) 6 Marksi
		1. A.	
0	a	1	Intecture
	2	body in VHDL (1	0 Marks)
	0	Write VHDL structural description of 1 Bit Full Adder. 0	6 Marks)
		to hit hit 2019 01:30 Att Att	
		B. B. A. A.	
		AT.	
		· 20f2	
		2	

		CBCS SCHEME							ISE
 USN		15EC53		9	а.	List and explain the short comings List the different steps of VHDL di	Module-5 of VHDL.	en andersie ^h Dierser bri	(04 %)
		Fifth Semester B.E. Degree Examination, June/July 2019 Verilog HDL	4				*	an single as charges of	(12 Ma
1 uz	10.	Shis. Max Marks 80		\$0	ч.	<ul> <li>Write VHDL code for 4 bit compare write VHDL code for full adder in</li> </ul>	OR 2007 Using behaviora structural deservation	description style style using "half adders	(85 M
		Note: Answer any FIVE full questions, choosing ONE full question from each module.				Expedie scalar data types of VHDE		Contraction and a second	(05 M) (05 M)
1	3. 6.	Mindule-1         (#8 Marks)           i. Discuss different type of module level with an example.         (#8 Marks)           b. List the baste type of design methodology. Differentiate between them.         (#8 Marks)					* * * * *		
2		OR What do you mean by instantiation and distances. Write a verifog cycle for 4 bit ripple carry counter to show instantiation and instances. What is the need of stimular block in simulation, discuss with an example (68 Marks)				7			
3	3, 15,	Module-2 1 ist and explain different system tasks and computer directives of verify. (10 Marks) 2 ist the components of a verify module. Write a verify code to list the components of SR latch (04 Marks)					•		
4	2.	OR Explain, how integer, real and time register data types used in verilog. (68 Marko)							
	b.	Show how connections between signals are specified in the module instantation and the pairs is a module definition. (05 Marks)							
		Module-3 Discuss on And Or Gales with respect to logic symbols, gate instantiation and truth tables (08 Marks)							
	12	Design AOI based 4-1 multipletser, write verilog description for the same and its stimulus. (08 Marks)	1						
	h	OR List the characteristics of continuous assignments (04 Marks) Write the veniog description of 4 bit full adder using dataflow operators and with citry look, ahead mechanism. (06 Marks)							
		Discuss briefly available gate delays in verilog. (06 Marks)							
7	a. h.	Module-4           Explain multiway branchings loops with examples.         (14 Marks)           Outline the characteristics of parallel blocks.         (02 Marks)		÷	i i				
8	a. h.	OR				,		e	
		1 of 2					2 of 2		

	Module – 1 Questions Bank Verilog HDL– 17EC53	T
	1. Explain typical design flow for VLSI circuits.	-
	2. Briefly explain evolution of CAD design	
	3. Write a short note on Emergence of HDL.	
1	4. What are the importance of HDL's in Digital design.	
	5. What are the features of Verilog HDL.	
	6. What are the recent trends in HDL.	
	7. With a relevant diagrams. Explain the types of digital design methodologies.	
	8. With an example of 4-bt Ripple Carry counter explain the design hierarchy.	
	9. Explain the different levels of abstraction used in Verilog HDL.	
	10. Write a Verilog HDl for 4-bit ripple carry counter and explain the module	
	instantiation for same.	
18	11. Mention the syntax for the following	
	a. Module	
	b. Illegal module nesting	
	12. Explain the two stypes of stimulus block.	
7	13. Consider an example of 4-bit ripple carry counter and explain design block's in	
Important	detail.	1
Important	14. Write a stimulus for 4-bit ripple carry counter.	
Questions	15. An interconnect switch(IS) contains the following components, a shared	
16	memory(MEM), a system controller(SC) and a data Crossbar (xbar).	
. +	a. Define the module MEM, SC and Xbar using the module/endmodule,	
	keywords. You do need to define the internals. Assume that the modules.	
	b. Define the module IS, using the module/endmodule keywords. Instantiate	1
	the modules MEM, SC and Xbar and call the instances mem1, sc1 and	
	xbar1 respectively. You do not need to define the internals. Assume that the	
	module IS has no terminals.	
	c. Define a stimulus block (Top), using the module/endmodule	
	keywords.Instantiate the design block IS and call the instance is1. This is	
15	the finalstep in building the simulation environment.	
	16. A 4-bit ripple carry adder (Ripple_Add) contains four 1-bit full adders (FA).	
	a. Define the module FA. Do not define the internals or the terminal list.	
	b. Define the module Ripple Add. Do not define the internals or the terminal	
	list. Instantiate four full adders of the type FA in the moduleRipple_Add	
	and call them fa0, fa1, fa2, and fa3.	
	17. Explain the typical design flow for designing VLSI IC circuits, with a neat flow	
	chart.	
Contract of the second of the	1a. Explain a Typical design flow for designing VLSI IC Circuits using the block	-
Model QP	diagram.	Decision and
(2015	1b. Explain the different levels of Abstraction used for programming in Verilog	08
Scheme)	2a. Explain a top-down design methodology and a bottom-up design methodology.	08
	2b. Explain components of a Verilog Module with a neat block diagram.	10
		00
2018 Jan	1a. Explain a typical design flow for designing VLSI IC circuit using the block diagram.	
(2015	10. Explain top down design methodology and bottom up design methodology	06
Scheme)	2a. With a block diagram of 4-bit Ripple carry counter, Explain the design hierarchy	10
	2b. Explain the trends in hardware Description languages (HDLs)	10
		06
2018 Jun	1a. Explain briefly the typical design flow for design of VLSI Circuits.	08
(2015	1b. Explain the 4-bit ripple carry counter with block diagram and design hierarchy.	08
Scheme)	2a. Explain briefly the two different design methodologies.	08
	2b. What is an instance? Explain module instantiation with an example.	08
	1a. Explain top-down design methodology with an example.	06
3010 T		
2019 Jan	1b. Explain the typical design flow for designing VI SI IC simultantia	
(2015	1b. Explain the typical design flow for designing VLSI IC circuits, with a neat flow chart	10
	<ol> <li>1b. Explain the typical design flow for designing VLSI IC circuits, with a neat flow chart.</li> <li>2a. Explain Bottom-up design methodology with an example.</li> <li>2b. Explain the different levels of abstraction used for programming in verilog.</li> </ol>	10 06

V

	<ul><li>3a. Explain System Tasks and Compiler Directives in verilog.</li><li>3b. What are the basic components of a module? Explain all the components of a verilog</li></ul>	00
	module with a neat block diagram.	00
	3c. Write verilog description of SR Latch. Also write stimulus code.	04
2019 Jan ( <i>2015</i>	4a. Write a note on: i) Registers ii) Nets iii) Arrays iv) Parameters v) Vectors vi) Memories.	12
Scheme)	4b. Declare a top-level module "Stimulus". Define reg_in(4 bits) and clk(1 bit) as register variables and reg_out(4 bits) as wire. Instantiate the module "shift-reg" in "stimulus" block and connect the ports by ordered list. Declare A (4 bit) and clock (1 bit) as inputs and B (4 bit) as output in "shift-reg" module. (no need to show internals). Write a verilog code for the above.	
2019 Jun	<ul><li>3a. List and explain different system tasks and compiler directives of verilog.</li><li>3b. list the components of a verilog module. Write a verilog code to list the components of</li></ul>	10
2015	SR latch.	00
Scheme)	<ul> <li>4a. Explain, how integer, real and time register data types used in verilog.</li> <li>4b. Show how connections between signals are specified in the module instantiation and the parts in a module definition.</li> </ul>	0

	Module – 4 Questions Bank Verilog HDL – 17EC53	
	<ol> <li>Describe the following statements with an example: initial and always</li> <li>What are blocking and non-blocking assignment statements?Explain with examples.</li> <li>With syntax explain conditional, branching and loop statements available in Verilog HDL behavioural description.</li> <li>Describe sequential and parallel blocks of Verilog HDL.</li> <li>Write Verilog HDL program of 4:1 mux using CASE statement.</li> <li>Write Verilog HDL program of 4:1 mux using If-else statement.</li> <li>Write Verilog HDL program of 4-bit synchronous up counter.</li> <li>Write Verilog HDL program of 4-bit asynchronous down counter.</li> </ol>	
Model QP (2015 Scheme)	<ul> <li>7a. Explain combined port declaration and combined ANSI C style port declaration with examples in Verilog.</li> <li>7b. Explain the conditional statements in Verilog.</li> <li>7c. Write a behavioral 4 bit counter program in Verilog.</li> <li>8a. Explain different Loop statements in Verilog.</li> <li>8b. Write a Verilog behavioral 4 to 1 Multiplexer program using CASE statement.</li> </ul>	04 04 08 08
2018 Jan (2015 Scheme)	<ul> <li>7a. Explain the blocking assignment statements and non-blocking assignment statements with relevant examples.</li> <li>7b. Write a note on the following loop statements: <ul> <li>(i) While loop</li> <li>(ii) Forever loop</li> </ul> </li> <li>8a.explain sequential and parallel blocks with examples.</li> </ul>	08 08 08 08
2018 Jun (2015 Scheme)	<ul> <li>7a. Explain blocking and non-blockign assignments in behavioural description with an example.</li> <li>7b. Explain structured procedures in behavioural description with examples.</li> <li>8a. Explain different types of event based timing control in verilog.</li> <li>8b. Explain with an example the two types of blocks in verilog behavioural description.</li> </ul>	10
2019 Jan (2015 Scheme)	<ul> <li>7a. Explain structured procedure statements in verilog.</li> <li>7b. Write a Verilog behavioral 8:1 multiplexer program using case statement.</li> <li>7c. Explain casex and casez statements in verilog.</li> <li>8a. Explain procedural assignment statements in verilog.</li> <li>8b. Explain sequential and parallel blocks with examples.</li> <li>8c. Write a verilog code to find the first bit with a value 1 in Flag = 16'b0010 0000 0000.</li> </ul>	
2019 Jun (2015 Scheme)	<ul> <li>7a. Explain multiway branching loops with examples.</li> <li>7b. Outline the characteristics of parallel blocks.</li> <li>8a. List and discuss different delay based timing control.</li> <li>8b. differentiate between blocking and non blocking assignments.</li> </ul>	

	6c. Define implicit continuous assignment delay and net declaration delay with an example.	06
	<ul> <li>5a. Write the verilog description of 4 bit ripple carry adder at gate level abstraction, with a neat block diagram. Also, write stimulus block.</li> <li>5b. What would be the output of the following: A=4'b1010, b=4'b1111</li> </ul>	08
2019 Jan (2015 Scheme)	i) a &b ii) a && b iii) &a iv) a >> 1 v) a >>> 1 vi) y ={2{a}} vii) a^b viii) z = {a,b}. 6a. A full subtractor has three 1-bit inputs x,y and z(previous borrow) and two 1-bit outputs D(Difference) and B(Borrow). The logci eauations are: $D = \overline{x} \overline{y}z + \overline{x}y\overline{z} + x\overline{y} \overline{z} + xyz$ $B = \overline{x}y + \overline{x}z + yz$ Write verilog description using dataflow modeling. Instantiate the subtractor module inside a stimulus block and test all possible combinations of inputs x, y and z. 6b. Design 4:1 Multiplexer using gate level modeling ro structural description. Write	08
	stimulus block.	08
	5a. Discuss on And/Or Gates with respect to logic symbols, gate instantiation and truth tables.	08
2019 Jun	5b. Design AOI based 4:1 multiplexer, write verilog description for the same and its stimulus.	08
2015	6a. List the characteristics of continuous assignments.	04
Scheme)	6b. Write the verilog description of 4 bit full adder using dataflow operators and with	
	carry look ahead mechanism.	06
	6c. Discuss briefly available gate delays in verilog.	00

÷

			17EC	53
ICEEC				
CITY ENGINEERING COLLEGE	(h)		12	
FIRST INTERNAL TEST	-	07/00/	2010	
		: 07/09/2		9
mch: EC Ti	me: 10.3	10am - 1	2.00pm	
b Name: VERILOG HDL	M	ax Mark	s: 50	
m & Sec: V Sem	mali	'ILC.	611-	
Tation. 1 /2 meet				
Note: Answer all Questions selecting any ONE FULL questions	from ea	ch part.		
Note: Answer all Questions selecting 9		Marks	CO's	BT's
PART-A	v. [	10 .	Ċ0-1	BT1
Explain Top-Down design methodology and Bottom-Up design methodolog     OR	<u>.                                    </u>			
. Explain Top-Down daise OR	er	10	CO-2	BT1
Explain monitoring, stopping and finishing in a simulation and also compile		10	0-2	
a l'adivas				
	module		001	BT3
Write a Verilog HDL for 4-bit ripple carry counter and explain the	module	10	CO-1	BIS
3. It is the station for same.			-	1
	-	1		
Write a note on following lexical conventions used in Verilog:				1
i) Operators		10	CO-2	BT
ii) Identifiers and keywords			1	1
4. iii) Escaped identifiers with suitable examples.				
ta Strings With Summer 1				
PART-C	eat flow	1	0	I BI
Explain the typical design flow for designing VLSI IC circuits, with a r	reat non	10	CO-	
2. 1		1	*	
	C	06	CO-	1 BT
a. Explain the trends in hardware Description languages (HDLs)		04	0-	1 0.
<b>b.</b> Briefly explain evolution of CAD design				
PARI-D		10	CO-	-1 B
7. Explain the different levels of abstraction used for programming in veril	og	10	100	x ] ~.
		1	1	1
Explain the following data types with an example of Verilog module:				
i) Nets			1	
i) Register		10	CO	-2 B
8. iii) Integers				
iv) Memories				
a) Time Register				
PARI-E		05	5	
a. Explain the two types of stimulus block.	ers (FA)			
	nal list		0	)-1 ]
b. A 4-bit ripple carry adder (Ripple_Add) contains the internals or the termin i) Define the module FA. Do not define the internals or the internal	als or t	he		)-1
1 0 1 Displa Add tha not define the meth	terro or .	ile		
terminal list Instantiate four full adders of the type the	life mour	0	5	
Ripple Add and call them fa0, fa1, fa2, and fa5.				
OR OR	a block's	in		
	aveform	& 1	0 C	0-2
Consider an example of 4-bit ripple carry counter and explain design				
10. detail. Write a stimulus for 4-bit ripple carry counter. (Both W				
10. detail. Write a stimulus for 4-bit ripple carry counter. (both w	nlving R	T4 - Anz	alyzing	
10. detail. Write a stimulus for 4-bit ripple carry counter. (Both And Transcript Output)         Blooms Taxonomy Levels (BTL):BT1- Explain BT2- Understanding BT3 – Application BT3 – Applic	oplying B'	T4 – Ana	alyzing	
10.       detail. Write a stimulus for 4-bit ripple carry counter. (Both And Transcript Output)         Blooms Taxonomy Levels (BTL):BT1- Explain BT2- Understanding BT3 – Application BT3 – Applicati	plying B'	T4 – Ana	ilyzing	
10.       detail. Write a stimulus for 4-bit ripple carry counter. (Both And Transcript Output)         Blooms Taxonomy Levels (BTL):BT1- Explain BT2- Understanding BT3 – Ap Course Outcomes (CO's):	plying B	cuits		
10.       detail. Write a stimulus for 4-bit ripple carry counter. (Both And Transcript Output)         Blooms Taxonomy Levels (BTL):BT1- Explain BT2- Understanding BT3 – Application Applicati	plying B	cuits		

uestion	Details of the Answer	Marks Distribution	Total Mark
No.	Top down design Bottom - up design.	Distribution	10
4'	TE Fop-leel		
	Isuf test	54	
	Line and see a	511 + 514	
1-12	Tient lent leat teat all call call call call	371	
	explain escaled		(
			10
2.	manitorij I manitar		
-	steppin	6M	
	\$manitary \$kopping \$ skop \$ skop \$ fimisly \$ fimisly \$ fimisl		
	fruislij Eliziet		
		124	
	Compilier douchtris.		
	' defilere ?	UM	
	1 melevele		
3.	Whit ripple levery Courter Blockdinger	- 4	lo
	lock Thit Hit Thit The Streeter -	2	
C	p p p p cuki-s		
	at TTT instruction	4	

odd 2019-20 17EC53- Vevilog UTDL

Question No.	Details of the Answer	Marks Distribution	Total Marks
6.	Trades in hordwoor desception large Evolution of CAD durryer	55	16
7.	Deffort Levels of Abschrachter * Dutaflow * Behavirol	each 2.5M	10
8,	* Grate level * Switch lovel. Nets: wive	2	10
	Register: reg Integer: diamal Notation. Memorios: defend usig Vector Notation. Thue Rigister: reg Filen	2 2 2 2	
9.1	Two types of stimulus block position Mapping Signal Name Mapping (b) Module FA module FA module Ripple-Add. FA fao C ); FA fat ( ); FA faz C );	9.5 9.5 5	10

anch: EC Time: 10.3 b Name: VERILOG HDL $G$ Some $G$ Som	Max M alyite	2.00pm arks: 50	-
Note: Answer all Questions selecting any ONE FULL questions from e	ach part.		
n. Questions	Marks	CO's	BT's
0. PART-A	10	CO-3	BT1
Discuss on And/Or Gates with respect to logic symbols, gate instantiation and	10	000	
	10	CO-2	BT1
2. What is the need of stimulus block in simulation, discuss with an example.		L	
Pak I-D	1		
Design a 2-to-1 Multiplexer using bufif0 and bufif1 gates. The delay specification			14
for these gates are as follows:			
Delay Min Typ Max	10	CO-3	BT3
3. Rise 1 2 3			
Fall 3 4 5		1	
Turn-off 5 6 7	1		
Write gate level description and stimulus in Verilog.			
Show how connections between signals are specified in the module instantiation	10	CO-2	BTI
4. Show how connections between signals are optimiles and the parts in a module definition.	1	1	
PARI-U			
A full subtractor has three 1-bit inputs x,y and z(previous borrow) and two 1-bi	t		
A full subtractor has three 1-bit inputs x, and equations are: outputs D(Difference) and B(Borrow). The logic equations are:			
$D = \overline{x}  \overline{y} z + \overline{x} y \overline{z} + x \overline{y} \overline{z} + x y z$	10	CO-3	BTI
	10	0-5	
	r	-	
Write verilog description using datation modering, moduling, module inside a stimulus block and test all possible combinations of inputs x,	y		
and g			
OR	04	T	T
a. List the characteristics of continuous assignments.		CO-3	BT
6 b Write the verilog description of 4 bit full adder using different f	06		1
with carry look ahead mechanism. PART-D			
PART-D	W		BT
Write a program for 4to1 Multiplexer, Using conditional Operators in datafle	w 10	CO-2	DI
7. level of abstraction in Verilog. OR			
$f_{ac}$ = 1 bit Full Adder are given as sum = $a^{b}b^{c}$	c;		
	by 10	CO-	2 BT
8. co=(a&b) (b&c) (c&a). Write the gate tevel instantiating and, or, xor gates only.	- de la compositione		
instantiating and, or, xor gates only. PART-E			
What would be the output of the following:			
	^h . 10	0 CO-	2 B
9. $\begin{vmatrix} A \doteq 4'b1010, b=4'b1111 \\ i) a \& b ii) a \& \& b ii) \& a iv) a >> 1 v) a >>> 1 vi) y = \{2\{a\}\}$ vii) a			
$v(ii) = \{a, b\},$			
111/2 (01)		0 CO	2 B
OR       10. Explain, how integer, real and time register data types used in verilog.	1	0 100	-

Circuits. CO2: write behavioral models of digital circuits. CO3: Verify behavioral and RTL models. Describe standard cell libraries and FPGAs.

# CITY ENGINEERING COLLEGE DEPARTMENT OF ELCECTRONICS & COMMUNICATION ENGINEERING SCHEME FOR VALUATION

1

INTERNAL TEST: <u>2IA</u>

uestion	$\begin{array}{c} \text{Section: } 5 \text{ A } \text{Sub Code: } 17EC33 \text{ Sub Name: } \sqrt{60000} \\ \text{Details of the Answer} \end{array}$	Marks Distribution	Total Marks
No.			10
1	And lor Gates Logic Symbols, gate intenticitien and Truthe Table [P106, Ex 5-1, P108]		L
Ú.	and with laber (Y, a, b);		•
	10-1- X and 01x2		
- 00 -	by biloxxx		
	2 0 × × × nand n1 (Y, a, b)i		- R
+	2 Doy nav oix 2 on n2 (Y, a, b); -	-4	
1	6 x 1 0 x x y not not (Y, a, b);	-/	
	Eliar y not nor (Train)		
2	a Dy or 0, x 2 (xor x1(Y, a, b))		
	b i x x X X X X X Y (Y, a, b);	1	
	D X 0 1X Z	6	
ļ.,	6 10 x x 6 10000		
	21 × 0 × x		
	$\left[\alpha\right] \xrightarrow{Y} \xrightarrow{Y0} \xrightarrow{0} \xrightarrow{1} \xrightarrow{Y2}$		
8. 7	5 x x x x x x	-	
	a mail 01x2		
	5 Profesty		1
	Z/ x x xx	/	10
.0	Meed of stimulus block in simuluation. [P60,P61 Need of stimulus block in simuluation.] P60,P61 * once a disign blocks is Completed, it must be		
er of	* once a disign blocks is comp	1.11	
		7	
		d d	
	Called Stimules Block ". Called Stimules Block ".		
	v. H. stimulus block lice /	1	
10	Stafflen Hover	HOD	ing
09	/Staff Un U.S. T	HOD	

Scheme of Valuation - 2019

Question	Details of the Answer	Marks Distribution	Total Marks
No. 4.	Signals specified in madule instances. 2 Methods. () Connecting by ordered list:		10
	to The Signals to be connected must appear in the module instantiation in the same order as the ports in the port list in the module definition. ix : module Stimulis;		•
	My E3:07 A, B; reg CIN; wire E3:07 SUM; wire C-OUT; fulleddy fa-ordord (Sum, Cout, A, B, CIN) < Stimulus >	6	
	maluli fallodely (Sun, (-out, a, b, Cutu); output [3:0] Sun; output C-out; hyput [3:0] a, b; input c_in; (machile intervels)		
•	Dennechus ports by name: Verily provides the Dennechus ports by name: Verily provides the Capability to Connect iscterival sigual to ports by port viames, value that by positions	14	
	Lix: fulladd4 fer_bynur(.c.out(c-out), .sur(svii) .b(B), .c.in(c-IN), . R(A)); Full subtractor D= xyz+ xyz + xyz + xyz		10
5.	$\begin{array}{c c} Truth Table & \overline{B} = \overline{X}Y + \overline{X} \neq + \overline{Y} \neq Dataflow Abstraction Abs$	$\left[ \right]$	>
	moduly test; , rug XIXIZ; wir d16; fs s1 (*x(x), *Y(x), *7(2), D(d), B(b));		. *
- Mari	initial & monitor (\$hime, "x=x,b, y= 1.b, 2=x,b, d=x,b, b=x. initial begin x=0; x=0; 2=0;	by x, y, z, d, k	

Question No.	. Details of the Answer	Marks Distribution	Total Marks
. 53	#10 x=0; Y=0; 7=1; #10 x=0; Y=1; 2=0; #10 x=0; Y=1; 2=1; #10 x=1; Y=0; 7=0; #10 x=1; Y=0; 2=1; #10 x=1; Y=1; 2=0; #10 x=1; Y=1; 2=1; #10 x=1; Y=1; 2=1;	4	
	Transcript output mateling the Freeth table Values.	3	
ba	Characterstics of Entinious assignment O the left hand side of an assigned must align 1	each portet 1 Harks	4
a	a scalar / Vector net / a Concatenation of scaler and Continious cursigenet are always active the		
a ⁶	assigned to the LHS net. B) The operander as the RHS I have the		×
	@ Deley Values Can be scalars /vectors		
	terms of time cluits. Delay Values are used to Centrol the time tohen a net is assigned the	alan ( ) al	
66	O module FALL (Sue, Cout, 9,6, Ch);	د 1- ۱۱ ه چونو 1- ۱۱ ه ه	6
	ansign & Cout, Sun y = at b + an; und modelle	2	Ъ.
-	Dearry lookaheed malousur; module FA (Suy, Court, a line)	1.27	
	output [3:0] Sui output c-out; input [3:0] a, b; input ai; wire PO, go, P1, g1, P2, g2, P3, g3; assign P0=2027, C4;	4	
	Usign $go = a[c] \land b[c], P1 = a[i] \land b[i], P2 = a[2] \land b[2], P3$ usign $go = a[c] \land b[c], P1 = a[i] \land b[i], P2 = a[2] \land b[2], P3$ usign $C1 = go   Potem   J] = a[i] \land b[i], P2 = a[2] \land b[2], P3$	$=a[3] \wedge b[3]$ $=a[3] \neq b[3]$	;
Sta cheme of Va	If assign cont = Ca, sun [1] = PIACA, Sun 2 = PIACA, Sun P2 AC2, Sun wolmachub	$L_3 = P_3 AC$	9P1490

: * 2

Question	Details of the Answer	Marks Distribution	Total Marks
No. 7.	4:1 Multiplexer Using Conditional operators in Dataflow Level of Abstraction. Conditional operator Syntex Condition-escor? true-wer : false-	- 2 expr;	10
	Verilog Program: module novela (out, 80, 81, 82, 83, 51, 50); 11 Port declaration. output out; input 80, 81, 82, 83; imput \$1, 50; 11 Use nested Conditional operator.	5	
	arsign out = s1 ? (so ? is : i2) : (so ? i1 : io); indmedule isuplaination -	2	
8.	full Addor Gratelevel Abstract Sum = a 1 b 1 C; Co = (a4b) ((b+C)) (c4)	a)	10
	module fa (sum, co, a, b, c); output sum, co); imput a, b, c; wire p4, p2, p3; 11 for products.	Cwith Comm	uls
	xo7 X1 (sum, a, b, c); and an1 (P1, a, b); and an2 (P2, b, c); and an3 (P3, c, a); o7 r1 (co, P1, P2, P3);	6 Curithe Com	านอร์)
	endimodule (CO, PI, PZ, IS), logic circuit (ST) Scur		
	P2 P2 P3 P3	20	
	, <i>F</i>		

Question Details of the Answer Marks Total No. Distribution Marks operators output for the input a= 4'b1010 9. 10 b=4'b1111 81 (i) a4b = 4'blow \$4'b1111 = 4'b1010 bitwise "and" operator 21 (11) affb = 4'b1010 & 4'b1111 = false/low logical "and" operator (111) fa = \$ 4'biolo => 1404140 **\$**1 Reduction 'f'operator. Result is 1'b0. (iv) a>>1 = 4'b 1010 Rightshift by 1 Court; 1 = 4 16 0101 (V) a>>>1 = 4 biolo arithmetic Rightship 120 = 416 1101 (Vi) Y= { 2 { a 3 } Ripheation operator 2 by 2 times. a= 4'b1010 = Y=8b10101010; Vii) and = 4'61010 14'61111 1 bitude xon operator = 4'b 0101 (VIII) Z = {a,b} concatenations operator. 2 a= 4 b1010 and b= 4 b1111 2=8'610101111; Integer, real and Time register 2+2-1010 10. data types in Verilog escample: > 4

	IL	000
12	1	P
0.1	hase	id
01		

## CITY ENGINEERING COLLEGE THIRD INTERNAL TEST

Branch: EC Sub Name: VERILOG HDL Sem & Sec: V Sem Duration: 1 ½ hrs.

1 C E

USN

E

C

Date:19/11/2019 Time: 10.30am – 12.00pm Max Marks: 50

Qn.	Questions	Marks	CO's	BT's
No.	DADE 4	~		
	PART-A		1	
1.	Explain monitoring, stopping and finishing in a simulation and also compiler directives.	10	CO-3	BT1
	OR			
2.	Explain multiway branching loops with small examples.	10	CO-2	BTI
	PART-B			
3.	Explain the typical design flow for designing VLSI IC circuits, with a neat flow chart.	10	CO-3	BT:
	OR			
4.	Explain different types of event based timing control in verilog.	10	CO-2	BT
	PART-C			
5.	Discuss briefly available gate delays in verilog.	10	CO-3	BT
	OR		atrice and a second	
6.	Explain the synthesis process with a block diagram.	10	CO-3	BT
	PART-D			
7.	Show how connections between signals are specified in the module instantiation and the parts in a module definition.	10	CO-2	BT
_	OR			
8.	Explain the relationship between a design entity and its entity declaration and architecture body in VHDL.	10	CO-2	BT
	PART-E			
9.	Explain sequential and parallel blocks with examples.	10	CO-2	BT
	OR			
10.	Explain the design tool flow followed in VLSI design with a neat flow diagram.	10	CO-2	BT

**Blooms Taxonomy Levels (BTL):**BTI- Explain BT2- Understanding BT3 – Applying BT4 – Analyzing **Course Outcomes (CO's): CO1:** Describe Verilog hardware description languages (HDL). Design Digital Circuits. **CO2:** Write behavioral models of digital circuits. Write Register Transfer Level (RTL) models of digital circuits. **CO3:** Verify behavioral and RTL models. Describe standard cell libraries and FPGAs.

## CITY ENGINEERING COLLEGE DEPARTMENT OF ELCECTRONICS & COMMUNICATION ENGINEERING SCHEME FOR VALUATION

INTERNAL TEST: THIRD

Semester & Section: 5 A Sub Code: 17EC53	Sub Name: Verilog Date: 19/11/2019
------------------------------------------	------------------------------------

Question No.	Details of the Answer	Marks Distribution	Total Marks
1.	monitoring : provides a mechanism to monitor a Signal When it's Value changes. Smonitor ("", P1, P2, P3 Pn); Stopping : puts the simulation in an interactive It's islused whenever the designer was to Suspend the simulation and example the Values of Signals in the design. # 100 of stop; Ginishing : task terminates the simulation. # 4000 \$finiship	2 od 2 2	10
	Compiler directives: an defined by using the 1216yword> Custrud. I define word SIZE 32 I include header.V	4	
2.	Hultiway branching loops. Case Gener Causer	2.5M * 4	10
	LOOPS - While For . Ment Repeat escomptes - atten- forever based		
3.	Desity Spect Televin Peret Fru Verificat Peseu (HDU) Fru Verificat Peseu (HDU) Fru Verificat Peseu Council Synthis M Council Synthis An bouch Council Pierus An bouch Council Planus An bouch Council Planus An bouch Clar An bouch Clar An bouch Clar An bouch Clar Council Council Clar An bouch	elirigen 64 Asgekar 44	10
PN	Staff This C.S.	nalitenju	3

Scheme of Valuation - 2019

Marks Total Question **Details of the Answer** Marks Distribution No. Went Bresed Timing Control 10 4. Regular event Control cach 2.5M * 4/19 Named went Control Event 'OR', Comma Operator @ + operator in scusificity list Grate dulay in Verileg. 5. 10 Rise delay 2 0,042 AT full delay 1112 2 troin of chery. 2 Min/ typ/ Hex Values. 4 Synthisis process in VHDL 6. 10 Behavival discription flattoning of hererdy and Transformation to a monolifue c RTL supresentation 6 DWICE Archekeet operator interfacing ad Selection Malele generation liser pple Device spectic optimization optimzed equettan methost for war with fitter/ explain with pour place & vale tool Volten Horer P.S. malitanjus 2

Scheme of Valuation - 2019

Total Marks Marks Details of the Answer Distribution Ouestion No. bliv module sustanticition & Module flifrisher. 10 Connections 7. 24 2 Methods Connection by ordered list isophin 24 escempte Conmention by ports namios escolu 24 lscenp 2 24 relationship blu disign with a stity declaste 10 & Architecture body in VHDL 8. entity declarentru 2 Interface dicturation entity declesitan synter esystem 4 Architer budy Syster + cescpia Architecture boxy 4 functional affin noitran 16 sequential black patting linitial using 9. 3 "begin & red" esystem atteast 2 percellul block · inside always / instead Usig 3 "fork & john" inplin: atleast 4 ports 2 Staff Korer C.S. malilhanjus

Scheme of Valuation - 2019

Question Marks Total Details of the Answer No. Distribution Marks in VLSI design of VHDL design Tool flow 10. 10. Dunce selection VHOL Synthesis derecht S design Sputtions Atucili +4 equation Fifter place & voute southing postlayout Testbady Repett file Simulation Perce othing ovegreij Hisoure Summoy stimuly file State Simulation Sofficer thug Jeale analy Detafile water escolerin Atleast Gepend nn 17 34 57 tree 7 over Staff P.S. mallilher Ins Scheme of Valuation - 2019 4

Pro All logic Gates Vth sem 1CEI7ECOI7 module all gates (all, ben, nota, Yand, Ynand, Yor, enput aen, ben; Yxor, Yxnos); en Ynda Yand cutput theta, Yand, Ynand, Yor, ben Ynor, Yxor, Yxnor; nand logte 01 Ynor assign Inota= v (aln); Xor assegn Yand = apn & ben; augn Ynand = v (arn& ben); aufgn Yor = ain | ben; assegn Ynor = v(aen/ben); assign Xxor = arn bin; augn Yxnor = v(ain bin); end rodule allgater Abstemulus; reg all, binj When Ynata, Yand, Ynand, Xor, Ynor, Yxor, Yxnor, allgates uut ( . aenfacon), . b.en ( ben), Ynot aen, ben, Ynota, Yand, Ynard, Yor, Ynor, Yxor, Yxnor); Eneblal begin aen = 0; ben = 0; #10 ben=01; #10 am=1; bin=1;

#10 bin=0; , , , ,

aln, ben, Ynota, Vand, Ynard, Yor, Ynor, Yxor, Xxnor); end module. Decoder 2104 module Dec2to4 (en, d_in, d_out); 2121 enput[i:0]d_en, en enputen; reg [3:0] d-out; were [1:0] d_en, en; always @ (en, d-th) begin ef (en) // Active Low g-out = 4'bZZZ; end Case (d-En) dout = 9 600 7 4 60001; 9 601 7 4 60010; 2 601 0; else begen 2 610: 14 600100; day 9'b11:14'b1000; default : 415 22 d-out= 4. 62723; end modelle.

reg [1:0] d_en, ea; wine [3:0] d_out Dec2to4 uut ( . en (en), . d_en (den), . d_out (dout)); Entral begin Carlon (des (d. Ph)) en=1; # 10 en=0 ; d_n=2'600; z d-ln = 2'b01; #10 3 d-Pn = 2 610; #10 #10 d_Pn=9'b11; #10 en=1 ; d_ln= 2'b00; end Enebeal #60 spenech; \$monchor (\$ 20me, " %.b %.b %.b); en, enthal den, dout); end module. Encoder without preservy ONC y-aut module enc-wpo-pros (en, a. en, yout); en f prooff enput [7:0]a-en; Inputen ; output [2:0] y-aut; 20 where [7:0] a_n; Whe en;

begin ep (en) // Active low. y-out = #3/bZZZ; end else Case (a-Pn) begin 9'600/: y-04-8'60000001 : y-out-3'6000; 2601:00 8 60000010 : y-out = 3 6001; 8 60000100 = y-out = 3 6010 21/610 : S/611: 81 60000000 : y-out = 3 6011; 8' booolooo : y_aut = 3'bloo; 8' booloooo : y-aut = 3'blo1; 8 601000000 = y-out = 361103 8' 61000000 ; y-out = 3 6111. default : y-out=3'bz zz; end case endmedule. modelle en_wo_pror_tb' ng [7:0] a.m; neg en where [2:0] yout, out (·a-en (ain), ·en(en), ·y-out(you) en-wo-preor Enthal begen ne ban en= 1 ; a-en= 8'61000000; #10 en=0; a_en= 8 601000000; #10

#10 a_9n=8'600001000; agn = 8'60000000: #10 a_Pn=8'b00000010: #10 a-Pn-8 60000001; #10 a_m=8'b10000001; #10 a_Pn = 8' b 00011101; #10 end #120 \$fenesh; enefal 7.6 %.6 %.b", agn, \$monetor (\$ temo, Enthal en, yout); end module. encoder with preasily module enc_w_preor (en, a_en, yout). Input [7:0]a_m; enpulen; autput [2:0] youl; where [7:0] a_inj witten; reg [2:0] y_out; always @ (on, a_in) begin g (en 3 == 1'b1) y-out = 362225 else begin [nen[77 - - 1/6] U-rout = 3'belli:

a_ln[5] == 1'b1) y_out = 3'b101; (a - Pn[4] = = 1'bi) y - out = 3'bloo; $a_{n}[3] = = 1'bi)$  y-out = 3 boli; (a-m[2] == 1'b1) y-out = 3'b010; 01-8-(a - m[i] = = 1'bi) y-out = 3'booi; [a_ln[o] == 1'bi) y-out = 3'booo; y-out= 3bzzz; default ond end module. module en w_pror_Hb; reg[7:0] a_m; negen; Wire [2:0] yout vuf( ·a. ln (a en) · er (en), · y-out (you)); en-wepperson Philipped befin en= 1; #10 enzo; #10 a-Én[7] = 8'61000000; #10 a_Pn[6] = 8'b0100000; *410* a_Por[5] = 8'600100000; #10  $a - \ln[4] = 8' 600010000'$ #10 a-m[3] = 8 600001000' AIM -- all

a_Pn[0] = 8' 50000000r; #10 end #120 & feneshi Eneftal #120 & feneshi Eneftal \$ monedors (\$ deme, ". b. Y. b. Y. b.") arn, en, youd); and module. bent comp to de 4 blt comparator module 4,627 Compositor (a.en, b.en, g-op, 1-0p, e-op) enpuf3:0]a.en, b.m; autput [3:0] g-op, L-op_ e-op; wre [3:0] a_in, bin; always @ neg [3:0] g-op_L-op_can always a beggn ef (a_Pn >b_Pn) 9-0p=1; qL-0p=0; e-0p=0; and else g ef (ainzb-Pn) 9-0p=0; L-0p=1; e-0p=0; end else  $begen g (a_{pn} = b_{pn});$ 0-0p=0 · 1-0p=0 · e-0p=1;

default g-op=1; Lop=1; e-op=1; end end module. module 4 bet Conparator_ +b; reg (\$3:0] a.m, bin; reg [3:0] g-op, L-op, e-op; 4 bet comparator + uut ( ·a_ en (aen), ·b_en (ben), ·g_of (grt), L-op(less), e-op(equi)); Entral begin a_ln=4'60011; bln=4'60010; #10 a-m= 4 61001 ; b-lh = 4 1101; #10 0_in=4 boion; b_en=4 bilio; #10 aln=4'60011; b-ln=4'60001; end # 40 \$ Aneh; "%be%b--> %by/b/ entital \$ moultor ( \$ denie, 1ª alt ain, ben, Pultal grt, less, equi); g Ou endmadule.



Visvesvaraya Technological University

# CITY ENGINEERING COLLEGE, BANGALORE

Sl NO	. USN	100 March 100 Ma	17EC53	17EC54	17EC553	17EC562	17ECL57	17ECL58	17ES51	STUDENT SIGNATURE
1	1CE17EC004	11 (7)(7)	33	34	30	31	25	36	33	
2	1CE17EC005	38	34	39	34	28	25	40	35	Contraction of the second
3	1CE17EC008	39	32	31	31	34	31	37	37	
4	1CE17EC009	32	21	32	24	26	22	36	33	
5	1CE17EC010	29	23	33	22	25	26	36	25	
6	1CE17EC011	28	26	30	23	31	35	36	30	
7	1CE17EC014	40	33	38	34	27	26	38	38	
8	1CE17EC015	34	29	34	23	27	25	33	29	110.00
9	1CE17EC016	34	28	28	32	31	26	35	33	
10	1CE17EC017	32	31	30	32	27	25	35	31	
11	1CE17EC019	30	27	30	29	29	36	35	29	
12	1CE17EC020	33	29	33	34	38	25	37	34	
13	1CE17EC021	30	24	20	26	23	24	32	26	
14	1CE17EC024	37	32	37	35	33	40	38	32	
15	1CE17EC026	40	32	39	33	32	35	35	34	the interestion
16	1CE17EC027	39	31	38	38	34	30	37	36	the second second
17	1CE17EC029	26	19	20	19	20	22	30	22	
18	1CE17EC031	35	31	36	34	36	26	38	30	
19	1CE17EC032	22	19	22	19	22	32	25	22	
	1CE17EC033	40	35	40	40	34	40	35	36	- Mellen Charge
-	1CE17EC035	38	34	38	38	34	40	39	35	
	1CE17EC036	32	31	39	30	33	35	38	32	
-	1CE17EC039	27	24	28	30	26	23	34	31	
_	1CE17EC042	22	19	22	19	19	23	31	25	
	1CE17EC043	29	28	30	20	25	34	35	29	
-	1CE17EC044	33	26	36	25	32	28	36	31	
-	1CE17EC045	36	33	31	26	31	35	38	29	
-	1CE17EC046	36	31	36	30	29	40	40	29	10
-	1CE17EC049	38	32	39	36	35	35	35	37	
-	1CE17EC052	40	31	40	33	39	37	40	36	
-	1CE17EC055	23	20	23	19	27	33	30	21	
-	ICE17EC056	34	34	26	31	32	38	40	33	
-	ICE17EC058	28	24	30	23	31	33	34	27	
-	LCE17EC059	29	26	30	23	27	28	36	30	
-	CE17EC062	35	28	32	33	30	31	37	28	
-	CE17EC063	27	30	30	22	31	37	38	29	
	CE17EC064	23	19	19	19	19	28	30	21	
8 1	CE17EC065	21	19	19	19	25	29	30	27	

### Module-5

## Istroduction to VHDL

- * Concept of VHDL
  - > VHOL is the VHSIC (Very high speed integrated Circuit) Hardware description language.
  - > VHOL is an international standard specification language for describing digital hardware used by industry wordwide.
  - -> VHDL Enables hardware modeling from the gate to system. level
  - -> VHDL provides a mechanism for digital design and reusable a design documentation.
- * History of VHOL
  - -> Very high speed integrated Circuit (VHSIC) program
    - · Launched in 1980
    - -> woods the workshop.
      - · Held in june 1981 in massachusetts.
      - · Discussion of VHSIC goals.
      - · compressed of members of Industry government and. academia.

-> PD 1983 a team of intermetrics, IBM and Texas instruments were awarded a Constructed develop VHDL.

- -> in August 1985, the final Version of the language Onder government Contract was released: VHDL Version 7.2
- and in 1988 an ANSI approved standard.
- → in september 1993, VHDL was restandardized to clarify and enhance the language (IEEE Standard 1076-1993)
   → VHDL is now undergoing international review to become an IEC Standard.

(Affiliatedto VTU,Belgaum,Approved by AICTE,NewDelhiandGovt. ofKarnataka) Kanakapura Road, Doddakallasandra, Bengaluru, Karnataka 560062 Tel:080-22560313,Fax:080-22560313,Web: http://cityengineeringcollege.ac.in/



### DEPARTMENT OF ELECTRONICSANDCOMMUNICATIONENGINEERING

### VerilogHDL(17EC53) (AsperChoicebasedCreditSystem(CBCS)Scheme) VTHSEMESTER

### **MODULE-5**

Syllabus:

Introduction to VHDL

Introduction: Why use VHDL? Shortcomings, Using VHDL for Design Synthesis, Design tool flow, Font conventions. Entities and Architectures: Introduction, A simple design, Design entities, Identifiers, Data objects, Data types, and Attributes.

### StudyMaterialReferred:

✓ Kevin Skahill, "VHDL for Programmable Logic", PHI/Pearson education.

**CompiledBy:** 

Prof.VishvaKiran R C Assistant professor Dept.of ECE,CEC

Mail

:vishvakiran@cityengineeringcollege.ac.in

+ A Signal or Variable that it an Rutager type hed that is to be Synthesized into logic schould be Constrained with a range, for Example.

Si Variable a: Poteger range -255 to 256;

+ <u>Floating Types</u>. -> Floating-point type Values are used to approximate. real numbers. Losse integens floating-point type Can be. Constrained.

-> The Duly predefined floating type 18 real, which includes, at minimum, the range - 1.0E38 to + 1.0E38, inclusive.

* Physical Types'--> Physical types Values are used as measurement cluigs. The Duly poclephied physical type it time. -> It's vange finders at roinimum, the vange of Suteger's -> Et provinary duit is fis (femto seconds) and in defended as falleeves -2147483647 to 2147483647 type time 1x range Eq:-Units br = 60 min;fs; ps = 1000fs; ns = 1000 ps; End units. US = 1000 ns;  $ms = 1000 \, \text{MS};$ See = 1000 ms; min = 60 set;

Composite Types: * Data Objects of Brahar types Can Only hold One Value at the Current Rimulation time. + Data Objects of Lorospossite types, oo the Other hand, Cap hold muttiple values at a time. + Composite types Consists of array types and record types * an Object of an arrowy type Conscitute of routtiple elements. If the Rame type. * The most Commonly used array types are those predified by the IEEE 1076 and 1164 Standards : type bit-vector i's array (natural ranges) of bit : type std_ulogic_vector is array (noturalrange <>) of std_ulogic; type std - logic - vector i're array (natural range <>) - f & Hologit; * An Object of a record type has multiple Elements -> Gerord Types!of different types. * Individual fields fa record (on be referenced by Element name. * The Journal shows a record type defination for iocurs, objects declared as that type, and. asseignment of valuy.

type iocell its record Buffer-inp: bit-Vector (7 down to 0); lnable : bit; buffer- out : bit_vector (Fdewnto 0); Chel record ;

Attribut & * An Attribute Provides information about iteme Erren as entities, architeutures, type and Bignald. Attributes that are useful in Synthesis. * Scalar types have value attributes. The Value. attributes are 'left, 'right, 'high, 'low and 'length. * The Attor bute 'left yields the leftmost value of type and 'right the right most. * The attainante 'high yields the grocatest value for type. * For Enumerated types, this value is the Same as "right.

* Table Boos below shows attributes and their return values.

Return value	Attribute description
Count'left = D States'left = idle	'left yields leftmostvalue & type.
Word left = 15 (ount'right = 127 states 'right = write Word Irigh = 0	bright yicids rightmost value of type
Count ! high = 127 States ! high = wonife	high yields greatest value & type
Word ' high = 15 Count' LOW = 0 States' LOW = idle ind / LOW = 0	low yields the lowest value of type
Word 10W =0 Count 1 length = 128 States 1 length = 4 Word 1 length = 16	l'length yields the number of elementa in a constrained and

17EC53 - VERILOG HDL

# ATTENDANCE

		ATTENDANCE	-			-			_
			30/7	31/7	5/8	7/8	14/8.	16/	7
SI.	Reg.No.	Name	3	2	3	3	4	G	11
No.	1		1	2	3	4	5	6	7
/1	17EC 004	AJAY MR	1	2	3	4	5	6	7
12	17ECCO5	AMRUTHA V	1	2	3	4	5	6	7
V 3	17EC008	ANSHU KUMARI H	1	2	3	9	5	. 6	7
14	17EC009	ANUSHA A	l	2	3	4	5	6	1
5	IZECOLO	APOORVA S	l	2	3	4	5	6	7
6	17ECO14	BHANUSHREE M	1	2	3	4	5	6	7
1	I7ECOIS	BHAVANA HE	1	2	3	4	5	6	7
8	17ECO16	BHAVANA M	ι	2	3	4	5	6	7
V9	I7ECOIT	BLESSING SHAROONS	1	2	3	4	5	6	7
10	17EC019	CHANDANA S	1	2	3	4	5	6	7
V11	17EC020		1	2	3	4	5	6	
V 12	ITECO21	DARSHAN A RAO	1	2	3	4	5	6	5
V13	17EC024		1	2	3	4	5	6	7
14	17EC026	HARSHINI S	1	2	3	4	5	6	7
15	17EC027		1	2	3	4	5	6	7
V 16	17EC029		l	2	3	4	5	6	-
V17	17EC031		1	2	3	4	5	6	1
V18	17EC033	-	1	2	3	4	5	6	7
119	17EC035		1	2	3	4	5	6	17
20	17EC036		t	,	2	3	4	5	
V21		PRADEEPA	1	å		2	3	4	5
22		PRIYANKA R	1	2	3	4	5	6	
V23		RACHITHA HK	1	2	3	4	5	6	7
24		RAKESH S	1	2	3	4	5	6	
25	17E CO 46	0	1	2		3	4	5	
	No. of Abs.					1		/	
	Initials		200	Ver	nes	Ve	- Ves	920	- (

# ASSESSMENT

201	101	10-71	001	logi	90	lad		[				-	-	1_	
20/8	2%	27/8	28/	29/8	30/8	3%	13	ZIA	Ta	ot Ma	arlea			Sessional Marks	
2	5	1	3	5	1	4	10	%	79	st Ma		30	10	ession	Remarks
8	9	10	11	12	13	14	60	of Attendance	1 50	2 50	3 50		ASS	540	
8	9	10	11	12	13	14		19	43	19	49	23	10	33	Alay M.R
¢	9	10	11	12		13		30	45	30	41	24	10		Amuutha.V
8	9	10		17	12	13		24	44	24	40	22	10	32	A when know t
8	٩	10	11	12	13	14		08	AB	28	23	11	10	21	THE WOOD ALONG
8	9	10	11	12	13	14		09	25	09	28	13	10	23	
8	9	10	11	12	13			28	46	28	40	23	10	33	BrandheerM
8	9	10.	U	12	13	14		10	40	10	41	19	10	29	Bhavana
8	.9	10	11	12	13	14	24	12	37	12	37	18	10	28	Bhavana Bhavano. H
8	9	10	1	4	12	13		16	41	16	44	21	10	31	Blagh
8	9	10	11	12		13		19	35	19	27	17	10	27	Chandona's
8		9	10	11	12	13		13	46	13	32	19	10	29	a) Wua
8	9	10	11	12	13	14		10	31	10.	31	15	9	24	Dorshan. D. Rev
Q	9	10	11	12	13	14	5	14	49	14	44	32	18	30	8. Dinya
8	9	10	11	12	13			24	46	24		23	09	32	Hogstimis
	8	9	10	11	12	13	1	29	39	29	34	21	10	31	Jiwandupsayer
.8	9	10	11	12	13	14		08	15	08.	22	9	10	19	<u>6</u>
¢	9	10	11	12	13	14 .		26	39	26	42	22	09	31	Wah.R
8.	9	10	<i>ll</i>	12	13	14		25	48	30	. 44	25	10	35	Tpla-S.
8	9	10	11	12	13	14		36	44	36	36	24	10	34	N Open prive
7	8	9	10	11	12	13		17	42	17	46	21	10	31	Ninish Pres
6	7	8	9	10	11	12		18	30	18	26	15	9	24	Vaderfe
2	7	8	9	18	4	12		10	45	10	33	18	10	28	Reyankert
8	9	10	11	12	13	14		10	36	10	37	17	9	26	Kachathak
•		8	9	10	11	12		26	39	26	79°	13	10	33	
7		8	9	10	11	12		18	41	18	49	22	9	31	Brijith N.G
-10	1/0	10	20	0/0		0/4		040	-	-	,				
May.	W	Vie	Var	Ven	Ver	Ver		Vag.	行わり	light	No.				

# ATTENDANCE

			39/7	31/7	5/8	7/8	14/8	14/8	1
SI. No.	Reg.No.		3	2	3	3	4	4	T
26	17 EC049	RESHMA CA	1	2	3	4	5	6	ŧ
27	17EC 052		1	2	3	4	5	6	t
28 *		SAQIBA TABASSUM	i	2	3	4	5	6	t
29 🗸		SHASHANK BR	l	2	3	4	5	6	t
30 🗸	17EC062		1	2		3	4	5	t
31 🗸	17EC063		v	1	2	3	4	5	t
32 🗸	17EC064		1	2	3	4		5	t
33 V	A	SYED SAMEER PASHASB	L	2	3	4	5	8	t
34 🗸	17EC067		l	2	3	4	5	6	t
35 N	ITECOTO		r	1	2	3	4	5	t
36 🖸	15EC032		0	t	2	3	4	5	t
37 🗸	ILECOOD	CHANDANA CJ	1		2	3	4	5	t
38 V		E. VIJAYALAKSHMI		1	2	3	4	5	-
39 V	ILEC016	JEEVAN S	*		1	2	3	4	t
40	ILECOL7	KAUSHIK A NotEligible	+	2	3	4	-5	6	L
41	17FC059	SHAYANA M.	6	t	2	3	4	5	T
42 1	T7ECO65		1		2	3	4	5	T
43	17ECU2	PRAVEEN	,	1	2	3	4	5	T
44 V	I7EC11	ARATHI		1	2	3	4	4	
45 V	17EC32	MADHUSUDHAN	1	2	3	4	5	6	Γ
46 🗸	17EC58		ι	2	3	4	5	6	Γ
47		LANESMERIN-					-		
48	12.5. 14								
49	dans 6	FAST MADE & R.							
50	Marchi	AND							
	No. of Abs.								
	Initials		Var	1/00	260	900	Va	Vai	

# ASSESSMENT

								001001							
29/8	21/8	27/8	28/8	2%	30/8	3%	AB							onal Ks	
2	5	1	3	5	1	4		%		st Ma		30	10	Sessional Marks	Remarks
8	9	10	11	12	13	14	60	of Attendance	1 50	2 50	3 50		Assu	040	
	8	9	10	ti	12	13		21	48	21	29	22	10	32	Parlingon
8	9	10	11	12	13	14		30	39	30	34	21	10	31	Resumach Loopa . K.M
8	9	10	11	12	13	6		AB	AB	AGEN2	38	10	10	20	
8	9	10	11	12	13	-0		39	37	39	47	25	9	34	Showhunk B.R
7	8	9	10	11	12	13		14	39	14	33	18	10	28	Soundaryav
7	2	8	9	10	11	12		19	39	19	40	20	10	30	<u> </u>
•		7	8	9	10	11		08	21	08	13	9	10	19	1. 8
8.	9	10	L1	12	13	14	1	39	46	39	45	27	10	37	Sala
8	9	10	11		12	13		07	29	07	42	16	10	26	Januskine C
6	7	8	9	10	4	12		15	35	15	22	15	8	22	Af.
7	8	19	10	lt	12			AB)	34	AB	08	7	3	10	Lanes
6	7	8	9	10	11	12		20	20	20.	22	7	5	12	charlow
7	.6	9	10	4	12	13		08	31	08	26	9	5	14	Philipp
6	7	8	9	10	11	12		08	27	08	28	9	5	14	Jewoos
-	8	9	10	11	12-	13	1	4	26	AB	No	te	tigit	sters	the
7	8	9	10	11	12	13		02	34	02	40	16	10	26	Maupine S
7	8	9	10	lt	12	13		2010	33	Fac	14	10	8	19	No.
7	8	9	10	11	12	13		OLr	24	04	A	09	19	18	63
6	7	8	9	10	11	12		10	37	10	31	16	10	26	Arathi. A
> 1	8	9	10	U	12	13		26	20	26	06	11	8	19	Hellnuchan
8	9	10	11	12	13	14		08	25	08	37	-15	9	24	shashiral. T
	-														A
									12.4						
									35						
2/0	olo	260	2/4	260	260	01		040	alas	ole	aler			760	24
Va	the	per .	la	DEE	our	Vee.		Vie	( Chila	Vezi	, they			Vec	

# **RECORD OF CLASS WORK**

Date	Period	Topics Covered
30/7/2019	3	Modulet: chapter 1: Jubroduction to VHDL & Verileg.
31/7/2019	2	Evolution of CAD Design, Emergence of HDL
5/8/2019	3	typical disign flow, Importance
7/8/2019	3	Cart tuporteepe of HDL Popularity of HDL
14/8/2019	4	Trends in HDL, Revision.
16/8/2019	4	Tutre or disign flow
19/8/2019	2	Top-down & Bottom-up Design Her
20/8/2019	2	4 bit Ripple Country Country
21/8/2019	5.	Modules and tustances.
27/8/2019	1.	Components of Simulation.
28/8/2019	3	Cent. Simulation Verilog Code Stepe
29/8/2019	5	example of stimulus block & disignable
30/8/2019	1,4	Jupo dat mar thank to the
31/8/2019	1	Number specification, strings, I deutifier,
3/9/2019	3,5	Keywords, iscaped I dutifier,
12/9/2019	3	Data types, Value sets, Nets, Register, Vecter
13/9/2019	5	Integer, Real and Time Register
16/9/2019	3	Ren Array, Memories, parameters,
17/9/2019	1,4	System tasks & Compiler diractives.
19/9/2019	3	Chapter-4 Modules and pork Components
20/9/2019	3	Port declaration, Port Connecting Rules.
21/9/2019	2	throtactical Names, Connecting posts to experience
23/9/2019	2	Revisian. Modules: chapters
25/9/2019	3	Gate level Module-eg, ANDIOR, buffmot
(R)	Vostra Moran	HOD'S Signature

Teachers Signature

**HOD'S Signature** 

# **RECORD OF CLASS WORK**

Date	Period	Topics Covered
25/9/2019	4	Cand, buffmot, buffif, notif, Among ist
26/9/2019	4	Grate level Kultiplexen, libit RCFA
27/9/2019	2	stimulus, Grate delags - two offeliles
30/9/2019	2	Rise time, fall time, min, Mox, typ
30/9/2019	5	programas on delay in galas, emer
1/10/2019	1	programas on delay in galas, emer chapter: 6 Dataflow modeling: Continious A
10/10/2019	3	Implicit declarcebien, Regular Asiguet deles
14/10/019	5	Net declaration delay , op Tuplicit delay.
15/10/2019	1	Esepussias, operators and operandes.
17/10/2019	3	escamples of Arithmatic, logical,
18/10/2019	3	unary operators escupio, logi Relatione
24/10/2019	1,3	equality biture, reductions shift
31/10/2019	2	lencality bitwice, meductices - shift lencalination, Repliceticus, Conditional
1/11/2019	2	100: 4:1 Mux dataflow model
6/uporg	4	
2/11/2019	1,2	Ase: 4 pit fullAdder deetaflow Horly. Module 4: Between douples 7: Behavived Hortility : Structured process
8/11/2019	3	initial statement, Always skatemate
9/11/2019	3	procedural i Blocking & Non Blocking Assige
11/11/2019	2	Timber Cartrol : Delay - Based Timing Cart
13/11/2019	3	Event - Based Timing Cartol
14/4/2019	3	Level sensitive Timing Central
15/11/2019	3	Conditional Statemts
16/4/2019	2	Multiway Branching Case, Loops.
Additional	esebra	for while, repeat, cases, sequenter

Tostere There

Teachers Signature

HOD'S Signature



## DEPARTMENT OF MECHANICAL ENGINEERING

### CIRCULAR

### Ref No: CEC/ME/DAC/ACY 2019-2020/01

Date: 25-07-2019

This is to inform the members of Department Advisory Committee that meeting is scheduled on 25-07-2019 at 10: 00 AM in ME department.

Agenda:

- Planning of Internships & Project work for 7th semester students.
- Involving students in technical activities.
- Conducting workshop/seminar/guest lectures.
- Planning to conduct value added course for students.
- Planning of Course preference, Course allocation & Work load distribution for upcoming odd semester.

0.

Dr.S.Karunakara

HOD



### DEPARTMENT OF MECHANICAL ENGINEERING

### **Department Advisory Committee Meeting**

Date: 25/07/2019 Time: 10:00 AM Venue: ME Department

DAC Members Present:

SI. No	Member Name	Designation	Role
1 1	Dr. S KARUNAKARA	HOD	Convenor
2	Dr. UMA T R	Professor	Member
3 1	HARSHA VARDHAN U	Professor	Co-Convenor
4	ANIL KUMAR R	Assistant Professor	Member
5 5	SHRUTI NAIK	Assistant Professor	Member
6 1	VIJAY KUMAR	Assistant Professor	Member
7 5	SAMPATH H P	Assistant Professor	Member
8 F	RAKESH Y D	Assistant Professor	Member
9 5	SHIVARAJA H B	Assistant Professor	Co-Convenor
10 A	AVINASH M	Assistant Professor	Member
11 V	/EERESH NAIK	Assistant Professor	Member
12 A	Abhilash K	Design Engineer	Alumni

The Department Advisory Committee meeting was conducted at Department of ME, on 25th July, 2019, at 10 AM.

### Agenda of the Meeting:

- Planning of Internships, Project work & Technical Seminar for 8th semester students.
- Involving students in technical activities.
- Planning of AICTE activity report for 8th semester students.
- Conducting workshop/seminar/guest lectures.
- Planning to display necessary details on notice board in the labs.
- Planning of Course preference, Course allocation & Work load distribution for upcoming even semester.



### **Minutes of Meeting:**

During the Department Advisory Committee meeting, an overview of the department was provided, showcasing student achievement, and faculty accomplishments and contributions. The members discussed suggestions for improvement and reviewed the meeting agenda.

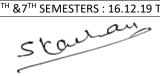
The HOD welcomed all the staff for the meeting. The following points were discussed as follows.

- The subject allotment for the Odd semester of 2019-20 and time table for the same was discussed and distributed.
- The staff members in charge of labs should arrange to display: Name of the lab, Do's and Do not's, Lab time table, List of students batches wise, list of Major equipment's, their date of purchase and last date of service
- The assignments have to be valued for marks as per the concerned scheme and to be kept along with bluebooks, attendance register and academic file.
- It was proposed to conduct a workshop, seminars & guest lecture on recent trending topics.
- The staff members were informed to conduct classes and labs regularly, to timely conduct and complete the entrusted responsibility, to actively participate in the dept and college activities and finally to take suitable actions for getting results and admissions to the dept.
- Attendance shortage list has to be given by respective class teachers and arrangements have to be made to send letters to the concerned parents.
   HOD thanked all the staff for having attended the meeting.

star

Dr.S.Karunakara

HOD



	A	UGUST 2019		SEPTEMBER 2019		OCTOBER 2019		NOVEMBER 2019	DE	CEMBER 2019
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
S	TARTING	G OF HIGHER SEMESTERS			1					
(3 rd ,5	th & 7 th S	Semesters <b>29.7.2019</b> MON)			2	GANDHI JAYANTI(DH)				
THU	1	STARTING OF FIRST SEM			3					
FRI	2				4		1	KANNADA RAJYOTSAVA(DH)		
SAT	3				5		2			
SUN	4		1		6		3		1	
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		2	
TUE	6		3		8	VIJAYA DASHAMI(DH)	5	SECOND CIE FOR FIRST SEM.	3	
WED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9		6		4	
THU	8		5	3 rd ,5 th & 7 th Semesters	10		7		5	
FRI	9		6		11		8		6	
SAT	10	2 ND SATURDAY HOLIDAY	7		12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7	
SUN	11		8		13		10		8	
MON	12	BAKRID(DH)	9		14		11		9	
TUE	13		10	MOHARAM (DH)	15		12		10	THIRD CIE FOR FIRS
WED	14		11		16		13		11	SEM
THU	15	INDEPENDENCE DAY(DH)	12		17		14		12	
FRI	16		13		18		15	KANAKA JAYANTHI(DH)	13	
SAT	17		14	2 ND SATURDAY HOLIDAY	19		16		14	
SUN	18		15		20		17		15	
MON	19		16		21		18		16	
TUE	20		17		22	SECOND INTERNAL ASSESSMENT	19		17	LAB INTERNALS FO
WED	21		18		23	3 rd ,5 th & 7 th Semesters	20	3 rd ,5 th & 7 th Semesters	18	1 st SEMESTERS
THU	22		19		24		21		19	
FRI	23		20	FIRST CIE FOR FIRST SEM.	25		22		20	
SAT	24	4 TH SATURDAY HOLIDAY	21	FINST CIE FOR FINST SEMI.	26	4 [™] SATURDAY HOLIDAY	23	4 TH SATURDAY HOLIDAY	21	LAST WORKING DAY
SUN	25		22		27		24		22	
MON	26		23		28		25		23	
TUE	27		24		29	DEEPAVALI(DH)	26	LAB INTERNALS FOR	24	VTU PRACTICAL:
WED	28		25		30		27	3 rd ,5 th &7 th SEMESTERS	25	1 ST SEMESTER:
THU	29		26		31		28		26	23.12.19 TO 3.1.2
FRI	30		27				29	LAST WORKING DAY 1 st SEM	27	THEORY EXAMS :
SAT	31		28	4 TH SATURDAY HOLIDAY			30	LAST WORKING DAY 3 RD ,5 TH &7 TH SEM	28	- 1 ST SEMESTERS : 6.1.20 TO 28.1.2020
SUN			29						29	
MON			30						30	
TUE							•		31	



ACADEMIC YEAR: 2019-20

## **Department of Mechanical Engineering**

### **COURSE PREFERENCE**

Name of the Faculty: Dr. S. Kolunationa. Designation: Profuer

Sl. No	Course Code and Name	Year/Semester
1	15 ME71 [Energy	IV./VII
2.	13 EUID LIS / Engineering	JI
į	(****	Ni IV h
2		

Signature of Faculty



ACADEMIC YEAR:

# **Department of Mechanical Engineering**

**COURSE PREFERENCE** 

Name of the Faculty: Dr. Unil, T. R Designation: Profues,

Sl. No	Course Code and Name	Year/Semester
1	Control Engineering ISME73	IV VAN
J.	Management & Economics 7 MES	VIII V
		$h = \frac{1}{2} \left( \frac{1}{2} \right)^{2}$

Signature of Faculty



# ACADEMIC YEAR: 2019-20(ODD)

# DEPARTMENT OF MECHANICAL ENGINEERING

# **COURSE ALLOCATION**

Sl.No	Name of the Faculty	Course Code and Name	Year/	Signature
			Semester	
1	Dr. S KARUNAKARA	15ME754, 17ME51	VII, V	ď.
2	Dr. UMA T R	15ME73, 17ME56	VII, V	mile
3	HARSHA VARDHAN U	18ME34, 17ME51	III, V	Bul
4	ANIL KUMAR R	18ME32, 15ME741	III, VII	oh ik
5	SHRUTI NAIK	15ME73, 18ME35	VII, III	Inuti
6	VIJAY KUMAR	18ME34, 17ME54	III, V	
7	SAMPATH H P	15ME71, 18ME31	VII, III	24J-
8	RAKESH Y D	18ME33, 15ME72	III, VII	D
0	SHIVARAJA H B	18ME31, 17ME56		E.
10	AVINASH M	18ME35, 17ME51	III, V	Cm_
11	VEERESH NAIK	17ME53, 15ME72	V,VII	Veerel

500 HOD

DEPARTMENT OF MECHANICAL ENGINEERING ODD 2019-2020 TIME TABLE

SEMESTER: III ME 'A' SEC CBCS

**2018 SCHEME** 

CLASS ROOM: A307

DAY	9:00 - 10:00 AM	10:00 - 11:00 AM	11:00 - 11:15 AM	11:15 AM - 12:15 PM	12:15 PM - 1:15 PM	LUNCH	2:00 – 3:00 PM	3:00 – 4:00 PM	4:00 – 5:00 PM
MON	18MAT31	18ME35		18ME32	18ME35		18ME34	18ME35	
TUE	18ME36B	18ME32		18MAT31	18ME36B	L	18MEL37B		
WED	18ME35	18ME33	<b>EAK</b>	18MAT31	18ME32	U	18ME35	18ME33	
THU	THU         18ME34         18MAT31		BREAK	18ME33	18ME32	N C	1	8MEL38B	
FRI	18ME33	18ME34		18ME36B	18ME36B	H			
SAT		RTS/YOGA PEK359/BYO							

SUBJECT CODE	SUBJECT NAME	SUBJECT HANDELED
18MAT31	Transform calculus, fourier series and Numerical techniques	Prof Vanitha G R
18ME32	Metal Casting, Forming & Joining process	Prof Anil Kumar R
18ME33	Material Science and Engineering	Prof Rakesh Y D
18ME34	Basic Thermodynamics	Prof Harshavardhan U
18ME35B	Metal cutting and forming	Dr Uma T R
18ME36B	Mechanical Measurements and Metrology	Prof Shruti Naik
18MEL37B	Mechanical Measurements and Metrology lab	Prof Shruti Naik
18MEL38B	Foundry, Forging and Welding lab	Prof Anil Kumar
Starte	•	

HOD, Dept. of ME

DEPARTMENT OF MECHANICAL ENGINEERING ODD 2019-2020 TIME TABLE

SEMESTER: V ME 'A' SEC CBCS

### 2017 SCHEME

### CLASS ROOM: A306

	1	2	TEA	3	4	LUNCH	5	6	7
DAY	9:00 AM	10:00AM	11:00 AM	11:15 AM	12:15 PM	1:15 PM	2:00 PM	3:00 PM	4:00 PM
	10:00 AM	11:00 AM	11:15AM	12:15 PM	1:15 PM	2:00 PM	3:00 PM	4:00 PM	5:00 PM
MO N	17ME51	17ME554		17ME554	17ME54				
TUE	17ME53	17ME54		17ME562	17ME52		17ME53	17ME562	
WED	17ME554	17ME562	B R	17ME51	17ME54	$egin{array}{c} L \ U \end{array}$	17ME554	17ME51	
THU	17ME52	17ME53		17ME52	17ME54	N C			
FRI	17ME52	17MEL581	K	17MEL53	17ME51	Н			
SAT	BNSK359/B	RTS/YOGA PEK359/BYO			EK359/BYOK				
	K.	359		35	59				

SUBJECT CODE	SUBJECT NAME	SUBJECT HANDELED
17ME51	Management & Economics	Prof Shruti Naik
18ME52	Design of Machine Elements I	Prof Sampath H P
18ME53	Dynamics of Machines	Veeresh Naik
18ME54	Turbo Machines	Prof Vijay Kumar
18ME554	Non Traditional Machining	Prof Anil Kumar
18ME562	Energy & Environment	Dr Uma T R
18MEL57	Fluid Mechanics Lab	Prof Harshavardhan U
18MEL58	Energy Conversion Lab	Prof Sampath H P

stouran HOD, Dept. of ME

DEPARTMENT OF MECHANICAL ENGINEERING ODD 2019-2020 TIME TABLE

SEMESTER: VII ME 'A' SEC CBCS

**2017 SCHEME** 

**CLASS ROOM: A305** 

DAY	1	2	TEA	3	4	LUNCH	5	6	7
MON	15ME71	15ME754		15ME72	15ME741		DI	ESIGN LAB	•
TUE	15ME72	15ME71		15ME73	15ME754		MAJOR P	IASE-I	
WED	15ME73	15ME72	K	15ME754	15ME741	L U	15ME754	15ME73	
THU	15ME741	15ME71	BREAK	15ME72	15ME73	N C			
FRI CIM LAB			15ME71	15ME741	Н	DEPART	MENT ACT	IVITY	
SAT	NSS/SPORTS/YOGA BNSK359/BPEK359/BYO K359			NSS/SPOR BNSK359/BPE					

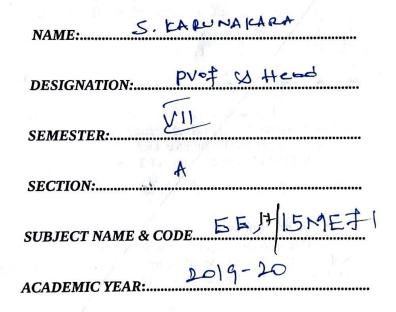
SUBJECT CODE	SUBJECT NAME	SUBJECT HANDELED
15ME71	<b>Control Engineering</b>	Dr. Uma T R
15ME72	CAD/CAM	Prof Rakesh Y D
15ME73	Total Quality Management	Shruti Naik
15ME741	Additive Manufacturing	Prof Anil Kumar
15ME754	Non-Conventional Energy Resources	Dr. S Karunakara
15MEL76	CIM LAB	Prof Shruti Naik
15MEL77	DESIGN LAB	Prof Sampath H P
15MEP78	PROJECT PHASE I	Prof Harshavardhan U
15MEP78 Stour		

HOD, Dept. of ME

(Doddakallsandra, Off Kanakapura Road, Bangalore-560061) Department of Mechanical Engineering



# **Faculty Academic File**



				Ċ	4	<b>S</b>			and and a	-10
1. Ale		CITY ENGIN	VEERI	NG COLLEGE, BENGALU	RU-5	60061. ACADEMIC CAL	ENDA	R 2019-20 (ODD SEM	)	
	A	JGUST 2019		SEPTEMBER 2019		OCTOBER 2019		NOVEMBER 2019		DECEMBER 2018
DAY	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT	Date	EVENT
CI ANT MILL	AND THE ADDRESS	OF HIGHER SEMESTERS	Standard State		1					
		emesters 29.7.2019 MON)			2	GANDHI JAYANTI(DH)			-	
THU	1	STARTING OF FIRST SEM			3					
FRI	2		P.		4		1	KANNADA RAJYOTSAVA(DH)	Contraction of the	
SAT	3		Frank - C		5	A CONTRACTOR OF A CONTRACT	2		4	2 2
SUN	4		1		6	The second second second	3		1 2	
MON	5		2	VINAYAKA CHATURTHI(DH)	7	MAHALAYA AMAVASYA(DH)	4		3	
TUE	6		3		8	VIJAYA DASHAMI(DH)	5 6		4	
WED	7	FIRST SEM INDUCTION	4	FIRST INTERNAL ASSESSMENT	9	Technical Talk for 3 rd and 5 th	galant, m. of Sp. 198		1. 194.20	1
THU	8		5	3 rd ,5 th & 7 th Semesters	10	sem	7		5	PRACTICAL EXAM
	0		6	the second s	11	5611	8		6	1st ,3rd ,5th & 7th
FRI SAT	9 10	2 ND SATURDAY HOLIDAY	7	Technical Talk for 7th sem	12	2 ND SATURDAY HOLIDAY	9	2 ND SATURDAY HOLIDAY	7	SEMESTERS
SUN	11	2 SATORDAT HOLIDAT	8		13		10	and the second of the second	8	3 13
MON	12	BAKRID(DH)	9		14		11		9	DEC 2019
TUE	13	D/ 11112 (D.1.)	10	MOHARAM (DH)	15	Industrial visit for 5 th sem	12		10	7 th SEM.
WED	14		11		16		13		11	6-14,
THU	15	INDEPENDENCE DAY(DH) .	12	FIRST CIE FOR FIRST SEM.	17	•	14		12	DEC 2018
FRI	16		13		18	th	15	KANAKA JAYANTHI(DH)	13	
SAT	17		14	2 ND SATURDAY HOLIDAY	19	Project Phase-1 for 7 th sem	16 ,		14 15	and a second state of the second second
SUN	18	States States	15	bit a second second	20	The demonstration of the second second	17		15	
MON	19		16	Industrial visit for 3 rd sem	21 22	SECOND INTERNAL ASSESSMENT	18 19	THIRD INTERNAL ASSESSMENT	17	
TUE	20		17		and the second	3 rd ,5 th & 7 th Semesters	20	3 rd ,5 th & 7 th Semesters	18	-
WED	21		18		23	SECOND CIE FOR FIRST SEM.	1.007 (PO18-122)	THIRD CIE FOR FIRST SEM	the State and the second	-
THU	22		19		24		21		19 20	THEORY EXAMS
FRI	23		20		25	TH CATHOR WINDLING	22	4 TH SATURDAY HOLIDAY	20	
SAT	24	4 TH SATURDAY HOLIDAY	21	Parents and Teacher meeting	26	4 TH SATURDAY HOLIDAY	23 24	4 SATUNDAT HULLDAT	22	1 st Sem
SUN	25		22	The second s	27 28		24		23	16.12.2019 to
MON	26		23		28	DEEPAVALI(DH)	25	LAB INTERNALS FOR	24	4.01.2020
TUE	27		24 25		30		20	LAB INTERNALS FOR 1 st ,3 rd ,5 th &7 th SEMESTERS	25	and ath a
WED	28		25		31		28	•	26	3 rd -7 th Sem 16.12.2019 to
THU	29		1 RA - 43 - 2 -		1		29	LAST WORKING DAY 1 SEM	27	07.02.2020
FRI	30		27				16		1000000	07.02.2020
SAT	31	Technical talk by Dr. Arunakumar on Fatigue	28	4 TH SATURDAY HOLIDAY			30	LAST WORKING DAY 3 RD ,5 TH &7th SEM	28	
SUN	CONTRACTOR N		29				4		29 30	
MON	r yeseallar 1		30						30	
TUE		5 Kento	^						51	

,

#### ENERGY ENGINEERING

		0 14	L-T-P		sment	Exam
Course	Code	Credits	L-I-P	SEE	CIA	Duration
Energy Engineering	15ME71	04	3-2-0	80	20	3Hrs

#### Courselearning objectives is to

- Understand energy scenario, energy sources and their utilization .
- Learn about energy conversion methods and their analysis
- Study the principles of renewable energy conversion systems
- Understand the concept of green energy and zero energy. .

Thermal Energy conversion system: Review of energy scenario in India, General Philosophy and need of Energy, Different Types of Fuels used for steam generation, Equipment for burning coal in lump form, strokers, different types, Oilburners, Advantages and Disadvantages of using pulverized fuel, Equipment for preparation and burning of pulverized coal, unit system and bin system. Pulverized fuel furnaces, cyclone furnace, Coal and ash handling, Generationof steam using forced circulation, high and supercritical pressures. Chimneys: Natural, forced, induced and balanced draft, Calculations and numerical involving height of chimney to produce a given draft. Coolingtowers and Ponds. Accessories for the Steam generators such asSuperheaters, De-superheater, control of superheaters, Economizers, Air preheatersand re-heaters.

#### 9 Hours

Diesel Engine Power System: Applications of Diesel Engines in Power field. Method of starting Diesel engines. Auxiliaries like cooling and lubricationsystem, filters, centrifuges, Oil heaters, intake and exhaust system, Layout ofdiesel power plant.

Hydro-Electric Energy: Hydrographs, flow duration and mass curves, unithydrograph and numerical. Storage and pondage, pumped storage plants, low, medium and high head plants, Penstock, water hammer, surge tanks, gates and valves. General layout of hydel power plants. 7 Hours

Solar Energy: Fundamentals; Solar Radiation; Estimation of solar radiation on horizontal and inclined surfaces; Measurement of solar radiation data, Solar Thermal systems: Introduction; Basics of thermodynamics and heat transfer; Flat plate collector; Evacuated Tubular Collector; Solar air collector; Solar concentrator; Solar distillation; Solar cooker; Solar refrigeration and air conditioning; Thermal energy storage systems, Solar Photovoltaic systems: Introduction; Solar cell Fundamentals; Characteristics and classification; Solar cell: Module, panel and Array construction; Photovoltaic thermal systems

**8 Hours** 

Module - IV

Wind Energy: Properties of wind, availability of wind energy in India, windvelocity and power from wind; major problems associated with wind power, wind machines; Types of wind machines and their characteristics, horizontaland vertical axis wind mills, coefficient of performance

Tidal Power: Tides and waves as energy suppliers and their mechanics; fundamental characteristics of tidal power, harnessing tidal energy, limitations.

Biomass Energy: Introduction; Photosynthesis Process; Biofuels; Biomass Resources; Biomass conversion technologies; Urban waste to energy conversion; Biomass gasification.

Green Energy: Introduction: Fuel cells: Overview; Classification of fuel cells; Operating principles; Fuel cell thermodynamics Nuclear, ocean, MHD, thermoelectric and geothermal energy applications; Origin and their types; Working principles, Zero energy Concepts

### **8 Hours**

#### **Course Outcomes**

At the end of the course, the student will be able to:

- Summarize the basic concepts of thermal energy systems,
- Identify renewable energy sources and their utilization.
- Understand the basic concepts of solar radiation and analyze the working of solar PV and thermal systems. Understand principles of energy conversion from alternate sources including wind, geothermal, ocean, biomass, biogas.
- Understand the concepts and applications of fuel cells, thermoelectric convertor and MHD generator.
- Identify methods of energy storage for specific applications

#### **TEXT BOOKS:**

- B H Khan, Non conventional energy resources, 3rd Edition, McGraw Hill Education
   Principles of Energy conversion, A. W. Culp Jr., McGraw Hill. 1996

#### **REFERENCE BOOKS:**

- 1. S.P. Sukhatme, Solar Energy: principles of Thermal Collection and Storage, Tata McGraw-Hill (1984).
- 2. C. S. Solanki, "Solar Photovoltaic's: Fundamental A pplications and Technologies, Prentice Hall of India, 2009.
- L.L. Freris, Wind Energy Conversion Systems, Prentice Hall, 1990. 3.

Scheme of Examination: Two question to be set from each module. Students have to answer five full questions, choosing at least one full question from each module.

C

# ENERGY ENGINEERING DAY WISE LESSON PLAN

ÆEK	DAY	MODULE	TOPICS PLANED	BLOOM'S TAXONOMY LEVEL (L)	COURSE OUT COME (CO)
3	1		Solar Energy: Fundamentals; Solar Radiation.	L1, L2	CO1, CO2
	2		Estimation of solar radiation on horizontal and inclined surfaces; Measurement of solar radiation data.	L1, L2	CO1, CO2
1	3		Solar Thermal systems: Introduction; Basics of thermodynamics and heat transfer.	L1, L2	CO1, CO2
	4		Flat plate collector; Evacuated Tubular Collector.	L1, L2	CO1, CO2
	5	ш	Solar air collector; Solar concentrator; Solar distillation; Solar cooker.	L1, L2	CO1, CO2
	6		Solar refrigeration and air conditioning; Thermal energy storage systems.	L1, L2	CO1, CO2
2	7		Solar Photovoltaic systems: Introduction; Solar cell Fundamentals.	L1, L2	CO1, CO2
	8		Characteristics and classification; Solar cell: Module, panel and Array construction.	L1, L2	CO1, CO2
	9		Photovoltaic thermal systems.	L1, L2	CO1, CO2
	10		Wind Energy: Properties of wind, availability of wind energy in India, wind velocity and power from wind.	L1, L2	CO1, CO2
3	11		Major problems associated with wind power, wind machines.	L1, L2	CO1, CO2
	12	1	Types of wind machines and their characteristics, horizontal and vertical axis wind mills.	L1, L2	CO1, CO2
	13	IV	coefficient of performance of a wind mill rotor & Numerical Examples.	L3, L4,L5	CO1, CO2
i i	14		Numerical Examples.	L3, L4,L5	CO1, CO2
4	15		Tidal Power: Tides and waves as energy suppliers and their mechanics.	L1, L2	CO1, CO3
1	16		fundamental characteristics of tidal power.	L1, L2	CO1, CO3
	17		harnessing tidal energy, limitations.	L1, L2	CO1, CO3
	18		Biomass Energy: Introduction; Photosynthesis Process.	L1, L2	CO1, CO2
5	19		Biofuels; Biomass Resources; Biomass conversion technologies.	L1, L2	CO1, CO2
	20		Urban waste to energy conversion; Biomass gasification.	L1, L2	CO1, CO2
	21	v	Green Energy: Introduction: Fuel cells: Overview; Classification of fuel cells.	L1, L2	CO4
6	22		Operating principles.	L1, L2	CO4
v	23		Fuel cell thermodynamics Nuclear, ocean, MHD.	L1, L2	CO4
	24		thermoelectric and geothermal energy applications.	L1, L2	CO4
	25		Origin and their types; Working principles, Zero energy Concepts.	L1, L2	CO4

~

	.6		Diesel Engine Power System: Applications of Diesel Engines in Power field.	L1, L2	CO4
Ĺ.	27		Method of starting Diesel engines. Auxiliaries like cooling and lubrication system, filters.	L1, L2	CO4
	28		Method of starting Diesel engines. Auxiliaries like centrifuges, Oil heaters, intake and exhaust system.	L1, L2	CO4
	29		Layout of diesel power plant.	L1, L2	CO1, CO3
8	30	п	Hydro-Electric Energy: Hydrographs, flow duration and mass curves, unit hydrograph and numerical.	L1, L2	CO1, CO3
• [	31		Numerical Examples.	L3, L4,L5	CO1, CO3
	32		Numerical Examples.	L3, L4,L5	CO1, CO3
	33		Storage and pondage, pumped storage plants, low, medium and high head plants, Penstock, water hammer, surge tanks, gates and valves.	L1, L2	CO1, CO3
	34		General layout of hydel power plants.	L1, L2	CO1, CO3
9	35		Thermal Energy conversion system: Review of energy scenario in India, General Philosophy and need of Energy.	L1, L2	CO4, CO5
Ó	36		Different Types of Fuels used for steam generation.	L1, L2	CO4, CO5
1	37		Equipment for burning coal in lump form, strokers, different types, Oil burners.	L1, L2	CO4, CO5
10	38		Advantages and Disadvantages of using pulverized fuel, Equipment for preparation and burning of pulverized coal, unit system and bin system.	L1, L2	CO4, CO5
	39	I	Pulverized fuel furnaces, cyclone furnace.	L1, L2	CO4, CO5
	40		Coal and ash handling, Generation of steam using forced circulation, high and supercritical pressures.	L1, L2	CO4, CO5
	41		Chimneys: Natural, forced, induced and balanced draft.	L1, L2	CO4, CO5
11	42		Calculations and numerical involving height of chimney to produce a given draft.	L1, L2	CO4, CO5
	43	1	Cooling towers and Ponds. Accessories for the Steam generators such as Superheaters, Desuperheater.	L1, L2	CO4, CO5
	44		control of superheaters, Economizers, Air preheaters and re- heaters.	L1, L2	CO4, CO5

### Course Outcomes

At the end of the course, the student will be able to:

Summarize the basic concepts of thermal energy systems, Identify renewable energy sources and their utilization

- Understand the basic concepts of solar radiation and analyze the working of solar PV and thermal systems.
- Understand principles of energy conversion from alternate sources including wind, geothermal, ocean, biomass.
- Understand the concepts and applications of fuel cells, thermoelectric convertor and MHD generator.
- Identify methods of energy storage for specific applications

### **TEXT BOOKS:**

- 1. B H Khan, Non conventional energy resources, 3rd Edition, McGraw Hill Education
- 2. Principles of Energy conversion, A. W. Culp Jr., McGraw Hill. 1996



startar

### FIRST INTERNAL TEST

#### PROGRAMME: MECHANICAL ENGINEERING COURSE NAME: ENERGY ENGINEERING SEM: VII Duration: 1.30 Hrs

DATE: 06/09/2019 TIME: 10.30-12.00

MAX MARKS: 40

3	Note: Answer any FIVE questions choosing atleast one from	each Pa	ri.	DEMO
SI.No	PART – A	Marks	CO'S	BT'S
1.	Discuss the modern layout of Thermal power plant	10	CO1	BT1, BT2
// area/	OR			
2.	Classify coal, composition and its uses	10	C01	BT1, BT2
	PART – B		and a	
3.	Explain the different types of circulation system adopted in boilers	10	C01	BT1, BT2
	OR			
4.	Explain with a neat sketch diesel power plant	10	CO1	BT1, BT2
A	PART-C			PA-1
5.	Discuss in detail any two lubricating systems	10	CO2	BT1, BT2
	OR			
6.	What are the different methods of fuel injection system used in diesel power plant	10	CO2	BT1, BT2
0.91	PART-D			
7.	With neat sketches classify different hydro -electric power plants based on heads	10	CO2	BT1, BT2
	OR			27
8.	Draw a neat layout of hydroelectric power plant and discuss its important parts	10	CO2	BT1, BT2
8.01	PART-E		Setter	i el 2 odi
9.	Explain the different types of gates used in hydroelectric power plants	10	CO2	BT1, BT2
	OR			
10.	What is meant by water hammer Explain different types of surge tanks?	10	CO2	BT1, BT2

### Blooms Taxonomy Levels (BTL) BT2- Understanding BT3 – Applying BT4 – Analyzing BT5- Evaluating

Course outcomes(CO's)

()

14

CO1- Explain the various approaches of TQM.

CO2- Infer the customer perception of quality.

# CITY ENGINEERIN COLLEGE DEPARTMENT OF .Mechanical

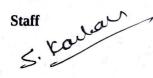
### SCHEME FOR VALUATION

**Semester & Section:** 

Internal Test ____

Date: 6 9 109

Question No.	Details of the Answer	Marks Distribution	Total Marks
1.	1 ayout therad plant Explanation	64	10
2.	cray col	6 } 4 }	10
3.	circulation in boilemp 3-types	9-117	10
٥	Statch Diesel layent Part Eap	41	10
	2 lubriceding Sup	5×2	10
.ک		3×3	10
6.	3 nethods of field p. plant	Sec. 20 March	
7	Hydro Elect p. plants - crash fiction	3+3+	15
8-	Hydro P. Plant layout parts Discuppie	4	10
٩.	TYPE of hoter Hypers p plant	3+3+4	P 10
10-	water herrow y surveye fact	4 6	10



HOD Lar



## <u>CITY</u> **ENGINEERING COLLEGE BANGALORE - 62**

500

## SECOND INTERNAL TEST

### PROGRAMME: MECHANICAL ENGINEERING **COURSE NAME: ENERGY ENGINEERING** SEM: VII **Duration: 1.30 Hrs**

G

22

Marks: 100

016

DATE: 21/10/2019 TIME: 10.30-12.00

MAX MARKS: 50

Dur	ation: 1.30 Hrs Note: Answer any FIVE questions choosing atleast one from	each Pa	rt.	
SI.No	PART – A	Marks	CO'S	BT'S
1.	With a neat sketch explain solar flat plate collector.	10	C01	BT1, BT2
	OR			
2.	With a neat sketch explain evacuated tube collector.	10	C01	BT1, BT2
-	PART – B			
3.	With neat sketches explain any two solar applications.	10	C01	BT1, BT2
-	OR	and the second	1	
4.	Explain briefly about the working principle of photovoltaic cell.	10	CO1	BT1, BT2
1.00	PART-C			N 175
5.	List down the advantages and limitations of solar energy and winged energy with reasons.	10	CO2	BT1, BT2
	OR			n na star star star star star star star sta
6.	Describe the Principle behind harnessing wind energy and how it is useful to mankind.	10	CO2	BT1, BT2
	PART-D		1	
7.	With neat sketches explain horizontal axis wind turbine and vertical axis wind turbine.	10	CO2	BT1, BT2
	OR			
8.	Compare horizontal and vertical axis wind turbines	10	CO2	BT1, BT2
	PART-E	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		- N - 0
9.	List down the places in India about the capacity solar energy and wind energy developed	10	CO2	BT1, BT2
	OR	1. J	No. 1	
10.	Explain briefly about the Principle, fuel, capacity, advantages and limitations of any four power plants	10	CO2	BT1, BT2

Blooms Taxonomy Levels (BTL) BT1-Remembering, BT2- Understanding BT3 – Applying BT4 – Analyzing BT5- Evaluating

2 Tert

Question **Details of the Answer** Marks Total **Distribution** Marks No. Skutch Plate collector 4 10 ١ þ Delcustion 10 Evacuature treke collector 4 Description 5 2. 10 5+2 2 Splar Applications 3. a 2 6 1 10 principle IVL Explanation 4. 10 ADV) Distor 5 } 5 Solar ____ 6) principle Wind Energy 10 Worden -6, 10 H. H. Wind TUR WE -52 7  $\mathcal{I}^{\mathcal{O}}$ 5) W.A. What I 8 10 ` ک ک Place of solar Engy Ly wind Engy 9. Fuel, copility ADV/ 1:00. 3+3 10 10 of power plants -

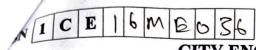


S. toubour

1

创

24/10/17



### SUB CODE: 15ME71

### CITY ENGINEERING COLLEGE THIRD INTERNAL TEST

Branch: MECHANICAL Sub Name: ENERGY ENGINEEING Sem & Sec:7TH A Max Marks: 50 Duration: 1 ½ hrs.

CED14PA

Date:18/11/2019 Time:10.30-12.00AM

Q No.	Sub Q No.	Questions	M	CO	BTL
		PART A			1
1;	a ·	With neat sketches explain single basin and double basin tidal power plant	10	<b>CO3</b>	BT1 BT2
		OR	19	5 9 . 1 7 5	DT
2	a	List down the advantages disadvantages and applications of tidal power plant	10	CO3	BT
	·	PART B	1.		BT
3•	·a	With neat sketch explain open cycle ocean thermal energy	10	CO3	BT
•		OR	20,00	r	BT
4	a	Outline the working principle of geothermal energy	10	CO3	BT
·		PART C			BT
5	a	Classify biomass energy	10	CO3	BT
•		<u>OR</u>	i M		BT
6.	a	With a neat sketch explain fixed dome digester	· 10	.CO3	BT
		PART D	1 13		BT
7	a	What is nuclear energy explain in detail about the working principle of nuclear reactor	10	CO3	BT.
		OR .			
	<u>`</u>	With a neat sketch explain open cycle MHD	10	CO3	BT
8*	a	PART E	1	A IA	
•		Write short notes on zero energy concept and fuel cell	10	.CO3	BT
.9	· a ·	Write short notes on zero energy concept and rule con-	ļ	.005	BT
•		<u>OR</u>		<u>.</u>	DT
10	- a -	Write short notes on thermoelectric power generation	10	CO3	BT

### ALL THE BEST-

Course objective	Course objective Definition
. CO3	Understand principles of energy conversion from alternate sources including wind,
	geothermal, ocean, biomass, and biogas.

S. KO.V

### CITY ENGINEERIN COLLEGE DEPARTMENT OF . Mechanical...

# SCHEME FOR VALUATION Internal Test <u>3</u>

**Semester & Section:** 

Total Marks Question **Details of the Answer** Distribution Marks No. the Single basin is Double 5+5 10 1. basin Tid-P Plet ADV DISAOV TID P. Plant A 10 6 Application > 2. Open cycle Ocean Theral Exp + layout 6+4 0 3. 10yout Geotlerned -Explanation -10 0 clossification Biprass (Anytuo) 10 545 5. ( Any two) Sketch tEXP Fix Dorce Dily 4-tb 10 6 42 10 Sketch NU cluse teender E-planstien 7 8: open and <u>rent</u> skeden 9. 200 engr Concept Freed cell 10 4 6 10 #5 10. There Electric P.P layeur 4 10 Ex plant 6 5 Karbau HOD Low Staff

1

18/11/19

Date:

**Energy Engineering** 

### Question Bank

- 1. Explain the working principle of biomass energy
- 2. Explain fixed dome plant of biomass energy
- 3. Explain the principle of ocean thermal energy
- 4. Discuss geothermal energy in detail
- 5. Explain biomass energy conversion concept
- 6. List down the advantages and disadvantages of GTE
- 7. Discuss the process principle of nuclear energy
- 8. List down the advantages and disadvantages of nuclear energy
- 9. Describe in detail about fuel cell
- 10.Explain zero energy concepts